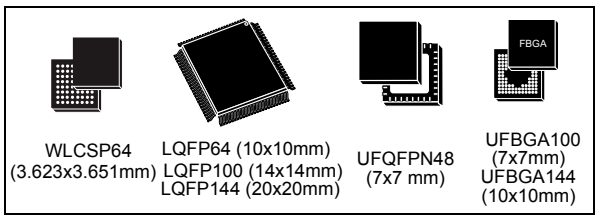
# STM32F412xE STM32F412xG

## Arm®-Cortex®-M4 32b MCU+FPU, 125 DMIPS, 1MB Flash, 256KB RAM, USB OTG FS, 17 TIMs, 1 ADC, 17 comm. interfaces

**Datasheet - production data**

## Features

- Dynamic Efficiency Line with BAM (Batch Acquisition Mode)
- Core: Arm® 32-bit Cortex®-M4 CPU with FPU, Adaptive real-time accelerator (ART Accelerator™) allowing 0-wait state execution from Flash memory, frequency up to 100 MHz, memory protection unit, 125 DMIPS/1.25 DMIPS/MHz (Dhrystone 2.1), and DSP instructions
- Memories
  - Up to 1 Mbyte of Flash memory
  - 256 Kbyte of SRAM
  - Flexible external static memory controller with up to 16-bit data bus: SRAM, PSRAM, NOR Flash memory
  - Dual mode Quad-SPI interface
- LCD parallel interface, 8080/6800 modes
- Clock, reset and supply management
  - 1.7 V to 3.6 V application supply and I/Os
  - POR, PDR, PVD and BOR
  - 4-to-26 MHz crystal oscillator
  - Internal 16 MHz factory-trimmed RC
  - 32 kHz oscillator for RTC with calibration
  - Internal 32 kHz RC with calibration
- Power consumption
  - Run: 112 µA/MHz (peripheral off)
  - Stop (Flash in Stop mode, fast wakeup time): 50 µA Typ @ 25 °C; 75 µA max @25 °C
  - Stop (Flash in Deep power down mode, slow wakeup time): down to 18 µA @ 25 °C; 40 µA max @25 °C
  - Standby: 2.4 µA @25 °C / 1.7 V without RTC; 12 µA @85 °C @1.7 V
  - $V_{BAT}$ supply for RTC: 1 µA @25 °C
- 1×12-bit, 2.4 MSPS ADC: up to 16 channels
- 2x digital filters for sigma delta modulator, 4x PDM interfaces, stereo microphone support
- General-purpose DMA: 16-stream DMA




WLCSP64 (3.623x3.651mm) | LQFP64 (10x10mm) LQFP100 (14x14mm) LQFP144 (20x20mm) | UFQFPN48 (7x7 mm) | UFBGA100 (7x7mm) UFBGA144 (10x10mm)

- Up to 17 timers: up to twelve 16-bit timers, two 32-bit timers up to 100 MHz each with up to four IC/OC/PWM or pulse counter and quadrature (incremental) encoder input, two watchdog timers (independent and window), one SysTick timer
- Debug mode
  - Serial wire debug (SWD) & JTAG
  - Cortex®-M4 Embedded Trace Macrocell™
- Up to 114 I/O ports with interrupt capability
  - Up to 109 fast I/Os up to 100 MHz
  - Up to 114 five V-tolerant I/Os
- Up to 17 communication interfaces
  - Up to 4x $I^2C$ interfaces (SMBus/PMBus)
  - Up to 4 USARTs (2 x 12.5 Mbit/s, 2 x 6.25 Mbit/s), ISO 7816 interface, LIN, IrDA, modem control)
  - Up to 5 SPI/I2Ss (up to 50 Mbit/s, SPI or I2S audio protocol), out of which 2 muxed full-duplex I2S interfaces
  - SDIO interface (SD/MMC/eMMC)
  - Advanced connectivity: USB 2.0 full-speed device/host/OTG controller with PHY
  - 2x CAN (2.0B Active)
- True random number generator
- CRC calculation unit
- 96-bit unique ID
- RTC: subsecond accuracy, hardware calendar
- All packages are ECOPACK®2

**Table 1. Device summary**

| Reference | Part number |
|---|---|
| STM32F412xE | STM32F412CE, STM32F412RE, STM32F412VE, STM32F412ZE |
| STM32F412xG | STM32F412CG, STM32F412RG, STM32F412VG, STM32F412ZG |



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# Contents


1 Introduction . . . . . 12

2 Description . . . . . 13

2.1 Compatibility with STM32F4 series . . . . . 16

3 Functional overview . . . . . 19

3.1 Arm® Cortex®-M4 with FPU core with embedded Flash and SRAM . . . . 19

3.2 Adaptive real-time memory accelerator (ART Accelerator™) . . . . . 19

3.3 Batch Acquisition mode (BAM) . . . . . 19

3.4 Memory protection unit . . . . . 20

3.5 Embedded Flash memory . . . . . 20

3.6 One-time programmable bytes . . . . . 20

3.7 CRC (cyclic redundancy check) calculation unit . . . . . 20

3.8 Embedded SRAM . . . . . 21

3.9 Multi-AHB bus matrix . . . . . 21

3.10 DMA controller (DMA) . . . . . 21

3.11 Flexible static memory controller (FSMC) . . . . . 22

3.12 Quad-SPI memory interface (QUAD-SPI) . . . . . 22

3.13 Nested vectored interrupt controller (NVIC) . . . . . 23

3.14 External interrupt/event controller (EXTI) . . . . . 23

3.15 Clocks and startup . . . . . 23

3.16 Boot modes . . . . . 24

3.17 Power supply schemes . . . . . 24

3.18 Power supply supervisor . . . . . 26

3.18.1 Internal reset ON . . . . . 26

3.18.2 Internal reset OFF . . . . . 26

3.19 Voltage regulator . . . . . 27

3.19.1 Regulator ON . . . . . 27

3.19.2 Regulator OFF . . . . . 28

3.19.3 Regulator ON/OFF and internal reset ON/OFF availability . . . . . 31

3.20 Real-time clock (RTC) and backup registers . . . . . 31

3.21 Low-power modes . . . . . 32




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3.22 $V_{BAT}$ operation . . . . . 32
3.23 Timers and watchdogs . . . . . 33
3.23.1 Advanced-control timers (TIM1, TIM8) . . . . . 35
3.23.2 General-purpose timers (TIMx) . . . . . 35
3.23.3 Basic timer (TIM6, TIM7) . . . . . 35
3.23.4 Independent watchdog . . . . . 36
3.23.5 Window watchdog . . . . . 36
3.23.6 SysTick timer . . . . . 36
3.24 Inter-integrated circuit interface (I2C) . . . . . 36
3.25 Universal synchronous/asynchronous receiver transmitters (USART) . . 37
3.26 Serial peripheral interface (SPI) . . . . . 37
3.27 Inter-integrated sound ($I^2S$) . . . . . 38
3.28 Audio PLL (PLLI2S) . . . . . 38
3.29 Digital filter for sigma-delta modulators (DFSDM) . . . . . 38
3.30 Secure digital input/output interface (SDIO) . . . . . 40
3.31 Controller area network (bxCAN) . . . . . 40
3.32 Universal serial bus on-the-go full-speed (USB_OTG_FS) . . . . . 40
3.33 Random number generator (RNG) . . . . . 41
3.34 General-purpose input/outputs (GPIOs) . . . . . 41
3.35 Analog-to-digital converter (ADC) . . . . . 41
3.36 Temperature sensor . . . . . 41
3.37 Serial wire JTAG debug port (SWJ-DP) . . . . . 41
3.38 Embedded Trace Macrocell™ . . . . . 42

**4 Pinouts and pin description . . . . . 43**
4.1 WLSCP64 pinout description . . . . . 43
4.2 UFQFPN48 pinout description . . . . . 44
4.3 LQFP64 pinout description . . . . . 45
4.4 LQFP100 pinout description . . . . . 46
4.5 LQFP144 pinout description . . . . . 47
4.6 UFBGA100 pinout description . . . . . 48
4.7 UFBGA144 pinout description . . . . . 49
4.8 Pin definition . . . . . 49



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5 Memory mapping . . . . . 74

6 Electrical characteristics . . . . . 78

6.1 Parameter conditions . . . . . 78
6.1.1 Minimum and maximum values . . . . . 78
6.1.2 Typical values . . . . . 78
6.1.3 Typical curves . . . . . 78
6.1.4 Loading capacitor . . . . . 78
6.1.5 Pin input voltage . . . . . 78
6.1.6 Power supply scheme . . . . . 79
6.1.7 Current consumption measurement . . . . . 80
6.2 Absolute maximum ratings . . . . . 80
6.3 Operating conditions . . . . . 82
6.3.1 General operating conditions . . . . . 82
6.3.2 VCAP_1/VCAP_2 external capacitors . . . . . 85
6.3.3 Operating conditions at power-up/power-down (regulator ON) . . . . . 85
6.3.4 Operating conditions at power-up / power-down (regulator OFF) . . . . . 86
6.3.5 Embedded reset and power control block characteristics . . . . . 86
6.3.6 Supply current characteristics . . . . . 87
6.3.7 Wakeup time from low-power modes . . . . . 105
6.3.8 External clock source characteristics . . . . . 107
6.3.9 Internal clock source characteristics . . . . . 111
6.3.10 PLL characteristics . . . . . 113
6.3.11 PLL spread spectrum clock generation (SSCG) characteristics . . . . . 115
6.3.12 Memory characteristics . . . . . 117
6.3.13 EMC characteristics . . . . . 119
6.3.14 Absolute maximum ratings (electrical sensitivity) . . . . . 121
6.3.15 I/O current injection characteristics . . . . . 122
6.3.16 I/O port characteristics . . . . . 123
6.3.17 NRST pin characteristics . . . . . 127
6.3.18 TIM timer characteristics . . . . . 128
6.3.19 Communications interfaces . . . . . 129
6.3.20 12-bit ADC characteristics . . . . . 141
6.3.21 Temperature sensor characteristics . . . . . 147
6.3.22 $V_{BAT}$ monitoring characteristics . . . . . 148
6.3.23 Embedded reference voltage . . . . . 148
6.3.24 DFSDM characteristics . . . . . 149



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6.3.25 FSMC characteristics . . . . . 150
6.3.26 SD/SDIO MMC/eMMC card host interface (SDIO) characteristics . . . 164
6.3.27 RTC characteristics . . . . . 166

**7 Package information . . . . . 167**
7.1 WLCSP64 package information . . . . . 167
7.2 UFQFPN48 package information . . . . . 170
7.3 LQFP64 package information . . . . . 173
7.4 LQFP100 package information . . . . . 177
7.5 LQFP144 package information . . . . . 180
7.6 UFBGA100 package information . . . . . 184
7.7 UFBGA144 package information . . . . . 187
7.8 Thermal characteristics . . . . . 190
7.8.1 Reference document . . . . . 190

**8 Part numbering . . . . . 191**

**Appendix A Recommendations when using the internal reset OFF . . . . . 192**

**Appendix B Application block diagrams . . . . . 193**
B.1 USB OTG full speed (FS) interface solutions . . . . . 193
B.2 Sensor Hub application example. . . . . 195
B.3 Display application example . . . . . 196

**Revision history . . . . . 197**



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# List of tables


Table 1. Device summary . . . 1
Table 2. STM32F412xE/G features and peripheral counts . . . 15
Table 3. Embedded bootloader interfaces . . . 24
Table 4. Regulator ON/OFF and internal power supply supervisor availability . . . 31
Table 5. Timer feature comparison . . . 34
Table 6. Comparison of I2C analog and digital filters . . . 36
Table 7. USART feature comparison . . . 37
Table 8. Legend/abbreviations used in the pinout table . . . 49
Table 9. STM32F412xE/G pin definition . . . 50
Table 10. FSMC pin definition . . . 64
Table 11. STM32F412xE/G alternate functions . . . 67
Table 12. STM32F412xE/G register boundary addresses . . . 75
Table 13. Voltage characteristics . . . 80
Table 14. Current characteristics . . . 81
Table 15. Thermal characteristics . . . 81
Table 16. General operating conditions . . . 82
Table 17. Features depending on the operating power supply range . . . 84
Table 18. VCAP_1/VCAP_2 operating conditions . . . 85
Table 19. Operating conditions at power-up / power-down (regulator ON) . . . 85
Table 20. Operating conditions at power-up / power-down (regulator OFF) . . . 86
Table 21. Embedded reset and power control block characteristics . . . 86
Table 22. Typical and maximum current consumption, code with data processing (ART accelerator disabled) running from SRAM - $V_{DD}$ = 1.7 V . . . 88
Table 23. Typical and maximum current consumption, code with data processing (ART accelerator disabled) running from SRAM - $V_{DD}$ = 3.6 V . . . 89
Table 24. Typical and maximum current consumption in run mode, code with data processing (ART accelerator enabled except prefetch) running from Flash memory- $V_{DD}$ = 1.7 V . . . 90
Table 25. Typical and maximum current consumption in run mode, code with data processing (ART accelerator enabled except prefetch) running from Flash memory - $V_{DD}$ = 3.6 V . . . 91
Table 26. Typical and maximum current consumption in run mode, code with data processing (ART accelerator disabled) running from Flash memory - $V_{DD}$ = 3.6 V . . . 92
Table 27. Typical and maximum current consumption in run mode, code with data processing (ART accelerator disabled) running from Flash memory - $V_{DD}$ = 1.7 V . . . 93
Table 28. Typical and maximum current consumption in run mode, code with data processing (ART accelerator enabled with prefetch) running from Flash memory - $V_{DD}$ = 3.6 V . . . 94
Table 29. Typical and maximum current consumption in Sleep mode - $V_{DD}$ = 3.6 V . . . 95
Table 30. Typical and maximum current consumption in Sleep mode - $V_{DD}$ = 1.7 V . . . 96
Table 31. Typical and maximum current consumptions in Stop mode - $V_{DD}$ = 1.7 V . . . 97
Table 32. Typical and maximum current consumption in Stop mode - $V_{DD}$=3.6 V . . . 97
Table 33. Typical and maximum current consumption in Standby mode - $V_{DD}$= 1.7 V . . . 97
Table 34. Typical and maximum current consumption in Standby mode - $V_{DD}$= 3.6 V . . . 98
Table 35. Typical and maximum current consumptions in $V_{BAT}$ mode . . . 98
Table 36. Switching output I/O current consumption . . . 101
Table 37. Peripheral current consumption . . . 102
Table 38. Low-power mode wakeup timings(1) . . . 106
Table 39. High-speed external user clock characteristics . . . 107
Table 40. Low-speed external user clock characteristics . . . 108
Table 41. HSE 4-26 MHz oscillator characteristics . . . 109




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Table 42. LSE oscillator characteristics ($f_{LSE}$ = 32.768 kHz) . . . 110
Table 43. HSI oscillator characteristics . . . 111
Table 44. LSI oscillator characteristics . . . 112
Table 45. Main PLL characteristics . . . 113
Table 46. PLLI2S (audio PLL) characteristics . . . 114
Table 47. SSCG parameter constraints . . . 115
Table 48. Flash memory characteristics . . . 117
Table 49. Flash memory programming . . . 117
Table 50. Flash memory programming with $V_{PP}$ voltage . . . 118
Table 51. Flash memory endurance and data retention . . . 118
Table 52. EMS characteristics for LQFP144 package . . . 119
Table 53. EMI characteristics for LQFP144 . . . 120
Table 54. ESD absolute maximum ratings . . . 121
Table 55. Electrical sensitivities . . . 121
Table 56. I/O current injection susceptibility . . . 122
Table 57. I/O static characteristics . . . 123
Table 58. Output voltage characteristics . . . 125
Table 59. I/O AC characteristics . . . 126
Table 60. NRST pin characteristics . . . 127
Table 61. TIMx characteristics . . . 128
Table 62. $I^2C$ characteristics . . . 129
Table 63. SCL frequency ($f_{PCLK1}$= 50 MHz, $V_{DD}$ = $V_{DD_I2C}$ = 3.3 V) . . . 130
Table 64. FMPI$^2C$ characteristics . . . 131
Table 65. SPI dynamic characteristics . . . 133
Table 66. $I^2S$ dynamic characteristics . . . 136
Table 67. QSPI dynamic characteristics in SDR mode . . . 138
Table 68. QSPI dynamic characteristics in DDR mode . . . 138
Table 69. USB OTG FS startup time . . . 139
Table 70. USB OTG FS DC electrical characteristics . . . 139
Table 71. USB OTG FS electrical characteristics . . . 140
Table 72. ADC characteristics . . . 141
Table 73. ADC accuracy at $f_{ADC}$ = 18 MHz . . . 142
Table 74. ADC accuracy at $f_{ADC}$ = 30 MHz . . . 143
Table 75. ADC accuracy at $f_{ADC}$ = 36 MHz . . . 143
Table 76. ADC dynamic accuracy at $f_{ADC}$ = 18 MHz - limited test conditions . . . 143
Table 77. ADC dynamic accuracy at $f_{ADC}$ = 36 MHz - limited test conditions . . . 143
Table 78. Temperature sensor characteristics . . . 147
Table 79. Temperature sensor calibration values . . . 147
Table 80. $V_{BAT}$ monitoring characteristics . . . 148
Table 81. Embedded internal reference voltage . . . 148
Table 82. Internal reference voltage calibration values . . . 148
Table 83. DFSDM characteristics . . . 149
Table 84. Asynchronous non-multiplexed SRAM/PSRAM/NOR - read timings . . . 152
Table 85. Asynchronous non-multiplexed SRAM/PSRAM/NOR read - NWAIT timings . . . 152
Table 86. Asynchronous non-multiplexed SRAM/PSRAM/NOR write timings . . . 153
Table 87. Asynchronous non-multiplexed SRAM/PSRAM/NOR write - NWAIT timings . . . 154
Table 88. Asynchronous multiplexed PSRAM/NOR read timings . . . 155
Table 89. Asynchronous multiplexed PSRAM/NOR read-NWAIT timings . . . 155
Table 90. Asynchronous multiplexed PSRAM/NOR write timings . . . 157



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Table 91. Asynchronous multiplexed PSRAM/NOR write-NWAIT timings . . . 157
Table 92. Synchronous multiplexed NOR/PSRAM read timings . . . 159
Table 93. Synchronous multiplexed PSRAM write timings . . . 161
Table 94. Synchronous non-multiplexed NOR/PSRAM read timings . . . 162
Table 95. Synchronous non-multiplexed PSRAM write timings . . . 164
Table 96. Dynamic characteristics: SD / MMC characteristics . . . 165
Table 97. Dynamic characteristics: eMMC characteristics VDD = 1.7 V to 1.9 V . . . 166
Table 98. RTC characteristics . . . 166
Table 99. WLCSP64 - 64-pin, 3.658 x 3.686 mm, 0.4 mm pitch wafer level chip scale package mechanical data . . . 168
Table 100. WLCSP64 recommended PCB design rules (0.4 mm pitch) . . . 169
Table 101. UFQFPN48 - 48-lead, 7x7 mm, 0.5 mm pitch, ultra thin fine pitch quad flat package mechanical data . . . 170
Table 102. LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat package mechanical data . . . 174
Table 103. LQPF100 - 100-pin, 14 x 14 mm low-profile quad flat package mechanical data . . . 177
Table 104. LQFP144 - 144-pin, 20 x 20 mm low-profile quad flat package mechanical data . . . 181
Table 105. UFBGA100 - 100-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package mechanical data . . . 184
Table 106. UFBGA100 recommended PCB design rules (0.5 mm pitch BGA) . . . 185
Table 107. UFBGA144 - 144-pin, 10 x 10 mm, 0.80 mm pitch, ultra fine pitch ball grid array package mechanical data . . . 187
Table 108. UFBGA144 recommended PCB design rules (0.80 mm pitch BGA) . . . 188
Table 109. Package thermal characteristics . . . 190
Table 110. Ordering information scheme . . . 191
Table 111. Document revision history . . . 197



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# List of figures


Figure 1. Compatible board design for LQFP100 package . . . 16
Figure 2. Compatible board design for LQFP64 package . . . 17
Figure 3. Compatible board design for LQFP144 package . . . 17
Figure 4. STM32F412xE/G block diagram . . . 18
Figure 5. Multi-AHB matrix . . . 21
Figure 6. VDDUSB connected to an external independent power supply . . . 25
Figure 7. Power supply supervisor interconnection with internal reset OFF . . . 27
Figure 8. Regulator OFF . . . 29
Figure 9. Startup in regulator OFF: slow $V_{DD}$ slope power-down reset risen after $V_{CAP_1}/V_{CAP_2}$ stabilization . . . 30
Figure 10. Startup in regulator OFF mode: fast $V_{DD}$ slope power-down reset risen before $V_{CAP_1}/V_{CAP_2}$ stabilization . . . 30
Figure 11. STM32F412xE/G WLCSP64 pinout . . . 43
Figure 12. STM32F412xE/G UFQFPN48 pinout . . . 44
Figure 13. STM32F412xE/G LQFP64 pinout . . . 45
Figure 14. STM32F412xE/G LQFP100 pinout . . . 46
Figure 15. STM32F412xE/G LQFP144 pinout . . . 47
Figure 16. STM32F412xE/G UFBGA100 pinout . . . 48
Figure 17. STM32F412xE/G UFBGA144 pinout . . . 49
Figure 18. Memory map . . . 74
Figure 19. Pin loading conditions . . . 78
Figure 20. Input voltage measurement . . . 78
Figure 21. Power supply scheme . . . 79
Figure 22. Current consumption measurement scheme . . . 80
Figure 23. External capacitor $C_{EXT}$ . . . 85
Figure 24. Typical $V_{BAT}$ current consumption (LSE and RTC ON/LSE oscillator "low power" mode selection) . . . 99
Figure 25. Typical $V_{BAT}$ current consumption (LSE and RTC ON/LSE oscillator "high drive" mode selection) . . . 99
Figure 26. Low-power mode wakeup . . . 105
Figure 27. High-speed external clock source AC timing diagram . . . 108
Figure 28. Low-speed external clock source AC timing diagram . . . 109
Figure 29. Typical application with an 8 MHz crystal . . . 110
Figure 30. Typical application with a 32.768 kHz crystal . . . 111
Figure 31. $ACC_{HSI}$ versus temperature . . . 112
Figure 32. $ACC_{LSI}$ versus temperature . . . 112
Figure 33. PLL output clock waveforms in center spread mode . . . 116
Figure 34. PLL output clock waveforms in down spread mode . . . 116
Figure 35. FT/TC I/O input characteristics . . . 124
Figure 36. I/O AC characteristics definition . . . 127
Figure 37. Recommended NRST pin protection . . . 128
Figure 38. $I^2C$ bus AC waveforms and measurement circuit . . . 130
Figure 39. $FMPI^2C$ timing diagram and measurement circuit . . . 132
Figure 40. SPI timing diagram - slave mode and CPHA = 0 . . . 134
Figure 41. SPI timing diagram - slave mode and CPHA = 1(1) . . . 135
Figure 42. SPI timing diagram - master mode(1) . . . 135
Figure 43. $I^2S$ slave timing diagram (Philips protocol)(1) . . . 137
Figure 44. $I^2S$ master timing diagram (Philips protocol)(1) . . . 137




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Figure 45. USB OTG FS timings: definition of data signal rise and fall time . . . 140
Figure 46. ADC accuracy characteristics . . . 144
Figure 47. Typical connection diagram using the ADC . . . 145
Figure 48. Power supply and reference decoupling ($V_{REF+}$ not connected to $V_{DDA}$) . . . 146
Figure 49. Power supply and reference decoupling ($V_{REF+}$ connected to $V_{DDA}$) . . . 147
Figure 50. Asynchronous non-multiplexed SRAM/PSRAM/NOR read waveforms . . . 151
Figure 51. Asynchronous non-multiplexed SRAM/PSRAM/NOR write waveforms . . . 153
Figure 52. Asynchronous multiplexed PSRAM/NOR read waveforms . . . 154
Figure 53. Asynchronous multiplexed PSRAM/NOR write waveforms . . . 156
Figure 54. Synchronous multiplexed NOR/PSRAM read timings . . . 158
Figure 55. Synchronous multiplexed PSRAM write timings . . . 160
Figure 56. Synchronous non-multiplexed NOR/PSRAM read timings . . . 162
Figure 57. Synchronous non-multiplexed PSRAM write timings . . . 163
Figure 58. SDIO high-speed mode . . . 165
Figure 59. SD default mode . . . 165
Figure 60. WLCSP64 - 64-pin, 3.658 x 3.686 mm, 0.4 mm pitch wafer level chip scale package outline . . . 167
Figure 61. WLCSP64 - 64-pin, 3.658 x 3.686 mm, 0.4 mm pitch wafer level chip scale recommended footprint . . . 168
Figure 62. WLCSP64 marking example (package top view) . . . 169
Figure 63. UFQFPN48 - 48-lead, 7x7 mm, 0.5 mm pitch, ultra thin fine pitch quad flat package outline . . . 170
Figure 64. UFQFPN48 recommended footprint . . . 171
Figure 65. UFQFPN48 marking example (package top view) . . . 172
Figure 66. LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat package outline . . . 173
Figure 67. LQFP64 recommended footprint . . . 175
Figure 68. LQFP64 marking example (package top view) . . . 176
Figure 69. LQFP100 - 100-pin, 14 x 14 mm low-profile quad flat package outline . . . 177
Figure 70. LQFP100 - 100-pin, 14 x 14 mm low-profile quad flat recommended footprint . . . 178
Figure 71. LQFP100 marking example (package top view) . . . 179
Figure 72. LQFP144 - 144-pin, 20 x 20 mm low-profile quad flat package outline . . . 180
Figure 73. LQFP144 - 144-pin,20 x 20 mm low-profile quad flat package recommended footprint . . . 182
Figure 74. LQFP144 marking example (package top view) . . . 183
Figure 75. UFBGA100 - 100-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package outline . . . 184
Figure 76. UFBGA100 - 100-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package recommended footprint . . . 185
Figure 77. UFBGA100 marking example (package top view) . . . 186
Figure 78. UFBGA144 - 144-pin, 10 x 10 mm, 0.80 mm pitch, ultra fine pitch ball grid array package outline . . . 187
Figure 79. UFBGA144 - 144-pin, 10 x 10 mm, 0.80 mm pitch, ultra fine pitch ball grid array recommended footprint . . . 188
Figure 80. UFBGA144 marking example (package top view) . . . 189
Figure 81. USB controller configured as peripheral-only and used in Full speed mode . . . 193
Figure 82. USB peripheral-only Full speed mode with direct connection for VBUS sense . . . 193
Figure 83. USB peripheral-only Full speed mode, VBUS detection using GPIO . . . 194
Figure 84. USB controller configured as host-only and used in full speed mode . . . 194
Figure 85. USB controller configured in dual mode and used in full speed mode . . . 195
Figure 86. Sensor Hub application example . . . 195



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Figure 87. Display application example . . . . . 196



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# 1 Introduction

This datasheet provides the description of the STM32F412xE/G microcontrollers.

For information on the Cortex®-M4 core, refer to the Cortex®-M4 programming manual (PM0214) available from *www.st.com*.



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# 2 Description

STM32F412xE/G devices are based on the high-performance Arm® Cortex®-M4 32-bit RISC core operating at a frequency of up to 100 MHz. Their Cortex®-M4 core features a Floating point unit (FPU) single precision which supports all Arm single-precision data-processing instructions and data types. It also implements a full set of DSP instructions and a memory protection unit (MPU) which enhances application security.

STM32F412xE/G devices belong to the STM32 Dynamic Efficiency™ product line (with products combining power efficiency, performance and integration) while adding a new innovative feature called Batch Acquisition Mode (BAM) allowing even more power consumption saving during data batching.

STM32F412xE/G devices incorporate high-speed embedded memories (up to 1 Mbyte of Flash memory, 256 Kbytes of SRAM), and an extensive range of enhanced I/Os and peripherals connected to two APB buses, three AHB buses and a 32-bit multi-AHB bus matrix.

All devices offer one 12-bit ADC, a low-power RTC, twelve general-purpose 16-bit timers, two PWM timers for motor control and two general-purpose 32-bit timers.

They also feature standard and advanced communication interfaces:

- Up to four $I^2C$s, including one $I^2C$ supporting Fast-Mode Plus
- Five SPIs
- Five $I^2S$s of which two are full duplex. To achieve audio class accuracy, the $I^2S$ peripherals can be clocked via a dedicated internal audio PLL, or via an external clock to allow synchronization.
- Four USARTs
- An SDIO/MMC interface
- A USB 2.0 OTG full-speed interface
- Two CANs.

In addition, STM32F412xE/G devices embed advanced peripherals:

- A flexible static memory controller interface (FSMC)
- A Quad-SPI memory interface
- A digital filter for sigma modulator (DFSDM), two filters, up to four inputs, and support of microphone MEMs.

STM32F412xE/G devices are offered in 7 packages ranging from 48 to 144 pins. The set of available peripherals depends on the selected package.

The STM32F412xE/G operates in the -40 to +125 °C temperature range from a 1.7 (PDR OFF) to 3.6 V power supply. A comprehensive set of power-saving modes allows the design of low-power applications.



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These features make the STM32F412xE/G microcontrollers suitable for a wide range of applications:

- Motor drive and application control
- Medical equipment
- Industrial applications: PLC, inverters, circuit breakers
- Printers, and scanners
- Alarm systems, video intercom, and HVAC
- Home audio appliances
- Mobile phone sensor hub
- Wearable devices
- Connected objects
- Wifi modules



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**Table 2. STM32F412xE/G features and peripheral counts**

| Peripherals | | STM32F412xE | | | | STM32F412xG | | | |
|---|---|---|---|---|---|---|---|---|---|
| Flash memory (Kbyte) | | 512 | | | | 1024 | | | |
| SRAM (Kbyte) | System | 256 | | | | | | | |
| FSMC memory controller(1) | | - | | 1 | | - | | 1 | |
| Quad-SPI memory interface | | - | 1 | | | - | 1 | | |
| Timers | General-purpose | 10 | | | | | | | |
| | Advanced-control | 2 | | | | | | | |
| | Basic | 2 | | | | | | | |
| Random number generator | | 1 | | | | | | | |
| Comm. interfaces | SPI/ $I^2S$ | 5/5 (2 full duplex) | | | | | | | |
| | $I^2C$ | 3 | | | | | | | |
| | $I^2CFMP$ | 1 | | | | | | | |
| | USART | 4(2) | 4 | | | 4(2) | 4 | | |
| | SDIO/MMC | 1 | | | | | | | |
| | USB/OTG FS Dual power rail | 1 No | | 1 Yes | | 1 No | | 1 Yes | |
| | CAN | 2 | | | | | | | |
| Number of digital Filters for Sigma-delta modulator | | 2 | 2 | | | 2 | 2 | | |
| Number of channels | | 3 | 4 | | | 3 | 4 | | |
| LCD parallel interface Data bus size | | - | 8 | 16 | | - | 8 | 16 | |
| GPIOs | | 36 | 50 | 81 | 114 | 36 | 50 | 81 | 114 |
| 12-bit ADC Number of channels | | 1 | | | | | | | |
| | | 10 | 16 | | | 10 | 16 | | |
| Maximum CPU frequency | | 100 MHz | | | | | | | |
| Operating voltage | | 1.7 to 3.6 V | | | | | | | |
| Operating temperatures | | Ambient temperatures: -40 to +85 °C / -40 to +105 °C/ -40 to +125 °C | | | | | | | |
| | | Junction temperature: -40 to +130 °C | | | | | | | |
| Package | | UFQFPN48 | LQFP64 WLCSP64 | UFBGA100 LQFP100 | UFBGA144 LQFP144 | UFQFPN48 | LQFP64 WLCSP64 | UFBGA100 LQFP100 | UFBGA144 LQFP144 |

1. The FSMC can also be used to interface most graphic LCD controllers.
2. Limited application for the USART3 since RX is not available for the UFQFPN48.



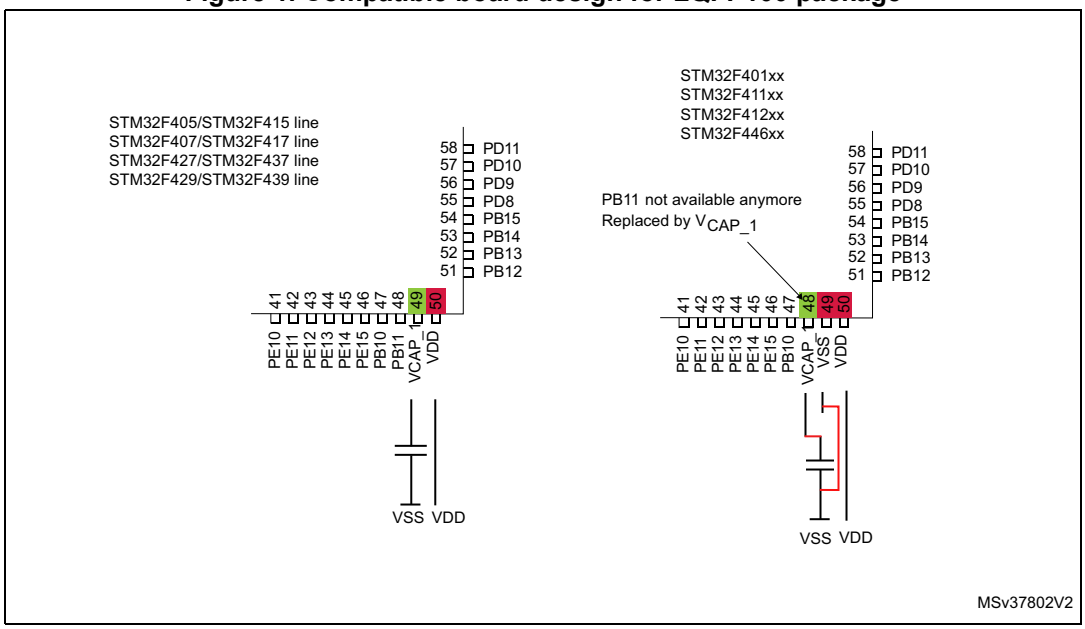
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## 2.1 Compatibility with STM32F4 series

The STM32F412xE/G are fully software and feature compatible with the STM32F4 series (STM32F42x, STM32F401, STM32F43x, STM32F41x, STM32F405 and STM32F407)

The STM32F412xE/G can be used as drop-in replacement of the other STM32F4 products but some slight changes have to be done on the PCB board.

**Figure 1. Compatible board design for LQFP100 package**






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**Figure 2. Compatible board design for LQFP64 package**

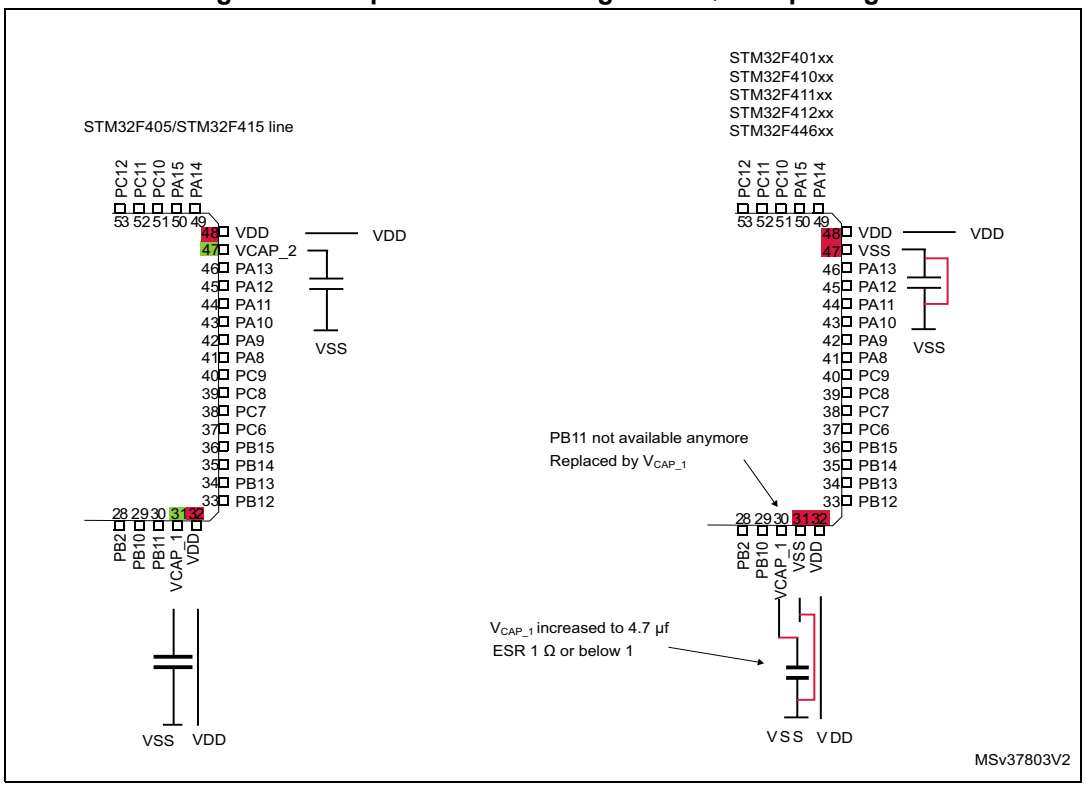
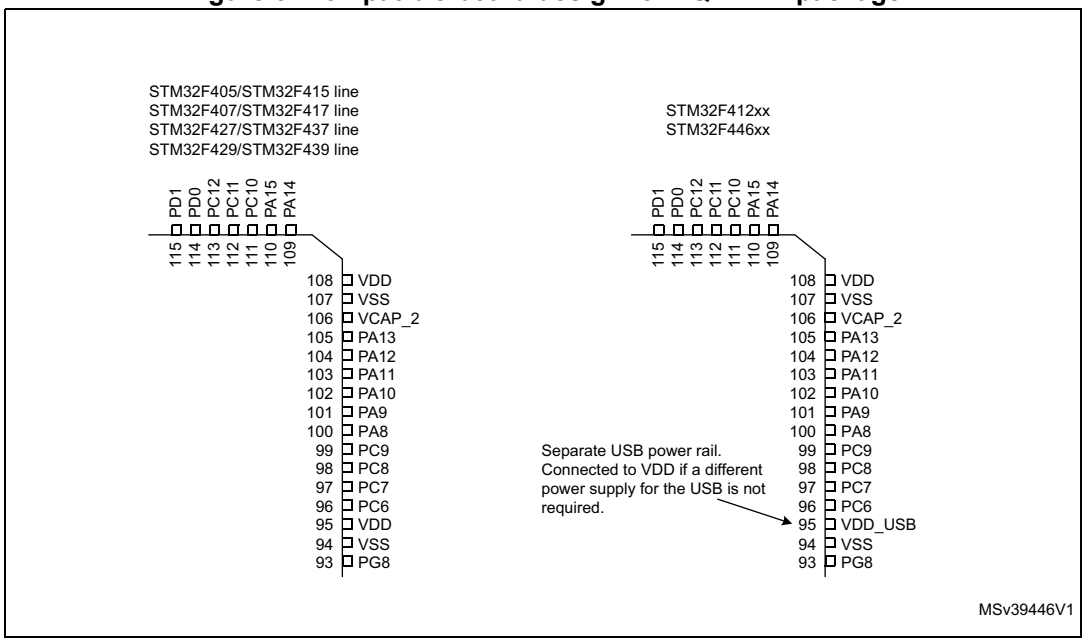


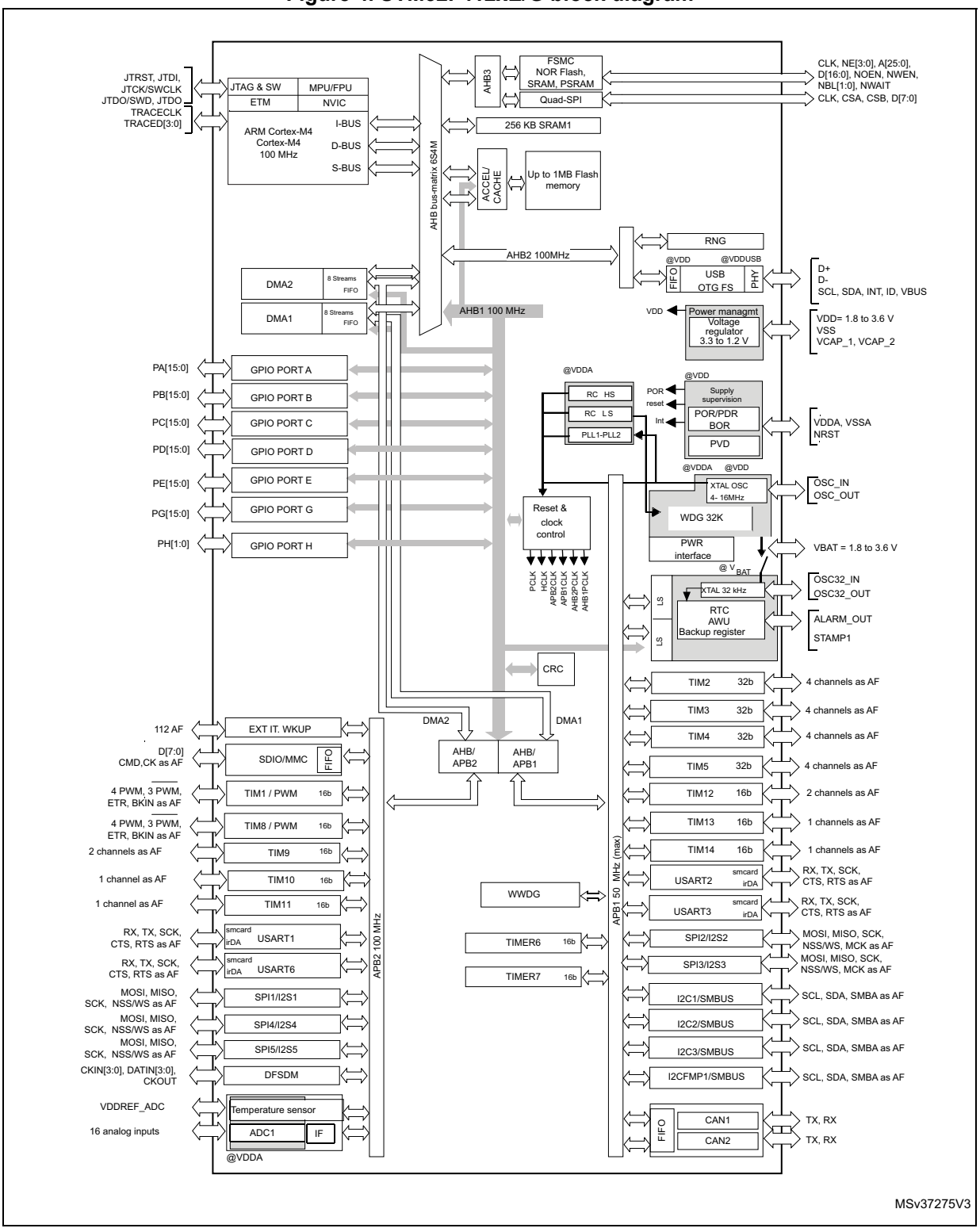

**Figure 3. Compatible board design for LQFP144 package**






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**Figure 4. STM32F412xE/G block diagram**




1. The timers connected to APB2 are clocked from TIMxCLK up to 100 MHz, while the timers connected to APB1 are clocked from TIMxCLK up to 50 MHz.



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# 3 Functional overview

## 3.1 Arm® Cortex®-M4 with FPU core with embedded Flash and SRAM

The Arm® Cortex®-M4 with FPU processor is the latest generation of Arm processors for embedded systems. It was developed to provide a low-cost platform that meets the needs of MCU implementation, with a reduced pin count and low-power consumption, while delivering outstanding computational performance and an advanced response to interrupts.

The Arm® Cortex®-M4 with FPU 32-bit RISC processor features exceptional code-efficiency, delivering the high-performance expected from an Arm core in the memory size usually associated with 8- and 16-bit devices.

The processor supports a set of DSP instructions which allow efficient signal processing and complex algorithm execution.

Its single precision FPU (floating point unit) speeds up software development by using metalanguage development tools, while avoiding saturation.

The STM32F412xE/G devices are compatible with all Arm tools and software.

*Figure 4* shows the general block diagram of the STM32F412xE/G.

*Note: Cortex®-M4 with FPU is binary compatible with Cortex®-M3.*

## 3.2 Adaptive real-time memory accelerator (ART Accelerator™)

The ART Accelerator™ is a memory accelerator which is optimized for STM32 industry-standard Arm® Cortex®-M4 with FPU processors. It balances the inherent performance advantage of the Arm® Cortex®-M4 with FPU over Flash memory technologies, which normally requires the processor to wait for the Flash memory at higher frequencies.

To release the processor full 125 DMIPS performance at this frequency, the accelerator implements an instruction prefetch queue and branch cache, which increases program execution speed from the 128-bit Flash memory. Based on CoreMark benchmark, the performance achieved thanks to the ART Accelerator is equivalent to 0 wait state program execution from Flash memory at a CPU frequency up to 100 MHz.

## 3.3 Batch Acquisition mode (BAM)

The Batch acquisition mode allows enhanced power efficiency during data batching. It enables data acquisition through any communication peripherals directly to memory using the DMA in reduced power consumption as well as data processing while the rest of the system is in low-power mode (including the flash and ART). For example in an audio system, a smart combination of PDM audio sample acquisition and processing from the DFSDM directly to RAM (flash and ART™ stopped) with the DMA using BAM followed by some very short processing from flash allows to drastically reduce the power consumption of the application. A dedicated application note (AN4515) describes how to implement the STM32F412xE/G BAM to allow the best power efficiency.



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## 3.4 Memory protection unit

The memory protection unit (MPU) is used to manage the CPU accesses to memory to prevent one task to accidentally corrupt the memory or resources used by any other active task. This memory area is organized into up to 8 protected areas that can in turn be divided up into 8 subareas. The protection area sizes are between 32 byte and the whole 4 Gbyte of addressable memory.

The MPU is especially helpful for applications where some critical or certified code has to be protected against the misbehavior of other tasks. It is usually managed by an RTOS (real-time operating system). If a program accesses a memory location that is prohibited by the MPU, the RTOS can detect it and take action. In an RTOS environment, the kernel can dynamically update the MPU area setting, based on the process to be executed.

The MPU is optional and can be bypassed for applications that do not need it.

## 3.5 Embedded Flash memory

The devices embed up to 1 Mbyte of Flash memory available for storing programs and data.

The Flash user area can be protected against reading by an entrusted code (Read Protection, RDP) with different protection levels.

The flash user sectors can also be individually protected against write operation.

Furthermore the proprietary readout protection (PCROP) can also individually protect the flash user sectors against D-bus read accesses.

(Additional information can be found in the product reference manual).

To optimize the power consumption the Flash memory can also be switched off in Run or in Sleep mode (see *Section 3.21: Low-power modes*).

Two modes are available: Flash in Stop mode or in DeepSleep mode (trade off between power saving and startup time.

Before disabling the Flash, the code must be executed from the internal RAM.

## 3.6 One-time programmable bytes

A one-time programmable area is available with16 OTP blocks of 32 bytes. Each block can be individually locked

(Additional information can be found in the product reference manual)

## 3.7 CRC (cyclic redundancy check) calculation unit

The CRC (cyclic redundancy check) calculation unit is used to get a CRC code from a 32-bit data word and a fixed generator polynomial.

Among other applications, CRC-based techniques are used to verify data transmission or storage integrity. In the scope of the EN/IEC 60335-1 standard, they offer a means of verifying the Flash memory integrity. The CRC calculation unit helps compute a software signature during runtime, to be compared with a reference signature generated at link-time and stored at a given memory location.



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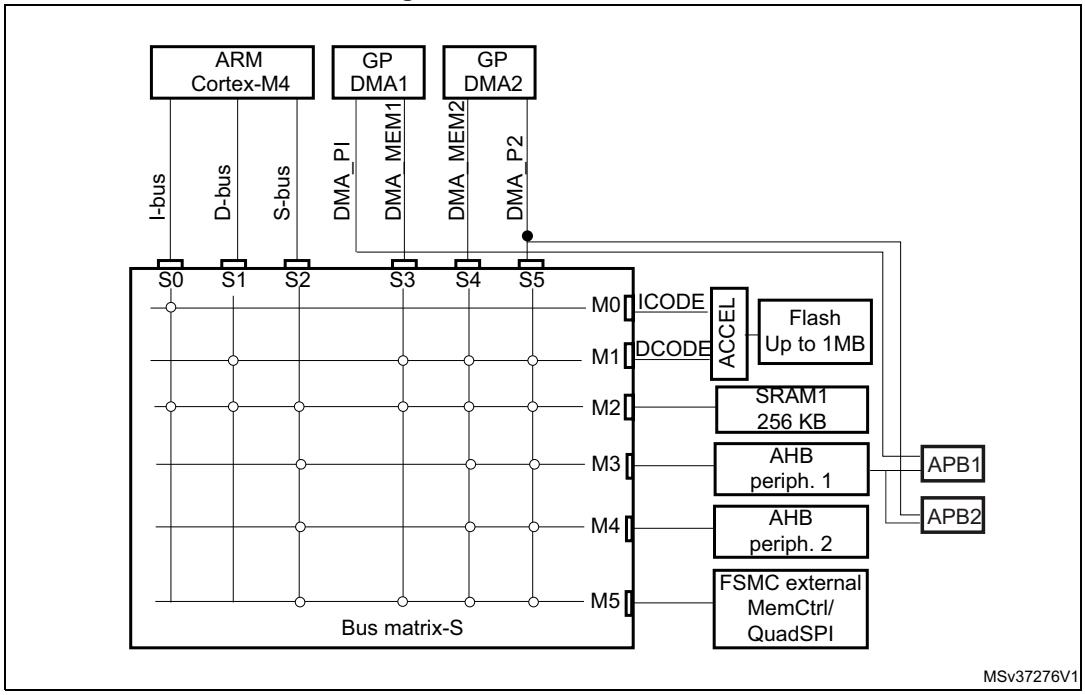
## 3.8 Embedded SRAM

All devices embed 256 Kbyte of system SRAM which can be accessed (read/write) at CPU clock speed with 0 wait states

## 3.9 Multi-AHB bus matrix

The 32-bit multi-AHB bus matrix interconnects all the masters (CPU, DMAs) and the slaves (Flash memory, RAM, AHB and APB peripherals) and ensures a seamless and efficient operation even when several high-speed peripherals work simultaneously.

**Figure 5. Multi-AHB matrix**




## 3.10 DMA controller (DMA)

The devices feature two general-purpose dual-port DMAs (DMA1 and DMA2) with 8 streams each. They are able to manage memory-to-memory, peripheral-to-memory and memory-to-peripheral transfers. They feature dedicated FIFOs for APB/AHB peripherals, support burst transfer and are designed to provide the maximum peripheral bandwidth (AHB/APB).

The two DMA controllers support circular buffer management, so that no specific code is needed when the controller reaches the end of the buffer. The two DMA controllers also have a double buffering feature, which automates the use and switching of two memory buffers without requiring any special code.

Each stream is connected to dedicated hardware DMA requests, with support for software trigger on each stream. Configuration is made by software and transfer sizes between source and destination are independent.



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The DMA can be used with the main peripherals:

- SPI and $I^2S$
- $I^2C$ and $I^2CFMP$
- USART
- General-purpose, basic and advanced-control timers TIMx
- SD/SDIO/MMC/eMMC host interface
- Quad-SPI
- ADC
- Digital Filter for sigma-delta modulator (DFSDM) with a separate stream for each filter.

## 3.11 Flexible static memory controller (FSMC)

The Flexible static memory controller (FSMC) includes a NOR/PSRAM memory controller. It features four Chip Select outputs supporting the following modes: SRAM, PSRAM and NOR Flash memory.

The main functions are:

- 8-,16-bit data bus width
- Write FIFO
- Maximum FSMC_CLK frequency for synchronous accesses is 90 MHz.

### LCD parallel interface

The FSMC can be configured to interface seamlessly with most graphic LCD controllers. It supports the Intel 8080 and Motorola 6800 modes, and is flexible enough to adapt to specific LCD interfaces. This LCD parallel interface capability makes it easy to build cost-effective graphic applications using LCD modules with embedded controllers or high performance solutions using external controllers with dedicated acceleration.

## 3.12 Quad-SPI memory interface (QUAD-SPI)

All devices embed a Quad-SPI memory interface, which is a specialized communication interface targeting single, dual or quad-SPI Flash memories. It can work in direct mode through registers, external Flash status register polling mode and memory mapped mode. Up to 256 Mbyte of external Flash memory are mapped. They can be accessed in 8, 16 or 32-bit mode. Code execution is also supported. The opcode and the frame format are fully programmable. Communication can be performed either in single data rate or dual data rate.



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## 3.13 Nested vectored interrupt controller (NVIC)

The devices embed a nested vectored interrupt controller able to manage 16 priority levels, and handle up to 81 maskable interrupt channels plus the 16 interrupt lines of the Cortex®-M4 with FPU.

- Closely coupled NVIC gives low-latency interrupt processing
- Interrupt entry vector table address passed directly to the core
- Allows early processing of interrupts
- Processing of late arriving, higher-priority interrupts
- Support tail chaining
- Processor state automatically saved
- Interrupt entry restored on interrupt exit with no instruction overhead

This hardware block provides flexible interrupt management features with minimum interrupt latency.

## 3.14 External interrupt/event controller (EXTI)

The external interrupt/event controller consists of 21 edge-detector lines used to generate interrupt/event requests. Each line can be independently configured to select the trigger event (rising edge, falling edge, both) and can be masked independently. A pending register maintains the status of the interrupt requests. The EXTI can detect an external line with a pulse width shorter than the Internal APB2 clock period. Up to 114 GPIOs can be connected to the 16 external interrupt lines.

## 3.15 Clocks and startup

On reset the 16 MHz internal RC oscillator is selected as the default CPU clock. The 16 MHz internal RC oscillator is factory-trimmed to offer 1% accuracy at 25 °C. The application can then select as system clock either the RC oscillator or an external 4-26 MHz clock source. This clock can be monitored for failure. If a failure is detected, the system automatically switches back to the internal RC oscillator and a software interrupt is generated (if enabled). This clock source is input to a PLL thus allowing to increase the frequency up to 100 MHz. Similarly, full interrupt management of the PLL clock entry is available when necessary (for example if an indirectly used external oscillator fails).

Several prescalers allow the configuration of the three AHB buses, the high-speed APB (APB2) and the low-speed APB (APB1) domains. The maximum frequency of the three AHB buses and high-speed APB domains is 100 MHz. The maximum allowed frequency of the low-speed APB domain is 50 MHz.

The devices embed a dedicated PLL (PLLI2S) which allows to achieve audio class performance. In this case, the $I^2S$ master clock can generate all standard sampling frequencies from 8 kHz to 192 kHz.



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## 3.16 Boot modes

At startup, boot pins are used to select one out of three boot options:

- Boot from user Flash memory
- Boot from system memory
- Boot from embedded SRAM

The boot loader is located in system memory. It is used to reprogram the Flash memory by using one of the interface listed in the *Table 3* or the USB OTG FS in device mode through DFU (device firmware upgrade).

**Table 3. Embedded bootloader interfaces**

| Package | USART1 PA9/ PA10 | USART2 PD6/ PD5 | USART3 PB11/ PB10 | I2C1 PB6/ PB7 | I2C2 PF0/ PF1 | I2C3 PA8/ PB4 | I2C FMP1 PB14/ PB15 | SPI1 PA4/ PA5/ PA6/ PA7 | SPI3 PA15/ PC10/ PC11/ PC12 | SPI4 PE11/ PE12/ PE13/ PE14 | CAN2 PB5/ PB13 | USB PA11 /P12 |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| UFQFPN48 | Y | - | - | Y | - | Y | Y | Y | - | - | Y | Y |
| WLCSP64 | Y | - | - | Y | - | Y | Y | Y | Y | - | Y | Y |
| LQFP64 | Y | - | - | Y | - | Y | Y | Y | Y | - | Y | Y |
| LQFP100 | Y | Y | - | Y | - | Y | Y | Y | Y | Y | Y | Y |
| LQFP144 | Y | Y | Y | Y | Y | Y | Y | Y | Y | Y | Y | Y |
| UFBGA100 | Y | Y | Y | Y | - | Y | Y | Y | Y | Y | Y | Y |
| UFBGA144 | Y | Y | Y | Y | Y | Y | Y | Y | Y | Y | Y | Y |

For more detailed information on the bootloader, refer to Application Note: AN2606, *STM32™ microcontroller system memory boot mode*.

## 3.17 Power supply schemes

- $V_{DD}$ = 1.7 to 3.6 V: external power supply for I/Os with the internal supervisor (POR/PDR) disabled, provided externally through $V_{DD}$ pins. Requires the use of an external power supply supervisor connected to the $V_{DD}$ and NRST pins.
- $V_{SSA}$, $V_{DDA}$ = 1.7 to 3.6 V: external analog power supplies for ADC, Reset blocks, RCs and PLL. $V_{DDA}$ and $V_{SSA}$ must be connected to $V_{DD}$ and $V_{SS}$, respectively, with decoupling technique.

*Note: The $V_{DD}$/$V_{DDA}$ minimum value of 1.7 V is obtained with the use of an external power supply supervisor (refer to Section 3.18.2: Internal reset OFF). Refer to Table 4: Regulator ON/OFF and internal power supply supervisor availability to identify the packages supporting this option.*

- $V_{BAT}$ = 1.65 to 3.6 V: power supply for RTC, external clock 32 kHz oscillator and backup registers (through power switch) when $V_{DD}$ is not present.
- $V_{DDUSB}$ can be connected either to VDD or an external independent power supply (3.0 to 3.6 V) for USB transceivers.
  For example, when device is powered at 1.8 V, an independent power supply 3.3V can be connected to $V_{DDUSB}$. When the $V_{DDUSB}$ is connected to a separated power supply,



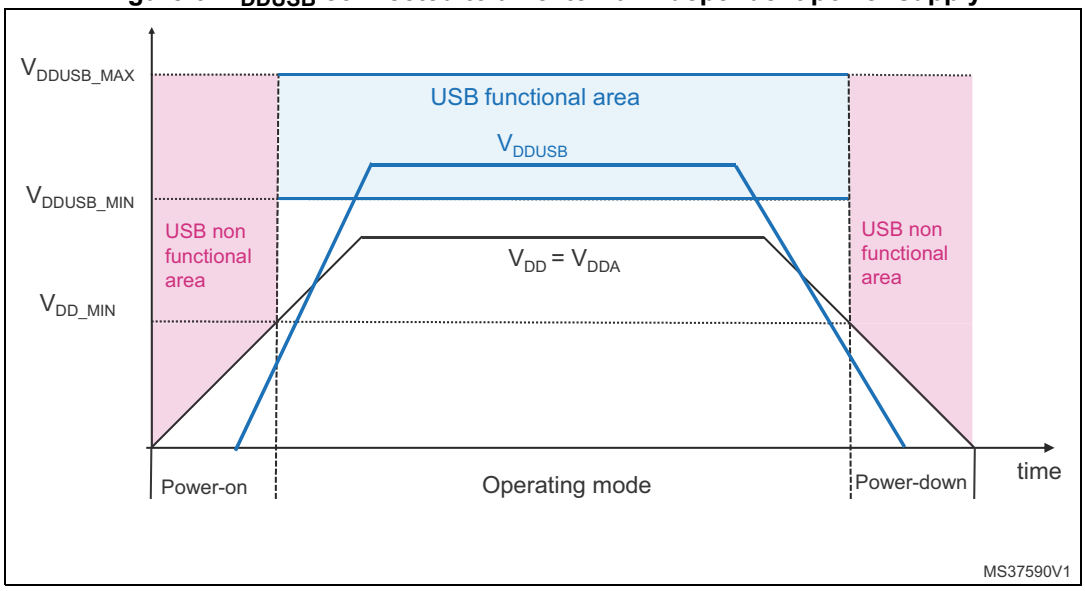
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it is independent from $V_{DD}$ or $V_{DDA}$ but it must be the last supply to be provided and the first to disappear.

The following conditions VDDUSB must be respected:

- During power-on phase ($V_{DD} < V_{DD_MIN}$), $V_{DDUSB}$ should be always lower than $V_{DD}$
- During power-down phase ($V_{DD} < V_{DD_MIN}$), $V_{DDUSB}$ should be always lower than $V_{DD}$
- $V_{DDUSB}$ rising and falling time rate specifications must be respected.
- In operating mode phase, $V_{DDUSB}$ could be lower or higher than VDD:
  - If USB is used, the associated GPIOs powered by $V_{DDUSB}$ are operating between $V_{DDUSB_MIN}$ and $V_{DDUSB_MAX}$.
  - If USB is not used, the associated GPIOs powered by $V_{DDUSB}$ are operating between $V_{DD_MIN}$ and $V_{DD_MAX}$.

**Figure 6. $V_{DDUSB}$ connected to an external independent power supply**






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## 3.18 Power supply supervisor

### 3.18.1 Internal reset ON

This feature is available for $V_{DD}$ operating voltage range 1.8 V to 3.6 V.

On packages embedding the PDR_ON pin, the power supply supervisor is enabled by holding PDR_ON high. On the other package, the power supply supervisor is always enabled.

The device has an integrated power-on reset (POR) / power-down reset (PDR) circuitry coupled with a Brownout reset (BOR) circuitry. At power-on, POR is always active, and ensures proper operation starting from 1.8 V. After the 1.8 V POR threshold level is reached, the option byte loading process starts, either to confirm or modify default thresholds, or to disable BOR permanently. Three BOR thresholds are available through option bytes.

The device remains in reset mode when $V_{DD}$ is below a specified threshold, $V_{POR/PDR}$ or $V_{BOR}$, without the need for an external reset circuit.

The device also features an embedded programmable voltage detector (PVD) that monitors the $V_{DD}/V_{DDA}$ power supply and compares it to the $V_{PVD}$ threshold. An interrupt can be generated when $V_{DD}/V_{DDA}$ drops below the $V_{PVD}$ threshold and/or when $V_{DD}/V_{DDA}$ is higher than the $V_{PVD}$ threshold. The interrupt service routine can then generate a warning message and/or put the MCU into a safe state. The PVD is enabled by software.

### 3.18.2 Internal reset OFF

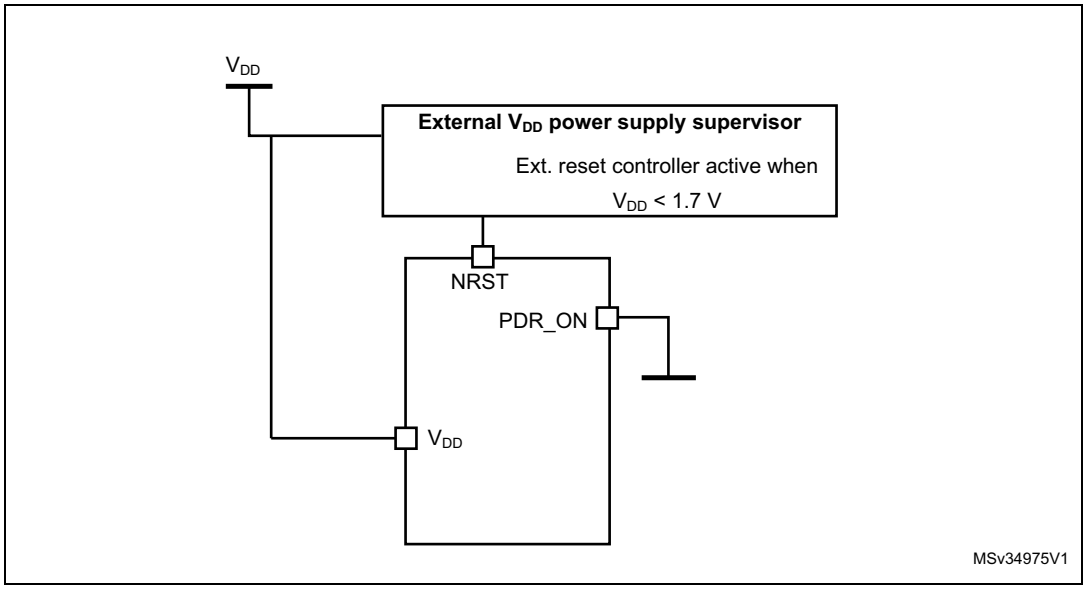
This feature is available only on packages featuring the PDR_ON pin. The internal power-on reset (POR) / power-down reset (PDR) circuitry is disabled by setting the PDR_ON pin to low.

An external power supply supervisor should monitor $V_{DD}$ and should set the device in reset mode when $V_{DD}$ is below 1.7 V. NRST should be connected to this external power supply supervisor. Refer to *Figure 7: Power supply supervisor interconnection with internal reset OFF*.



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**Figure 7. Power supply supervisor interconnection with internal reset OFF(1)**




1. The PRD_ON pin is available only on WLCSP64, UFBGA100, UFBGA144 and LQFP144 packages.

A comprehensive set of power-saving mode allows to design low-power applications.

When the internal reset is OFF, the following integrated features are no longer supported:

- The integrated power-on reset (POR) / power-down reset (PDR) circuitry is disabled.
- The brownout reset (BOR) circuitry must be disabled.
- The embedded programmable voltage detector (PVD) is disabled.
- $V_{BAT}$ functionality is no more available and VBAT pin should be connected to $V_{DD}$.

## 3.19 Voltage regulator

The regulator has three operating modes:

– Main regulator mode (MR)
– Low power regulator (LPR)
– Power-down

### 3.19.1 Regulator ON

On packages embedding the BYPASS_REG pin, the regulator is enabled by holding BYPASS_REG low. The WLCSP64 is available in two versions, one with the regulator internally enabled and one with the regulator internally disabled. On all other packages, the regulator is always enabled.



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There are three power modes configured by software when the regulator is ON:

- MR is used in the nominal regulation mode (With different voltage scaling in Run mode)

  In Main regulator mode (MR mode), different voltage scaling are provided to reach the best compromise between maximum frequency and dynamic power consumption.
- LPR is used in the Stop mode

  The LP regulator mode is configured by software when entering Stop mode.
- Power-down is used in Standby mode.

  The Power-down mode is activated only when entering in Standby mode. The regulator output is in high impedance and the kernel circuitry is powered down, inducing zero consumption. The contents of the registers and SRAM are lost.

Depending on the package, one or two external ceramic capacitors should be connected on the $V_{CAP_1}$ and $V_{CAP_2}$ pins. The $V_{CAP_2}$ pin is only available for the 100 pins and 144 pins packages.

All packages have the regulator ON feature.

### 3.19.2 Regulator OFF

The regulator is disabled by holding BYPASS_REG pin high.

This feature is available only on UFBGA100 and UFBGA144 packages, which feature the BYPASS_REG pin. The WLCSP64 is available in two versions, one with a fixed enabled regulator and one with a fixed disabled regulator (see *Table 4: Regulator ON/OFF and internal power supply supervisor availability* and *Section 8: Part numbering*). The regulator OFF mode allows to supply externally a $V_{12}$ voltage source through $V_{CAP_1}$ and $V_{CAP_2}$ pins.

Since the internal voltage scaling is not managed internally, the external voltage value must be aligned with the targeted maximum frequency.

The two 2.2 µF ceramic capacitors should be replaced by two 100 nF decoupling capacitors.

When the regulator is OFF, there is no more internal monitoring on $V_{12}$. An external power supply supervisor should be used to monitor the $V_{12}$ of the logic power domain. PA0 pin should be used for this purpose, and act as power-on reset on $V_{12}$ power domain.

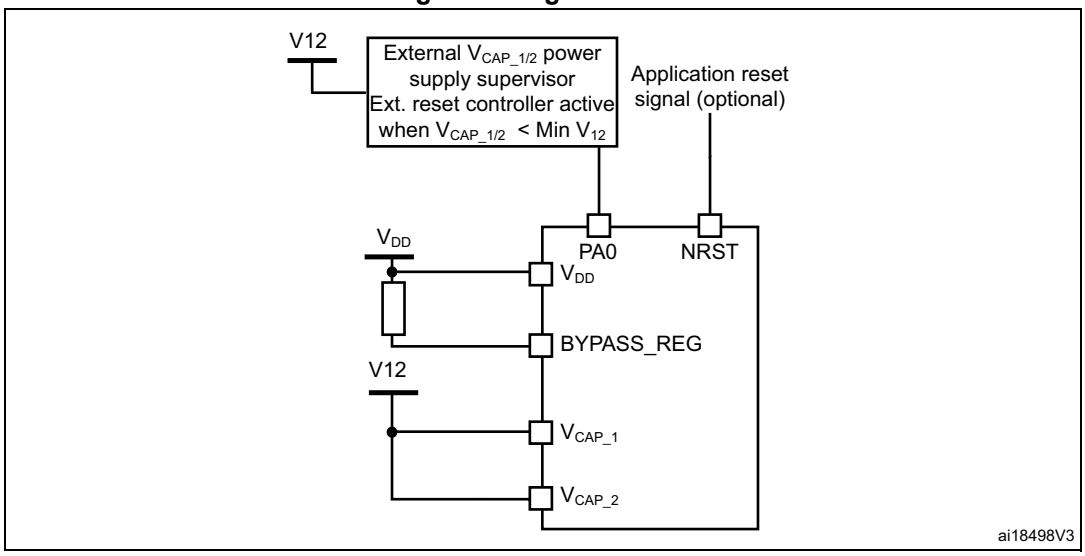
In regulator OFF mode, the following features are no more supported:

- PA0 cannot be used as a GPIO pin since it allows to reset a part of the $V_{12}$ logic power domain which is not reset by the NRST pin.
- As long as PA0 is kept low, the debug mode cannot be used under power-on reset. As a consequence, PA0 and NRST pins must be managed separately if the debug connection under reset or pre-reset is required.



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**Figure 8. Regulator OFF**




The following conditions must be respected:

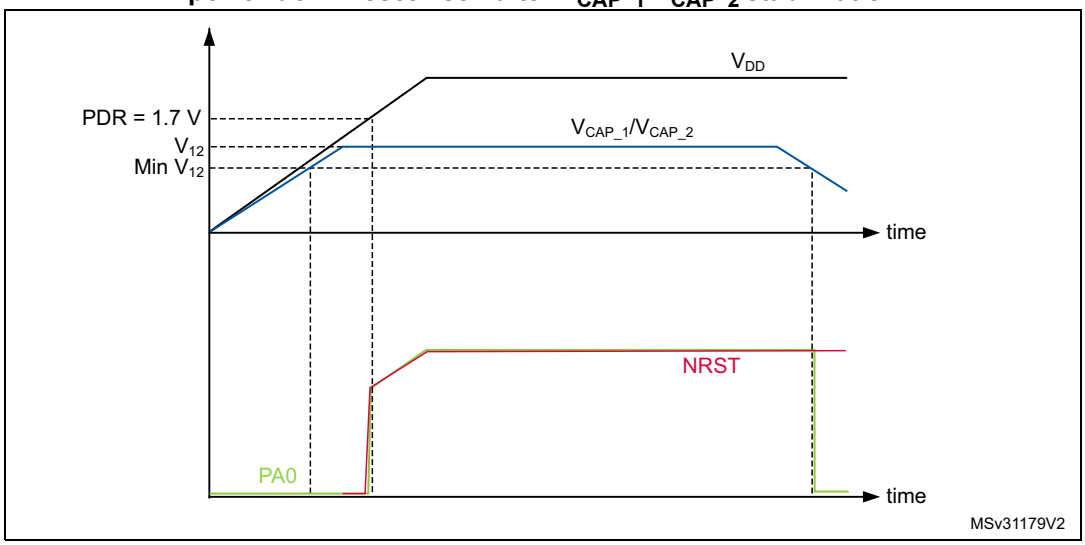
- $V_{DD}$ should always be higher than $V_{CAP_1}$ and $V_{CAP_2}$ to avoid current injection between power domains.
- If the time for $V_{CAP_1}$ and $V_{CAP_2}$ to reach $V_{12}$ minimum value is faster than the time for $V_{DD}$ to reach 1.7 V, then PA0 should be kept low to cover both conditions: until $V_{CAP_1}$ and $V_{CAP_2}$ reach $V_{12}$ minimum value and until $V_{DD}$ reaches 1.7 V (see *Figure 9*).
- Otherwise, if the time for $V_{CAP_1}$ and $V_{CAP_2}$ to reach $V_{12}$ minimum value is slower than the time for $V_{DD}$ to reach 1.7 V, then PA0 could be asserted low externally (see *Figure 10*).
- If $V_{CAP_1}$ and $V_{CAP_2}$ go below $V_{12}$ minimum value and $V_{DD}$ is higher than 1.7 V, then a reset must be asserted on PA0 pin.

*Note: The minimum value of $V_{12}$ depends on the maximum frequency targeted in the application.*



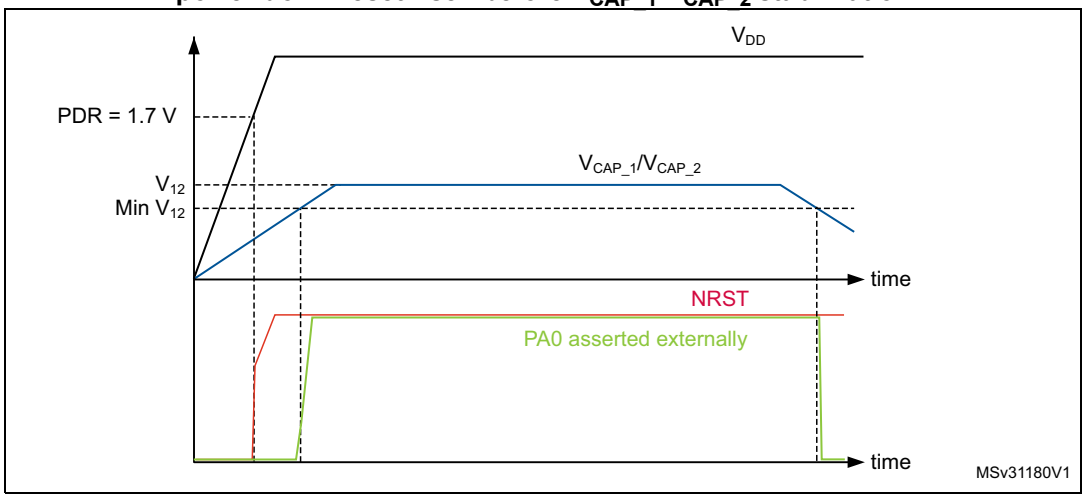
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**Figure 9. Startup in regulator OFF: slow $V_{DD}$ slope power-down reset risen after $V_{CAP_1}/V_{CAP_2}$ stabilization**




1. This figure is valid whatever the internal reset mode (ON or OFF).

**Figure 10. Startup in regulator OFF mode: fast $V_{DD}$ slope power-down reset risen before $V_{CAP_1}/V_{CAP_2}$ stabilization**




1. This figure is valid whatever the internal reset mode (ON or OFF).



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### 3.19.3 Regulator ON/OFF and internal reset ON/OFF availability

**Table 4. Regulator ON/OFF and internal power supply supervisor availability**

| Package | Regulator ON | Regulator OFF | Power supply supervisor ON | Power supply supervisor OFF |
|---|---|---|---|---|
| UFQFPN48 | Yes | No | Yes | No |
| WLCSP64 | Yes | No | Yes<br>PDR_ON set to $V_{DD}$ | Yes<br>PDR_ON set to $V_{SS}$ |
| WLCSP64 option P(1) | No | Yes | Yes<br>PDR_ON set to $V_{DD}$ | Yes<br>PDR_ON set to $V_{SS}$ |
| LQFP64 | Yes | No | Yes | No |
| LQFP100 | Yes | No | Yes | No |
| LQFP144 | Yes | No | Yes<br>PDR_ON set to VDD | Yes<br>PDR_ON set to $V_{SS}$ |
| UFBGA100 | Yes<br>BYPASS_REG set to VSS | Yes<br>BYPASS_REG set to VDD | | |
| UFBGA144 | Yes<br>BYPASS_REG set to VSS | Yes<br>BYPASS_REG set to VDD | | |

1. Refer to *Section 8: Part numbering*.

## 3.20 Real-time clock (RTC) and backup registers

The backup domain includes:

- The real-time clock (RTC)
- 20 backup registers

The real-time clock (RTC) is an independent BCD timer/counter. Dedicated registers contain the second, minute, hour (in 12/24 hour), week day, date, month, year, in BCD (binary-coded decimal) format. Correction for 28, 29 (leap year), 30, and 31 day of the month are performed automatically. The RTC features a reference clock detection, a more precise second source clock (50 or 60 Hz) can be used to enhance the calendar precision. The RTC provides a programmable alarm and programmable periodic interrupts with wakeup from Stop and Standby modes. The sub-seconds value is also available in binary format.

It is clocked by a 32.768 kHz external crystal, resonator or oscillator, the internal low-power RC oscillator or the high-speed external clock divided by 128. The internal low-speed RC has a typical frequency of 32 kHz. The RTC can be calibrated using an external 512 Hz output to compensate for any natural quartz deviation.

Two alarm registers are used to generate an alarm at a specific time and calendar fields can be independently masked for alarm comparison. To generate a periodic interrupt, a 16-bit programmable binary auto-reload downcounter with programmable resolution is available and allows automatic wakeup and periodic alarms from every 120 µs to every 36 hours.

A 20-bit prescaler is used for the time base clock. It is by default configured to generate a time base of 1 second from a clock at 32.768 kHz.

The backup registers are 32-bit registers used to store 80 byte of user application data when $V_{DD}$ power is not present. Backup registers are not reset by a system, a power reset,



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or when the device wakes up from the Standby mode (see *Section 3.21: Low-power modes*).

Additional 32-bit registers contain the programmable alarm subseconds, seconds, minutes, hours, day, and date.

The RTC and backup registers are supplied through a switch that is powered either from the $V_{DD}$ supply when present or from the $V_{BAT}$ pin.

## 3.21 Low-power modes

The devices support three low-power modes to achieve the best compromise between low power consumption, short startup time and available wakeup sources:

- **Sleep mode**

  In Sleep mode, only the CPU is stopped. All peripherals continue to operate and can wake up the CPU when an interrupt/event occurs.

  To further reduce the power consumption, the Flash memory can be switched off before entering in Sleep mode. Note that this requires a code execution from the RAM.

- **Stop mode**

  The Stop mode achieves the lowest power consumption while retaining the contents of SRAM and registers. All clocks in the 1.2 V domain are stopped, the PLL, the HSI RC and the HSE crystal oscillators are disabled. The voltage regulator can also be put either in normal or in low-power mode.

  The device can be woken up from the Stop mode by any of the EXTI line (the EXTI line source can be one of the 16 external lines, the PVD output, the RTC alarm/ wakeup/ tamper/ time stamp events).

- **Standby mode**

  The Standby mode is used to achieve the lowest power consumption. The internal voltage regulator is switched off so that the entire 1.2 V domain is powered off. The PLL, the HSI RC and the HSE crystal oscillators are also switched off. After entering Standby mode, the SRAM and register contents are lost except for registers in the backup domain when selected.

  The device exits the Standby mode when an external reset (NRST pin), an IWDG reset, a rising edge on one of the WKUP pins, or an RTC alarm/ wakeup/ tamper/time stamp event occurs.

  Standby mode is not supported when the embedded voltage regulator is bypassed and the 1.2 V domain is controlled by an external power.

## 3.22 $V_{BAT}$ operation

The VBAT pin allows to power the device $V_{BAT}$ domain from an external battery, an external super-capacitor, or from $V_{DD}$ when no external battery and an external super-capacitor are present.

$V_{BAT}$ operation is activated when $V_{DD}$ is not present.

The VBAT pin supplies the RTC and the backup registers.

*Note: When the microcontroller is supplied from VBAT, external interrupts and RTC alarm/events do not exit it from $V_{BAT}$ operation. When PDR_ON pin is not connected to $V_{DD}$ (internal*



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*Reset OFF), the $V_{BAT}$ functionality is no more available and VBAT pin should be connected to $V_{DD}$.*

## 3.23 Timers and watchdogs

The devices embed two advanced-control timer, ten general-purpose timers, two basic timers, two watchdog timers and one SysTick timer.

All timer counters can be frozen in debug mode.

*Table 5* compares the features of the advanced-control and general-purpose timers.



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**Table 5. Timer feature comparison**

| Timer type | Timer | Counter resolution | Counter type | Prescaler factor | DMA request generation | Capture/ compare channels | Complemen-tary output | Max. interface clock (MHz) | Max. timer clock (MHz) |
|---|---|---|---|---|---|---|---|---|---|
| Advanced-control | TIM1, TIM8 | 16-bit | Up, Down, Up/down | Any integer between 1 and 65536 | Yes | 4 | Yes | 100 | 100 |
| General purpose | TIM2, TIM5 | 32-bit | Up, Down, Up/down | Any integer between 1 and 65536 | Yes | 4 | No | 50 | 100 |
| | TIM3, TIM4 | 16-bit | Up, Down, Up/down | Any integer between 1 and 65536 | Yes | 4 | No | 50 | 100 |
| | TIM9 | 16-bit | Up | Any integer between 1 and 65536 | No | 2 | No | 100 | 100 |
| | TIM10, TIM11 | 16-bit | Up | Any integer between 1 and 65536 | No | 1 | No | 100 | 100 |
| | TIM12 | 16-bit | Up | Any integer between 1 and 65536 | No | 2 | No | 50 | 100 |
| | TIM13, TIM14 | 16-bit | Up | Any integer between 1 and 65536 | No | 1 | No | 50 | 100 |
| Basic timers | TIM6, TIM7 | 16-bit | Up | Any integer between 1 and 65536 | Yes | 0 | No | 50 | 100 |



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### 3.23.1 Advanced-control timers (TIM1, TIM8)

The advanced-control timers (TIM1/8) can be seen as three-phase PWM generator multiplexed on 4 independent channels. They have complementary PWM outputs with programmable inserted dead times. They can also be considered as complete general-purpose timers. Their 4 independent channels can be used for:

- Input capture
- Output compare
- PWM generation (edge- or center-aligned modes)
- One-pulse mode output

If configured as standard 16-bit timers, they have the same features as the general-purpose TIMx timers. If configured as a 16-bit PWM generator, they have full modulation capability (0-100%).

The advanced-control timers can work together with the TIMx timers via the Timer Link feature for synchronization or event chaining.

TIM1 and TIM8 support independent DMA request generation.

### 3.23.2 General-purpose timers (TIMx)

There are ten synchronizable general-purpose timers embedded in the STM32F412xE/G (see *Table 5* for differences).

- **TIM2, TIM3, TIM4, TIM5**

  The STM32F412xE/G devices include 4 full-featured general-purpose timers: TIM2. TIM3, TIM4 and TIM5. TIM2 and TIM5 timers are based on a 32-bit auto-reload up/downcounter and a 16-bit prescaler while TIM3 and TIM4 timers are based on a 16-bit auto-reload up/downcounter plus a 16-bit prescaler. They all features four independent channels for input capture/output compare, PWM or one-pulse mode output. This gives up to 15 input capture/output compare/PWMs

  TIM2. TIM3, TIM4 and TIM5 general-purpose timers can operate together or in conjunction with the other general-purpose timers and TIM1 advanced-control timer via the Timer Link feature for synchronization or event chaining.

  Any of these general-purpose timers can be used to generate PWM output.

  TIM2. TIM3, TIM4 and TIM5 channels have independent DMA request generation. They are capable of handling quadrature (incremental) encoder signals and the digital outputs from 1 to 4 hall-effect sensors.

- **TIM9, TIM10, TIM11, TIM12, TIM13 and TIM14**

  These timers are based on a 16-bit auto-reload upcounter and a 16-bit prescaler. TIM10, TIM11, TIM13 and TIM14 feature one independent channel, whereas TIM9 and TIM12 have two independent channels for input capture/output compare, PWM or one-pulse mode output. They can be synchronized with TIM2. TIM3, TIM4 and TIM5 full-featured general-purpose timers or used as simple time bases.

### 3.23.3 Basic timer (TIM6, TIM7)

TIM6 and TIM7 timers are basic 16-bit timers. They support independent DMA request generation.



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### 3.23.4 Independent watchdog

The independent watchdog is based on a 12-bit downcounter and 8-bit prescaler. It is clocked from an independent 32 kHz internal RC and as it operates independently from the main clock, it can operate in Stop and Standby modes. It can be used either as a watchdog to reset the device when a problem occurs, or as a free-running timer for application timeout management. It is hardware- or software-configurable through the option bytes.

### 3.23.5 Window watchdog

The window watchdog is based on a 7-bit downcounter that can be set as free-running. It can be used as a watchdog to reset the device when a problem occurs. It is clocked from the main clock. It has an early warning interrupt capability and the counter can be frozen in debug mode.

### 3.23.6 SysTick timer

This timer is dedicated to real-time operating systems, but could also be used as a standard downcounter. It features:

- A 24-bit downcounter
- Autoreload capability
- Maskable system interrupt generation when the counter reaches 0
- Programmable clock source.

## 3.24 Inter-integrated circuit interface ($I^2C$)

The devices feature up to four $I^2C$ bus interfaces which can operate in multimaster and slave modes:

- One $I^2C$ interface supports the Standard mode (up to 100 kHz), Fast-mode (up to 400 kHz) modes and Fast-mode plus (up to 1 MHz).
- Three $I^2C$ interfaces support the Standard mode (up to 100 KHz) and the Fast mode (up to 400 KHz). Their frequency can be increased up to 1 MHz. For more details on the complete solution, refer to the nearest STMicroelectronics sales office.

All $I^2C$ interfaces features 7/10-bit addressing mode and 7-bit addressing mode (as slave) and embed a hardware CRC generation/verification.

They can be served by DMA and they support SMBus 2.0/PMBus.

The devices also include programmable analog and digital noise filters (see *Table 6*).

**Table 6. Comparison of I2C analog and digital filters**

| | Analog filter | Digital filter |
|---|---|---|
| Pulse width of suppressed spikes | ≥ 50 ns | Programmable length from 1 to 15 I2C peripheral clocks |



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## 3.25 Universal synchronous/asynchronous receiver transmitters (USART)

The devices embed four universal synchronous/asynchronous receiver transmitters (USART1, USART2, USART3 and USART6).

These four interfaces provide asynchronous communication, IrDA SIR ENDEC support, multiprocessor communication mode, single-wire half-duplex communication mode and have LIN Master/Slave capability. USART1 and USART6 interfaces are able to communicate at speeds of up to 12.5 Mbit/s. USART2 and USART3 interfaces communicate at up to 6.25 bit/s.

All USART interfaces provide hardware management of the CTS and RTS signals, Smart Card mode (ISO 7816 compliant) and SPI-like communication capability. All interfaces can be served by the DMA controller.

**Table 7. USART feature comparison**

| USART name | Standard features | Modem (RTS/CTS) | LIN | SPI master | irDA | Smartcard (ISO 7816) | Max. baud rate in Mbit/s (oversampling by 16) | Max. baud rate in Mbit/s (oversampling by 8) | APB mapping |
|---|---|---|---|---|---|---|---|---|---|
| USART1 | X | X | X | X | X | X | 6.25 | 12.5 | APB2 (max. 100 MHz) |
| USART2 | X | X | X | X | X | X | 3.12 | 6.25 | APB1 (max. 50 MHz) |
| USART3 (1) | X | X | X | X | X | X | 3.12 | 6.25 | APB1 (max. 50 MHz) |
| USART6 | X | X | X | X | X | X | 6.25 | 12.5 | APB2 (max. 100 MHz) |

1. The RX is not available for the UFQFPN48 package.

## 3.26 Serial peripheral interface (SPI)

The devices feature five SPIs in slave and master modes in full-duplex and simplex communication modes. SPI1, SPI4 and SPI5 can communicate at up to 50 Mbit/s, SPI2 and SPI3 can communicate at up to 25 Mbit/s. The 3-bit prescaler gives 8 master mode frequencies and the frame is configurable to 8 bits or 16 bits. The hardware CRC generation/verification supports basic SD Card/MMC modes. All SPIs can be served by the DMA controller.

The SPI interfaces can be configured to operate in TI mode for communications in master mode and slave mode.



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## 3.27 Inter-integrated sound ($I^2S$)

Five standard $I^2S$ interfaces (multiplexed with SPI1 to SPI5) are available. They can be operated in master or slave mode, in simplex communication mode, and full duplex mode for I2S2 and I2S3. All $I^2S$ interfaces can be configured to operate with a 16-/32-bit resolution as an input or output channel. I2Sx audio sampling frequencies from 8 kHz up to 192 kHz are supported. When either or both of the $I^2S$ interfaces is/are configured in master mode, the master clock can be output to the external DAC/CODEC at 256 times the sampling frequency.

All $I^2Sx$ interfaces can be served by the DMA controller.

## 3.28 Audio PLL (PLLI2S)

The devices feature an additional dedicated PLL for audio $I^2S$ applications. It allows to achieve error-free $I^2S$ sampling clock accuracy without compromising on the CPU performance, while using USB peripherals.

Different sources can be selected for the I2S master clock of the APB1 and the I2S master clock of the APB2. This gives the flexibility to work with two different audio sampling frequencies. The different possible sources are the main PLL, the PLLI2S, HSE or HSI clocks or an external clock provided through a pin (external PLL or Codec output)

The PLLI2S configuration can be modified to manage an $I^2S$ sample rate change without disabling the main PLL (PLL) used for CPU, USB and Ethernet interfaces.

The audio PLL can be programmed with very low error to obtain sampling rates ranging from 8 KHz to 192 KHz.

## 3.29 Digital filter for sigma-delta modulators (DFSDM)

The device embeds one DFSDM with 2 digital filters modules and 4 external input serial channels (transceivers) or alternately 2 internal parallel inputs support.

The amount of filters defines the number of conversions which can be performed simultaneously.

The DFSDM peripheral is dedicated to interface the external ΣΔ modulators to microcontroller and then to perform digital filtering of the received data streams (which represent analog value on ΣΔ modulators inputs). DFSDM can also interface PDM (Pulse Density Modulation) microphones and perform PDM to PCM conversion and filtering in hardware. DFSDM features optional parallel data stream inputs from microcontrollers memory (through DMA/CPU transfers into DFSDM).

DFSDM transceivers support several serial interface formats (to support various ΣΔ modulators). DFSDM digital filter modules perform digital processing according user selected filter parameters with up to 24-bit final ADC resolution.



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The DFSDM peripheral supports:

- 4 multiplexed input digital serial channels:
  - configurable SPI interface to connect various SD modulator(s)
  - configurable Manchester coded 1 wire interface support
  - PDM (Pulse Density Modulation) microphone input support
  - maximum input clock frequency up to 20 MHz (10 MHz for Manchester coding)
  - clock output for SD modulator(s): 0...20 MHz
- alternative inputs from 4 internal digital parallel channels (up to 16 bit input resolution):
  - internal sources: device memory data streams (DMA)
- 2 digital filter modules with adjustable digital signal processing:
  - Sinc$^x$ filter: filter order/type (1...5), oversampling ratio (up to 1...1024)
  - integrator: oversampling ratio (1...256)
- up to 24-bit output data resolution, signed output data format
- automatic data offset correction (offset stored in register by user)
- continuous or single conversion
- start-of-conversion triggered by
  - software trigger
  - internal timers
  - external events
  - start-of-conversion synchronously with first digital filter module (DFSDM1FLT0)
- analog watchdog feature:
  - low value and high value data threshold registers
  - dedicated configurable Sinc$^x$ digital filter (order = 1...3, oversampling ratio = 1...32
  - input from digital output data or from selected input digital serial channels
  - continuous monitoring independently from standard conversion
- short circuit detector to detect saturated analog input values (bottom and top range):
  - up to 8-bit counter to detect 1...256 consecutive 0's or 1's on serial data stream
  - monitoring continuously each input serial channel
- break signal generation on analog watchdog event or on short circuit detector event
- extremes detector:
  - storage of minimum and maximum values of final conversion data
  - refreshed by software
- DMA capability to read the final conversion data
- interrupts: end of conversion, overrun, analog watchdog, short circuit input serial channel clock absence
- "regulator" or injected" conversions:
  - "regular" conversions can be requested at any time or even in continuous mode without having any impact on the timing of "injected" conversions
  - "injected" conversions for precise timing and with high conversion priority.



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## 3.30 Secure digital input/output interface (SDIO)

An SD/SDIO/MMC host interface is available, that supports MultiMediaCard System Specification Version 4.2 in three different databus modes: 1-bit (default), 4-bit and 8-bit.

The interface allows data transfer at up to 50 MHz, and is compliant with the SD Memory Card Specification Version 2.0.

The SDIO Card Specification Version 2.0 is also supported with two different databus modes: 1-bit (default) and 4-bit.

The current version supports only one SD/SDIO/MMC4.2 card at any one time and a stack of MMC4.1 or previous.

In addition to SD/SDIO/MMC/eMMC, this interface is fully compliant with the CE-ATA digital protocol Rev1.1.

## 3.31 Controller area network (bxCAN)

The two CANs are compliant with the 2.0A and B (active) specifications with a bitrate up to 1 Mbit/s. They can receive and transmit standard frames with 11-bit identifiers as well as extended frames with 29-bit identifiers. Each CAN has three transmit mailboxes, two receive FIFOS with 3 stages and 28 shared scalable filter banks (all of them can be used even if one CAN is used). 256 byte of SRAM are allocated for each CAN.

## 3.32 Universal serial bus on-the-go full-speed (USB_OTG_FS)

The devices embed an USB OTG full-speed device/host/OTG peripheral with integrated transceivers. The USB OTG FS peripheral is compliant with the USB 2.0 specification and with the OTG 1.0 specification. It has software-configurable endpoint setting and supports suspend/resume. The USB OTG full-speed controller requires a dedicated 48 MHz clock that is generated by a PLL connected to the HSE oscillator. The Battery Charging Detection (BCD) can detect and identify the type of port, it is connected to (standard USB or charger). The type of charging is also detected: Dedicated Charging Port (DCP), Charging Downstream Port (CDP) and Standard Downstream Port (SDP). Some packages provide a dedicated USB power rail allowing a different supply for the USB and for the rest of the chip. For instance the chip can be powered with the minimum specified supply and the USB running at the level defined by the standard. The major features are:

- Combined Rx and Tx FIFO size of 320 × 35 bits with dynamic FIFO sizing
- Supports the session request protocol (SRP) and host negotiation protocol (HNP)
- 6 bidirectional endpoints
- 12 host channels with periodic OUT support
- HNP/SNP/IP inside (no need for any external resistor)
- For OTG/Host modes, a power switch is needed in case bus-powered devices are connected
- Link Power Management (LPM)
- Battery Charging Detection (BCD) supporting DCP, CDP and SDP



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## 3.33 Random number generator (RNG)

All devices embed an RNG that delivers 32-bit random numbers generated by an integrated analog circuit.

## 3.34 General-purpose input/outputs (GPIOs)

Each of the GPIO pins can be configured by software as output (push-pull or open-drain, with or without pull-up or pull-down), as input (floating, with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog alternate functions. All GPIOs are high-current-capable and have speed selection to better manage internal noise, power consumption and electromagnetic emission.

The I/O configuration can be locked if needed by following a specific sequence in order to avoid spurious writing to the I/Os registers.

Fast I/O handling allowing maximum I/O toggling up to 100 MHz.

## 3.35 Analog-to-digital converter (ADC)

One 12-bit analog-to-digital converter is embedded and shares up to 16 external channels, performing conversions in the single-shot or scan mode. In scan mode, automatic conversion is performed on a selected group of analog inputs.

The ADC can be served by the DMA controller. An analog watchdog feature allows very precise monitoring of the converted voltage of one, some or all selected channels. An interrupt is generated when the converted voltage is outside the programmed thresholds.

To synchronize A/D conversion and timers, the ADCs could be triggered by any of TIM1, TIM2, TIM3, TIM4 or TIM5 timer.

## 3.36 Temperature sensor

The temperature sensor has to generate a voltage that varies linearly with temperature. The conversion range is between 1.7 V and 3.6 V. The temperature sensor is internally connected to the ADC_IN18 input channel which is used to convert the sensor output voltage into a digital value. Refer to the reference manual for additional information.

As the offset of the temperature sensor varies from chip to chip due to process variation, the internal temperature sensor is mainly suitable for applications that detect temperature changes instead of absolute temperatures. If an accurate temperature reading is needed, then an external temperature sensor part should be used.

## 3.37 Serial wire JTAG debug port (SWJ-DP)

The Arm SWJ-DP interface is embedded, and is a combined JTAG and serial wire debug port that enables either a serial wire debug or a JTAG probe to be connected to the target.

Debug is performed using 2 pins only instead of 5 required by the JTAG (JTAG pins could be re-use as GPIO with alternate function): the JTAG TMS and TCK pins are shared with SWDIO and SWCLK, respectively, and a specific sequence on the TMS pin is used to switch between JTAG-DP and SW-DP.



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## 3.38 Embedded Trace Macrocell™

The Arm Embedded Trace Macrocell provides a greater visibility of the instruction and data flow inside the CPU core by streaming compressed data at a very high rate from the STM32F412xE/G through a small number of ETM pins to an external hardware trace port analyzer (TPA) device. The TPA is connected to a host computer using any high-speed channel available. Real-time instruction and data flow activity can be recorded and then formatted for display on the host computer that runs the debugger software. TPA hardware is commercially available from common development tool vendors.

The Embedded Trace Macrocell operates with third party debugger software tools.

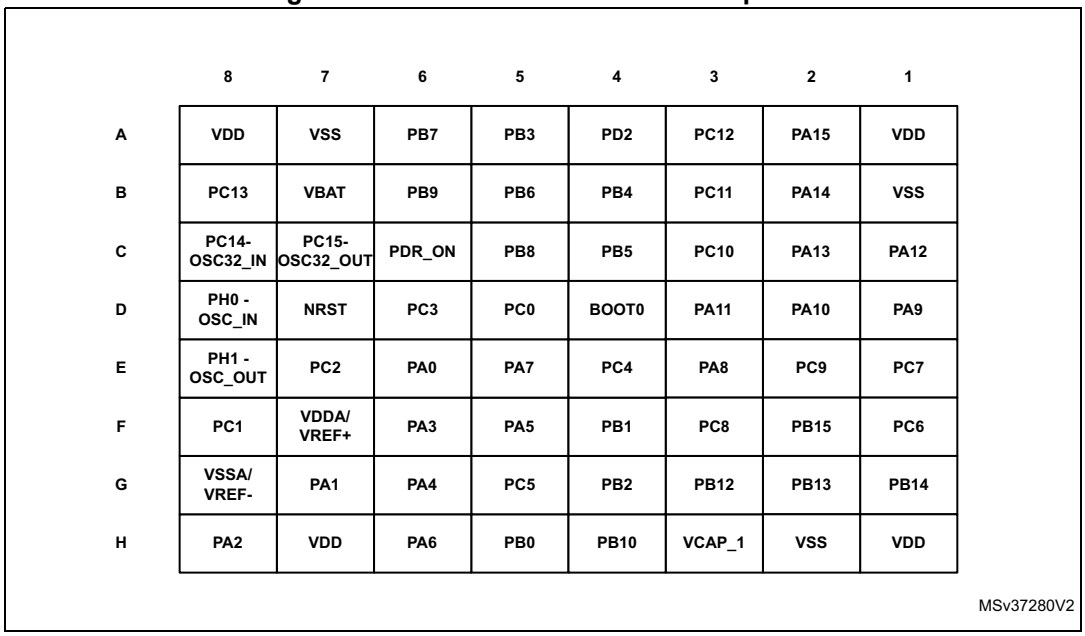


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# 4 Pinouts and pin description

## 4.1 WLSCP64 pinout description

**Figure 11. STM32F412xE/G WLCSP64 pinout**



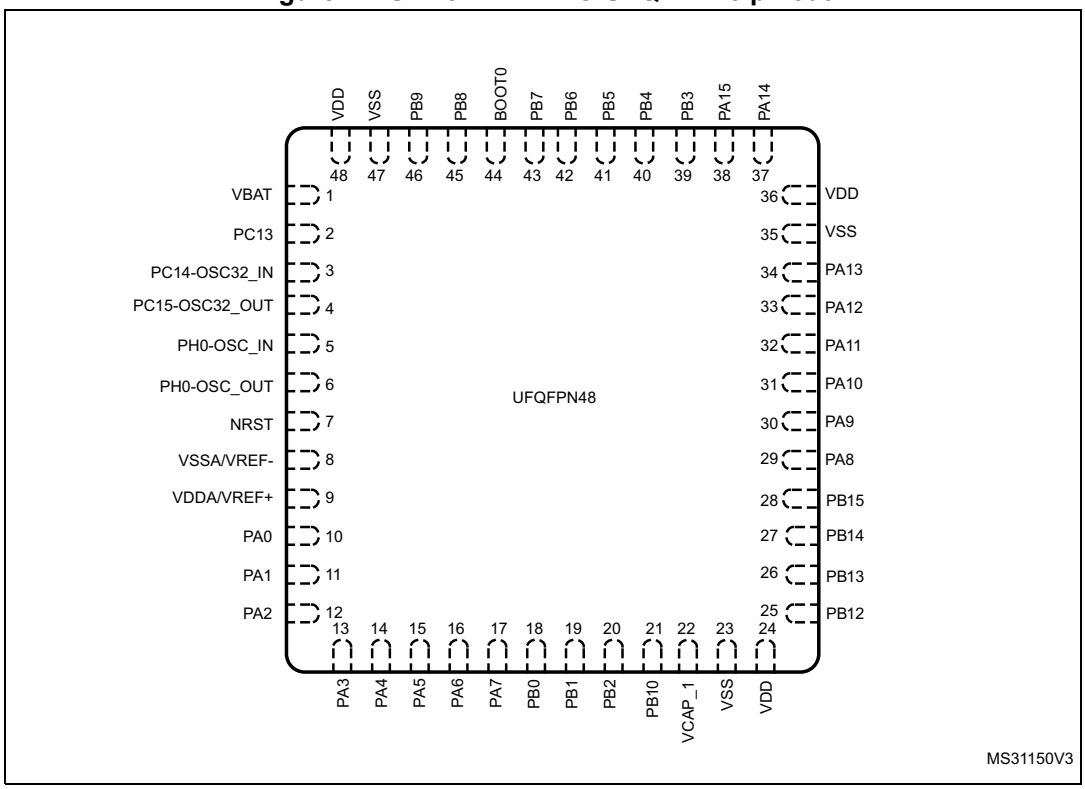

1. The above figure shows the package bump side.



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## 4.2 UFQFPN48 pinout description

**Figure 12. STM32F412xE/G UFQFPN48 pinout**



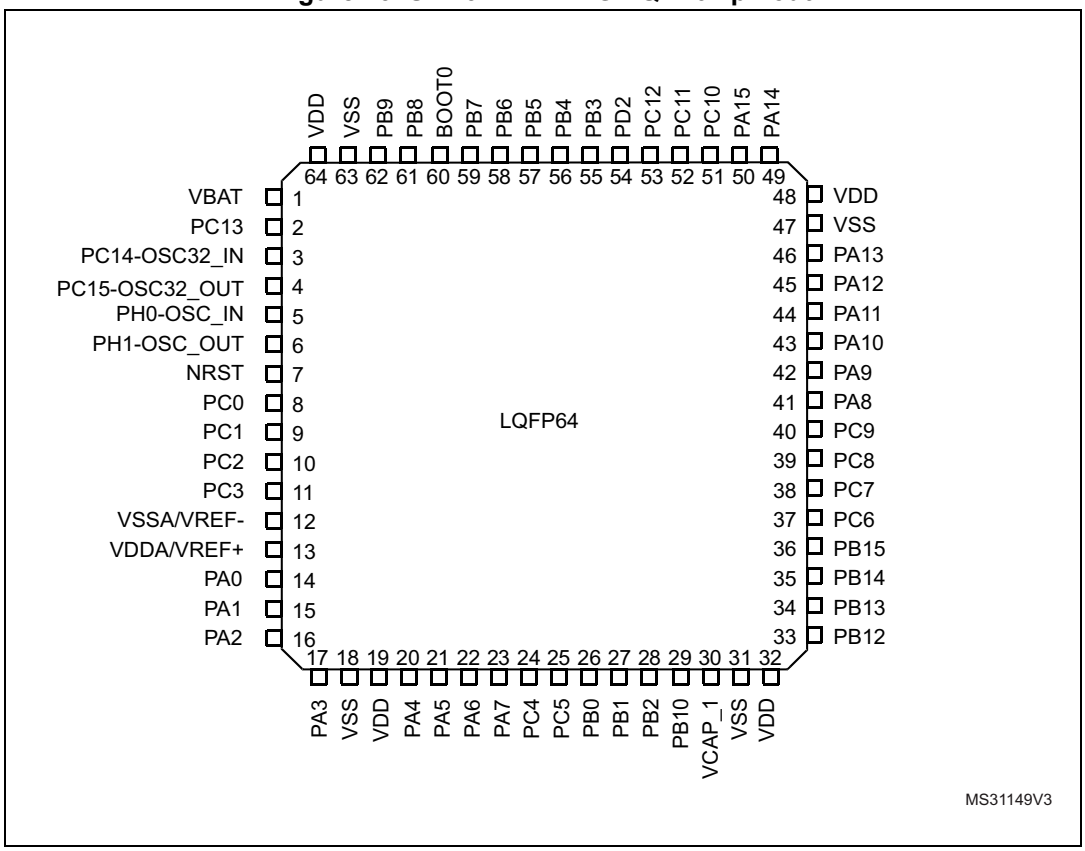

1. The above figure shows the package top view.



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## 4.3 LQFP64 pinout description

**Figure 13. STM32F412xE/G LQFP64 pinout**



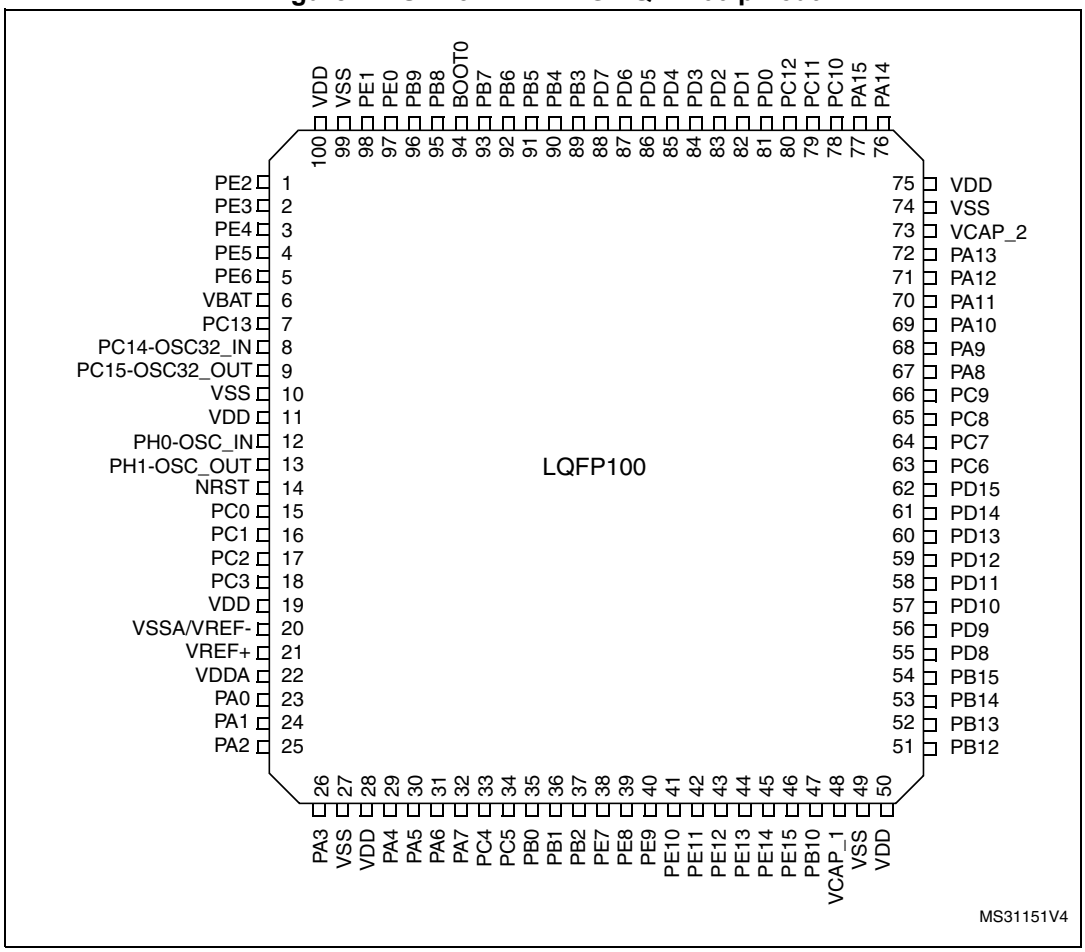

1. The above figure shows the package top view.



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## 4.4 LQFP100 pinout description

**Figure 14. STM32F412xE/G LQFP100 pinout**



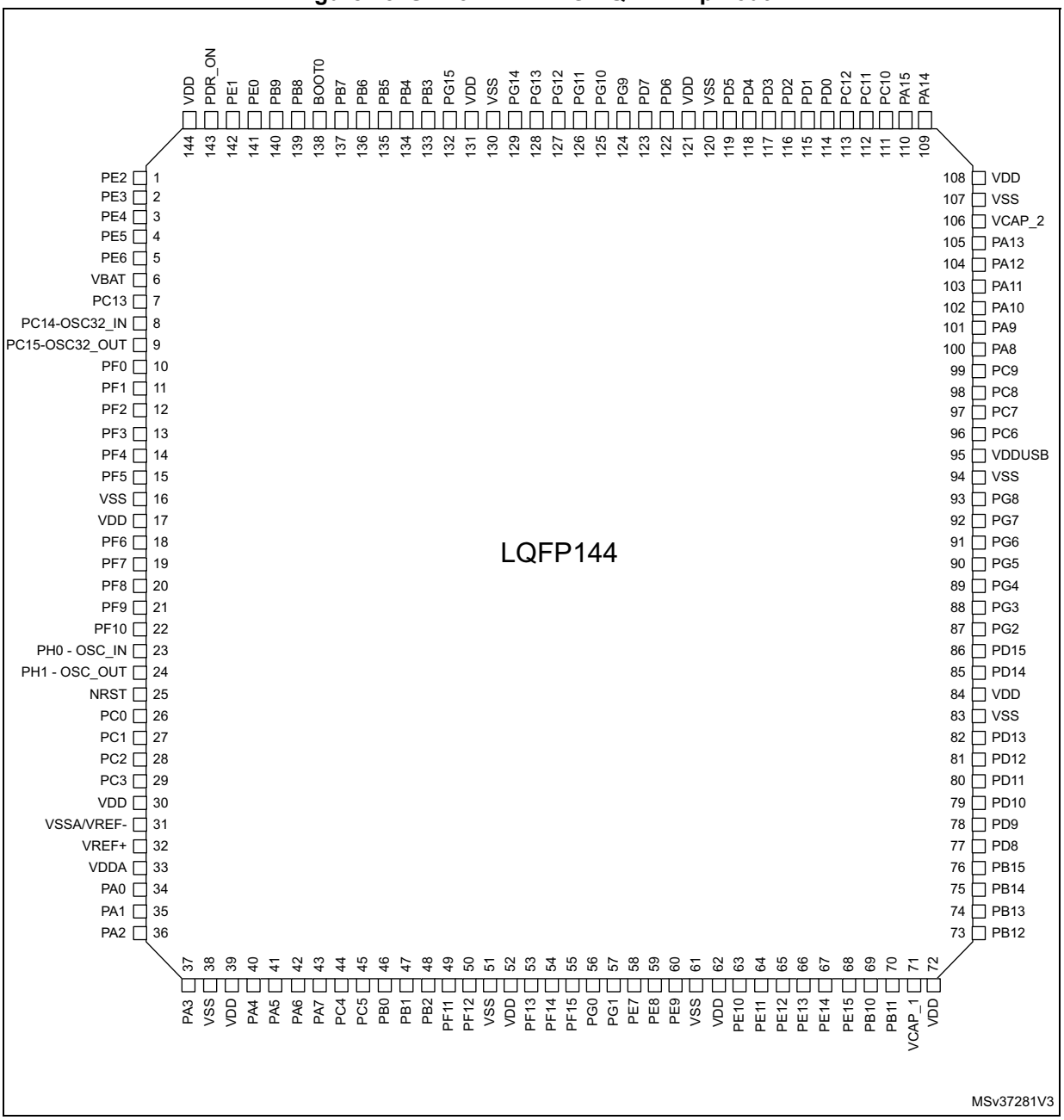

1. The above figure shows the package top view.



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## 4.5 LQFP144 pinout description

**Figure 15. STM32F412xE/G LQFP144 pinout**



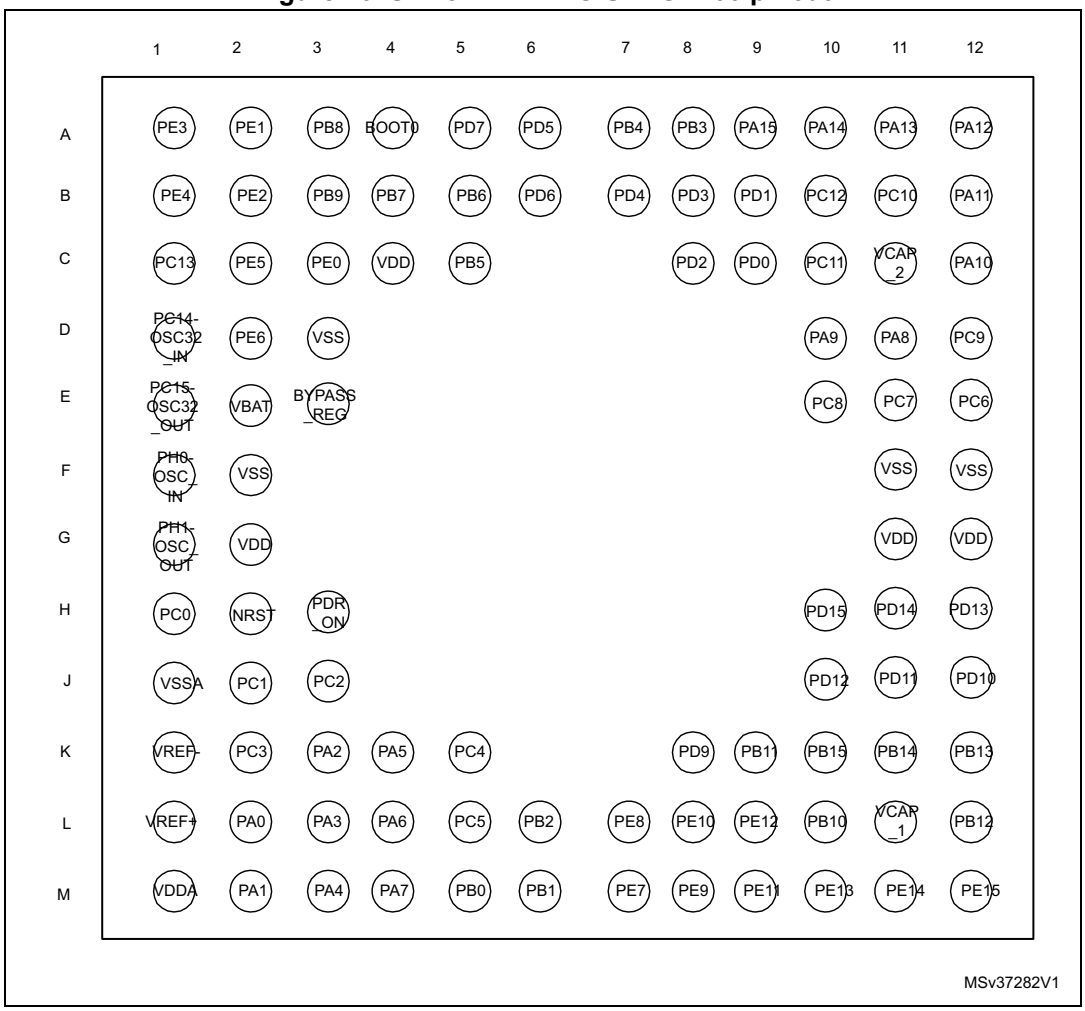

1. The above figure shows the package top view.



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## 4.6 UFBGA100 pinout description

**Figure 16. STM32F412xE/G UFBGA100 pinout**



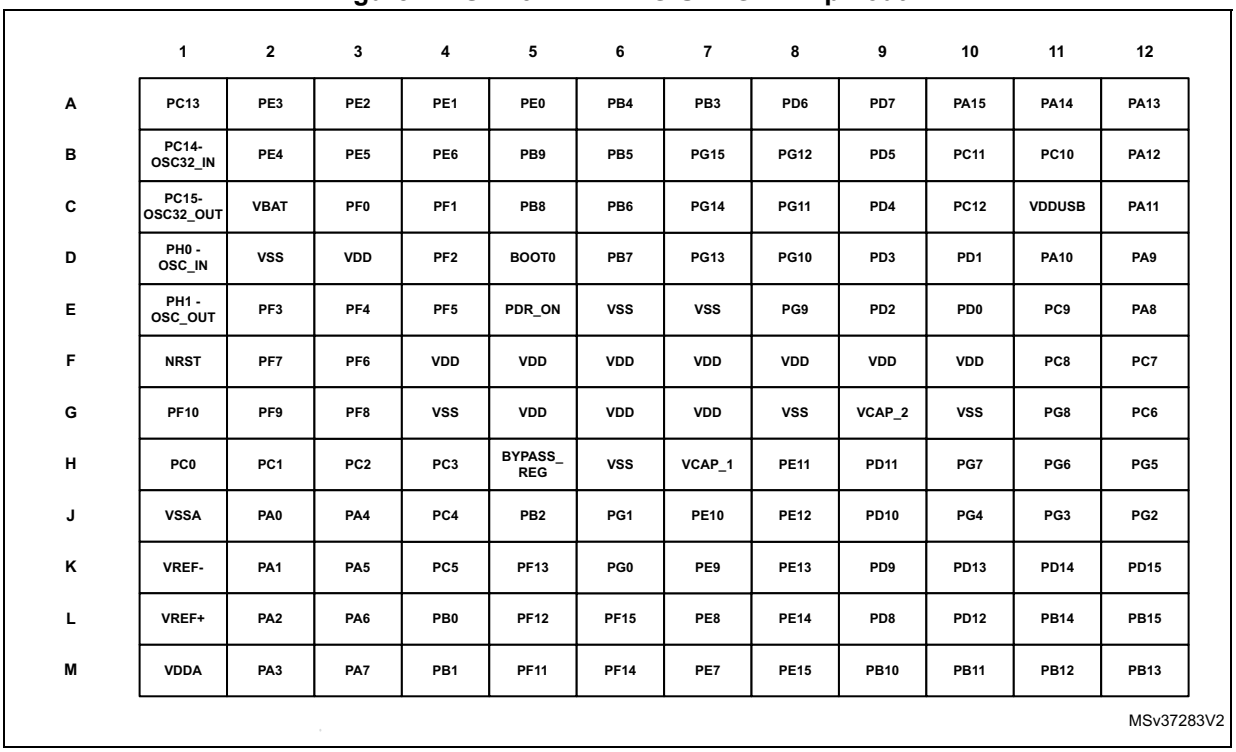

1. The above figure shows the package top view.



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## 4.7 UFBGA144 pinout description

**Figure 17. STM32F412xE/G UFBGA144 pinout**



| | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| A | PC13 | PE3 | PE2 | PE1 | PE0 | PB4 | PB3 | PD6 | PD7 | PA15 | PA14 | PA13 |
| B | PC14-OSC32_IN | PE4 | PE5 | PE6 | PB9 | PB5 | PG15 | PG12 | PD5 | PC11 | PC10 | PA12 |
| C | PC15-OSC32_OUT | VBAT | PF0 | PF1 | PB8 | PB6 | PG14 | PG11 | PD4 | PC12 | VDDUSB | PA11 |
| D | PH0 - OSC_IN | VSS | VDD | PF2 | BOOT0 | PB7 | PG13 | PG10 | PD3 | PD1 | PA10 | PA9 |
| E | PH1 - OSC_OUT | PF3 | PF4 | PF5 | PDR_ON | VSS | VSS | PG9 | PD2 | PD0 | PC9 | PA8 |
| F | NRST | PF7 | PF6 | VDD | VDD | VDD | VDD | VDD | VDD | VDD | PC8 | PC7 |
| G | PF10 | PF9 | PF8 | VSS | VDD | VDD | VDD | VSS | VCAP_2 | VSS | PG8 | PC6 |
| H | PC0 | PC1 | PC2 | PC3 | BYPASS_REG | VSS | VCAP_1 | PE11 | PD11 | PG7 | PG6 | PG5 |
| J | VSSA | PA0 | PA4 | PC4 | PB2 | PG1 | PE10 | PE12 | PD10 | PG4 | PG3 | PG2 |
| K | VREF- | PA1 | PA5 | PC5 | PF13 | PG0 | PE9 | PE13 | PD9 | PD13 | PD14 | PD15 |
| L | VREF+ | PA2 | PA6 | PB0 | PF12 | PF15 | PE8 | PE14 | PD8 | PD12 | PB14 | PB15 |
| M | VDDA | PA3 | PA7 | PB1 | PF11 | PF14 | PE7 | PE15 | PB10 | PB11 | PB12 | PB13 |

MSv37283V2

1. The above figure shows the package top view.

## 4.8 Pin definition

**Table 8. Legend/abbreviations used in the pinout table**

| Name | Abbreviation | Definition |
|---|---|---|
| Pin name | Unless otherwise specified in brackets below the pin name, the pin function during and after reset is the same as the actual pin name | |
| Pin type | S | Supply pin |
| | I | Input only pin |
| | I/O | Input/ output pin |
| I/O structure | FT | 5 V tolerant I/O |
| | TC | Standard 3.3 V I/O |
| | B | Dedicated BOOT0 pin |
| | NRST | Bidirectional reset pin with embedded weak pull-up resistor |
| Notes | Unless otherwise specified by a note, all I/Os are set as floating inputs during and after reset | |



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**Table 8. Legend/abbreviations used in the pinout table (continued)**

| Name | Abbreviation | Definition |
|---|---|---|
| Alternate functions | Functions selected through GPIOx_AFR registers | |
| Additional functions | Functions directly selected/enabled through peripheral registers | |

**Table 9. STM32F412xE/G pin definition**

| Pin Number | | | | | | | Pin name (function after reset)(1) | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| UFQFPN48 | LQFP64 | WLCSP64 | LQFP100 | UFBGA100 | UFBGA144 | LQFP144 | | | | | | |
| - | - | - | 1 | B2 | A3 | 1 | PE2 | I/O | FT | - | TRACECLK, SPI4_SCK/I2S4_CK, SPI5_SCK/I2S5_CK, QUADSPI_BK1_IO2, FSMC_A23, EVENTOUT | - |
| - | - | - | 2 | A1 | A2 | 2 | PE3 | I/O | FT | - | TRACED0, FSMC_A19, EVENTOUT | - |
| - | - | - | 3 | B1 | B2 | 3 | PE4 | I/O | FT | - | TRACED1, SPI4_NSS/I2S4_WS, SPI5_NSS/I2S5_WS, DFSDM1_DATIN3, FSMC_A20, EVENTOUT | - |
| - | - | - | 4 | C2 | B3 | 4 | PE5 | I/O | FT | - | TRACED2, TIM9_CH1, SPI4_MISO, SPI5_MISO, DFSDM1_CKIN3, FSMC_A21, EVENTOUT | - |
| - | - | - | 5 | D2 | B4 | 5 | PE6 | I/O | FT | - | TRACED3, TIM9_CH2, SPI4_MOSI/I2S4_SD, SPI5_MOSI/I2S5_SD, FSMC_A22, EVENTOUT | - |
| 1 | 1 | B7 | 6 | E2 | C2 | 6 | VBAT | S | - | - | - | VBAT |
| 2 | 2 | B8 | 7 | C1 | A1 | 7 | PC13 | I/O | FT | (2)(3) | EVENTOUT | TAMP_1 |
| 3 | 3 | C8 | 8 | D1 | B1 | 8 | PC14-OSC32_IN | I/O | FT | (2)(3)(4) | EVENTOUT | OSC32_IN |



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Table 9. STM32F412xE/G pin definition (continued)

| Pin Number | | | | | | | Pin name (function after reset)(1) | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| UFQFPN48 | LQFP64 | WLCSP64 | LQFP100 | UFBGA100 | UFBGA144 | LQFP144 | | | | | | |
| 4 | 4 | C7 | 9 | E1 | C1 | 9 | PC15-OSC32_OUT | I/O | FT | (2)(4) | EVENTOUT | OSC32_OUT |
| - | - | - | - | - | C3 | 10 | PF0 | I/O | FT | - | I2C2_SDA, FSMC_A0, EVENTOUT | - |
| - | - | - | - | - | C4 | 11 | PF1 | I/O | FT | - | I2C2_SCL, FSMC_A1, EVENTOUT | - |
| - | - | - | - | - | D4 | 12 | PF2 | I/O | FT | - | I2C2_SMBA, FSMC_A2, EVENTOUT | - |
| - | - | - | - | - | E2 | 13 | PF3 | I/O | FT | - | TIM5_CH1, FSMC_A3, EVENTOUT | - |
| - | - | - | - | - | E3 | 14 | PF4 | I/O | FT | - | TIM5_CH2, FSMC_A4, EVENTOUT | - |
| - | - | - | - | - | E4 | 15 | PF5 | I/O | FT | - | TIM5_CH3, FSMC_A5, EVENTOUT | - |
| - | - | - | 10 | F2 | D2 | 16 | VSS | S | - | - | - | - |
| - | - | - | 11 | G2 | D3 | 17 | VDD | S | - | - | - | - |
| - | - | - | - | - | F3 | 18 | PF6 | I/O | FT | - | TRACED0, TIM10_CH1, QUADSPI_BK1_IO3, EVENTOUT | - |
| - | - | - | - | - | F2 | 19 | PF7 | I/O | FT | - | TRACED1, TIM11_CH1, QUADSPI_BK1_IO2, EVENTOUT | - |
| - | - | - | - | - | G3 | 20 | PF8 | I/O | FT | - | TIM13_CH1, QUADSPI_BK1_IO0, EVENTOUT | - |
| - | - | - | - | - | G2 | 21 | PF9 | I/O | FT | - | TIM14_CH1, QUADSPI_BK1_IO1, EVENTOUT | - |
| - | - | - | - | - | G1 | 22 | PF10 | I/O | FT | - | TIM1_ETR, TIM5_CH4, EVENTOUT | - |
| 5 | 5 | D8 | 12 | F1 | D1 | 23 | PH0 - OSC_IN | I/O | FT | (4) | EVENTOUT | OSC_IN |
| 6 | 6 | E8 | 13 | G1 | E1 | 24 | PH1 - OSC_OUT | I/O | FT | (4) | EVENTOUT | OSC_OUT |
| 7 | 7 | D7 | 14 | H2 | F1 | 25 | NRST | I/O | RST | - | - | NRST |



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**Table 9. STM32F412xE/G pin definition (continued)**

| Pin Number | | | | | | | Pin name (function after reset)(1) | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| UFQFPN48 | LQFP64 | WLCSP64 | LQFP100 | UFBGA100 | UFBGA144 | LQFP144 | | | | | | |
| - | 8 | D5 | 15 | H1 | H1 | 26 | PC0 | I/O | FT | - | EVENTOUT | ADC1_10, WKUP2 |
| - | 9 | F8 | 16 | J2 | H2 | 27 | PC1 | I/O | FT | - | EVENTOUT | ADC1_11, WKUP3 |
| - | 10 | E7 | 17 | J3 | H3 | 28 | PC2 | I/O | FT | - | SPI2_MISO, I2S2ext_SD, DFSDM1_CKOUT, FSMC_NWE, EVENTOUT | ADC1_12 |
| - | 11 | D6 | 18 | K2 | H4 | 29 | PC3 | I/O | FT | - | SPI2_MOSI/I2S2_SD, FSMC_A0, EVENTOUT | ADC1_13 |
| - | - | - | 19 | - | - | 30 | VDD | S | - | - | - | - |
| 8 | 12 | G8 | 20 | - | - | 31 | VSSA/ VREF | S | - | - | - | - |
| - | - | - | - | J1 | J1 | - | VSSA | S | - | - | - | - |
| - | - | - | - | K1 | K1 | - | VREF- | S | - | - | - | - |
| 9 | 13 | F7 | - | - | - | - | VDDA/ VREF+ | S | - | - | - | - |
| - | - | - | 21 | L1 | L1 | 32 | VREF+ | S | - | - | - | - |
| - | - | - | 22 | M1 | M1 | 33 | VDDA | S | - | - | - | - |
| 10 | 14 | E6 | 23 | L2 | J2 | 34 | PA0 | I/O | FT | - | TIM2_CH1/TIM2_ETR, TIM5_CH1, TIM8_ETR, USART2_CTS, EVENTOUT | ADC1_0, WKUP1 |
| 11 | 15 | G7 | 24 | M2 | K2 | 35 | PA1 | I/O | FT | - | TIM2_CH2, TIM5_CH2, SPI4_MOSI/I2S4_SD, USART2_RTS, QUADSPI_BK1_IO3, EVENTOUT | ADC1_1 |
| 12 | 16 | H8 | 25 | K3 | L2 | 36 | PA2 | I/O | FT | - | TIM2_CH3, TIM5_CH3, TIM9_CH1, I2S2_CKIN, USART2_TX, FSMC_D4/FSMC_DA4, EVENTOUT | ADC1_2 |



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Table 9. STM32F412xE/G pin definition (continued)

| Pin Number | | | | | | | Pin name (function after reset)(1) | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| UFQFPN48 | LQFP64 | WLCSP64 | LQFP100 | UFBGA100 | UFBGA144 | LQFP144 | | | | | | |
| 13 | 17 | F6 | 26 | L3 | M2 | 37 | PA3 | I/O | FT | - | TIM2_CH4, TIM5_CH4, TIM9_CH2, I2S2_MCK, USART2_RX, FSMC_D5/FSMC_DA5, EVENTOUT | ADC1_3 |
| - | 18 | - | 27 | - | G4 | 38 | VSS | S | - | - | - | - |
| - | - | - | - | E3 | H5 | - | BYPASS_REG | I | FT | - | - | - |
| - | 19 | H7 | 28 | - | F4 | 39 | VDD | S | - | - | - | - |
| 14 | 20 | G6 | 29 | M3 | J3 | 40 | PA4 | I/O | FT | - | SPI1_NSS/I2S1_WS, SPI3_NSS/I2S3_WS, USART2_CK, DFSDM1_DATIN1, FSMC_D6/FSMC_DA6, EVENTOUT | ADC1_4 |
| 15 | 21 | F5 | 30 | K4 | K3 | 41 | PA5 | I/O | FT | - | TIM2_CH1/TIM2_ETR, TIM8_CH1N, SPI1_SCK/I2S1_CK, DFSDM1_CKIN1, FSMC_D7/FSMC_DA7, EVENTOUT | ADC1_5 |
| 16 | 22 | H6 | 31 | L4 | L3 | 42 | PA6 | I/O | FT | - | TIM1_BKIN, TIM3_CH1, TIM8_BKIN, SPI1_MISO, I2S2_MCK, TIM13_CH1, QUADSPI_BK2_IO0, SDIO_CMD, EVENTOUT | ADC1_6 |
| 17 | 23 | E5 | 32 | M4 | M3 | 43 | PA7 | I/O | FT | - | TIM1_CH1N, TIM3_CH2, TIM8_CH1N, SPI1_MOSI/I2S1_SD, TIM14_CH1, QUADSPI_BK2_IO1, EVENTOUT | ADC1_7 |
| - | 24 | E4 | 33 | K5 | J4 | 44 | PC4 | I/O | FT | - | I2S1_MCK, QUADSPI_BK2_IO2, FSMC_NE4, EVENTOUT | ADC1_14 |



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Table 9. STM32F412xE/G pin definition (continued)

| Pin Number | | | | | | | Pin name (function after reset)(1) | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| UFQFPN48 | LQFP64 | WLCSP64 | LQFP100 | UFBGA100 | UFBGA144 | LQFP144 | | | | | | |
| - | 25 | G5 | 34 | L5 | K4 | 45 | PC5 | I/O | FT | - | I2CFMP1_SMBA, USART3_RX, QUADSPI_BK2_IO3, FSMC_NOE, EVENTOUT | ADC1_15 |
| 18 | 26 | H5 | 35 | M5 | L4 | 46 | PB0 | I/O | FT | - | TIM1_CH2N, TIM3_CH3, TIM8_CH2N, SPI5_SCK/I2S5_CK, EVENTOUT | ADC1_8 |
| 19 | 27 | F4 | 36 | M6 | M4 | 47 | PB1 | I/O | FT | - | TIM1_CH3N, TIM3_CH4, TIM8_CH3N, SPI5_NSS/I2S5_WS, DFSDM1_DATIN0, QUADSPI_CLK, EVENTOUT | ADC1_9 |
| 20 | 28 | G4 | 37 | L6 | J5 | 48 | PB2 | I/O | FT | - | DFSDM1_CKIN0, QUADSPI_CLK, EVENTOUT | BOOT1 |
| - | - | - | - | - | M5 | 49 | PF11 | I/O | FT | - | TIM8_ETR, EVENTOUT | - |
| - | - | - | - | - | L5 | 50 | PF12 | I/O | FT | - | TIM8_BKIN, FSMC_A6, EVENTOUT | - |
| - | - | - | - | - | - | 51 | VSS | S | - | - | - | - |
| - | - | - | - | - | G5 | 52 | VDD | S | - | - | - | - |
| - | - | - | - | - | K5 | 53 | PF13 | I/O | FT | - | I2CFMP1_SMBA, FSMC_A7, EVENTOUT | - |
| - | - | - | - | - | M6 | 54 | PF14 | I/O | FT | - | I2CFMP1_SCL, FSMC_A8, EVENTOUT | - |
| - | - | - | - | - | L6 | 55 | PF15 | I/O | FT | - | I2CFMP1_SDA, FSMC_A9, EVENTOUT | - |
| - | - | - | - | - | K6 | 56 | PG0 | I/O | FT | - | CAN1_RX, FSMC_A10, EVENTOUT | - |
| - | - | - | - | - | J6 | 57 | PG1 | I/O | FT | - | CAN1_TX, FSMC_A11, EVENTOUT | - |



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Table 9. STM32F412xE/G pin definition (continued)

| Pin Number | | | | | | | Pin name (function after reset)(1) | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| UFQFPN48 | LQFP64 | WLCSP64 | LQFP100 | UFBGA100 | UFBGA144 | LQFP144 | | | | | | |
| - | - | - | 38 | M7 | M7 | 58 | PE7 | I/O | FT | - | TIM1_ETR, DFSDM1_DATIN2, QUADSPI_BK2_IO0, FSMC_D4/FSMC_DA4, EVENTOUT | - |
| - | - | - | 39 | L7 | L7 | 59 | PE8 | I/O | FT | - | TIM1_CH1N, DFSDM1_CKIN2, QUADSPI_BK2_IO1, FSMC_D5/FSMC_DA5, EVENTOUT | - |
| - | - | - | 40 | M8 | K7 | 60 | PE9 | I/O | FT | - | TIM1_CH1, DFSDM1_CKOUT, QUADSPI_BK2_IO2, FSMC_D6/FSMC_DA6, EVENTOUT | - |
| - | - | - | - | - | - | 61 | VSS | S | - | - | - | - |
| - | - | - | - | - | G6 | 62 | VDD | S | - | - | - | - |
| - | - | - | 41 | L8 | J7 | 63 | PE10 | I/O | FT | - | TIM1_CH2N, QUADSPI_BK2_IO3, FSMC_D7/FSMC_DA7, EVENTOUT | - |
| - | - | - | 42 | M9 | H8 | 64 | PE11 | I/O | FT | - | TIM1_CH2, SPI4_NSS/I2S4_WS, SPI5_NSS/I2S5_WS, FSMC_D8/FSMC_DA8, EVENTOUT | - |
| - | - | - | 43 | L9 | J8 | 65 | PE12 | I/O | FT | - | TIM1_CH3N, SPI4_SCK/I2S4_CK, SPI5_SCK/I2S5_CK, FSMC_D9/FSMC_DA9, EVENTOUT | - |
| - | - | - | 44 | M10 | K8 | 66 | PE13 | I/O | FT | - | TIM1_CH3, SPI4_MISO, SPI5_MISO, FSMC_D10/FSMC_DA10, EVENTOUT | - |
| - | - | - | 45 | M11 | L8 | 67 | PE14 | I/O | FT | - | TIM1_CH4, SPI4_MOSI/I2S4_SD, SPI5_MOSI/I2S5_SD, FSMC_D11/FSMC_DA11, EVENTOUT | - |



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Table 9. STM32F412xE/G pin definition (continued)

| Pin Number | | | | | | | Pin name (function after reset)(1) | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| UFQFPN48 | LQFP64 | WLCSP64 | LQFP100 | UFBGA100 | UFBGA144 | LQFP144 | | | | | | |
| - | - | - | 46 | M12 | M8 | 68 | PE15 | I/O | FT | - | TIM1_BKIN, FSMC_D12/FSMC_DA12, EVENTOUT | - |
| 21 | 29 | H4 | 47 | L10 | M9 | 69 | PB10 | I/O | FT | - | TIM2_CH3, I2C2_SCL, SPI2_SCK/I2S2_CK, I2S3_MCK, USART3_TX, I2CFMP1_SCL, SDIO_D7, EVENTOUT | - |
| - | - | - | - | K9 | M10 | 70 | PB11 | I/O | FT | - | TIM2_CH4, I2C2_SDA, I2S2_CKIN, USART3_RX, EVENTOUT | - |
| 22 | 30 | H3 | 48 | L11 | H7 | 71 | VCAP_1 | S | - | - | - | - |
| 23 | 31 | H2 | 49 | F12 | H6 | - | VSS | S | - | - | - | - |
| 24 | 32 | H1 | 50 | G12 | G7 | 72 | VDD | S | - | - | - | - |
| 25 | 33 | G3 | 51 | L12 | M11 | 73 | PB12 | I/O | FT | - | TIM1_BKIN, I2C2_SMBA, SPI2_NSS/I2S2_WS, SPI4_NSS/I2S4_WS, SPI3_SCK/I2S3_CK, USART3_CK, CAN2_RX, DFSDM1_DATIN1, FSMC_D13/FSMC_DA13, EVENTOUT | - |
| 26 | 34 | G2 | 52 | K12 | M12 | 74 | PB13 | I/O | FT | - | TIM1_CH1N, I2CFMP1_SMBA, SPI2_SCK/I2S2_CK, SPI4_SCK/I2S4_CK, USART3_CTS, CAN2_TX, DFSDM1_CKIN1, EVENTOUT | - |



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Table 9. STM32F412xE/G pin definition (continued)

| Pin Number | | | | | | | Pin name (function after reset)(1) | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| UFQFPN48 | LQFP64 | WLCSP64 | LQFP100 | UFBGA100 | UFBGA144 | LQFP144 | | | | | | |
| 27 | 35 | G1 | 53 | K11 | L11 | 75 | PB14 | I/O | FT | - | TIM1_CH2N, TIM8_CH2N, I2CFMP1_SDA, SPI2_MISO, I2S2ext_SD, USART3_RTS, DFSDM1_DATIN2, TIM12_CH1, FSMC_D0/FSMC_DA0, SDIO_D6, EVENTOUT | - |
| 28 | 36 | F2 | 54 | K10 | L12 | 76 | PB15 | I/O | FT | - | RTC_50Hz, TIM1_CH3N, TIM8_CH3N, I2CFMP1_SCL, SPI2_MOSI/I2S2_SD, DFSDM1_CKIN2, TIM12_CH2, SDIO_CK, EVENTOUT | - |
| - | - | - | 55 | - | L9 | 77 | PD8 | I/O | FT | - | USART3_TX, FSMC_D13/ FSMC_DA13, EVENTOUT | - |
| - | - | - | 56 | K8 | K9 | 78 | PD9 | I/O | FT | - | USART3_RX, FSMC_D14/FSMC_DA14, EVENTOUT | - |
| - | - | - | 57 | J12 | J9 | 79 | PD10 | I/O | FT | - | USART3_CK, FSMC_D15/FSMC_DA15, EVENTOUT | - |
| - | - | - | 58 | J11 | H9 | 80 | PD11 | I/O | FT | - | I2CFMP1_SMBA, USART3_CTS, QUADSPI_BK1_IO0, FSMC_A16, EVENTOUT | - |
| - | - | - | 59 | J10 | L10 | 81 | PD12 | I/O | FT | - | TIM4_CH1, I2CFMP1_SCL, USART3_RTS, QUADSPI_BK1_IO1, FSMC_A17, EVENTOUT | - |



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Table 9. STM32F412xE/G pin definition (continued)

| Pin Number | | | | | | | Pin name (function after reset)(1) | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| UFQFPN48 | LQFP64 | WLCSP64 | LQFP100 | UFBGA100 | UFBGA144 | LQFP144 | | | | | | |
| - | - | - | 60 | H12 | K10 | 82 | PD13 | I/O | FT | - | TIM4_CH2, I2CFMP1_SDA, QUADSPI_BK1_IO3, FSMC_A18, EVENTOUT | - |
| - | - | - | - | - | G8 | 83 | VSS | S | - | - | - | - |
| - | - | - | - | - | F8 | 84 | VDD | S | - | - | - | - |
| - | - | - | 61 | H11 | K11 | 85 | PD14 | I/O | FT | - | TIM4_CH3, I2CFMP1_SCL, FSMC_D0/FSMC_DA0, EVENTOUT | - |
| - | - | - | 62 | H10 | K12 | 86 | PD15 | I/O | FT | - | TIM4_CH4, I2CFMP1_SDA, FSMC_D1/FSMC_DA1, EVENTOUT | - |
| - | - | - | - | - | J12 | 87 | PG2 | I/O | FT | - | FSMC_A12, EVENTOUT | - |
| - | - | - | - | - | J11 | 88 | PG3 | I/O | FT | - | FSMC_A13, EVENTOUT | - |
| - | - | - | - | - | J10 | 89 | PG4 | I/O | FT | - | FSMC_A14, EVENTOUT | - |
| - | - | - | - | - | H12 | 90 | PG5 | I/O | FT | - | FSMC_A15, EVENTOUT | - |
| - | - | - | - | - | H11 | 91 | PG6 | I/O | FT | - | QUADSPI_BK1_NCS, EVENTOUT | - |
| - | - | - | - | - | H10 | 92 | PG7 | I/O | FT | - | USART6_CK, EVENTOUT | - |
| - | - | - | - | - | G11 | 93 | PG8 | I/O | FT | - | USART6_RTS, EVENTOUT | - |
| - | - | - | - | - | - | 94 | VSS | S | - | - | - | - |
| - | - | - | - | - | F10 | - | VDD | S | - | | | |
| - | - | - | - | - | C11 | 95 | VDDUSB | S | - | - | - | - |



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Table 9. STM32F412xE/G pin definition (continued)

| Pin Number | | | | | | | Pin name (function after reset)(1) | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| UFQFPN48 | LQFP64 | WLCSP64 | LQFP100 | UFBGA100 | UFBGA144 | LQFP144 | | | | | | |
| - | 37 | F1 | 63 | E12 | G12 | 96 | PC6 | I/O | FT | - | TIM3_CH1, TIM8_CH1, I2CFMP1_SCL, I2S2_MCK, DFSDM1_CKIN3, USART6_TX, FSMC_D1/FSMC_DA1, SDIO_D6, EVENTOUT | - |
| - | 38 | E1 | 64 | E11 | F12 | 97 | PC7 | I/O | FT | - | TIM3_CH2, TIM8_CH2, I2CFMP1_SDA, SPI2_SCK/I2S2_CK, I2S3_MCK, USART6_RX, DFSDM1_DATIN3, SDIO_D7, EVENTOUT | - |
| - | 39 | F3 | 65 | E10 | F11 | 98 | PC8 | I/O | FT | - | TIM3_CH3, TIM8_CH3, USART6_CK, QUADSPI_BK1_IO2, SDIO_D0, EVENTOUT | - |
| - | 40 | E2 | 66 | D12 | E11 | 99 | PC9 | I/O | FT | - | MCO_2, TIM3_CH4, TIM8_CH4, I2C3_SDA, I2S2_CKIN, QUADSPI_BK1_IO0, SDIO_D1, EVENTOUT | - |
| 29 | 41 | E3 | 67 | D11 | E12 | 100 | PA8 | I/O | FT | - | MCO_1, TIM1_CH1, I2C3_SCL, USART1_CK, USB_FS_SOF, SDIO_D1, EVENTOUT | - |
| 30 | 42 | D1 | 68 | D10 | D12 | 101 | PA9 | I/O | FT | - | TIM1_CH2, I2C3_SMBA, USART1_TX, USB_FS_VBUS, SDIO_D2, EVENTOUT | - |
| 31 | 43 | D2 | 69 | C12 | D11 | 102 | PA10 | I/O | FT | - | TIM1_CH3, SPI5_MOSI/I2S5_SD, USART1_RX, USB_FS_ID, EVENTOUT | - |



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Table 9. STM32F412xE/G pin definition (continued)

| Pin Number | | | | | | | Pin name (function after reset)(1) | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| UFQFPN48 | LQFP64 | WLCSP64 | LQFP100 | UFBGA100 | UFBGA144 | LQFP144 | | | | | | |
| 32 | 44 | D3 | 70 | B12 | C12 | 103 | PA11 | I/O | FT | - | TIM1_CH4, SPI4_MISO, USART1_CTS, USART6_TX, CAN1_RX, USB_FS_DM, EVENTOUT | - |
| 33 | 45 | C1 | 71 | A12 | B12 | 104 | PA12 | I/O | FT | - | TIM1_ETR, SPI5_MISO, USART1_RTS, USART6_RX, CAN1_TX, USB_FS_DP, EVENTOUT | - |
| 34 | 46 | C2 | 72 | A11 | A12 | 105 | PA13 | I/O | FT | - | JTMS-SWDIO, EVENTOUT | - |
| - | - | - | 73 | C11 | G9 | 106 | VCAP_2 | S | - | - | - | - |
| 35 | 47 | B1 | 74 | F11 | G10 | 107 | VSS | S | - | - | - | - |
| 36 | 48 | - | 75 | G11 | - | - | VDD | S | - | - | - | - |
| - | - | A1 | - | - | F9 | 108 | VDD | S | - | - | - | - |
| 37 | 49 | B2 | 76 | A10 | A11 | 109 | PA14 | I/O | FT | - | JTCK-SWCLK, EVENTOUT | - |
| 38 | 50 | A2 | 77 | A9 | A10 | 110 | PA15 | I/O | FT | - | JTDI, TIM2_CH1/TIM2_ETR, SPI1_NSS/I2S1_WS, SPI3_NSS/I2S3_WS, USART1_TX, EVENTOUT | - |
| - | 51 | C3 | 78 | B11 | B11 | 111 | PC10 | I/O | FT | - | SPI3_SCK/I2S3_CK, USART3_TX, QUADSPI_BK1_IO1, SDIO_D2, EVENTOUT | - |
| - | 52 | B3 | 79 | C10 | B10 | 112 | PC11 | I/O | FT | - | I2S3ext_SD, SPI3_MISO, USART3_RX, QUADSPI_BK2_NCS, FSMC_D2/FSMC_DA2, SDIO_D3, EVENTOUT | - |



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Table 9. STM32F412xE/G pin definition (continued)

| Pin Number | | | | | | | Pin name (function after reset)(1) | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| UFQFPN48 | LQFP64 | WLCSP64 | LQFP100 | UFBGA100 | UFBGA144 | LQFP144 | | | | | | |
| - | 53 | A3 | 80 | B10 | C10 | 113 | PC12 | I/O | FT | - | SPI3_MOSI/I2S3_SD, USART3_CK, FSMC_D3/FSMC_DA3, SDIO_CK, EVENTOUT | - |
| - | - | - | 81 | C9 | E10 | 114 | PD0 | I/O | FT | - | CAN1_RX, FSMC_D2/FSMC_DA2, EVENTOUT | - |
| - | - | - | 82 | B9 | D10 | 115 | PD1 | I/O | FT | - | CAN1_TX, FSMC_D3/FSMC_DA3, EVENTOUT | - |
| - | 54 | A4 | 83 | C8 | E9 | 116 | PD2 | I/O | FT | - | TIM3_ETR, FSMC_NWE, SDIO_CMD, EVENTOUT | - |
| - | - | - | 84 | B8 | D9 | 117 | PD3 | I/O | FT | - | TRACED1, SPI2_SCK/I2S2_CK, DFSDM1_DATIN0, USART2_CTS, QUADSPI_CLK, FSMC_CLK, EVENTOUT | - |
| - | - | - | 85 | B7 | C9 | 118 | PD4 | I/O | FT | - | DFSDM1_CKIN0, USART2_RTS, FSMC_NOE, EVENTOUT | - |
| - | - | - | 86 | A6 | B9 | 119 | PD5 | I/O | FT | - | USART2_TX, FSMC_NWE, EVENTOUT | - |
| - | - | - | - | - | E7 | 120 | VSS | S | - | - | - | - |
| - | - | - | - | - | F7 | 121 | VDD | S | - | - | - | - |
| - | - | - | 87 | B6 | A8 | 122 | PD6 | I/O | FT | - | SPI3_MOSI/I2S3_SD, DFSDM1_DATIN1, USART2_RX, FSMC_NWAIT, EVENTOUT | - |
| - | - | - | 88 | A5 | A9 | 123 | PD7 | I/O | FT | - | DFSDM1_CKIN1, USART2_CK, FSMC_NE1, EVENTOUT | - |



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Table 9. STM32F412xE/G pin definition (continued)

| Pin Number | | | | | | | Pin name (function after reset)(1) | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| UFQFPN48 | LQFP64 | WLCSP64 | LQFP100 | UFBGA100 | UFBGA144 | LQFP144 | | | | | | |
| - | - | - | - | - | E8 | 124 | PG9 | I/O | FT | - | USART6_RX, QUADSPI_BK2_IO2, FSMC_NE2, EVENTOUT | - |
| - | - | - | - | - | D8 | 125 | PG10 | I/O | FT | - | FSMC_NE3, EVENTOUT | - |
| - | - | - | - | - | C8 | 126 | PG11 | I/O | FT | - | CAN2_RX, EVENTOUT | - |
| - | - | - | - | - | B8 | 127 | PG12 | I/O | FT | - | USART6_RTS, CAN2_TX, FSMC_NE4, EVENTOUT | - |
| - | - | - | - | - | D7 | 128 | PG13 | I/O | FT | - | TRACED2, USART6_CTS, FSMC_A24, EVENTOUT | - |
| - | - | - | - | - | C7 | 129 | PG14 | I/O | FT | - | TRACED3, USART6_TX, QUADSPI_BK2_IO3, FSMC_A25, EVENTOUT | - |
| - | - | - | - | - | - | 130 | VSS | S | - | - | - | - |
| - | - | - | - | - | F6 | 131 | VDD | S | - | - | - | - |
| - | - | - | - | - | B7 | 132 | PG15 | I/O | FT | - | USART6_CTS, EVENTOUT | - |
| 39 | 55 | A5 | 89 | A8 | A7 | 133 | PB3 | I/O | FT | - | JTDO-SWO, TIM2_CH2, I2CFMP1_SDA, SPI1_SCK/I2S1_CK, SPI3_SCK/I2S3_CK, USART1_RX, I2C2_SDA, EVENTOUT | - |
| 40 | 56 | B4 | 90 | A7 | A6 | 134 | PB4 | I/O | FT | - | JTRST, TIM3_CH1, SPI1_MISO, SPI3_MISO, I2S3ext_SD, I2C3_SDA, SDIO_D0, EVENTOUT | - |



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**Table 9. STM32F412xE/G pin definition (continued)**

| Pin Number | | | | | | | Pin name (function after reset)(1) | Pin type | I/O structure | Notes | Alternate functions | Additional functions |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| UFQFPN48 | LQFP64 | WLCSP64 | LQFP100 | UFBGA100 | UFBGA144 | LQFP144 | | | | | | |
| 41 | 57 | C4 | 91 | C5 | B6 | 135 | PB5 | I/O | FT | - | TIM3_CH2, I2C1_SMBA, SPI1_MOSI/I2S1_SD, SPI3_MOSI/I2S3_SD, CAN2_RX, SDIO_D3, EVENTOUT | - |
| 42 | 58 | B5 | 92 | B5 | C6 | 136 | PB6 | I/O | FT | - | TIM4_CH1, I2C1_SCL, USART1_TX, CAN2_TX, QUADSPI_BK1_NCS, SDIO_D0, EVENTOUT | - |
| 43 | 59 | A6 | 93 | B4 | D6 | 137 | PB7 | I/O | FT | - | TIM4_CH2, I2C1_SDA, USART1_RX, FSMC_NL, EVENTOUT | - |
| 44 | 60 | D4 | 94 | A4 | D5 | 138 | BOOT0 | I | B | - | - | VPP |
| 45 | 61 | C5 | 95 | A3 | C5 | 139 | PB8 | I/O | FT | - | TIM4_CH3, TIM10_CH1, I2C1_SCL, SPI5_MOSI/I2S5_SD, CAN1_RX, I2C3_SDA, SDIO_D4, EVENTOUT | - |
| 46 | 62 | B6 | 96 | B3 | B5 | 140 | PB9 | I/O | FT | - | TIM4_CH4, TIM11_CH1, I2C1_SDA, SPI2_NSS/I2S2_WS, CAN1_TX, I2C2_SDA, SDIO_D5, EVENTOUT | - |
| - | - | - | 97 | C3 | A5 | 141 | PE0 | I/O | FT | - | TIM4_ETR, FSMC_NBL0, EVENTOUT | - |
| - | - | - | 98 | A2 | A4 | 142 | PE1 | I/O | FT | - | FSMC_NBL1, EVENTOUT | - |
| 47 | 63 | A7 | 99 | D3 | E6 | - | VSS | S | - | - | - | - |
| - | - | C6 | - | H3 | E5 | 143 | PDR_ON | I | FT | - | - | - |
| 48 | 64 | A8 | 100 | C4 | F5 | 144 | VDD | S | - | - | - | - |

1. Function availability depends on the chosen device.
2. PC13, PC14 and PC15 are supplied through the power switch. Since the switch only sinks a limited amount of current (3 mA), the use of GPIOs PC13 to PC15 in output mode is limited:
   - The speed should not exceed 2 MHz with a maximum load of 30 pF.
   - These I/Os must not be used as a current source (e.g. to drive an LED).



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3. Main function after the first backup domain power-up. Later on, it depends on the contents of the RTC registers even after reset (because these registers are not reset by the main reset). For details on how to manage these I/Os, refer to the RTC register description sections in the STM32F412xE/Greference manual.
4. FT = 5 V tolerant except when in analog mode or oscillator mode (for PC14, PC15, PH0 and PH1).

**Table 10. FSMC pin definition**

| Pins | FSMC | | 64 pins | 100 pins | 144 pins |
|---|---|---|---|---|---|
| | LCD/NOR/PSRAM/SRAM | NOR/PSRAM Mux | | | |
| PE2 | A23 | A23 | - | Yes | Yes |
| PE3 | A19 | A19 | - | Yes | Yes |
| PE4 | A20 | A20 | - | Yes | Yes |
| PE5 | A21 | A21 | - | Yes | Yes |
| PE6 | A22 | A22 | - | Yes | Yes |
| PF0 | A0 | - | - | - | Yes |
| PF1 | A1 | - | - | - | Yes |
| PF2 | A2 | - | - | - | Yes |
| PF3 | A3 | - | - | - | Yes |
| PF4 | A4 | - | - | - | Yes |
| PF5 | A5 | - | - | - | Yes |
| PC2 | NWE | NWE | Yes | Yes | Yes |
| PC3 | A0 | - | Yes | Yes | Yes |
| PA2 | D4 | DA4 | Yes | Yes | Yes |
| PA3 | D5 | DA5 | Yes | Yes | Yes |
| PA4 | D6 | DA6 | Yes | Yes | Yes |
| PA5 | D7 | DA7 | Yes | Yes | Yes |
| PC4 | NE4 | NE4 | Yes | Yes | Yes |
| PC5 | NOE | NOE | Yes | Yes | Yes |
| PF12 | A6 | - | - | - | Yes |
| PF13 | A7 | - | - | - | Yes |
| PF14 | A8 | - | - | - | Yes |
| PF15 | A9 | - | - | - | Yes |
| PG0 | A10 | - | - | - | Yes |
| PG1 | A11 | - | - | - | Yes |
| PE7 | D4 | DA4 | - | Yes | Yes |
| PE8 | D5 | DA5 | - | Yes | Yes |
| PE9 | D6 | DA6 | - | Yes | Yes |
| PE10 | D7 | DA7 | - | Yes | Yes |



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Table 10. FSMC pin definition

| Pins | FSMC | | 64 pins | 100 pins | 144 pins |
|---|---|---|---|---|---|
| | LCD/NOR/PSRAM/SRAM | NOR/PSRAM Mux | | | |
| PE11 | D8 | DA8 | - | Yes | Yes |
| PE12 | D9 | DA9 | - | Yes | Yes |
| PE13 | D10 | DA10 | - | Yes | Yes |
| PE14 | D11 | DA11 | - | Yes | Yes |
| PE15 | D12 | DA12 | - | Yes | Yes |
| PB12 | D13 | DA13 | Yes | Yes | Yes |
| PB14 | D0 | DA0 | Yes | Yes | Yes |
| PD8 | D13 | DA13 | - | - | Yes |
| PD9 | D14 | DA14 | - | Yes | Yes |
| PD10 | D15 | DA15 | - | Yes | Yes |
| PD11 | A16 | A16 | - | Yes | Yes |
| PD12 | A17 | A17 | - | Yes | Yes |
| PD13 | A18 | A18 | - | Yes | Yes |
| PD14 | D0 | DA0 | - | Yes | Yes |
| PD15 | D1 | DA1 | - | Yes | Yes |
| PG2 | A12 | - | - | - | Yes |
| PG3 | A13 | - | - | - | Yes |
| PG4 | A14 | - | - | - | Yes |
| PG5 | A15 | - | - | - | Yes |
| PC6 | D1 | DA1 | Yes | Yes | Yes |
| PC11 | D2 | DA2 | Yes | Yes | Yes |
| PC12 | D3 | DA3 | Yes | Yes | Yes |
| PD0 | D2 | DA2 | - | Yes | Yes |
| PD1 | D3 | DA3 | - | Yes | Yes |
| PD2 | NWE | NWE | Yes | Yes | Yes |
| PD3 | CLK | CLK | - | Yes | Yes |
| PD4 | NOE | NOE | - | Yes | Yes |
| PD5 | NWE | NEW | - | Yes | Yes |
| PD6 | NWAIT | NWAIT | - | Yes | Yes |
| PD7 | NE1 | NE1 | - | Yes | Yes |
| PG9 | NE2 | NE2 | - | - | Yes |
| PG10 | NE3 | NE3 | - | - | Yes |
| PG12 | A24 | A24 | - | - | Yes |



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**Table 10. FSMC pin definition**

| Pins | FSMC | | 64 pins | 100 pins | 144 pins |
|---|---|---|---|---|---|
| | LCD/NOR/PSRAM/SRAM | NOR/PSRAM Mux | | | |
| PG14 | A25 | A25 | - | - | Yes |
| PB7 | NL | NL | Yes | Yes | Yes |
| PE0 | NBL0 | NBL0 | - | Yes | Yes |
| PE1 | NBL1 | NBL1 | - | Yes | Yes |



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## Table 11. STM32F412xE/G alternate functions

| Port | | AF0 | AF1 | AF2 | AF3 | AF4 | AF5 | AF6 | AF7 | AF8 | AF9 | AF10 | AF12 | AF15 |
|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|
| | | SYS_AF | TIM1/ TIM2 | TIM3/ TIM4/ TIM5 | TIM8/ TIM9/ TIM10/ TIM11 | I2C1/ I2C2/ I2C3/ I2CFMP1 | SPI1/I2S1/ SPI2/I2S2/ SPI3/I2S3/ SPI4/I2S4 | SPI2/I2S2/SPI3 /I2S3/SPI4/ I2S4/SPI5/I2S5 /DFSDM1 | SPI3/I2S3/ USART1/ USART2/ USART3 | DFSDM1/ USART3/ USART6/ CAN1 | I2C2/I2C3/ I2CFMP1/ CAN1/CAN2 /TIM12/ TIM13/TIM14 /QUADSPI | DFSDM1/ QUADSPI/ FSMC /OTG1_FS | FSMC /SDIO | SYS_AF |
| Port A | PA0 | - | TIM2_CH1/ TIM2_ETR | TIM5_CH1 | TIM8_ETR | - | - | - | USART2_CTS | - | - | - | - | EVENTOUT |
| | PA1 | - | TIM2_CH2 | TIM5_CH2 | - | - | SPI4_MOSI/I 2S4_SD | - | USART2_RTS | - | QUADSPI_ BK1_IO3 | - | - | EVENTOUT |
| | PA2 | - | TIM2_CH3 | TIM5_CH3 | TIM9_CH1 | - | I2S2_CKIN | - | USART2_TX | - | - | - | FSMC_D4 | EVENTOUT |
| | PA3 | - | TIM2_CH4 | TIM5_CH4 | TIM9_CH2 | - | I2S2_MCK | - | USART2_RX | - | - | - | FSMC_D5 | EVENTOUT |
| | PA4 | - | - | - | - | - | SPI1_NSS/I2 S1_WS | SPI3_NSS/ I2S3_WS | USART2_CK | DFSDM1_ DATIN1 | - | - | FSMC_D6 | EVENTOUT |
| | PA5 | - | TIM2_CH1/ TIM2_ETR | - | TIM8_CH1N | - | SPI1_SCK/ I2S1_CK | - | - | DFSDM1_ CKIN1 | - | - | FSMC_D7 | EVENTOUT |
| | PA6 | - | TIM1_BKIN | TIM3_CH1 | TIM8_BKIN | - | SPI1_MISO | I2S2_MCK | - | - | TIM13_ CH1 | QUADSPI_ BK2_IO0 | SDIO_CMD | EVENTOUT |
| | PA7 | - | TIM1_CH1N | TIM3_CH2 | TIM8_CH1N | - | SPI1_MOSI/I 2S1_SD | - | - | - | TIM14_ CH1 | QUADSPI_ BK2_IO1 | - | EVENTOUT |
| | PA8 | MCO_1 | TIM1_CH1 | - | - | I2C3_SCL | - | - | USART1_CK | - | - | USB_FS_ SOF | SDIO_D1 | EVENTOUT |
| | PA9 | - | TIM1_CH2 | - | - | I2C3_ SMBA | - | - | USART1_TX | - | - | USB_FS_ VBUS | SDIO_D2 | EVENTOUT |
| | PA10 | - | TIM1_CH3 | - | - | - | - | SPI5_MOSI/ I2S5_SD | USART1_RX | - | - | USB_FS_ID | - | EVENTOUT |
| | PA11 | - | TIM1_CH4 | - | - | - | - | SPI4_MISO | USART1_CTS | USART6_ TX | CAN1_RX | USB_FS_DM | - | EVENTOUT |
| | PA12 | - | TIM1_ETR | - | - | - | - | SPI5_MISO | USART1_RTS | USART6_ RX | CAN1_TX | USB_FS_DP | - | EVENTOUT |
| | PA13 | JTMS-SWDIO | - | - | - | - | - | - | - | - | - | - | - | EVENTOUT |
| | PA14 | JTCK-SWCLK | - | - | - | - | - | - | - | - | - | - | - | EVENTOUT |
| | PA15 | JTDI | TIM2_CH1/ TIM2_ETR | - | - | - | SPI1_NSS/ I2S1_WS | SPI3_NSS/ I2S3_WS | USART1_TX | - | - | - | - | EVENTOUT |

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**Table 11. STM32F412xE/G alternate functions (continued)**

| Port | | AF0 | AF1 | AF2 | AF3 | AF4 | AF5 | AF6 | AF7 | AF8 | AF9 | AF10 | AF12 | AF15 |
|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|
| | | SYS_AF | TIM1/ TIM2 | TIM3/ TIM4/ TIM5 | TIM8/ TIM9/ TIM10/ TIM11 | I2C1/ I2C2/ I2C3/ I2CFMP1 | SPI1/I2S1/ SPI2/I2S2/ SPI3/I2S3/ SPI4/I2S4 | SPI2/I2S2/SPI3 /I2S3/SPI4/ I2S4/SPI5/I2S5 /DFSDM1 | SPI3/I2S3/ USART1/ USART2/ USART3 | DFSDM1/ USART3/ USART6/ CAN1 | I2C2/I2C3/ I2CFMP1/ CAN1/CAN2 /TIM12/ TIM13/TIM14 /QUADSPI | DFSDM1/ QUADSPI/ FSMC /OTG1_FS | FSMC /SDIO | SYS_AF |
| Port B | PB0 | - | TIM1_CH2N | TIM3_CH3 | TIM8_CH2N | - | - | SPI5_SCK/ I2S5_CK | - | - | - | - | - | EVENTOUT |
| | PB1 | - | TIM1_CH3N | TIM3_CH4 | TIM8_CH3N | - | - | SPI5_NSS/ I2S5_WS | - | DFSDM1_ DATIN0 | QUADSPI_ CLK | - | - | EVENTOUT |
| | PB2 | - | - | - | - | - | - | DFSDM1_ CKIN0 | - | - | QUADSPI_ CLK | - | - | EVENTOUT |
| | PB3 | JTDO-SWO | TIM2_CH2 | | | I2CFMP1_ SDA | SPI1_SCK/I2 S1_CK | SPI3_SCK/ I2S3_CK | USART1_RX | - | I2C2_SDA | - | - | EVENTOUT |
| | PB4 | JTRST | - | TIM3_CH1 | - | - | SPI1_MISO | SPI3_MISO | I2S3ext_ SD | - | I2C3_SDA | - | SDIO_D0 | EVENTOUT |
| | PB5 | - | - | TIM3_CH2 | - | I2C1_SMBA | SPI1_MOSI/I 2S1_SD | SPI3_MOSI/ I2S3_SD | - | - | CAN2_RX | - | SDIO_D3 | EVENTOUT |
| | PB6 | - | - | TIM4_CH1 | - | I2C1_SCL | - | - | USART1_TX | - | CAN2_TX | QUADSPI_ BK1_NCS | SDIO_D0 | EVENTOUT |
| | PB7 | - | - | TIM4_CH2 | - | I2C1_SDA | - | - | USART1_RX | - | - | - | FSMC_NL | EVENTOUT |
| | PB8 | - | - | TIM4_CH3 | TIM10_CH1 | I2C1_SCL | - | SPI5_MOSI/I2S 5_SD | - | CAN1_RX | I2C3_SDA | - | SDIO_D4 | EVENTOUT |
| | PB9 | - | - | TIM4_CH4 | TIM11_CH1 | I2C1_SDA | SPI2_NSS/ I2S2_WS | - | - | CAN1_TX | I2C2_SDA | - | SDIO_D5 | EVENTOUT |
| | PB10 | - | TIM2_CH3 | - | - | I2C2_SCL | SPI2_SCK/ I2S2_CK | I2S3_MCK | USART3_TX | - | I2CFMP1_ SCL | - | SDIO_D7 | EVENTOUT |
| | PB11 | - | TIM2_CH4 | - | - | I2C2_SDA | I2S2_CKIN | - | USART3_RX | - | - | - | - | EVENTOUT |
| | PB12 | - | TIM1_BKIN | - | - | I2C2_SMBA | SPI2_NSS/ I2S2_WS | SPI4_NSS/ I2S4_WS | SPI3_SCK/ I2S3_CK | USART3_ CK | CAN2_RX | DFSDM1_ DATIN1 | FSMC_D13/F SMC_DA13 | EVENTOUT |
| | PB13 | - | TIM1_CH1N | - | - | I2CFMP1_ SMBA | SPI2_SCK/ I2S2_CK | SPI4_SCK/ I2S4_CK | - | USART3_ CTS | CAN2_TX | DFSDM1_ CKIN1 | - | EVENTOUT |
| | PB14 | - | TIM1_CH2N | - | TIM8_CH2N | I2CFMP1_ SDA | SPI2_MISO | I2S2ext_SD | USART3_ RTS | DFSDM1_ DATIN2 | TIM12_CH1 | FSMC_D0 | SDIO_D6 | EVENTOUT |
| | PB15 | RTC_ 50Hz | TIM1_CH3N | - | TIM8_CH3N | I2CFMP1_ SCL | SPI2_MOSI/I 2S2_SD | - | - | DFSDM1_ CKIN2 | TIM12_CH2 | - | SDIO_CK | EVENTOUT |

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**Table 11. STM32F412xE/G alternate functions (continued)**

| Port | | AF0 | AF1 | AF2 | AF3 | AF4 | AF5 | AF6 | AF7 | AF8 | AF9 | AF10 | AF12 | AF15 |
|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|
| | | SYS_AF | TIM1/ TIM2 | TIM3/ TIM4/ TIM5 | TIM8/ TIM9/ TIM10/ TIM11 | I2C1/ I2C2/ I2C3/ I2CFMP1 | SPI1/I2S1/ SPI2/I2S2/ SPI3/I2S3/ SPI4/I2S4 | SPI2/I2S2/SPI3 /I2S3/SPI4/ I2S4/SPI5/I2S5 /DFSDM1 | SPI3/I2S3/ USART1/ USART2/ USART3 | DFSDM1/ USART3/ USART6/ CAN1 | I2C2/I2C3/ I2CFMP1/ CAN1/CAN2 /TIM12/ TIM13/TIM14 /QUADSPI | DFSDM1/ QUADSPI/ FSMC /OTG1_FS | FSMC /SDIO | SYS_AF |
| Port C | PC0 | - | - | - | - | - | - | - | - | - | - | - | - | EVENTOUT |
| | PC1 | - | - | - | - | - | - | - | - | - | - | - | - | EVENTOUT |
| | PC2 | - | - | - | - | - | SPI2_MISO | I2S2ext_SD | - | DFSDM1_ CKOUT | - | - | FSMC_NWE | EVENTOUT |
| | PC3 | - | - | - | - | - | SPI2_MOSI/I 2S2_SD | - | - | - | - | - | FSMC_A0 | EVENTOUT |
| | PC4 | - | - | - | - | - | I2S1_MCK | - | - | - | - | QUADSPI_ BK2_IO2 | FSMC_NE4 | EVENTOUT |
| | PC5 | - | - | - | - | I2CFMP1_ SMBA | - | - | USART3_RX | - | - | QUADSPI_ BK2_IO3 | FSMC_NOE | EVENTOUT |
| | PC6 | - | - | TIM3_CH1 | TIM8_CH1 | I2CFMP1_ SCL | I2S2_MCK | DFSDM1_ CKIN3 | - | USART6_ TX | - | FSMC_D1 | SDIO_D6 | EVENTOUT |
| | PC7 | - | - | TIM3_CH2 | TIM8_CH2 | I2CFMP1_ SDA | SPI2_SCK/ I2S2_CK | I2S3_MCK | - | USART6_ RX | - | DFSDM1_ DATIN3 | SDIO_D7 | EVENTOUT |
| | PC8 | - | - | TIM3_CH3 | TIM8_CH3 | - | - | - | - | USART6_ CK | QUADSPI_ BK1_IO2 | - | SDIO_D0 | EVENTOUT |
| | PC9 | MCO_2 | - | TIM3_CH4 | TIM8_CH4 | I2C3_SDA | I2S2_CKIN | - | - | - | QUADSPI_ BK1_IO0 | - | SDIO_D1 | EVENTOUT |
| | PC10 | - | - | - | - | - | - | SPI3_SCK/ I2S3_CK | USART3_TX | - | QUADSPI_ BK1_IO1 | - | SDIO_D2 | EVENTOUT |
| | PC11 | - | - | - | - | - | I2S3ext_SD | SPI3_MISO | USART3_RX | - | QUADSPI_ BK2_NCS | FSMC_D2 | SDIO_D3 | EVENTOUT |
| | PC12 | - | - | - | - | - | - | SPI3_MOSI/ I2S3_SD | USART3_CK | - | - | FSMC_D3 | SDIO_CK | EVENTOUT |
| | PC13 | - | - | - | - | - | - | - | - | - | - | - | - | EVENTOUT |
| | PC14 | - | - | - | - | - | - | - | - | - | - | - | - | EVENTOUT |
| | PC15 | - | - | - | - | - | - | - | - | - | - | - | - | EVENTOUT |

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**Table 11. STM32F412xE/G alternate functions (continued)**

| Port | | AF0 | AF1 | AF2 | AF3 | AF4 | AF5 | AF6 | AF7 | AF8 | AF9 | AF10 | AF12 | AF15 |
|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|
| | | SYS_AF | TIM1/ TIM2 | TIM3/ TIM4/ TIM5 | TIM8/ TIM9/ TIM10/ TIM11 | I2C1/ I2C2/ I2C3/ I2CFMP1 | SPI1/I2S1/ SPI2/I2S2/ SPI3/I2S3/ SPI4/I2S4 | SPI2/I2S2/SPI3 /I2S3/SPI4/ I2S4/SPI5/I2S5 /DFSDM1 | SPI3/I2S3/ USART1/ USART2/ USART3 | DFSDM1/ USART3/ USART6/ CAN1 | I2C2/I2C3/ I2CFMP1/ CAN1/CAN2 /TIM12/ TIM13/TIM14 /QUADSPI | DFSDM1/ QUADSPI/ FSMC /OTG1_FS | FSMC /SDIO | SYS_AF |
| Port D | PD0 | - | - | - | - | - | - | - | - | - | CAN1_RX | - | FSMC_D2/FSMC_DA2 | EVENTOUT |
| | PD1 | - | - | - | - | - | - | - | - | - | CAN1_TX | - | FSMC_D3/FSMC_DA3 | EVENTOUT |
| | PD2 | - | - | TIM3_ETR | - | - | - | - | - | - | - | FSMC_NWE | SDIO_CMD | EVENTOUT |
| | PD3 | TRACED1 | - | - | - | - | SPI2_SCK/ I2S2_CK | DFSDM1_ DATIN0 | USART2_ CTS | - | QUADSPI_ CLK | - | FSMC_CLK | EVENTOUT |
| | PD4 | - | - | - | - | - | - | DFSDM1_ CKIN0 | USART2_ RTS | - | - | - | FSMC_NOE | EVENTOUT |
| | PD5 | - | - | - | - | - | - | - | USART2_TX | - | - | - | FSMC_NWE | EVENTOUT |
| | PD6 | - | - | - | - | - | SPI3_MOSI/I 2S3_SD | DFSDM1_ DATIN1 | USART2_RX | - | - | - | FSMC_ NWAIT | EVENTOUT |
| | PD7 | - | - | - | - | - | - | DFSDM1_ CKIN1 | USART2_CK | - | - | - | FSMC_NE1 | EVENTOUT |
| | PD8 | - | - | - | - | - | - | - | USART3_TX | - | - | - | FSMC_D13/ FSMC_DA13 | EVENTOUT |
| | PD9 | - | - | - | - | - | - | - | USART3_RX | - | - | - | FSMC_D14/ FSMC_DA14 | EVENTOUT |
| | PD10 | - | - | - | - | - | - | - | USART3_CK | - | - | - | FSMC_D15/ FSMC_DA15 | EVENTOUT |
| | PD11 | - | - | - | - | I2CFMP1_ SMBA | - | - | USART3_ CTS | - | QUADSPI_ BK1_IO0 | - | FSMC_A16 | EVENTOUT |
| | PD12 | - | - | TIM4_CH1 | - | I2CFMP1_ SCL | | | USART3_ RTS | - | QUADSPI_ BK1_IO1 | - | FSMC_A17 | EVENTOUT |
| | PD13 | - | - | TIM4_CH2 | - | I2CFMP1_ SDA | - | - | - | - | QUADSPI_ BK1_IO3 | - | FSMC_A18 | EVENTOUT |
| | PD14 | - | - | TIM4_CH3 | - | I2CFMP1_ SCL | - | - | - | - | - | - | FSMC_D0/ FSMC_DA0 | EVENTOUT |
| | PD15 | - | - | TIM4_CH4 | - | I2CFMP1_ SDA | - | - | - | - | - | - | FSMC_D1/ FSMC_DA1 | EVENTOUT |

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**Table 11. STM32F412xE/G alternate functions (continued)**

| Port | | AF0 | AF1 | AF2 | AF3 | AF4 | AF5 | AF6 | AF7 | AF8 | AF9 | AF10 | AF12 | AF15 |
|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|
| | | SYS_AF | TIM1/ TIM2 | TIM3/ TIM4/ TIM5 | TIM8/ TIM9/ TIM10/ TIM11 | I2C1/ I2C2/ I2C3/ I2CFMP1 | SPI1/I2S1/ SPI2/I2S2/ SPI3/I2S3/ SPI4/I2S4 | SPI2/I2S2/SPI3 /I2S3/SPI4/ I2S4/SPI5/I2S5 /DFSDM1 | SPI3/I2S3/ USART1/ USART2/ USART3 | DFSDM1/ USART3/ USART6/ CAN1 | I2C2/I2C3/ I2CFMP1/ CAN1/CAN2 /TIM12/ TIM13/TIM14 /QUADSPI | DFSDM1/ QUADSPI/ FSMC /OTG1_FS | FSMC /SDIO | SYS_AF |
| Port E | PE0 | - | - | TIM4_ETR | - | - | - | - | - | - | - | - | FSMC_NBL0 | EVENTOUT |
| | PE1 | - | - | - | - | - | - | - | - | - | - | - | FSMC_NBL1 | EVENTOUT |
| | PE2 | TRACECLK | - | - | - | - | SPI4_SCK/ I2S4_CK | SPI5_SCK/ I2S5_CK | - | - | QUADSPI_ BK1_IO2 | - | FSMC_A23 | EVENTOUT |
| | PE3 | TRACED0 | - | - | - | - | - | - | - | - | - | - | FSMC_A19 | EVENTOUT |
| | PE4 | TRACED1 | - | - | - | - | SPI4_NSS/ I2S4_WS | SPI5_NSS/ I2S5_WS | - | DFSDM1_ DATIN3 | - | - | FSMC_A20 | EVENTOUT |
| | PE5 | TRACED2 | - | - | TIM9_CH1 | - | SPI4_MISO | SPI5_MISO | - | DFSDM1_ CKIN3 | - | - | FSMC_A21 | EVENTOUT |
| | PE6 | TRACED3 | - | - | TIM9_CH2 | - | SPI4_MOSI/I 2S4_SD | SPI5_MOSI/ I2S5_SD | - | - | - | - | FSMC_A22 | EVENTOUT |
| | PE7 | - | TIM1_ETR | - | - | - | - | DFSDM1_ DATIN2 | - | - | - | QUADSPI_ BK2_IO0 | FSMC_D4/ FSMC_DA4 | EVENTOUT |
| | PE8 | - | TIM1_CH1N | - | - | - | - | DFSDM1_ CKIN2 | - | - | - | QUADSPI_ BK2_IO1 | FSMC_D5/ FSMC_DA5 | EVENTOUT |
| | PE9 | - | TIM1_CH1 | - | - | - | - | DFSDM1_ CKOUT | - | - | - | QUADSPI_ BK2_IO2 | FSMC_D6/ FSMC_DA6 | EVENTOUT |
| | PE10 | - | TIM1_CH2N | - | - | - | - | - | - | - | - | QUADSPI_ BK2_IO3 | FSMC_D7/ FSMC_DA7 | EVENTOUT |
| | PE11 | - | TIM1_CH2 | - | - | - | SPI4_NSS/ I2S4_WS | SPI5_NSS/ I2S5_WS | - | - | - | | FSMC_D8/ FSMC_DA8 | EVENTOUT |
| | PE12 | - | TIM1_CH3N | - | - | - | SPI4_SCK/ I2S4_CK | SPI5_SCK/ I2S5_CK | - | - | - | - | FSMC_D9/ FSMC_DA9 | EVENTOUT |
| | PE13 | - | TIM1_CH3 | - | - | - | SPI4_MISO | SPI5_MISO | - | - | - | - | FSMC_D10/ FSMC_DA10 | EVENTOUT |
| | PE14 | - | TIM1_CH4 | - | - | - | SPI4_MOSI/I 2S4_SD | SPI5_MOSI/ I2S5_SD | - | - | - | - | FSMC_D11/ FSMC_DA11 | EVENTOUT |
| | PE15 | - | TIM1_BKIN | - | - | - | - | - | - | - | - | - | FSMC_D12/ FSMC_DA12 | EVENTOUT |

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**Table 11. STM32F412xE/G alternate functions (continued)**

| Port | | AF0 | AF1 | AF2 | AF3 | AF4 | AF5 | AF6 | AF7 | AF8 | AF9 | AF10 | AF12 | AF15 |
|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|
| | | SYS_AF | TIM1/ TIM2 | TIM3/ TIM4/ TIM5 | TIM8/ TIM9/ TIM10/ TIM11 | I2C1/ I2C2/ I2C3/ I2CFMP1 | SPI1/I2S1/ SPI2/I2S2/ SPI3/I2S3/ SPI4/I2S4 | SPI2/I2S2/SPI3 /I2S3/SPI4/ I2S4/SPI5/I2S5 /DFSDM1 | SPI3/I2S3/ USART1/ USART2/ USART3 | DFSDM1/ USART3/ USART6/ CAN1 | I2C2/I2C3/ I2CFMP1/ CAN1/CAN2 /TIM12/ TIM13/TIM14 /QUADSPI | DFSDM1/ QUADSPI/ FSMC /OTG1_FS | FSMC /SDIO | SYS_AF |
| Port F | PF0 | - | - | - | - | I2C2_SDA | - | - | - | - | - | - | FSMC_A0 | EVENTOUT |
| | PF1 | - | - | - | - | I2C2_SCL | - | - | - | - | - | - | FSMC_A1 | EVENTOUT |
| | PF2 | - | - | - | - | I2C2_SMBA | - | - | - | - | - | - | FSMC_A2 | EVENTOUT |
| | PF3 | - | - | TIM5_CH1 | - | - | - | - | - | - | - | - | FSMC_A3 | EVENTOUT |
| | PF4 | - | - | TIM5_CH2 | - | - | - | - | - | - | - | - | FSMC_A4 | EVENTOUT |
| | PF5 | - | - | TIM5_CH3 | - | - | - | - | - | - | - | - | FSMC_A5 | EVENTOUT |
| | PF6 | TRACED0 | - | - | TIM10_CH1 | - | - | - | - | - | QUADSPI_ BK1_IO3 | - | - | EVENTOUT |
| | PF7 | TRACED1 | - | - | TIM11_CH1 | - | - | - | - | - | QUADSPI_ BK1_IO2 | - | - | EVENTOUT |
| | PF8 | - | - | - | - | - | - | - | - | - | TIM13_CH1 | QUADSPI_ BK1_IO0 | - | EVENTOUT |
| | PF9 | - | - | - | - | - | - | - | - | - | TIM14_CH1 | QUADSPI_ BK1_IO1 | - | EVENTOUT |
| | PF10 | - | TIM1_ETR | TIM5_CH4 | - | - | - | - | - | - | - | - | - | EVENTOUT |
| | PF11 | - | - | - | TIM8_ETR | - | - | - | - | - | - | - | - | EVENTOUT |
| | PF12 | - | - | - | TIM8_BKIN | - | - | - | - | - | - | - | FSMC_A6 | EVENTOUT |
| | PF13 | - | - | - | - | I2CFMP1_ SMBA | - | - | - | - | - | - | FSMC_A7 | EVENTOUT |
| | PF14 | - | - | - | - | I2CFMP1_ SCL | - | - | - | - | - | - | FSMC_A8 | EVENTOUT |
| | PF15 | - | - | - | - | I2CFMP1_ SDA | - | - | - | - | - | - | FSMC_A9 | EVENTOUT |

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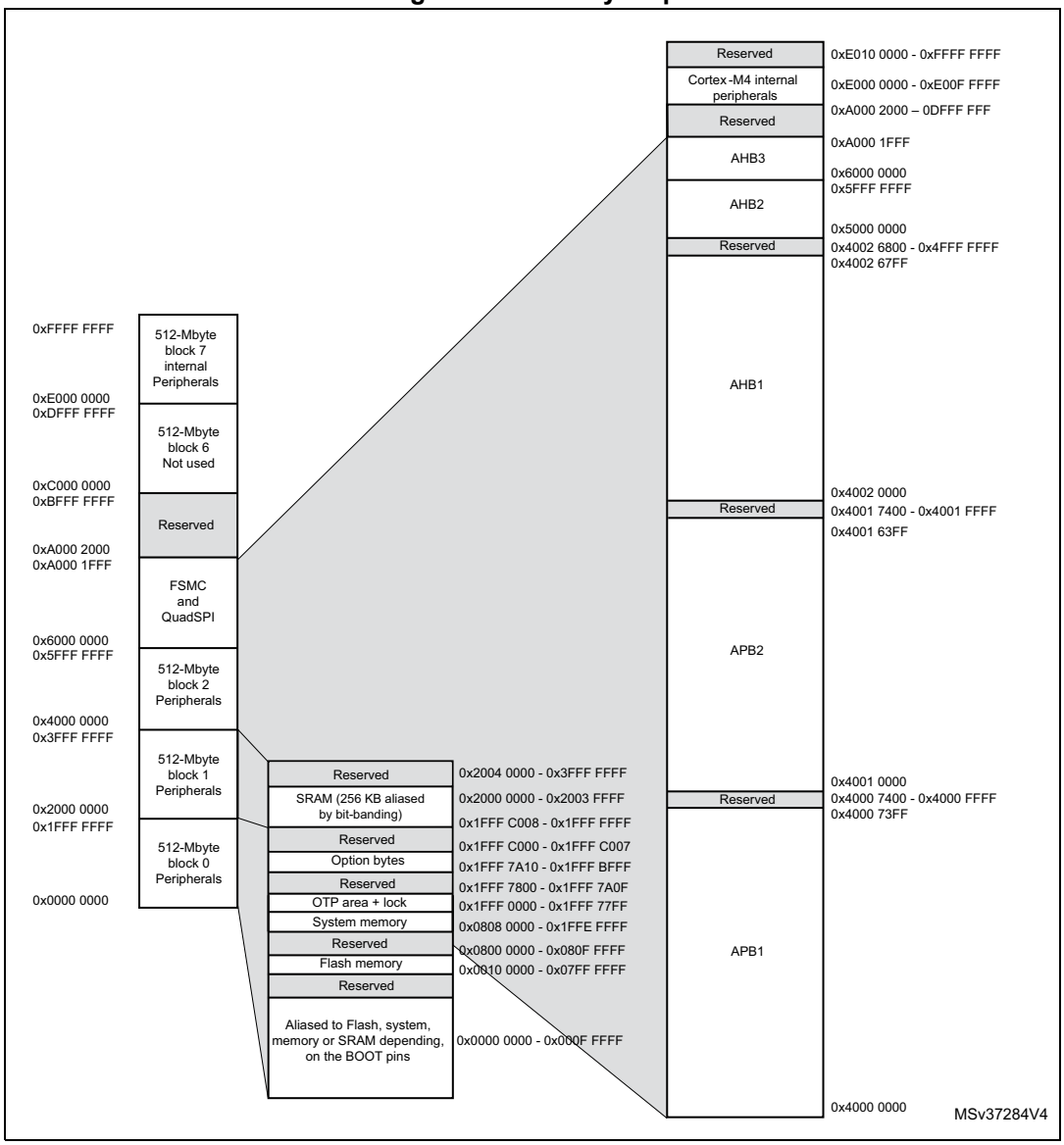
**Table 11. STM32F412xE/G alternate functions (continued)**

| Port | | AF0 | AF1 | AF2 | AF3 | AF4 | AF5 | AF6 | AF7 | AF8 | AF9 | AF10 | AF12 | AF15 |
|---|---|---|---|---|---|---|---|---|---|---|---|---|---|---|
| | | SYS_AF | TIM1/ TIM2 | TIM3/ TIM4/ TIM5 | TIM8/ TIM9/ TIM10/ TIM11 | I2C1/ I2C2/ I2C3/ I2CFMP1 | SPI1/I2S1/ SPI2/I2S2/ SPI3/I2S3/ SPI4/I2S4 | SPI2/I2S2/SPI3 /I2S3/SPI4/ I2S4/SPI5/I2S5 /DFSDM1 | SPI3/I2S3/ USART1/ USART2/ USART3 | DFSDM1/ USART3/ USART6/ CAN1 | I2C2/I2C3/ I2CFMP1/ CAN1/CAN2 /TIM12/ TIM13/TIM14 /QUADSPI | DFSDM1/ QUADSPI/ FSMC /OTG1_FS | FSMC /SDIO | SYS_AF |
| Port G | PG0 | - | - | - | - | - | - | - | - | - | CAN1_RX | - | FSMC_A10 | EVENTOUT |
| | PG1 | - | - | - | - | - | - | - | - | - | CAN1_TX | - | FSMC_A11 | EVENTOUT |
| | PG2 | - | - | - | - | - | - | - | - | - | - | - | FSMC_A12 | EVENTOUT |
| | PG3 | - | - | - | - | - | - | - | - | - | - | - | FSMC_A13 | EVENTOUT |
| | PG4 | - | - | - | - | - | - | - | - | - | - | - | FSMC_A14 | EVENTOUT |
| | PG5 | - | - | - | - | - | - | - | - | - | - | - | FSMC_A15 | EVENTOUT |
| | PG6 | - | - | - | - | - | - | - | - | - | - | QUADSPI_ BK1_NCS | - | EVENTOUT |
| | PG7 | - | - | - | - | - | - | - | - | USART6_ CK | - | - | - | EVENTOUT |
| | PG8 | - | - | - | - | - | - | - | - | USART6_ RTS | - | - | - | EVENTOUT |
| | PG9 | - | - | - | - | - | - | - | - | USART6_ RX | QUADSPI_ BK2_IO2 | - | FSMC_NE2 | EVENTOUT |
| | PG10 | - | - | - | - | - | - | - | - | - | - | - | FSMC_NE3 | EVENTOUT |
| | PG11 | - | - | - | - | - | - | - | - | - | CAN2_RX | - | - | EVENTOUT |
| | PG12 | - | - | - | - | - | - | - | - | USART6_ RTS | CAN2_TX | - | FSMC_NE4 | EVENTOUT |
| | PG13 | TRACED2 | - | - | - | - | - | - | - | USART6_ CTS | - | - | FSMC_A24 | EVENTOUT |
| | PG14 | TRACED3 | - | - | - | - | - | - | - | USART6_ TX | QUADSPI_ BK2_IO3 | - | FSMC_A25 | EVENTOUT |
| | PG15 | - | - | - | - | - | - | - | - | USART6_ CTS | - | - | - | EVENTOUT |
| Port H | PH0 | - | - | - | - | - | - | - | - | - | - | - | - | EVENTOUT |
| | PH1 | - | - | - | - | - | - | - | - | - | - | - | - | EVENTOUT |

# 5 Memory mapping

The memory map is shown in *Figure 18*.

**Figure 18. Memory map**






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**Table 12. STM32F412xE/G register boundary addresses**

| Bus | Boundary address | Peripheral |
|---|---|---|
| | 0xE010 0000 - 0xFFFF FFFF | Reserved |
| Cortex®-M4 | 0xE000 0000 - 0xE00F FFFF | Cortex-M4 internal peripherals |
| AHB3 | 0xA000 2000 - 0xDFFF FFFF | Reserved |
| | 0xA000 1000 - 0xA000 1FFF | QuadSPI control register |
| | 0xA000 0000 - 0xA000 0FFF | FSMC control register |
| | 0x9000 0000 - 0x9FFF FFFF | QUADSPI |
| | 0x7000 0000 - 0x08FFF FFFF | Reserved |
| | 0x6000 0000 - 0x6FFF FFFF | FSMC |
| AHB2 | 0x5006 0C00 - 0x5FFF FFFF | Reserved |
| | 0x5006 0800 0x5006 0BFF | RNG |
| | 0x5004 000- 0x5006 07FF | Reserved |
| | 0x5000 0000 - 0x5003 FFFF | USB OTG FS |
| AHB1 | 0x4002 6800 - 0x4FFF FFFF | Reserved |
| | 0x4002 6400 - 0x4002 67FF | DMA2 |
| | 0x4002 6000 - 0x4002 63FF | DMA1 |
| | 0x4002 5000 - 0x4002 4FFF | Reserved |
| | 0x4002 3C00 - 0x4002 3FFF | Flash interface register |
| | 0x4002 3800 - 0x4002 3BFF | RCC |
| | 0x4002 3400 - 0x4002 37FF | Reserved |
| | 0x4002 3000 - 0x4002 33FF | CRC |
| | 0x4002 2000 - 0x4002 2FFF | Reserved |
| | 0x4002 1C00 - 0x4002 1FFF | GPIOH |
| | 0x4002 1800 - 0x4002 1BFF | GPIOG |
| | 0x4002 1400 - 0x4002 17FF | GPIOF |
| | 0x4002 1000 - 0x4002 13FF | GPIOE |
| | 0x4002 0C00 - 0x4002 0FFF | GPIOD |
| | 0x4002 0800 - 0x4002 0BFF | GPIOC |
| | 0x4002 0400 - 0x4002 07FF | GPIOB |
| | 0x4002 0000 - 0x4002 03FF | GPIOA |



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Table 12. STM32F412xE/G register boundary addresses (continued)

| Bus | Boundary address | Peripheral |
|---|---|---|
| APB2 | 0x4001 6400- 0x4001 FFFF | Reserved |
| | 0x4001 6000 - 0x4001 63FF | DFSDM1 |
| | 0x4001 5400 - 0x4001 5FFF | Reserved |
| | 0x4001 5000 - 0x4001 53FF | SPI5/I2S5 |
| | 0x4001 4800 - 0x4001 4BFF | TIM11 |
| | 0x4001 4400 - 0x4001 47FF | TIM10 |
| | 0x4001 4000 - 0x4001 43FF | TIM9 |
| | 0x4001 3C00 - 0x4001 3FFF | EXTI |
| | 0x4001 3800 - 0x4001 3BFF | SYSCFG |
| | 0x4001 3400 - 0x4001 37FF | SPI4/I2S4 |
| | 0x4001 3000 - 0x4001 33FF | SPI1/I2S1 |
| | 0x4001 2C00 - 0x4001 2FFF | SDIO |
| | 0x4001 2400 - 0x4001 2BFF | Reserved |
| | 0x4001 2000 - 0x4001 23FF | ADC1 |
| | 0x4001 1800 - 0x4001 1FFF | Reserved |
| | 0x4001 1400 - 0x4001 17FF | USART6 |
| | 0x4001 1000 - 0x4001 13FF | USART1 |
| | 0x4001 0800 - 0x4001 0FFF | Reserved |
| | 0x4001 0400 - 0x4001 07FF | TIM8 |
| | 0x4001 0000 - 0x4001 03FF | TIM1 |
| | 0x4000 7400 - 0x4000 FFFF | Reserved |



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Table 12. STM32F412xE/G register boundary addresses (continued)

| Bus | Boundary address | Peripheral |
|---|---|---|
| APB1 | 0x4000 7000 - 0x4000 73FF | PWR |
| | 0x4000 6C00 - 0x4000 6FFF | Reserved |
| | 0x4000 6800- 0x4000 6BFF | CAN2 |
| | 0x4000 6400- 0x4000 67FF | CAN1 |
| | 0x4000 6000- 0x4000 63FF | I2CFMP1 |
| | 0x4000 5C00 - 0x4000 5FFF | I2C3 |
| | 0x4000 5800 - 0x4000 5BFF | I2C2 |
| | 0x4000 5400 - 0x4000 57FF | I2C1 |
| | 0x4000 4C00 - 0x4000 53FF | Reserved |
| | 0x4000 4800 - 0x4000 4BFF | USART3 |
| | 0x4000 4400 - 0x4000 47FF | USART2 |
| | 0x4000 4000 - 0x4000 43FF | I2S3ext |
| | 0x4000 3C00 - 0x4000 3FFF | SPI3 / I2S3 |
| | 0x4000 3800 - 0x4000 3BFF | SPI2 / I2S2 |
| | 0x4000 3400 - 0x4000 37FF | I2S2ext |
| | 0x4000 3000 - 0x4000 33FF | IWDG |
| | 0x4000 2C00 - 0x4000 2FFF | WWDG |
| | 0x4000 2800 - 0x4000 2BFF | RTC & BKP Registers |
| | 0x4000 2400 - 0x4000 27FF | Reserved |
| | 0x4000 2000 - 0x4000 23FF | TIM14 |
| | 0x4000 1C00 - 0x4000 1FFF | TIM13 |
| | 0x4000 1800 - 0x4000 1BFF | TIM12 |
| | 0x4000 1400 - 0x4000 17FF | TIM7 |
| | 0x4000 1000 - 0x4000 13FF | TIM6 |
| | 0x4000 0C00 - 0x4000 0FFF | TIM5 |
| | 0x4000 0800 - 0x4000 0BFF | TIM4 |
| | 0x4000 0400 - 0x4000 07FF | TIM3 |
| | 0x4000 0000 - 0x4000 03FF | TIM2 |



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# 6 Electrical characteristics

## 6.1 Parameter conditions

Unless otherwise specified, all voltages are referenced to $V_{SS}$.

### 6.1.1 Minimum and maximum values

Unless otherwise specified the minimum and maximum values are guaranteed in the worst conditions of ambient temperature, supply voltage and frequencies by tests in production on 100% of the devices with an ambient temperature at $T_A$ = 25 °C and $T_A$ = $T_A$max (given by the selected temperature range).

Data based on characterization results, design simulation and/or technology characteristics are indicated in the table footnotes and are not tested in production. Based on characterization, the minimum and maximum values refer to sample tests and represent the mean value plus or minus three times the standard deviation (mean ±3 σ).

### 6.1.2 Typical values

Unless otherwise specified, typical data are based on $T_A$ = 25 °C, $V_{DD}$ = 3.3 V (for the 1.7 V ≤$V_{DD}$ ≤3.6 V voltage range). They are given only as design guidelines and are not tested.

Typical ADC accuracy values are determined by characterization of a batch of samples from a standard diffusion lot over the full temperature range, where 95% of the devices have an error less than or equal to the value indicated (mean ±2 σ).

### 6.1.3 Typical curves

Unless otherwise specified, all typical curves are given only as design guidelines and are not tested.

### 6.1.4 Loading capacitor

The loading conditions used for pin parameter measurement are shown in *Figure 19*.

### 6.1.5 Pin input voltage

The input voltage measurement on a pin of the device is described in *Figure 20*.

**Figure 19. Pin loading conditions**

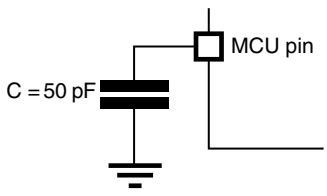
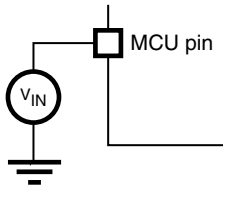



**Figure 20. Input voltage measurement**

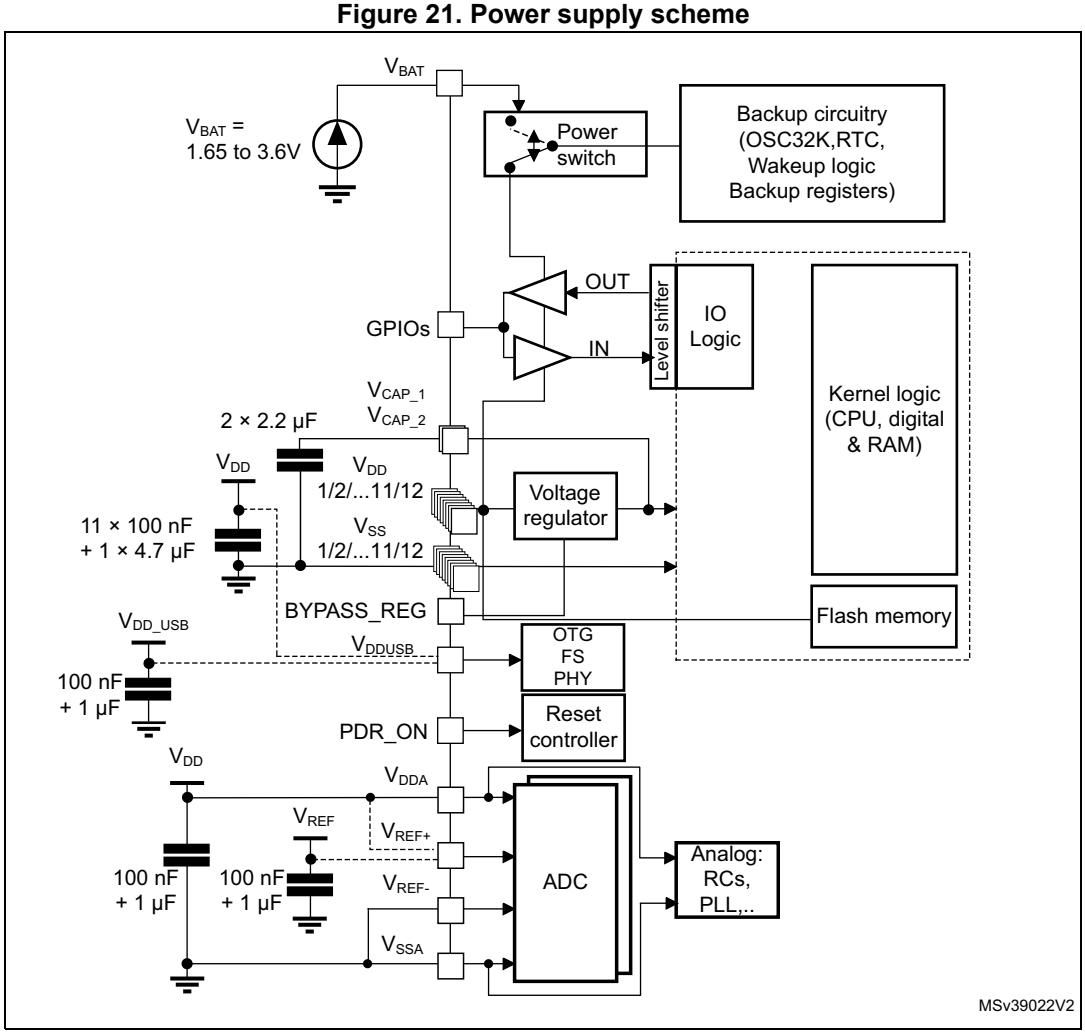





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### 6.1.6 Power supply scheme

**Figure 21. Power supply scheme**




1. To connect PDR_ON pin, refer to Section: Power supply supervisor.
2. The 4.7 µF ceramic capacitor must be connected to one of the $V_{DD}$ pin.
3. VCAP_2 pad is only available on 100-pin and 144-pin packages.
4. $V_{DDA}$=$V_{DD}$ and $V_{SSA}$=$V_{SS}$.
5. $V_{DDUSB}$ is a dedicated independent USB power supply for the on-chip full-speed OTG PHY module and associated DP/DM GPIOs. $V_{DDUSB}$ value does not depend on the $V_{DD}$ and $V_{DDA}$ values, but it must be the last supply to be provided and the first to disappear.

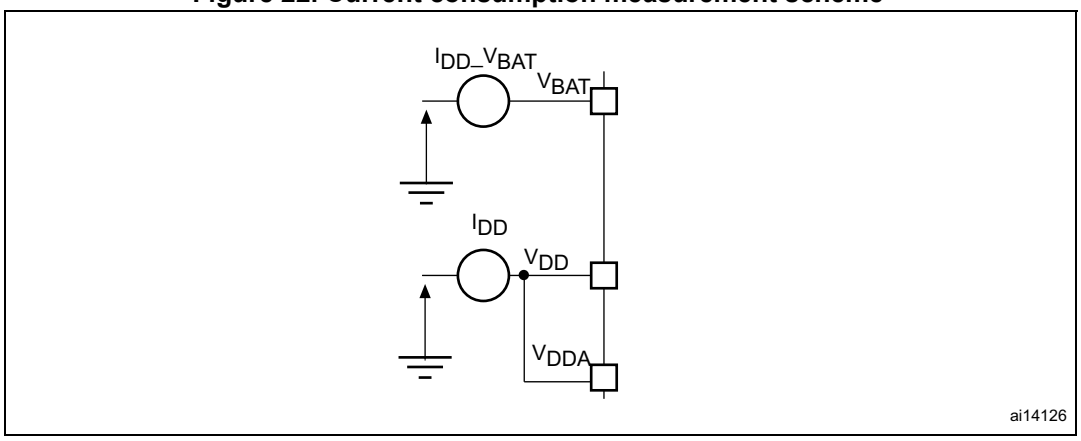
**Caution:** Each power supply pair (for example $V_{DD}$/$V_{SS}$, $V_{DDA}$/$V_{SSA}$) must be decoupled with filtering ceramic capacitors as shown above. These capacitors must be placed as close as possible to, or below, the appropriate pins on the underside of the PCB to ensure good operation of the device. It is not recommended to remove filtering capacitors to reduce PCB size or cost. This might cause incorrect operation of the device.



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### 6.1.7 Current consumption measurement

**Figure 22. Current consumption measurement scheme**




## 6.2 Absolute maximum ratings

Stresses above the absolute maximum ratings listed in *Table 13: Voltage characteristics*, *Table 14: Current characteristics*, and *Table 15: Thermal characteristics* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

**Table 13. Voltage characteristics**

| Symbol | Ratings | Min | Max | Unit |
|---|---|---|---|---|
| $V_{DD}$–$V_{SS}$ | External main supply voltage (including $V_{DDA}$, $V_{DD}$, $V_{DDUSB}$ and $V_{BAT}$)(1) | –0.3 | 4.0 | V |
| $V_{IN}$ | Input voltage on FT and TC pins(2) | $V_{SS}$–0.3 | $V_{DD}$+4.0 | |
| | Input voltage on any other pin | $V_{SS}$–0.3 | 4.0 | |
| | Input voltage for BOOT0 | $V_{SS}$ | 9.0 | |
| $\lvert\Delta V_{DDx}\rvert$ | Variations between different $V_{DD}$ power pins | - | 50 | mV |
| $\lvert V_{SSX} - V_{SS}\rvert$ | Variations between all the different ground pins | - | 50 | |
| $V_{ESD(HBM)}$ | Electrostatic discharge voltage (human body model) | see *Section 6.3.14: Absolute maximum ratings (electrical sensitivity)* | | |

1. All main power ($V_{DD}$, $V_{DDA}$, $V_{DDUSB}$) and ground ($V_{SS}$, $V_{SSA}$) pins must always be connected to the external power supply, in the permitted range.
2. $V_{IN}$ maximum value must always be respected. Refer to *Table 14* for the values of the maximum allowed injected current.



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**Table 14. Current characteristics**

| Symbol | Ratings | Max. | Unit |
|---|---|---|---|
| $\Sigma I_{VDD}$ | Total current into sum of all $V_{DD_x}$ power lines (source)(1) | 160 | mA |
| $\Sigma I_{VSS}$ | Total current out of sum of all $V_{SS_x}$ ground lines (sink)(1) | -160 | |
| $\Sigma I_{VDDUSB}$ | Total current into $V_{DDUSB}$ power lines (source) | 25 | |
| $I_{VDD}$ | Maximum current into each $V_{DD_x}$ power line (source)(1) | 100 | |
| $I_{VSS}$ | Maximum current out of each $V_{SS_x}$ ground line (sink)(1) | -100 | |
| $I_{IO}$ | Output current sunk by any I/O and control pin | 25 | |
| | Output current sourced by any I/O and control pin | -25 | |
| $\Sigma I_{IO}$ | Total output current sunk by sum of all I/O and control pins (2) | 120 | |
| | Total output current sunk by sum of all USB I/Os | 25 | |
| | Total output current sourced by sum of all I/Os and control pins(2) | -120 | |
| $I_{INJ(PIN)}$ (3) | Injected current on FT and TC pins (4) | –5/+0 | |
| | Injected current on NRST and B pins (4) | | |
| $\Sigma I_{INJ(PIN)}$ | Total injected current (sum of all I/O and control pins)(5) | ±25 | |

1. All main power ($V_{DD}$, $V_{DDA}$, $V_{DDUSB}$) and ground ($V_{SS}$, $V_{SSA}$) pins must always be connected to the external power supply, in the permitted range.
2. This current consumption must be correctly distributed over all I/Os and control pins.
3. Negative injection disturbs the analog performance of the device. See note in *Section 6.3.20: 12-bit ADC characteristics*.
4. Positive injection is not possible on these I/Os and does not occur for input voltages lower than the specified maximum value.
5. When several inputs are submitted to a current injection, the maximum $\Sigma I_{INJ(PIN)}$ is the absolute sum of the positive and negative injected currents (instantaneous values).

**Table 15. Thermal characteristics**

| Symbol | Ratings | Value | Unit |
|---|---|---|---|
| $T_{STG}$ | Storage temperature range | –65 to +150 | °C |
| $T_J$ | Maximum junction temperature | 130 | |
| $T_{LEAD}$ | Maximum lead temperature during soldering (WLCSP64, LQFP64/100/144, UFQFPN48, UFBGA100/144) | see note (1) | |

1. Compliant with JEDEC Std J-STD-020D (for small body, Sn-Pb or Pb assembly), the ST ECOPACK® 7191395 specification, and the European directive on Restrictions on Hazardous Substances (ROHS directive 2011/65/EU, July 2011).



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## 6.3 Operating conditions

### 6.3.1 General operating conditions

**Table 16. General operating conditions**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $f_{HCLK}$ | Internal AHB clock frequency | Power Scale3: Regulator ON, VOS[1:0] bits in PWR_CR register = 0x01 | 0 | - | 64 | MHz |
| | | Power Scale2: Regulator ON, VOS[1:0] bits in PWR_CR register = 0x10 | 0 | - | 84 | |
| | | Power Scale1: Regulator ON, VOS[1:0] bits in PWR_CR register = 0x11 | 0 | - | 100 | |
| $f_{PCLK1}$ | Internal APB1 clock frequency | - | 0 | - | 50 | MHz |
| $f_{PCLK2}$ | Internal APB2 clock frequency | - | 0 | - | 100 | MHz |
| $V_{DD}$ | Standard operating voltage | - | 1.7(1) | - | 3.6 | V |
| $V_{DDA}$(2)(3) | Analog operating voltage (ADC limited to 1.2 M samples) | Must be the same potential as $V_{DD}$(4) | 1.7(1) | - | 2.4 | V |
| | Analog operating voltage (ADC limited to 2.4 M samples) | | 2.4 | - | 3.6 | |
| $V_{DDUSB}$ | USB supply voltage (supply voltage for PA11 and PA12 pins) | USB not used | 1.7 | 3.3 | 3.6 | V |
| | | USB used(5) | 3.0 | - | 3.6 | |
| $V_{BAT}$ | Backup operating voltage | - | 1.65 | - | 3.6 | V |
| $V_{12}$ | Regulator ON: 1.2 V internal voltage on VCAP_1/VCAP_2 pins | VOS[1:0] bits in PWR_CR register = 0x01 Max frequency 64 MHz | 1.08(6) | 1.14 | 1.20(6) | V |
| | | VOS[1:0] bits in PWR_CR register = 0x10 Max frequency 84 MHz | 1.20(6) | 1.26 | 1.32(6) | |
| | | VOS[1:0] bits in PWR_CR register = 0x11 Max frequency 100 MHz | 1.26 | 1.32 | 1.38 | |
| $V_{12}$ | Regulator OFF: 1.2 V external voltage must be supplied on VCAP_1/VCAP_2 pins | Max frequency 64 MHz | 1.10 | 1.14 | 1.20 | V |
| | | Max frequency 84 MHz | 1.20 | 1.26 | 1.32 | |
| | | Max frequency 100 MHz | 1.26 | 1.32 | 1.38 | |
| $V_{IN}$ | Input voltage on RST, FT and TC pins(7) | $2\ V \le V_{DD} \le 3.6\ V$ | -0.3 | - | 5.5 | V |
| | | $V_{DD} \le 2\ V$ | -0.3 | - | 5.2 | |
| | Input voltage on BOOT0 pin | - | 0 | - | 9 | |



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**Table 16. General operating conditions (continued)**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $P_D$ | Power dissipation at $T_A$ = 85°C for range 6 or $T_A$ = 105°C for range 7(8) | UFQFPN48 | - | - | 625 | mW |
| | | WLCSP64 | - | - | 392 | |
| | | LQFP64 | - | - | 425 | |
| | | LQFP100 | - | - | 465 | |
| | | LQFP144 | - | - | 571 | |
| | | UFBGA100 | - | - | 351 | |
| | | UFBGA144 | - | - | 416 | |
| $P_D$ | Power dissipation at $T_A$ = 125 °C for range 3(8) | UFQFPN48 | - | - | 156 | |
| | | WLCSP64 | - | - | 98 | |
| | | LQFP64 | - | - | 106 | |
| | | LQFP100 | - | - | 116 | |
| | | LQFP144 | - | - | 142 | |
| | | UFBGA100 | - | - | 88 | |
| | | UFBGA144 | - | - | 104 | |
| $T_A$ | Ambient temperature for range 6 | Maximum power dissipation | -40 | - | 85 | °C |
| | | Low power dissipation(9) | -40 | - | 105 | |
| | Ambient temperature for range 7 | Maximum power dissipation | -40 | - | 105 | |
| | | Low power dissipation(9) | -40 | - | 125 | |
| | Ambient temperature for range 3 | Maximum power dissipation | -40 | - | 110 | |
| | | Low power dissipation(9) | -40 | - | 130 | |
| $T_J$ | Junction temperature range | Range 6 | -40 | - | 105 | |
| | | Range 7 | -40 | - | 125 | |
| | | Range 3 | -40 | - | 130 | |

1. $V_{DD}/V_{DDA}$ minimum value of 1.7 V with the use of an external power supply supervisor (refer to *Section 3.18.2: Internal reset OFF*).
2. When the ADC is used, refer to *Table 72: ADC characteristics*.
3. If $V_{REF+}$ pin is present, it must respect the following condition: $V_{DDA}$-$V_{REF}$+ < 1.2 V.
4. It is recommended to power $V_{DD}$ and $V_{DDA}$ from the same source. A maximum difference of 300 mV between $V_{DD}$ and $V_{DDA}$ can be tolerated during power-up and power-down operation.
5. Only the DM ($P_{A11}$) and DP ($P_{A12}$) pads are supplied through $V_{DDUSB}$. For application where the $V_{BUS}$ ($P_{A9}$) is directly connected to the chip, a minimum $V_{DD}$ supply of 2.7V is required.

   (some application examples are shown in appendix B)
6. Guaranteed by test in production
7. To sustain a voltage higher than $V_{DD}$+0.3, the internal Pull-up and Pull-Down resistors must be disabled
8. If $T_A$ is lower, higher $P_D$ values are allowed as long as $T_J$ does not exceed $T_{Jmax}$.
9. In low power dissipation state, $T_A$ can be extended to this range as long as $T_J$ does not exceed $T_{Jmax}$.



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**Table 17. Features depending on the operating power supply range**

| Operating power supply range | ADC operation | Maximum Flash memory access frequency with no wait states ($f_{Flashmax}$) | Maximum Flash memory access frequency with wait states (1)(2) | I/O operation | Clock output frequency on I/O pins(3) | Possible Flash memory operations |
|---|---|---|---|---|---|---|
| $V_{DD}$ =1.7 to 2.1 V(4) | Conversion time up to 1.2 Msps | 16 MHz(5) | 100 MHz with 6 wait states | – No I/O compensation | up to 30 MHz | 8-bit erase and program operations only |
| $V_{DD}$ = 2.1 to 2.4 V | Conversion time up to 1.2 Msps | 18 MHz | 100 MHz with 5 wait states | – No I/O compensation | up to 30 MHz | 16-bit erase and program operations |
| $V_{DD}$ = 2.4 to 2.7 V | Conversion time up to 2.4 Msps | 24 MHz | 100 MHz with 4 wait states | – I/O compensation works | up to 50 MHz | 16-bit erase and program operations |
| $V_{DD}$ = 2.7 to 3.6 V(6) | Conversion time up to 2.4 Msps | 30 MHz | 100 MHz with 3 wait states | – I/O compensation works | – up to 100 MHz when $V_{DD}$ = 3.0 to 3.6 V<br>– up to 50 MHz when $V_{DD}$ = 2.7 to 3.0 V | 32-bit erase and program operations |

1. Applicable only when the code is executed from Flash memory. When the code is executed from RAM, no wait state is required.
2. Thanks to the ART accelerator and the 128-bit Flash memory, the number of wait states given here does not impact the execution speed from Flash memory since the ART accelerator allows to achieve a performance equivalent to 0 wait state program execution.
3. Refer to *Table 59: I/O AC characteristics* for frequencies vs. external load.
4. $V_{DD}/V_{DDA}$ minimum value of 1.7 V, with the use of an external power supply supervisor (refer to *Section 3.18.2: Internal reset OFF*).
5. Prefetch available over the complete VDD supply range.
6. The voltage range for the USB full speed embedded PHY can drop down to 2.7 V. However the electrical characteristics of D- and D+ pins will be degraded between 2.7 and 3 V.



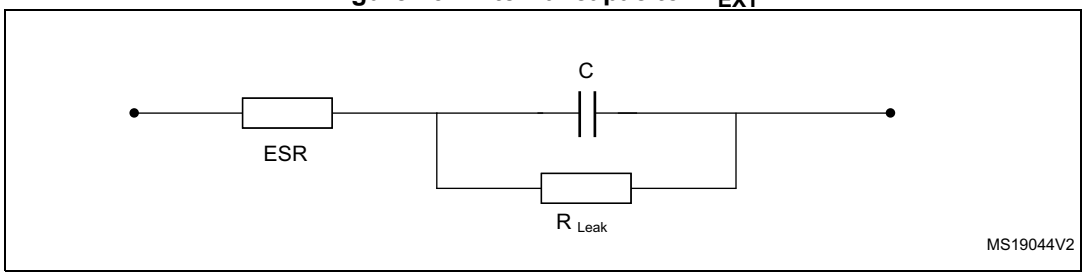
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### 6.3.2 VCAP_1/VCAP_2 external capacitors

Stabilization for the main regulator is achieved by connecting the external capacitor $C_{EXT}$ to the VCAP_1 and VCAP_2 pins. For packages supporting only 1 VCAP pin, the 2 CEXT capacitors are replaced by a single capacitor.

$C_{EXT}$ is specified in *Table 18*.

**Figure 23. External capacitor $C_{EXT}$**




1. Legend: ESR is the equivalent series resistance.

**Table 18. VCAP_1/VCAP_2 operating conditions(1)**

| Symbol | Parameter | Conditions |
|---|---|---|
| CEXT | Capacitance of external capacitor with the pins VCAP_1 and VCAP_2 available | 2.2 µF |
| ESR | ESR of external capacitor with the pins VCAP_1 and VCAP_2 available | < 2 Ω |
| CEXT | Capacitance of external capacitor with a single VCAP pin available | 4.7 µF |
| ESR | ESR of external capacitor with a single VCAP pin available | < 1 Ω |

1. When bypassing the voltage regulator, the two 2.2 µF $V_{CAP}$ capacitors are not required and should be replaced by two 100 nF decoupling capacitors.

### 6.3.3 Operating conditions at power-up/power-down (regulator ON)

Subject to general operating conditions for $T_A$.

**Table 19. Operating conditions at power-up / power-down (regulator ON)**

| Symbol | Parameter | Min | Max | Unit |
|---|---|---|---|---|
| $t_{VDD}$ | $V_{DD}$ rise time rate | 20 | ∞ | µs/V |
| | $V_{DD}$ fall time rate | 20 | ∞ | |



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### 6.3.4 Operating conditions at power-up / power-down (regulator OFF)

Subject to general operating conditions for $T_A$.

**Table 20. Operating conditions at power-up / power-down (regulator OFF)(1)**

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---|---|---|---|---|---|
| $t_{VDD}$ | $V_{DD}$ rise time rate | Power-up | 20 | ∞ | µs/V |
| | $V_{DD}$ fall time rate | Power-down | 20 | ∞ | |
| $t_{VCAP}$ | $V_{CAP_1}$ and $V_{CAP_2}$ rise time rate | Power-up | 20 | ∞ | |
| | $V_{CAP_1}$ and $V_{CAP_2}$ fall time rate | Power-down | 20 | ∞ | |

1. To reset the internal logic at power-down, a reset must be applied on pin PA0 when $V_{DD}$ reach below 1.08 V.

*Note: This feature is only available for UFBGA100 and UFBGA144 packages.*

### 6.3.5 Embedded reset and power control block characteristics

The parameters given in *Table 21* are derived from tests performed under ambient temperature and $V_{DD}$ supply voltage @ 3.3V.

**Table 21. Embedded reset and power control block characteristics**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $V_{PVD}$ | Programmable voltage detector level selection | PLS[2:0]=000 (rising edge) | 2.09 | 2.14 | 2.19 | V |
| | | PLS[2:0]=000 (falling edge) | 1.98 | 2.04 | 2.08 | |
| | | PLS[2:0]=001 (rising edge) | 2.23 | 2.30 | 2.37 | |
| | | PLS[2:0]=001 (falling edge) | 2.13 | 2.19 | 2.25 | |
| | | PLS[2:0]=010 (rising edge) | 2.39 | 2.45 | 2.51 | |
| | | PLS[2:0]=010 (falling edge) | 2.29 | 2.35 | 2.39 | |
| | | PLS[2:0]=011 (rising edge) | 2.54 | 2.60 | 2.65 | |
| | | PLS[2:0]=011 (falling edge) | 2.44 | 2.51 | 2.56 | |
| | | PLS[2:0]=100 (rising edge) | 2.70 | 2.76 | 2.82 | |
| | | PLS[2:0]=100 (falling edge) | 2.59 | 2.66 | 2.71 | |
| | | PLS[2:0]=101 (rising edge) | 2.86 | 2.93 | 2.99 | |
| | | PLS[2:0]=101 (falling edge) | 2.65 | 2.84 | 3.02 | |
| | | PLS[2:0]=110 (rising edge) | 2.96 | 3.03 | 3.10 | |
| | | PLS[2:0]=110 (falling edge) | 2.85 | 2.93 | 2.99 | |
| | | PLS[2:0]=111 (rising edge) | 3.07 | 3.14 | 3.21 | |
| | | PLS[2:0]=111 (falling edge) | 2.95 | 3.03 | 3.09 | |
| $V_{PVDhyst}$(2) | PVD hysteresis | - | - | 100 | - | mV |
| $V_{POR/PDR}$ | Power-on/power-down reset threshold | Falling edge | 1.60(1) | 1.68 | 1.76 | V |
| | | Rising edge | 1.64 | 1.72 | 1.80 | |



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**Table 21. Embedded reset and power control block characteristics (continued)**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $V_{PDRhyst}$(2) | PDR hysteresis | - | - | 40 | - | mV |
| $V_{BOR1}$ | Brownout level 1 threshold | Falling edge | 2.13 | 2.19 | 2.24 | V |
| | | Rising edge | 2.23 | 2.29 | 2.33 | |
| $V_{BOR2}$ | Brownout level 2 threshold | Falling edge | 2.44 | 2.50 | 2.56 | |
| | | Rising edge | 2.53 | 2.59 | 2.63 | |
| $V_{BOR3}$ | Brownout level 3 threshold | Falling edge | 2.75 | 2.83 | 2.88 | |
| | | Rising edge | 2.85 | 2.92 | 2.97 | |
| $V_{BORhyst}$(2) | BOR hysteresis | - | - | 100 | - | mV |
| $T_{RSTTEMPO}$(2)(3) | POR reset timing | - | 0.5 | 1.5 | 3.0 | ms |
| $I_{RUSH}$(2) | In-Rush current on voltage regulator power-on (POR or wakeup from Standby) | - | - | 160 | 200 | mA |
| $E_{RUSH}$(2) | In-Rush energy on voltage regulator power-on (POR or wakeup from Standby) | $V_{DD}$ = 1.7 V, $T_A$ = 125 °C, $I_{RUSH}$ = 171 mA for 31 µs | - | - | 5.4 | µC |

1. The product behavior is guaranteed by design down to the minimum $V_{POR/PDR}$ value.
2. Guaranteed by design, not tested in production.
3. The reset timing is measured from the power-on (POR reset or wakeup from $V_{BAT}$) to the instant when first instruction is fetched by the user application code.

### 6.3.6 Supply current characteristics

The current consumption is a function of several parameters and factors such as the operating voltage, ambient temperature, I/O pin loading, device software configuration, operating frequencies, I/O pin switching rate, program location in memory and executed binary code.
The current consumption is measured as described in *Figure 22: Current consumption measurement scheme*.

All the run-mode current consumption measurements given in this section are performed with a reduced code that gives a consumption equivalent to CoreMark code.



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### Typical and maximum current consumption

The MCU is placed under the following conditions:

- All I/O pins are in input mode with a static value at VDD or VSS (no load).
- All peripherals are disabled except if it is explicitly mentioned.
- The Flash memory access time is adjusted to both $f_{HCLK}$ frequency and VDD ranges (refer to *Table 17: Features depending on the operating power supply range*).
- The voltage scaling is adjusted to $f_{HCLK}$ frequency as follows:
  - Scale 3 for $f_{HCLK} \leq 64$ MHz
  - Scale 2 for 64 MHz < $f_{HCLK} \leq 84$ MHz
  - Scale 1 for 84 MHz < $f_{HCLK} \leq 100$ MHz
- The system clock is HCLK, $f_{PCLK1} = f_{HCLK}/2$, and $f_{PCLK2} = f_{HCLK}$.
- External clock is 4 MHz and PLL is ON except if it is explicitly mentioned.
- The maximum values are obtained for $V_{DD}$ = 3.6 V and a maximum ambient temperature ($T_A$), and the typical values for $T_A$= 25 °C and $V_{DD}$ = 3.3 V unless otherwise specified.

**Table 22. Typical and maximum current consumption, code with data processing (ART accelerator disabled) running from SRAM - $V_{DD}$ = 1.7 V**

| Symbol | Parameter | Conditions | $f_{HCLK}$ (MHz) | Typ | Max(1) | | | | Unit |
|---|---|---|---|---|---|---|---|---|---|
| | | | | $T_A$= 25 °C | $T_A$= 25 °C | $T_A$= 85 °C | $T_A$= 105 °C | $T_A$= 125 °C | |
| $I_{DD}$ | Supply current in **Run mode** | External clock, PLL ON, all peripherals enabled(2)(3) | 100 | 28.1 | 30.24 | 31.27 | 32.21 | 34.21 | mA |
| | | | 84 | 22.7 | 24.05 | 24.54 | 25.11 | 26.74 | |
| | | | 64 | 15.7 | 16.99 | 17.47 | 18.03 | 19.71 | |
| | | | 50 | 12.3 | 13.36 | 13.82 | 14.36 | 15.51 | |
| | | | 25 | 6.5 | 7.44 | 7.82 | 8.30 | 8.96 | |
| | | | 20 | 5.6 | 6.16 | 6.66 | 7.20 | 7.77 | |
| | | HSI, PLL off, all peripherals enabled(2)(3) | 16 | 3.9 | 4.70 | 5.31 | 6.08 | 6.57 | |
| | | | 1 | 0.6 | 0.78 | 1.33 | 1.98 | 2.14 | |
| | | External clock, PLL ON, all peripherals disabled(3) | 100 | 14.0 | 15.48 | 16.08 | 16.83 | 18.51 | |
| | | | 84 | 11.3 | 12.23 | 12.75 | 13.41 | 16.09 | |
| | | | 64 | 7.9 | 8.84 | 9.31 | 10.01 | 11.61 | |
| | | | 50 | 6.2 | 7.06 | 7.53 | 8.19 | 9.50 | |
| | | | 25 | 3.4 | 4.18 | 4.61 | 5.13 | 5.95 | |
| | | | 20 | 2.9 | 3.44 | 3.98 | 4.65 | 5.39 | |
| | | HSI, PLL off, all peripherals disabled(3) | 16 | 2.0 | 2.51 | 3.13 | 3.89 | 4.51 | |
| | | | 1 | 0.5 | 0.64 | 1.21 | 1.90 | 2.21 | |

1. Based on characterization, not tested in production unless otherwise specified
2. When analog peripheral blocks such as ADC, HSE, LSE, HSI, or LSI are ON, an additional power consumption has to be considered.
3. When the ADC is ON (ADON bit set in the ADC_CR2 register), add an additional power consumption of 1.6 mA for the analog part.



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**Table 23. Typical and maximum current consumption, code with data processing (ART accelerator disabled) running from SRAM - $V_{DD}$ = 3.6 V**

| Symbol | Parameter | Conditions | $f_{HCLK}$ (MHz) | Typ | Max(1) | | | | Unit |
|---|---|---|---|---|---|---|---|---|---|
| | | | | $T_A$= 25 °C | $T_A$= 25 °C | $T_A$= 85 °C | $T_A$= 105 °C | $T_A$= 125 °C | |
| $I_{DD}$ | Supply current in **Run mode** | External clock, PLL ON, all peripherals enabled(2) | 100 | 28.4 | 28.80(3) | 30.84 | 32.39 | 34.40(3) | mA |
| | | | 84 | 23.0 | 24.09(3) | 25.20 | 26.57 | 28.30(3) | |
| | | | 64 | 16.0 | 16.83(3) | 17.77 | 19.12 | 20.90(3) | |
| | | | 50 | 12.6 | 13.46 | 13.98 | 14.68 | 15.85 | |
| | | | 25 | 6.8 | 7.63 | 8.14 | 8.61 | 9.30 | |
| | | | 20 | 5.8 | 6.31 | 6.74 | 7.43 | 8.03 | |
| | | HSI, PLL OFF(4), all peripherals enabled(2) | 16 | 3.9 | 4.65 | 5.33 | 6.11 | 6.60 | |
| | | | 1 | 0.6 | 0.78 | 1.34 | 2.00 | 2.16 | |
| | | External clock, PLL ON, all peripherals disabled(2) | 100 | 14.3 | 15.09(3) | 16.22 | 17.90 | 19.72(3) | |
| | | | 84 | 11.6 | 12.28(3) | 13.36 | 14.99 | 16.80(3) | |
| | | | 64 | 8.2 | 8.75(3) | 9.68 | 11.21 | 13.00(3) | |
| | | | 50 | 6.5 | 7.21 | 7.69 | 8.47 | 9.74 | |
| | | | 25 | 3.6 | 4.22 | 4.68 | 5.29 | 6.08 | |
| | | | 20 | 3.2 | 3.65 | 4.18 | 4.94 | 5.68 | |
| | | HSI, PLL OFF, all peripherals disabled(2) | 16 | 2.0 | 2.48 | 3.12 | 3.94 | 4.54 | |
| | | | 1 | 0.5 | 0.65 | 1.26 | 1.94 | 2.24 | |

1. Based on characterization, not tested in production unless otherwise specified
2. When the ADC is ON (ADON bit set in the ADC_CR2 register), add an additional power consumption of 1.6 mA for the analog part.
3. Tested in production
4. When analog peripheral blocks such as ADC, HSE, LSE, HSI, or LSI are ON, an additional power consumption has to be considered



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**Table 24. Typical and maximum current consumption in run mode, code with data processing (ART accelerator enabled except prefetch) running from Flash memory- $V_{DD}$ = 1.7 V**

| Symbol | Parameter | Conditions | $f_{HCLK}$ (MHz) | Typ | Max(1) | | | | Unit |
|---|---|---|---|---|---|---|---|---|---|
| | | | | $T_A$ = 25 °C | $T_A$ = 25 °C | $T_A$ = 85 °C | $T_A$ = 105 °C | $T_A$ = 125 °C | |
| $I_{DD}$ | Supply current in **Run mode** | External clock, PLL ON, all peripherals enabled(2)(3) | 100 | 26.9 | 28.78 | 29.86 | 31.30 | 33.08 | mA |
| | | | 84 | 21.6 | 23.14 | 23.93 | 24.89 | 26.31 | |
| | | | 64 | 15.0 | 16.08 | 16.70 | 17.46 | 18.45 | |
| | | | 50 | 11.8 | 12.74 | 13.33 | 14.07 | 14.87 | |
| | | | 25 | 6.3 | 7.13 | 7.69 | 8.30 | 8.77 | |
| | | | 20 | 5.5 | 6.09 | 6.64 | 7.30 | 7.72 | |
| | | HSI, PLL OFF, all peripherals enabled(2) | 16 | 3.9 | 4.20 | 4.78 | 5.49 | 5.81 | |
| | | | 1 | 0.9 | 0.98 | 1.50 | 2.20 | 2.33 | |
| | | External clock, PLL ON(4) all peripherals disabled(2) | 100 | 12.7 | 13.82 | 14.71 | 15.76 | 17.53 | |
| | | | 84 | 10.3 | 11.20 | 11.97 | 12.96 | 14.41 | |
| | | | 64 | 7.2 | 7.87 | 8.57 | 9.41 | 10.47 | |
| | | | 50 | 5.7 | 6.33 | 7.02 | 7.87 | 8.75 | |
| | | | 25 | 3.2 | 3.77 | 4.38 | 5.13 | 5.71 | |
| | | | 20 | 2.9 | 3.31 | 3.93 | 4.69 | 5.22 | |
| | | HSI, PLL OFF, all peripherals disabled(2) | 16 | 2.1 | 2.25 | 2.83 | 3.56 | 3.96 | |
| | | | 1 | 0.7 | 0.83 | 1.42 | 2.12 | 2.36 | |

1. Based on characterization, not tested in production unless otherwise specified.
2. Add an additional power consumption of 1.6 mA per ADC for the analog part. In applications, this consumption occurs only while the ADC is ON (ADON bit is set in the ADC_CR2 register).
3. When the ADC is ON (ADON bit set in the ADC_CR2), add an additional power consumption of 1.6mA per ADC for the analog part.
4. Refer to *Table 45* and RM0383 for the possible PLL VCO setting



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**Table 25. Typical and maximum current consumption in run mode, code with data processing (ART accelerator enabled except prefetch) running from Flash memory - $V_{DD}$ = 3.6 V**

| Symbol | Parameter | Conditions | $f_{HCLK}$ (MHz) | Typ | Max(1) | | | | Unit |
|---|---|---|---|---|---|---|---|---|---|
| | | | | $T_A$ = 25 °C | $T_A$ = 25 °C | $T_A$ = 85 °C | $T_A$ = 105 °C | $T_A$ = 125 °C | |
| $I_{DD}$ | Supply current in **Run mode** | External clock, PLL ON(2), all peripherals enabled(3) | 100 | 27.2 | 28.70(4) | 30.14 | 31.98 | 33.80 | mA |
| | | | 84 | 21.9 | 23.60 | 24.31 | 25.37 | 26.82 | |
| | | | 64 | 15.2 | 16.45 | 17.03 | 17.87 | 18.89 | |
| | | | 50 | 12.1 | 13.12 | 13.67 | 14.46 | 15.29 | |
| | | | 25 | 6.6 | 7.59 | 8.12 | 8.77 | 9.27 | |
| | | | 20 | 5.7 | 6.51 | 7.07 | 7.77 | 8.21 | |
| | | HSI, PLL OFF, all peripherals enabled(3) | 16 | 4.0 | 4.32 | 4.88 | 5.69 | 6.01 | |
| | | | 1 | 0.8 | 1.14 | 1.67 | 2.38 | 2.51 | |
| | | External clock, PLL ON(2) all peripherals disabled(3) | 100 | 13.0 | 14.06(4) | 15.34 | 17.27 | 19.20 | |
| | | | 84 | 10.5 | 11.21 | 12.16 | 13.47 | 14.98 | |
| | | | 64 | 7.5 | 8.29 | 9.01 | 9.88 | 10.99 | |
| | | | 50 | 6.0 | 6.73 | 7.32 | 8.27 | 9.20 | |
| | | | 25 | 3.5 | 4.18 | 4.73 | 5.57 | 6.19 | |
| | | | 20 | 3.1 | 3.72 | 4.25 | 5.10 | 5.67 | |
| | | HSI, PLL OFF, all peripherals disabled(3) | 16 | 2.1 | 2.41 | 2.94 | 3.75 | 4.17 | |
| | | | 1 | 0.7 | 0.99 | 1.51 | 2.30 | 2.56 | |

1. Based on characterization, not tested in production unless otherwise specified.
2. Refer to *Table 45* and RM0383 for the possible PLL VCO setting
3. Add an additional power consumption of 1.6 mA per ADC for the analog part. In applications, this consumption occurs only while the ADC is ON (ADON bit is set in the ADC_CR2 register).
4. Tested in production.



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**Table 26. Typical and maximum current consumption in run mode, code with data processing (ART accelerator disabled) running from Flash memory - $V_{DD}$ = 3.6 V**

| Symbol | Parameter | Conditions | $f_{HCLK}$ (MHz) | Typ | Max(1) | | | | Unit |
|---|---|---|---|---|---|---|---|---|---|
| | | | | $T_A$ = 25 °C | $T_A$ = 25 °C | $T_A$ = 85 °C | $T_A$ = 105 °C | $T_A$ = 125 °C | |
| $I_{DD}$ | Supply current in **Run mode** | External clock, PLL ON(2), all peripherals enabled(3) | 100 | 36.3 | 38.95 | 41.19 | 42.95 | 45.40 | mA |
| | | | 84 | 31.1 | 33.22 | 34.81 | 36.10 | 38.16 | |
| | | | 64 | 22.3 | 23.97 | 25.10 | 26.23 | 27.73 | |
| | | | 50 | 18.3 | 19.77 | 20.65 | 21.73 | 22.97 | |
| | | | 25 | 10.1 | 11.39 | 12.16 | 13.11 | 13.86 | |
| | | | 20 | 8.6 | 9.60 | 10.25 | 11.06 | 11.69 | |
| | | HSI, PLL OFF, all peripherals enabled(3) | 16 | 6.3 | 6.85 | 7.51 | 8.38 | 8.85 | |
| | | | 1 | 1.1 | 1.39 | 1.82 | 2.61 | 2.76 | |
| | | External clock, PLL ON(2) all peripherals disabled(3) | 100 | 22.1 | 23.95 | 25.80 | 27.50 | 30.58 | |
| | | | 84 | 19.7 | 20.79 | 22.52 | 24.12 | 26.82 | |
| | | | 64 | 14.5 | 15.88 | 17.21 | 18.54 | 20.62 | |
| | | | 50 | 12.2 | 13.38 | 14.59 | 15.79 | 17.56 | |
| | | | 25 | 7.0 | 8.05 | 8.89 | 10.16 | 11.29 | |
| | | | 20 | 6.0 | 6.84 | 7.51 | 8.52 | 9.47 | |
| | | HSI, PLL OFF, all peripherals disabled(3) | 16 | 4.4 | 4.91 | 5.56 | 6.54 | 7.28 | |
| | | | 1 | 0.9 | 1.25 | 1.79 | 2.59 | 2.88 | |

1. Based on characterization, not tested in production unless otherwise specified.
2. Refer to *Table 45* and RM0383 for the possible PLL VCO setting
3. Add an additional power consumption of 1.6 mA per ADC for the analog part. In applications, this consumption occurs only while the ADC is ON (ADON bit is set in the ADC_CR2 register).



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**Table 27. Typical and maximum current consumption in run mode, code with data processing (ART accelerator disabled) running from Flash memory - $V_{DD}$ = 1.7 V**

| Symbol | Parameter | Conditions | $f_{HCLK}$ (MHz) | Typ | Max(1) | | | | Unit |
|---|---|---|---|---|---|---|---|---|---|
| | | | | $T_A$ = 25 °C | $T_A$ = 25 °C | $T_A$ = 85 °C | $T_A$ = 105 °C | $T_A$ = 125 °C | |
| $I_{DD}$ | Supply current in **Run mode** | External clock, PLL ON, all peripherals enabled(2)(3) | 100 | 35.9 | 38.55 | 40.77 | 42.52 | 44.95 | mA |
| | | | 84 | 29.4 | 31.59 | 33.12 | 34.42 | 36.38 | |
| | | | 64 | 22.4 | 24.02 | 25.15 | 26.28 | 27.78 | |
| | | | 50 | 18.6 | 20.07 | 21.08 | 22.05 | 23.30 | |
| | | | 25 | 10.3 | 11.62 | 12.39 | 13.34 | 14.10 | |
| | | | 20 | 8.9 | 9.85 | 10.59 | 11.32 | 11.96 | |
| | | HSI, PLL OFF, all peripherals enabled(2)(3) | 16 | 6.7 | 7.26 | 8.04 | 8.80 | 9.30 | |
| | | | 1 | 1.1 | 1.44 | 1.99 | 2.66 | 2.81 | |
| | | External clock, PLL ON(3) all peripherals disabled | 100 | 21.7 | 23.55 | 25.48 | 27.07 | 30.10 | |
| | | | 84 | 18.0 | 19.16 | 20.93 | 22.39 | 24.89 | |
| | | | 64 | 14.6 | 15.93 | 17.32 | 18.59 | 20.68 | |
| | | | 50 | 12.5 | 13.63 | 14.90 | 16.07 | 17.87 | |
| | | | 25 | 7.2 | 8.25 | 9.26 | 10.26 | 11.41 | |
| | | | 20 | 6.3 | 7.15 | 7.99 | 8.84 | 9.83 | |
| | | HSI, PLL OFF, all peripherals disabled(3) | 16 | 4.9 | 5.37 | 6.20 | 7.03 | 7.82 | |
| | | | 1 | 1.0 | 1.30 | 1.91 | 2.65 | 2.95 | |

1. Based on characterization, not tested in production unless otherwise specified.
2. Add an additional power consumption of 1.6 mA per ADC for the analog part. In applications, this consumption occurs only while the ADC is ON (ADON bit is set in the ADC_CR2 register).
3. When the ADC is ON (ADON bit set in the ADC_CR2), add an additional power consumption of 1.6mA per ADC for the analog part.



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**Table 28. Typical and maximum current consumption in run mode, code with data processing (ART accelerator enabled with prefetch) running from Flash memory - $V_{DD}$ = 3.6 V**

| Symbol | Parameter | Conditions | $f_{HCLK}$ (MHz) | Typ | Max(1) | | | | Unit |
|---|---|---|---|---|---|---|---|---|---|
| | | | | $T_A$ = 25 °C | $T_A$ = 25 °C | $T_A$ = 85 °C | $T_A$ = 105 °C | $T_A$ = 125 °C | |
| $I_{DD}$ | Supply current in **Run mode** | External clock, PLL ON, all peripherals enabled(2) | 100 | 38.9 | 41.10 | 42.85 | 44.28 | 46.80 | mA |
| | | | 84 | 32.8 | 34.61 | 35.77 | 36.72 | 38.81 | |
| | | | 64 | 23.6 | 24.96 | 25.84 | 26.64 | 28.16 | |
| | | | 50 | 18.7 | 19.90 | 20.67 | 21.45 | 22.67 | |
| | | | 25 | 10.1 | 11.11 | 11.70 | 12.40 | 13.10 | |
| | | | 20 | 8.6 | 9.46 | 10.07 | 10.81 | 11.43 | |
| | | HSI, PLL OFF, all peripherals enabled | 16 | 6.3 | 6.77 | 7.42 | 8.21 | 8.68 | |
| | | | 1 | 1.1 | 1.35 | 1.84 | 2.59 | 2.74 | |
| | | External clock, PLL ON(2) all peripherals disabled | 100 | 24.7 | 26.11 | 27.59 | 28.84 | 32.07 | |
| | | | 84 | 21.4 | 22.22 | 23.53 | 24.66 | 27.42 | |
| | | | 64 | 15.8 | 16.80 | 17.90 | 18.99 | 21.12 | |
| | | | 50 | 12.6 | 13.51 | 14.52 | 15.54 | 17.28 | |
| | | | 25 | 7.0 | 7.85 | 8.57 | 9.39 | 10.44 | |
| | | | 20 | 6.0 | 6.67 | 7.37 | 8.26 | 9.19 | |
| | | HSI, PLL OFF, all peripherals disabled | 16 | 4.5 | 4.80 | 5.47 | 6.33 | 7.04 | |
| | | | 1 | 0.9 | 1.25 | 1.81 | 2.58 | 2.87 | |

1. Based on characterization, not tested in production unless otherwise specified.
2. Add an additional power consumption of 1.6 mA per ADC for the analog part. In applications, this consumption occurs only while the ADC is ON (ADON bit is set in the ADC_CR2 register).



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**Table 29. Typical and maximum current consumption in Sleep mode - $V_{DD}$ = 3.6 V**

| Symbol | Parameter | Conditions | $f_{HCLK}$ (MHz) | Typ | Max(1) | | | | Unit |
|---|---|---|---|---|---|---|---|---|---|
| | | | | $T_A$ = 25 °C | $T_A$ = 25 °C | $T_A$ = 85 °C | $T_A$ = 105 °C | $T_A$ = 125 °C | |
| $I_{DD}$ | Supply current in **Sleep mode** | All peripherals enabled(2), External clock, PLL ON, Flash deep power down | 100 | 17.7 | 18.48(3) | 19.83 | 21.70 | 24.00 | mA |
| | | | 84 | 14.3 | 15.39 | 16.31 | 17.48 | 19.34 | |
| | | | 64 | 10.0 | 10.71 | 11.35 | 12.13 | 13.41 | |
| | | | 50 | 7.9 | 8.53 | 9.13 | 9.89 | 10.94 | |
| | | | 25 | 4.4 | 4.99 | 5.46 | 6.11 | 6.75 | |
| | | | 20 | 4.0 | 4.42 | 4.95 | 5.64 | 6.23 | |
| | | All peripherals enabled(2), HSI, PLL OFF, Flash deep power down | 16 | 2.7 | 2.83 | 3.47 | 4.21 | 4.66 | |
| | | | 1 | 0.5 | 0.68 | 1.25 | 1.92 | 2.12 | |
| | | All peripherals enabled(2), External clock, PLL ON Flash ON | 100 | 18.1 | 19.39 | 20.70 | 22.24 | 24.59 | |
| | | | 84 | 14.7 | 15.80 | 16.71 | 17.92 | 19.82 | |
| | | | 64 | 10.3 | 11.02 | 11.66 | 12.45 | 13.77 | |
| | | | 50 | 8.2 | 8.88 | 9.53 | 10.26 | 11.35 | |
| | | | 25 | 4.7 | 5.30 | 5.82 | 6.53 | 7.23 | |
| | | | 20 | 4.2 | 4.67 | 5.18 | 5.90 | 6.53 | |
| | | All peripherals enabled(2), HSI, PLL OFF, Flash ON | 16 | 2.7 | 3.10 | 3.72 | 4.50 | 4.98 | |
| | | | 1 | 0.8 | 0.93 | 1.50 | 2.18 | 2.41 | |
| | | All peripherals disabled, External clock, PLL ON(2), Flash deep power down | 100 | 3.2 | 3.42(3) | 4.98 | 6.88 | 9.70 | |
| | | | 84 | 2.6 | 3.09 | 3.63 | 4.44 | 6.26 | |
| | | | 64 | 2.0 | 2.33 | 2.81 | 3.46 | 4.87 | |
| | | | 50 | 1.7 | 2.02 | 2.54 | 3.12 | 4.39 | |
| | | | 25 | 1.2 | 1.63 | 2.21 | 2.89 | 4.08 | |
| | | | 20 | 1.3 | 1.62 | 2.09 | 2.78 | 3.92 | |
| | | All peripherals disabled, HSI, PLL OFF(2), Flash deep power down | 16 | 0.5 | 0.63 | 1.24 | 1.92 | 2.71 | |
| | | | 1 | 0.4 | 0.53 | 1.14 | 1.82 | 2.57 | |
| | | All peripherals disabled, External clock, PLL ON(2), Flash ON | 100 | 3.6 | 4.17 | 4.84 | 5.63 | 7.93 | |
| | | | 84 | 3.0 | 3.49 | 4.13 | 4.88 | 6.88 | |
| | | | 64 | 2.3 | 2.69 | 3.23 | 3.85 | 5.42 | |
| | | | 50 | 2.0 | 2.33 | 2.83 | 3.45 | 4.86 | |
| | | | 25 | 1.4 | 1.88 | 2.39 | 3.06 | 4.31 | |
| | | | 20 | 1.5 | 1.88 | 2.43 | 3.06 | 4.31 | |
| | | All peripherals disabled, HSI, PLL OFF(2), Flash ON | 16 | 0.8 | 0.91 | 1.50 | 2.22 | 3.13 | |
| | | | 1 | 0.7 | 0.78 | 1.37 | 2.09 | 2.95 | |

1. Based on characterization, not tested in production unless otherwise specified.
2. Add an additional power consumption of 1.6 mA per ADC for the analog part. In applications, this consumption occurs only while the ADC is ON (ADON bit is set in the ADC_CR2 register).
3. Tested in production.



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**Table 30. Typical and maximum current consumption in Sleep mode - $V_{DD}$ = 1.7 V**

| Symbol | Parameter | Conditions | $f_{HCLK}$ (MHz) | Typ | Max(1) | | | | Unit |
|---|---|---|---|---|---|---|---|---|---|
| | | | | $T_A$ = 25 °C | $T_A$ = 25 °C | $T_A$ = 85 °C | $T_A$ = 105 °C | $T_A$ = 125 °C | |
| $I_{DD}$ | Supply current in **Sleep mode** | External clock, PLL ON, Flash deep power down, all peripherals enabled(2) | 100 | 17.3 | 18.62 | 19.90 | 21.40 | 23.67 | mA |
| | | | 84 | 14.0 | 15.08 | 16.04 | 17.16 | 18.97 | |
| | | | 64 | 9.7 | 10.41 | 11.02 | 11.80 | 13.06 | |
| | | | 50 | 7.6 | 8.27 | 8.89 | 9.62 | 10.64 | |
| | | | 25 | 4.2 | 4.79 | 5.35 | 6.00 | 6.63 | |
| | | | 20 | 3.7 | 4.11 | 4.67 | 5.31 | 5.88 | |
| | | HSI, PLL OFF(2), Flash deep power down, all peripherals enabled | 16 | 2.4 | 2.81 | 3.45 | 4.20 | 4.64 | |
| | | | 1 | 0.5 | 0.67 | 1.27 | 1.91 | 2.11 | |
| | | External clock, PLL ON(2) all peripherals enabled, Flash ON | 100 | 17.8 | 19.08 | 20.35 | 21.90 | 24.22 | |
| | | | 84 | 14.4 | 15.49 | 16.42 | 17.59 | 19.46 | |
| | | | 64 | 10.0 | 10.76 | 11.43 | 12.18 | 13.47 | |
| | | | 50 | 7.9 | 8.58 | 9.19 | 9.94 | 10.99 | |
| | | | 25 | 4.4 | 4.99 | 5.54 | 6.21 | 6.87 | |
| | | | 20 | 4.0 | 4.42 | 4.95 | 5.64 | 6.23 | |
| | | HSI, PLL OFF(2), all peripherals enabled, Flash ON | 16 | 2.7 | 3.09 | 3.75 | 4.49 | 4.97 | |
| | | | 1 | 0.8 | 0.93 | 1.52 | 2.18 | 2.41 | |
| $I_{DD}$ | Supply current in **Sleep mode** | All peripherals disabled, External clock, PLL ON(2), Flash deep power down | 100 | 2.9 | 3.51 | 4.14 | 4.90 | 5.59 | mA |
| | | | 84 | 2.4 | 2.83 | 3.46 | 4.16 | 4.74 | |
| | | | 64 | 1.7 | 2.08 | 2.59 | 3.18 | 3.63 | |
| | | | 50 | 1.4 | 1.77 | 2.23 | 2.84 | 3.24 | |
| | | | 25 | 1.0 | 1.37 | 1.88 | 2.50 | 2.85 | |
| | | | 20 | 1.3 | 1.37 | 1.88 | 2.50 | 2.85 | |
| | | All peripherals disabled, HSI, PLL OFF(2), Flash deep power down | 16 | 0.5 | 0.63 | 1.23 | 1.91 | 2.18 | |
| | | | 1 | 0.4 | 0.52 | 1.13 | 1.81 | 2.07 | |
| | | All peripherals disabled, External clock, PLL ON(2), Flash ON | 100 | 3.3 | 3.22 | 3.98 | 4.90 | 5.59 | |
| | | | 84 | 2.8 | 2.62 | 3.30 | 4.16 | 4.74 | |
| | | | 64 | 2.1 | 1.89 | 2.50 | 3.18 | 3.63 | |
| | | | 50 | 1.7 | 1.58 | 2.16 | 2.84 | 3.24 | |
| | | | 25 | 1.2 | 1.28 | 1.82 | 2.50 | 2.85 | |
| | | | 20 | 1.3 | 1.28 | 1.82 | 2.50 | 2.85 | |
| | | All peripherals disabled, HSI, PLL OFF(2), Flash ON | 16 | 0.8 | 0.88 | 1.36 | 1.91 | 2.18 | |
| | | | 1 | 0.7 | 0.77 | 1.26 | 1.81 | 2.07 | |

1. Based on characterization, not tested in production unless otherwise specified.
2. Add an additional power consumption of 1.6 mA per ADC for the analog part. In applications, this consumption occurs only while the ADC is ON (ADON bit is set in the ADC_CR2 register).



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**Table 31. Typical and maximum current consumptions in Stop mode - $V_{DD}$ = 1.7 V**

| Symbol | Conditions | Parameter | Typ(1) | Max(1) | | | | Unit |
|---|---|---|---|---|---|---|---|---|
| | | | $T_A$ = 25 °C | $T_A$ = 25 °C | $T_A$ = 85 °C | $T_A$ = 105 °C | $T_A$ = 125 °C | |
| $I_{DD_STOP}$ | Flash in Stop mode, all oscillators OFF, no independent watchdog | Main regulator usage | 121.1 | 168.0 | 648.7 | 1213.0 | 2970.0 | µA |
| | | Low power regulator usage | 50.8 | 74.8 | 651.3 | 1328.0 | 2730.0 | |
| | Flash in Deep power down mode, all oscillators OFF, no independent watchdog | Main regulator usage | 79.1 | 122.0 | 609.1 | 1181.0 | 2540.0 | |
| | | Low power regulator usage | 22.4 | 74.7 | 631.9 | 1286.0 | 2680.0 | |
| | | Low power low voltage regulator usage | 18.5 | 40.0 | 548.3 | 1145.0 | 2480.0 | |

1. Based on characterization, not tested in production.

**Table 32. Typical and maximum current consumption in Stop mode - $V_{DD}$=3.6 V**

| Symbol | Conditions | Parameter | Typ | Max(1) | | | | Unit |
|---|---|---|---|---|---|---|---|---|
| | | | $T_A$ = 25 °C | $T_A$ = 25 °C | $T_A$ = 85 °C | $T_A$ = 105 °C | $T_A$ = 125 °C | |
| $I_{DD_STOP}$ | Flash in Stop mode, all oscillators OFF, no independent watchdog | Main regulator usage | 124.0 | 179.0(2) | 907.2 | 1762.0 | 3000.0(2) | µA |
| | | Low power regulator usage | 52.8 | 75.0(2) | 757.6 | 1559.0 | 2750.0 | |
| | Flash in Deep power down mode, all oscillators OFF, no independent watchdog | Main regulator usage | 87.6 | 123.0 | 698.5 | 1374.0 | 2550.0 | |
| | | Low power regulator usage | 26.2 | 74.7 | 737.2 | 1515.0 | 2700.0 | |
| | | Low power low voltage regulator usage | 20.1 | 40.0(2) | 619.1 | 1299.0 | 2500.0(2) | |

1. Based on characterization, not tested in production.
2. Tested in production.

**Table 33. Typical and maximum current consumption in Standby mode - $V_{DD}$= 1.7 V**

| Symbol | Parameter | Conditions | Typ(1) | Max(2) | | | | Unit |
|---|---|---|---|---|---|---|---|---|
| | | | $T_A$ = 25 °C | $T_A$ = 25 °C | $T_A$ = 85 °C | $T_A$ = 105 °C | $T_A$ = 125 °C | |
| $I_{DD_STBY}$ | Supply current in Standby mode | Low-speed oscillator (LSE in low drive mode) and RTC ON | 1.8 | 3.7 | 12.9 | 23.7 | 50.7 | µA |
| | | Low-speed oscillator (LSE in high drive mode) and RTC ON | 2.6 | 4.5 | 13.7 | 24.5 | 51.6 | |
| | | RTC and LSE OFF | 1.1 | 3.0 | 12.2 | 23 | 50.0 | |

1. When the PDR is OFF (internal reset is OFF), the typical current consumption is reduced by 1.2 µA.
2. Based on characterization, not tested in production unless otherwise specified.



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**Table 34. Typical and maximum current consumption in Standby mode - $V_{DD}$= 3.6 V**

| Symbol | Parameter | Conditions | Typ(1) | Max(2) | | | | Unit |
|---|---|---|---|---|---|---|---|---|
| | | | $T_A$ = 25 °C | $T_A$ = 25 °C | $T_A$ = 85 °C | $T_A$ = 105 °C | $T_A$ = 125 °C | |
| $I_{DD_STBY}$ | Supply current in Standby mode | Low-speed oscillator (LSE in low drive mode) and RTC ON | 3.7 | 5.4 | 17.2 | 31.2 | 62.3 | µA |
| | | Low-speed oscillator (LSE in high drive mode) and RTC ON | 4.5 | 6.2 | 18.0 | 32.0 | 63.2 | |
| | | RTC and LSE OFF | 2.6 | 4.0 | 16.0 | 30.0 | 61.0(3) | |

1. When the PDR is OFF (internal reset is OFF), the typical current consumption is reduced by 1.2 µA.
2. Guaranteed by characterization, not tested in production unless otherwise specified.
3. Tested in production.

**Table 35. Typical and maximum current consumptions in $V_{BAT}$ mode**

| Symbol | Parameter | Conditions(1) | Typ | | | | Max(2) | | | Unit |
|---|---|---|---|---|---|---|---|---|---|---|
| | | | $T_A$ = 25 °C | | | | $T_A$ = 85 °C | $T_A$ = 105 °C | $T_A$ = 125 °C | |
| | | | $V_{BAT}$ = 1.7 V | $V_{BAT}$= 2.4 V | $V_{BAT}$ = 3.3 V | $V_{BAT}$ = 3.6 V | $V_{BAT}$ = 3.6 V | | | |
| $I_{DD_VBAT}$ | Backup domain supply current | Low-speed oscillator (LSE in low-drive mode) and RTC ON | 0.74 | 0.87 | 1.04 | 1.11 | 3.0 | 5.0 | 10.0 | µA |
| | | Low-speed oscillator (LSE in high-drive mode) and RTC ON | 1.52 | 1.70 | 1.97 | 2.09 | 3.8 | 5.8 | 11.6 | |
| | | RTC and LSE OFF | 0.04 | 0.04 | 0.05 | 0.05 | 2.0 | 4.0 | 8.0 | |

1. Crystal used: Abracon ABS07-120-32.768 kHz-T with a $C_L$ of 6 pF for typical values.
2. Guaranteed by characterization, not tested in production.



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**Figure 24. Typical $V_{BAT}$ current consumption (LSE and RTC ON/LSE oscillator "low power" mode selection)**

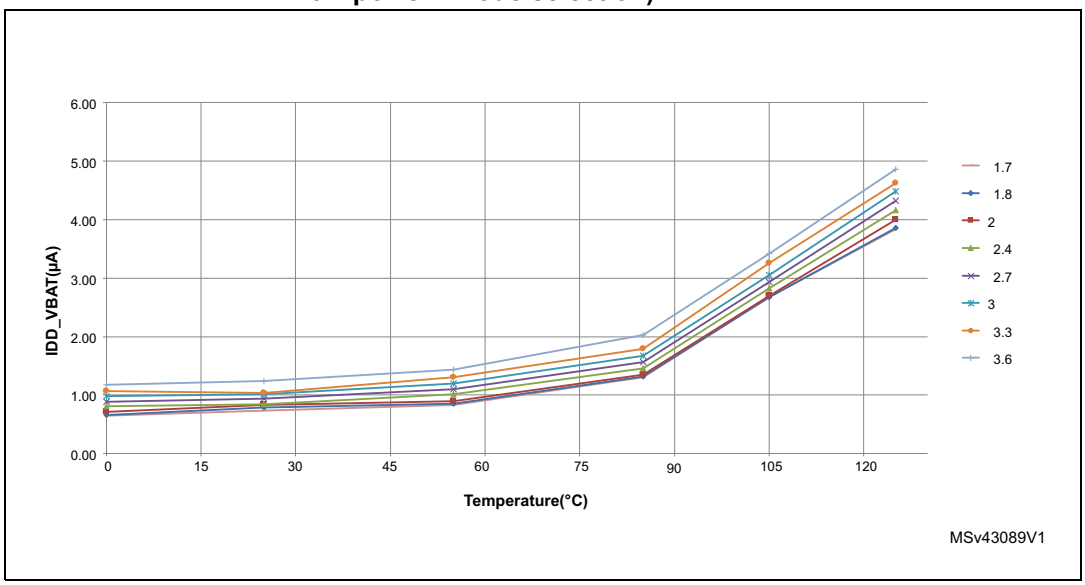
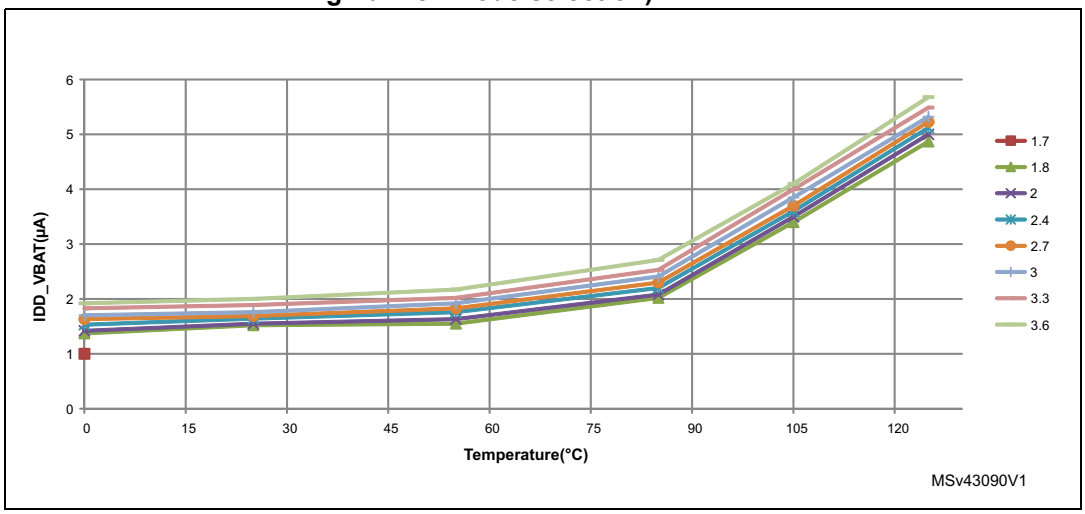



**Figure 25. Typical $V_{BAT}$ current consumption (LSE and RTC ON/LSE oscillator "high drive" mode selection)**






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### I/O system current consumption

The current consumption of the I/O system has two components: static and dynamic.

**I/O static current consumption**

All the I/Os used as inputs with pull-up generate current consumption when the pin is externally held low. The value of this current consumption can be simply computed by using the pull-up/pull-down resistors values given in *Table 57: I/O static characteristics*.

For the output pins, any external pull-down or external load must also be considered to estimate the current consumption.

Additional I/O current consumption is due to I/Os configured as inputs if an intermediate voltage level is externally applied. This current consumption is caused by the input Schmitt trigger circuits used to discriminate the input value. Unless this specific configuration is required by the application, this supply current consumption can be avoided by configuring these I/Os in analog mode. This is notably the case of ADC input pins which should be configured as analog inputs.

**Caution:** Any floating input pin can also settle to an intermediate voltage level or switch inadvertently, as a result of external electromagnetic noise. To avoid current consumption related to floating pins, they must either be configured in analog mode, or forced internally to a definite digital value. This can be done either by using pull-up/down resistors or by configuring the pins in output mode.

**I/O dynamic current consumption**

In addition to the internal peripheral current consumption (see *Table 37: Peripheral current consumption*), the I/Os used by an application also contribute to the current consumption. When an I/O pin switches, it uses the current from the MCU supply voltage to supply the I/O pin circuitry and to charge/discharge the capacitive load (internal or external) connected to the pin:

$$I_{SW} = V_{DD} \times f_{SW} \times C$$

where

$I_{SW}$ is the current sunk by a switching I/O to charge/discharge the capacitive load

$V_{DD}$ is the MCU supply voltage

$f_{SW}$ is the I/O switching frequency

C is the total capacitance seen by the I/O pin: $C = C_{INT} + C_{EXT}$

The test pin is configured in push-pull output mode and is toggled by software at a fixed frequency.



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**Table 36. Switching output I/O current consumption**

| Symbol | Parameter | Conditions[1] | I/O toggling frequency ($f_{SW}$) | Typ | Unit |
|---|---|---|---|---|---|
| IDDIO | I/O switching current | $V_{DD}$ = 3.3 V<br>C = $C_{INT}$ | 2 MHz | 0.05 | mA |
| | | | 8 MHz | 0.15 | |
| | | | 25 MHz | 0.45 | |
| | | | 50 MHz | 0.85 | |
| | | | 60 MHz | 1.00 | |
| | | | 84 MHz | 1.40 | |
| | | | 90 MHz | 1.67 | |
| | | $V_{DD}$ = 3.3 V<br>$C_{EXT}$ = 0 pF<br>C = $C_{INT}$ + $C_{EXT}$ + $C_S$ | 2 MHz | 0.10 | |
| | | | 8 MHz | 0.35 | |
| | | | 25 MHz | 1.05 | |
| | | | 50 MHz | 2.20 | |
| | | | 60 MHz | 2.40 | |
| | | | 84 MHz | 3.55 | |
| | | | 90 MHz | 4.23 | |
| | | $V_{DD}$ = 3.3 V<br>$C_{EXT}$ =10 pF<br>C = $C_{INT}$ + $C_{EXT}$ + $C_S$ | 2 MHz | 0.20 | |
| | | | 8 MHz | 0.65 | |
| | | | 25 MHz | 1.85 | |
| | | | 50 MHz | 2.45 | |
| | | | 60 MHz | 4.70 | |
| | | | 84 MHz | 8.80 | |
| | | | 90 MHz | 10.47 | |
| | | $V_{DD}$ = 3.3 V<br>$C_{EXT}$ = 22 pF<br>C = $C_{INT}$ + $C_{EXT}$ + $C_S$ | 2 MHz | 0.25 | |
| | | | 8 MHz | 1.00 | |
| | | | 25 MHz | 3.45 | |
| | | | 50 MHz | 7.15 | |
| | | | 60 MHz | 11.55 | |
| | | $V_{DD}$ = 3.3 V<br>$C_{EXT}$ = 33 pF<br>C = $C_{INT}$ + $C_{EXT}$ + $C_S$ | 2 MHz | 0.32 | |
| | | | 8 MHz | 1.27 | |
| | | | 25 MHz | 3.88 | |
| | | | 50 MHz | 12.34 | |

1. CS is the PCB board capacitance including the pad pin. CS = 7 pF (estimated value).



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### On-chip peripheral current consumption

The MCU is placed under the following conditions:

- At startup, all I/O pins are in analog input configuration.
- All peripherals are disabled unless otherwise mentioned.
- The ART accelerator is ON.
- Voltage Scale 2 mode selected, internal digital voltage V12 = 1.26 V.
- HCLK is the system clock at 100 MHz. $f_{PCLK1} = f_{HCLK}/2$, and $f_{PCLK2} = f_{HCLK}$.
  The given value is calculated by measuring the difference of current consumption
  - with all peripherals clocked off,
  - with only one peripheral clocked on,
  - scale 1 with $f_{HCLK}$ = 100 MHz,
  - scale 2 with $f_{HCLK}$ = 84 MHz,
  - scale 3 with $f_{HCLK}$ = 64 MHz.
- Ambient operating temperature is 25 °C and $V_{DD}$=3.3 V.

**Table 37. Peripheral current consumption**

| Peripheral | | $I_{DD}$ (Typ) | | | Unit |
|---|---|---|---|---|---|
| | | Scale 1 | Scale 2 | Scale 3 | |
| AHB1 | GPIOA | 1.84 | 1.75 | 1.55 | µA/MHz |
| | GPIOB | 1.90 | 1.80 | 1.61 | |
| | GPIOC | 1.77 | 1.67 | 1.50 | |
| | GPIOD | 1.67 | 1.58 | 1.42 | |
| | GPIOE | 1.75 | 1.67 | 1.48 | |
| | GPIOF | 1.65 | 1.56 | 1.39 | |
| | GPIOG | 1.65 | 1.56 | 1.39 | |
| | GPIOH | 0.62 | 0.57 | 0.53 | |
| | CRC | 0.26 | 0.25 | 0.22 | |
| | DMA1(1) | 1,71N+2,98 | 1,62N+2,87 | 1,45N+2,58 | |
| | DMA2(1) | 1,78N+2,62 | 1,70N+2.53 | 1,52N+2.26 | |
| AHB2 | RNG | 0.77 | 0.74 | 0.66 | |
| | USB_OTG_FS | 19.68 | 18.73 | 16.78 | |
| AHB3 | FSMC | 5.36 | 5.11 | 4.56 | |
| | QSPI | 9.99 | 9.51 | 8.53 | |



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**Table 37. Peripheral current consumption (continued)**

| Peripheral | | $I_{DD}$ (Typ) | | | Unit |
|---|---|---|---|---|---|
| | | Scale 1 | Scale 2 | Scale 3 | |
| APB1 | AHB-APB1 bridge | 1.10 | 1.00 | 0.94 | µA/MHz |
| | TIM2 | 13.62 | 12.95 | 11.59 | |
| | TIM3 | 10.56 | 10.05 | 8.97 | |
| | TIM4 | 10.72 | 10.21 | 9.12 | |
| | TIM5 | 13.46 | 12.83 | 11.47 | |
| | TIM6 | 2.92 | 2.79 | 2.47 | |
| | TIM7 | 2.72 | 2.60 | 2.31 | |
| | TIM12 | 6.22 | 5.93 | 5.28 | |
| | TIM13 | 4.70 | 4.48 | 3.97 | |
| | TIM14 | 4.60 | 4.38 | 3.91 | |
| | WWDG | 1.76 | 1.67 | 1.47 | |
| | SPI2/I2S2 | 4.04 | 3.83 | 3.41 | |
| | SPI3/I2S3 | 4.26 | 4.05 | 3.62 | |
| | USART2 | 4.42 | 4.19 | 3.75 | |
| | USART3 | 4.44 | 4.21 | 3.75 | |
| | I2C1 | 4.32 | 4.10 | 3.66 | |
| | I2C2 | 4.36 | 4.17 | 3.69 | |
| | I2C3 | 4.36 | 4.14 | 3.69 | |
| | I2CFMP1 | 5.96 | 5.69 | 5.06 | |
| | CAN1 | 6.18 | 5.90 | 5.25 | |
| | CAN2 | 5.86 | 5.52 | 4.97 | |
| | PWR | 1.82 | 1.69 | 1.56 | |



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**Table 37. Peripheral current consumption (continued)**

| Peripheral | | $I_{DD}$ (Typ) | | | Unit |
|---|---|---|---|---|---|
| | | Scale 1 | Scale 2 | Scale 3 | |
| APB2 | AHB-APB2 bridge | 0.09 | 0.07 | 0.08 | µA/MHz |
| | TIM1 | 6.83 | 6.46 | 5.81 | |
| | TIM8 | 6.63 | 6.29 | 5.63 | |
| | USART1 | 3.31 | 3.11 | 2.80 | |
| | USART6 | 3.21 | 3.02 | 2.73 | |
| | ADC1 | 3.51 | 3.31 | 2.98 | |
| | SDIO | 3.74 | 3.51 | 3.17 | |
| | SPI1 | 1.47 | 1.36 | 1.23 | |
| | SPI4 | 1.56 | 1.45 | 1.31 | |
| | SYSCFG | 0.54 | 0.49 | 0.45 | |
| | TIM9 | 3.09 | 2.92 | 2.63 | |
| | TIM10 | 1.91 | 1.79 | 1.61 | |
| | TIM11 | 1.93 | 1.81 | 1.64 | |
| | SPI5 | 1.54 | 1.44 | 1.30 | |
| | DFSDM1 | 4.25 | 4.02 | 3.61 | |
| Bus Matrix | | 3.23 | 3.06 | 2.73 | |

1. N is the number of stream enable (1...8).



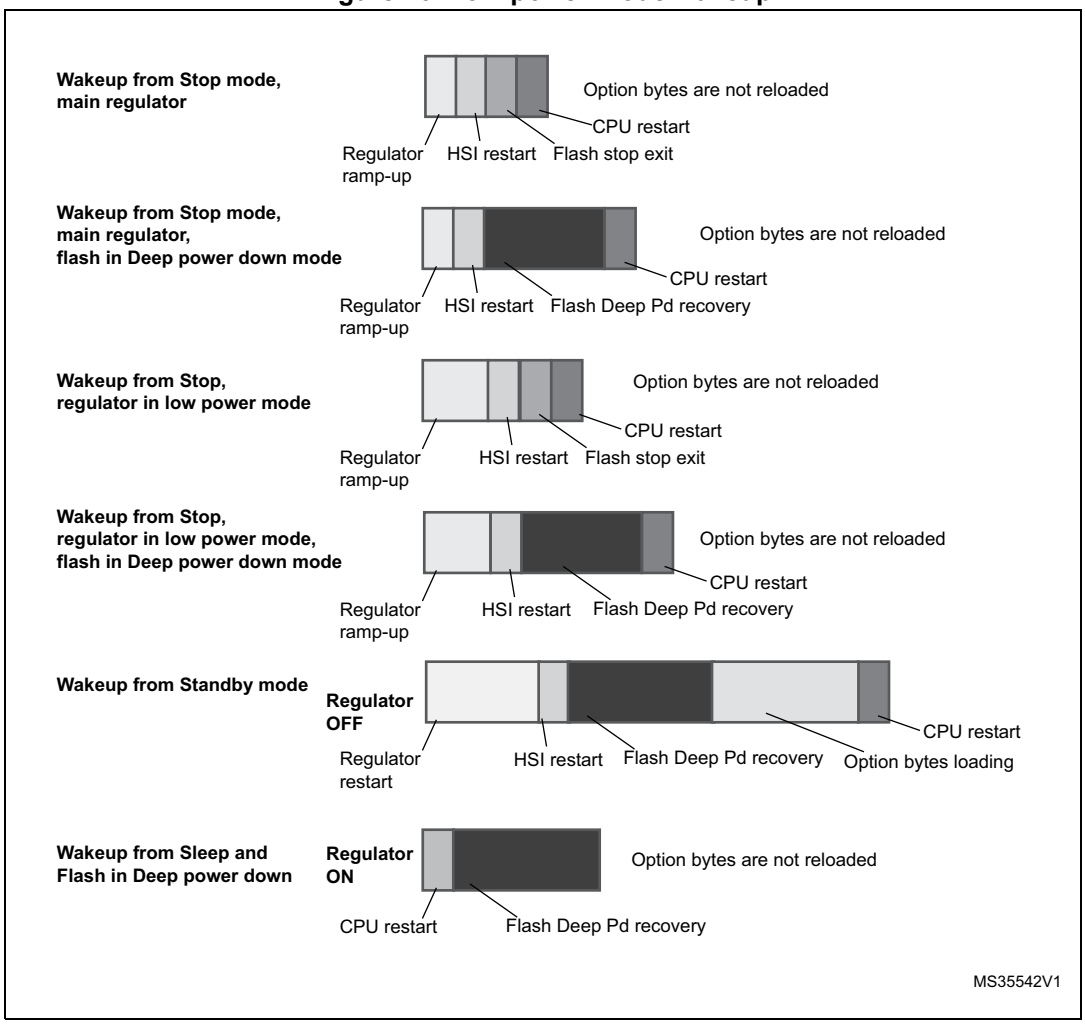
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### 6.3.7 Wakeup time from low-power modes

The wakeup times given in *Table 38* are measured starting from the wakeup event trigger up to the first instruction executed by the CPU:

- For Stop or Sleep modes: the wakeup event is WFE.
- WKUP (PA0/PC0/PC1) pins are used to wakeup from Standby, Stop and Sleep modes.

**Figure 26. Low-power mode wakeup**




All timings are derived from tests performed under ambient temperature and $V_{DD}$=3.3 V.



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**Table 38. Low-power mode wakeup timings(1)**

| Symbol | Parameter | Conditions | Min(1) | Typ(1) | Max(1) | Unit |
|---|---|---|---|---|---|---|
| $t_{WUSLEEP}$ | Wakeup from Sleep mode | - | - | 4 | 6 | clk cycles |
| $t_{WUSLEEPFDSM}$ | | Flash memory in Deep power down mode | - | - | 50.0 | µs |
| $t_{WUSTOP}$ | Wakeup from STOP mode Code execution on Flash | Main regulator | - | 12.9 | 15.0 | µs |
| | | Main regulator, Flash memory in Deep power down mode | - | 104.9 | 120.0 | |
| | | Wakeup from Stop mode, regulator in low power mode(2) | - | 20.8 | 28.0 | |
| | | Regulator in low power mode, Flash memory in Deep power down mode(2) | - | 112.9 | 130.0 | |
| $t_{WUSTOP}$ | Wakeup from STOP mode code execution on RAM(3) | Main regulator with Flash in Stop mode or Deep power down | - | 4.9 | 7.0 | |
| | | Wakeup from Stop mode, regulator in low power mode and Flash in Stop mode or Deep power down(2) | - | 12.8 | 20.0 | |
| $t_{WUSTDBY}$ | Wakeup from Standby mode | - | - | 316.8 | 400.0 | |
| $t_{WUFLASH}$ | Wakeup of Flash | From Flash_Stop mode | - | | 11.0 | |
| | | From Flash Deep power down mode | - | | 50.0 | |

1. Guaranteed by characterization, not tested in production.
2. The specification is valid for wakeup from regulator in low power mode or low power low voltage mode, since the timing difference is negligible.
3. For the faster wakeup time for code execution on RAM, the Flash must be in STOP or DeepPower Down mode (see reference manual RM0402).



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## 6.3.8 External clock source characteristics

### High-speed external user clock generated from an external source

In bypass mode the HSE oscillator is switched off and the input pin is a standard I/O. The external clock signal has to respect the *Table 57*. However, the recommended clock input waveform is shown in *Figure 27*.

The characteristics given in *Table 39* result from tests performed using an high-speed external clock source, and under ambient temperature and supply voltage conditions summarized in *Table 16*.

**Table 39. High-speed external user clock characteristics**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $f_{HSE_ext}$ | External user clock source frequency(1) | | 1 | - | 50 | MHz |
| $V_{HSEH}$ | OSC_IN input pin high level voltage | | $0.7V_{DD}$ | - | $V_{DD}$ | V |
| $V_{HSEL}$ | OSC_IN input pin low level voltage | | $V_{SS}$ | - | $0.3V_{DD}$ | |
| $t_{w(HSE)}$ $t_{w(HSE)}$ | OSC_IN high or low time(1) | | 5 | - | - | ns |
| $t_{r(HSE)}$ $t_{f(HSE)}$ | OSC_IN rise or fall time(1) | | - | - | 10 | |
| $C_{in(HSE)}$ | OSC_IN input capacitance(1) | | - | 5 | - | pF |
| $DuCy_{(HSE)}$ | Duty cycle | | 45 | - | 55 | % |
| $I_L$ | OSC_IN Input leakage current | $V_{SS} \leq V_{IN} \leq V_{DD}$ | - | - | ±1 | µA |

1. Guaranteed by design, not tested in production.



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### Low-speed external user clock generated from an external source

In bypass mode the LSE oscillator is switched off and the input pin is a standard I/O. The external clock signal has to respect the *Table 57*. However, the recommended clock input waveform is shown in *Figure 28*.

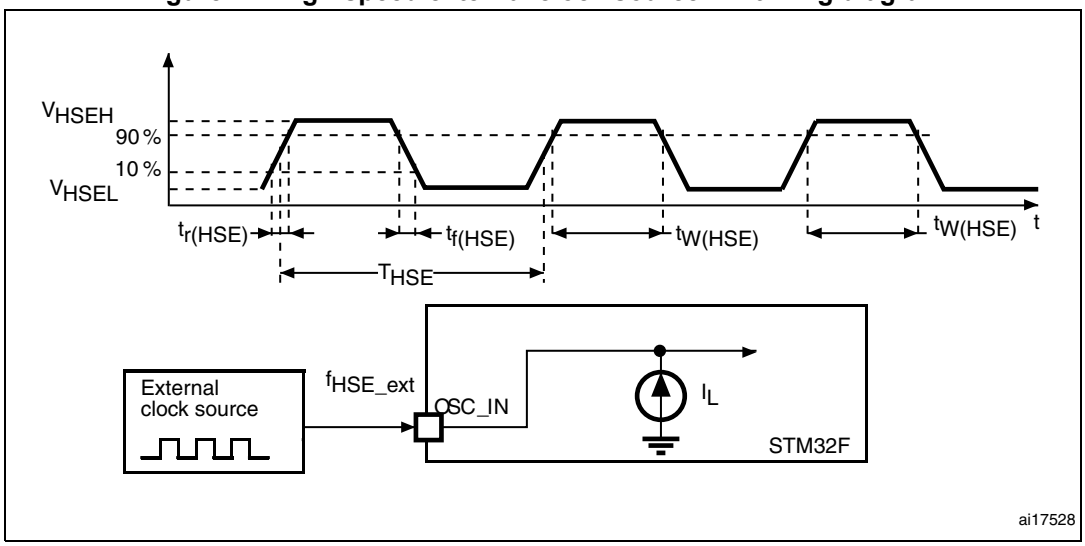
The characteristics given in *Table 40* result from tests performed using an low-speed external clock source, and under ambient temperature and supply voltage conditions summarized in *Table 16*.

**Table 40. Low-speed external user clock characteristics**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $f_{LSE_ext}$ | User External clock source frequency(1) | | - | 32.768 | 1000 | kHz |
| $V_{LSEH}$ | OSC32_IN input pin high level voltage | | $0.7V_{DD}$ | - | $V_{DD}$ | V |
| $V_{LSEL}$ | OSC32_IN input pin low level voltage | | $V_{SS}$ | - | $0.3V_{DD}$ | |
| $t_{w(LSE)}$ $t_{f(LSE)}$ | OSC32_IN high or low time(1) | | 450 | - | - | ns |
| $t_{r(LSE)}$ $t_{f(LSE)}$ | OSC32_IN rise or fall time(1) | | - | - | 50 | |
| $C_{in(LSE)}$ | OSC32_IN input capacitance(1) | | - | 5 | - | pF |
| $DuCy_{(LSE)}$ | Duty cycle | | 30 | - | 70 | % |
| $I_L$ | OSC32_IN Input leakage current | $V_{SS} \le V_{IN} \le V_{DD}$ | - | - | ±1 | µA |

1. Guaranteed by design, not tested in production.

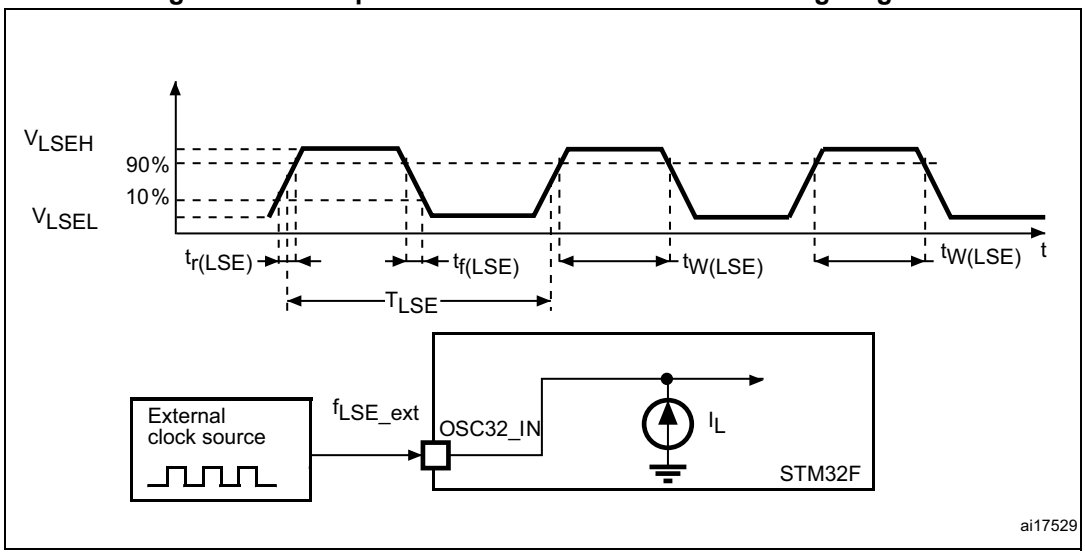
**Figure 27. High-speed external clock source AC timing diagram**






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**Figure 28. Low-speed external clock source AC timing diagram**




## High-speed external clock generated from a crystal/ceramic resonator

The high-speed external (HSE) clock can be supplied with a 4 to 26 MHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on characterization results obtained with typical external components specified in *Table 41*. In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

**Table 41. HSE 4-26 MHz oscillator characteristics(1)**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $f_{OSC_IN}$ | Oscillator frequency | | 4 | - | 26 | MHz |
| $R_F$ | Feedback resistor | | - | 200 | - | kΩ |
| $I_{DD}$ | HSE current consumption | $V_{DD}$=3.3 V, ESR= 30 Ω, $C_L$=5 pF @25 MHz | - | 450 | - | µA |
| | | $V_{DD}$=3.3 V, ESR= 30 Ω, $C_L$=10 pF @25 MHz | - | 530 | - | |
| $ACC_{HSE}$(2) | HSE accuracy | - | -500 | - | 500 | ppm |
| $G_{m_crit_max}$ | Maximum critical crystal $g_m$ | Startup | - | - | 1 | mA/V |
| $t_{SU(HSE)}$(3) | Startup time | $V_{DD}$ is stabilized | - | 2 | - | ms |

1. Guaranteed by design, not tested in production.
2. This parameter depends on the crystal used in the application. The minimum and maximum values must be respected to comply with USB standard specifications.
3. $t_{SU(HSE)}$ is the startup time measured from the moment it is enabled (by software) to a stabilized 8 MHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer

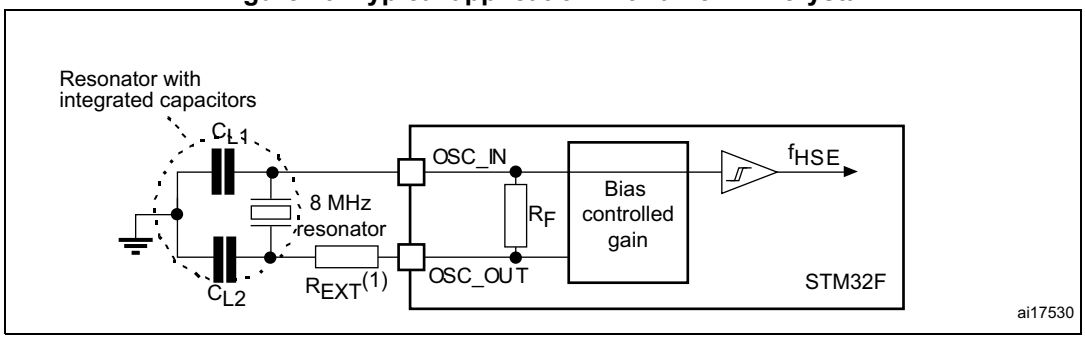


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For $C_{L1}$ and $C_{L2}$, it is recommended to use high-quality external ceramic capacitors in the 5 pF to 25 pF range (Typ.), designed for high-frequency applications, and selected to match the requirements of the crystal or resonator (see *Figure 29*). $C_{L1}$ and $C_{L2}$ are usually the same size. The crystal manufacturer typically specifies a load capacitance which is the series combination of $C_{L1}$ and $C_{L2}$. PCB and MCU pin capacitance must be included (10 pF can be used as a rough estimate of the combined pin and board capacitance) when sizing $C_{L1}$ and $C_{L2}$.

*Note: For information on selecting the crystal, refer to the application note AN2867 "Oscillator design guide for ST microcontrollers" available from the ST website www.st.com.*

**Figure 29. Typical application with an 8 MHz crystal**




1. $R_{EXT}$ value depends on the crystal characteristics.

### Low-speed external clock generated from a crystal/ceramic resonator

The low-speed external (LSE) clock can be supplied with a 32.768 kHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on characterization results obtained with typical external components specified in *Table 42*. In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

The LSE high-power mode allows to cover a wider range of possible crystals but with a cost of higher power consumption.

**Table 42. LSE oscillator characteristics ($f_{LSE}$ = 32.768 kHz) (1)**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $R_F$ | Feedback resistor | - | - | 18.4 | - | MΩ |
| $I_{DD}$ | LSE current consumption | Low-power mode (default) | - | - | 1 | µA |
| | | High-drive mode | - | - | 3 | |
| $ACC_{LSE}$ (2) | LSE accuracy | - | -500 | - | 500 | ppm |
| $G_m$_crit_max | Maximum critical crystal $g_m$ | Startup, low-power mode | - | - | 0.56 | µA/V |
| | | Startup, high-drive mode | - | - | 1.50 | |
| $t_{SU(LSE)}$ (3) | startup time | $V_{DD}$ is stabilized | - | 2 | - | s |

1. Guaranteed by design, not tested in production.



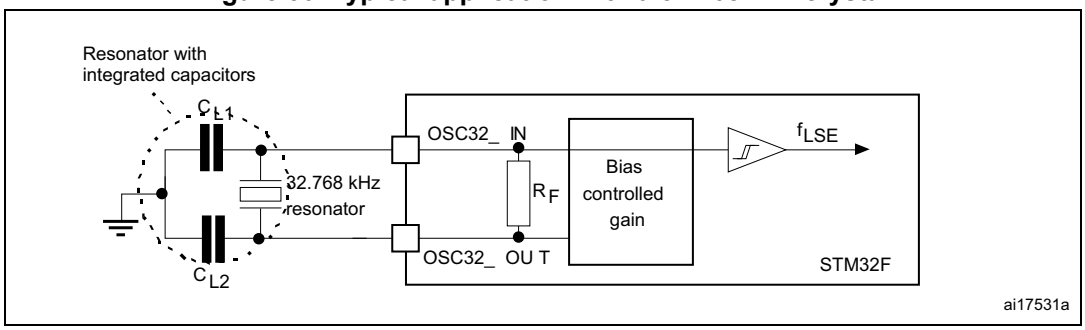
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2. This parameter depends on the crystal used in the application. Refer to the application note AN2867.
3. $t_{SU(LSE)}$ is the startup time measured from the moment it is enabled (by software) to a stabilized 32.768 kHz oscillation is reached. This value is guaranteed by characterization and not tested in production. It is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer.

*Note: For information on selecting the crystal, refer to the application note AN2867 "Oscillator design guide for ST microcontrollers" available from the ST website www.st.com.*

*For information about the LSE high-power mode, refer to the reference manual RM0383.*

**Figure 30. Typical application with a 32.768 kHz crystal**




## 6.3.9 Internal clock source characteristics

The parameters given in *Table 43* and *Table 44* are derived from tests performed under ambient temperature and $V_{DD}$ supply voltage conditions summarized in *Table 16*.

### High-speed internal (HSI) RC oscillator

**Table 43. HSI oscillator characteristics (1)**

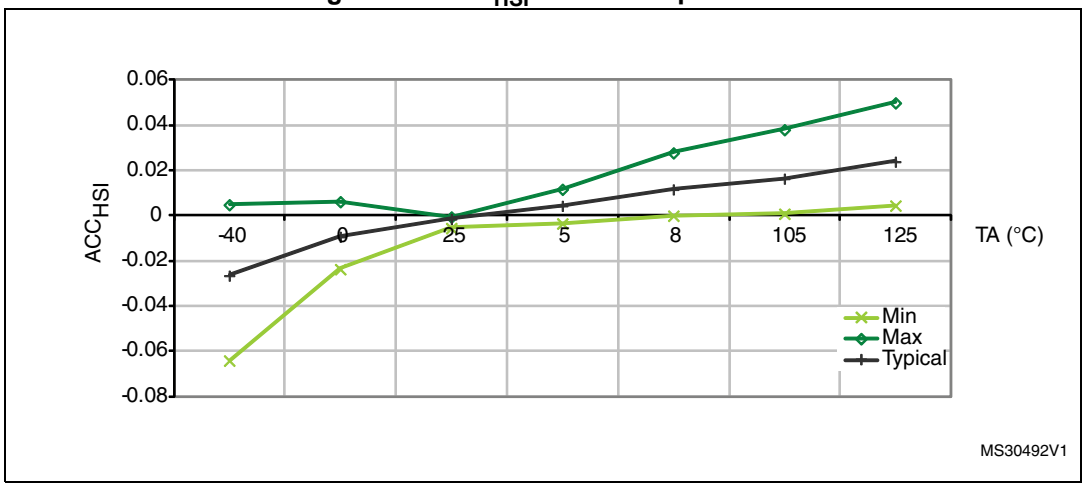
| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|---|
| $f_{HSI}$ | Frequency | - | | - | 16 | - | MHz |
| $ACC_{HSI}$ | Accuracy of the HSI oscillator | HSI user trimming step(2) | | - | - | 1 | % |
| | | Factory-calibrated | $T_A$ = -40 to 125 °C(3) | -8 | - | 5.5 | % |
| | | | $T_A$ = -40 to 105 °C(3) | -8 | - | 4.5 | % |
| | | | $T_A$ = -10 to 85 °C(3) | -4 | - | 4 | % |
| | | | $T_A$ = 25 °C(4) | -1 | - | 1 | % |
| $t_{su(HSI)}$(2) | HSI oscillator startup time | | - | - | 2.2 | 4 | µs |
| $I_{DD(HSI)}$(2) | HSI oscillator power consumption | | - | - | 60 | 80 | µA |

1. $V_{DD}$ = 3.3 V, $T_A$ = -40 to 125 °C unless otherwise specified.
2. Guaranteed by design, not tested in production
3. Based on characterization, not tested in production
4. Factory calibrated, parts not soldered.



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**Figure 31. $ACC_{HSI}$ versus temperature**




1. Guaranteed by characterization, not tested in production.

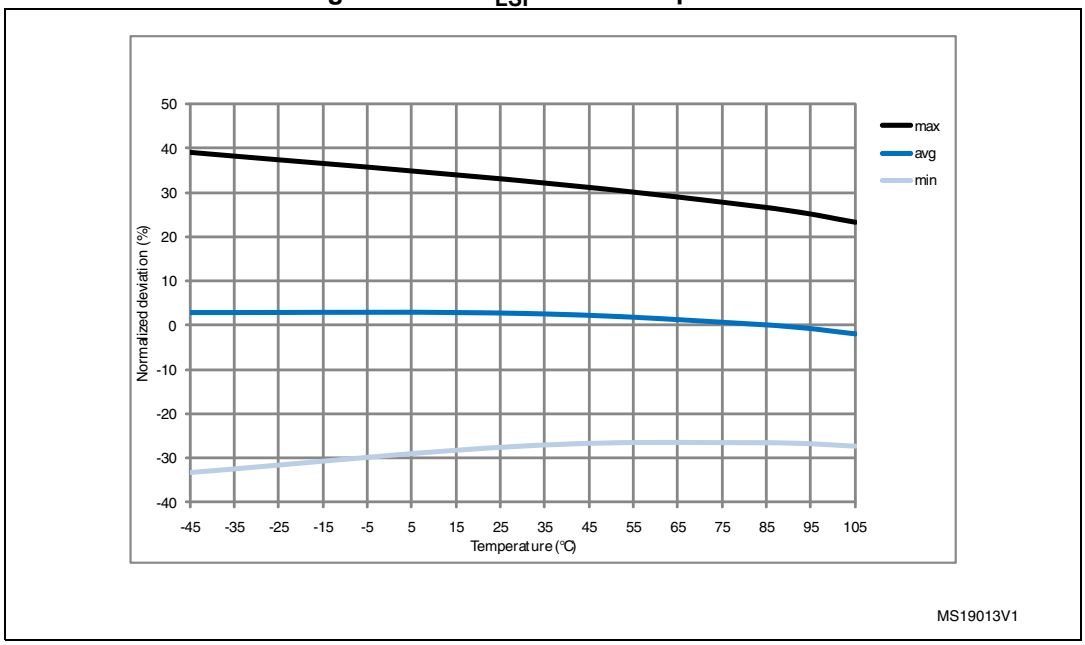
## Low-speed internal (LSI) RC oscillator

**Table 44. LSI oscillator characteristics (1)**

| Symbol | Parameter | Min | Typ | Max | Unit |
|---|---|---|---|---|---|
| $f_{LSI}$(2) | Frequency | 17 | 32 | 47 | kHz |
| $t_{su(LSI)}$(3) | LSI oscillator startup time | - | 15 | 40 | µs |
| $I_{DD(LSI)}$(3) | LSI oscillator power consumption | - | 0.4 | 0.6 | µA |

1. $V_{DD}$ = 3 V, $T_A$ = -40 to 125 °C unless otherwise specified.
2. Guaranteed by characterization, not tested in production.
3. Guaranteed by design, not tested in production.

**Figure 32. $ACC_{LSI}$ versus temperature**






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### 6.3.10 PLL characteristics

The parameters given in *Table 45* and *Table 46* are derived from tests performed under temperature and $V_{DD}$ supply voltage conditions summarized in *Table 16*.

**Table 45. Main PLL characteristics**

| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|---|
| $f_{PLL_IN}$ | PLL input clock(1) | - | | 0.95(2) | 1 | 2.10 | MHz |
| $f_{PLL_OUT}$ | PLL multiplier output clock | - | | 24 | - | 100 | MHz |
| $f_{PLL48_OUT}$ | 48 MHz PLL multiplier output clock | - | | - | 48 | 75 | MHz |
| $f_{VCO_OUT}$ | PLL VCO output | - | | 100 | - | 432 | MHz |
| $t_{LOCK}$ | PLL lock time | VCO freq = 100 MHz | | 75 | - | 200 | µs |
| | | VCO freq = 432 MHz | | 100 | - | 300 | |
| Jitter(3) | Cycle-to-cycle jitter | System clock 100 MHz | RMS | - | 25 | - | ps |
| | | | peak to peak | - | ±150 | - | |
| | Period Jitter | | RMS | - | 15 | - | |
| | | | peak to peak | - | ±200 | - | |
| | Bit Time CAN jitter | Cycle to cycle at 1 MHz on 1000 samples. | | - | 330 | - | |
| $I_{DD(PLL)}$(4) | PLL power consumption on VDD | VCO freq = 100 MHz<br>VCO freq = 432 MHz | | 0.15<br>0.45 | - | 0.40<br>0.75 | mA |
| $I_{DDA(PLL)}$(4) | PLL power consumption on VDDA | VCO freq = 100 MHz<br>VCO freq = 432 MHz | | 0.30<br>0.55 | - | 0.40<br>0.85 | |

1. Take care of using the appropriate division factor M to obtain the specified PLL input clock values. The M factor is shared between PLL and PLLI2S.
2. Guaranteed by design, not tested in production.
3. The use of two PLLs in parallel could degraded the Jitter up to +30%.
4. Guaranteed by characterization, not tested in production.



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**Table 46. PLLI2S (audio PLL) characteristics**

| Symbol | Parameter | Conditions | | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|---|
| $f_{PLLI2S_IN}$ | PLLI2S input clock(1) | - | | 0.95(2) | 1 | 2.10 | MHz |
| $f_{PLLI2S_OUT}$ | PLLI2S multiplier output clock | - | | - | - | 216 | |
| $f_{VCO_OUT}$ | PLLI2S VCO output | - | | 100 | - | 432 | |
| $t_{LOCK}$ | PLLI2S lock time | VCO freq = 100 MHz | | 75 | - | 200 | µs |
| | | VCO freq = 432 MHz | | 100 | - | 300 | |
| Jitter(3) | Master I2S clock jitter | Cycle to cycle at 12.288 MHz on 48 kHz period, N=432, R=5 | RMS | - | 90 | - | ps |
| | | | peak to peak | - | ±280 | - | |
| | | Average frequency of 12.288 MHz N = 432, R = 5 on 1000 samples | | - | 90 | - | |
| | WS I2S clock jitter | Cycle to cycle at 48 KHz on 1000 samples | | - | 400 | - | |
| $I_{DD(PLLI2S)}$(4) | PLLI2S power consumption on $V_{DD}$ | VCO freq = 100 MHz<br>VCO freq = 432 MHz | | 0.15<br>0.45 | - | 0.40<br>0.75 | mA |
| $I_{DDA(PLLI2S)}$(4) | PLLI2S power consumption on $V_{DDA}$ | VCO freq = 100 MHz<br>VCO freq = 432 MHz | | 0.30<br>0.55 | - | 0.40<br>0.85 | |

1. Take care of using the appropriate division factor M to have the specified PLL input clock values.
2. Guaranteed by design, not tested in production.
3. Value given with main PLL running.
4. Guaranteed by characterization, not tested in production.



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### 6.3.11 PLL spread spectrum clock generation (SSCG) characteristics

The spread spectrum clock generation (SSCG) feature allows to reduce electromagnetic interferences (see *Table 53: EMI characteristics for LQFP144*). It is available only on the main PLL.

**Table 47. SSCG parameter constraints**

| Symbol | Parameter | Min | Typ | Max(1) | Unit |
|---|---|---|---|---|---|
| $f_{Mod}$ | Modulation frequency | - | - | 10 | kHz |
| md | Peak modulation depth | 0.25 | - | 2 | % |
| MODEPER * INCSTEP | (Modulation period) * (Increment Step) | - | - | $2^{15}$-1 | - |

1. Guaranteed by design, not tested in production.

**Equation 1**

The frequency modulation period (MODEPER) is given by the equation below:

$$MODEPER = round[f_{PLL_IN} / (4 \times f_{Mod})]$$

$f_{PLL_IN}$ and $f_{Mod}$ must be expressed in Hz.

As an example:

If $f_{PLL_IN}$ = 1 MHz, and $f_{MOD}$ = 1 kHz, the modulation depth (MODEPER) is given by equation 1:

$$MODEPER = round[10^6 / (4 \times 10^3)] = 250$$

**Equation 2**

Equation 2 allows to calculate the increment step (INCSTEP):

$$INCSTEP = round[((2^{15} - 1) \times md \times PLLN) / (100 \times 5 \times MODEPER)]$$

$f_{VCO_OUT}$ must be expressed in MHz.

With a modulation depth (md) = ±2 % (4 % peak to peak), and PLLN = 240 (in MHz):

$$INCSTEP = round[((2^{15} - 1) \times 2 \times 240) / (100 \times 5 \times 250)] = 126 md(quantitazed)\%$$

An amplitude quantization error may be generated because the linear modulation profile is obtained by taking the quantized values (rounded to the nearest integer) of MODPER and INCSTEP. As a result, the achieved modulation depth is quantized. The percentage quantized modulation depth is given by the following formula:

$$md_{quantized}\% = (MODEPER \times INCSTEP \times 100 \times 5) / ((2^{15} - 1) \times PLLN)$$

As a result:

$$md_{quantized}\% = (250 \times 126 \times 100 \times 5) / ((2^{15} - 1) \times 240) = 2.002\%(peak)$$



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*Figure 33* and *Figure 34* show the main PLL output clock waveforms in center spread and down spread modes, where:

F0 is $f_{PLL_OUT}$ nominal.

$T_{mode}$ is the modulation period.

md is the modulation depth.

**Figure 33. PLL output clock waveforms in center spread mode**

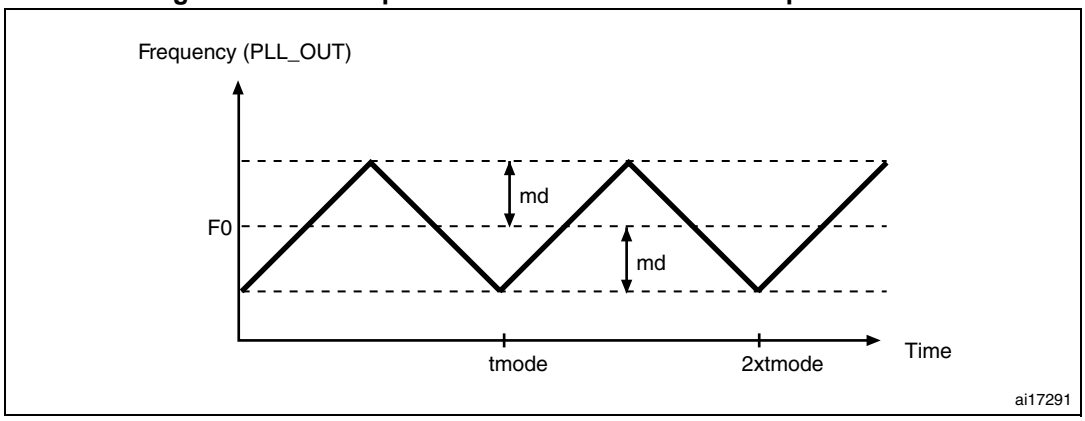
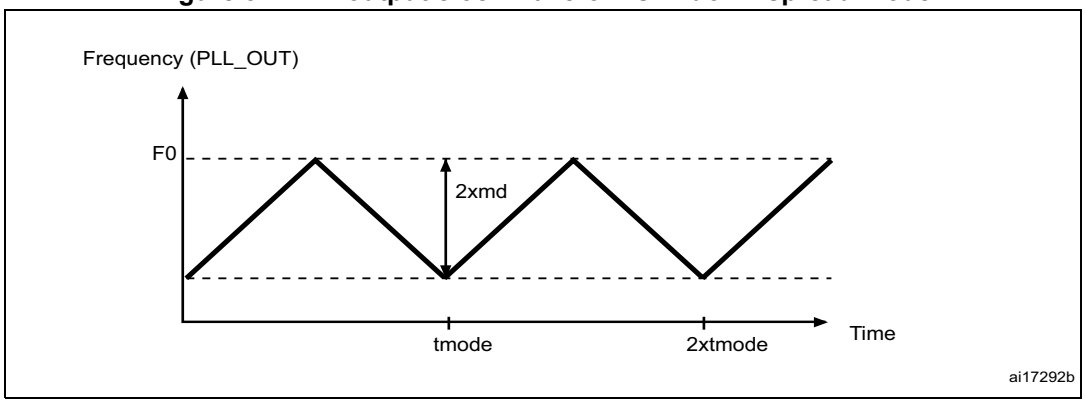



**Figure 34. PLL output clock waveforms in down spread mode**






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## 6.3.12 Memory characteristics

### Flash memory

The characteristics are given at $T_A$ = -40 to 125 °C unless otherwise specified.

The devices are shipped to customers with the Flash memory erased.

**Table 48. Flash memory characteristics**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $I_{DD}$ | Supply current | Write / Erase 8-bit mode, $V_{DD}$ = 1.7 V | - | 5 | - | mA |
| | | Write / Erase 16-bit mode, $V_{DD}$ = 2.1 V | - | 8 | - | |
| | | Write / Erase 32-bit mode, $V_{DD}$ = 3.3 V | - | 12 | - | |

**Table 49. Flash memory programming**

| Symbol | Parameter | Conditions | Min(1) | Typ | Max(1) | Unit |
|---|---|---|---|---|---|---|
| $t_{prog}$ | Word programming time | Program/erase parallelism (PSIZE) = x 8/16/32 | - | 16 | 100(2) | µs |
| $t_{ERASE16KB}$ | Sector (16 KB) erase time | Program/erase parallelism (PSIZE) = x 8 | - | 400 | 800 | ms |
| | | Program/erase parallelism (PSIZE) = x 16 | - | 300 | 600 | |
| | | Program/erase parallelism (PSIZE) = x 32 | - | 250 | 500 | |
| $t_{ERASE64KB}$ | Sector (64 KB) erase time | Program/erase parallelism (PSIZE) = x 8 | - | 1200 | 2400 | ms |
| | | Program/erase parallelism (PSIZE) = x 16 | - | 700 | 1400 | |
| | | Program/erase parallelism (PSIZE) = x 32 | - | 550 | 1100 | |
| $t_{ERASE128KB}$ | Sector (128 KB) erase time | Program/erase parallelism (PSIZE) = x 8 | - | 2 | 4 | s |
| | | Program/erase parallelism (PSIZE) = x 16 | - | 1.3 | 2.6 | |
| | | Program/erase parallelism (PSIZE) = x 32 | - | 1 | 2 | |
| $t_{ME}$ | Mass erase time | Program/erase parallelism (PSIZE) = x 8 | - | 16 | 32 | s |
| | | Program/erase parallelism (PSIZE) = x 16 | - | 11 | 22 | |
| | | Program/erase parallelism (PSIZE) = x 32 | - | 8 | 16 | |



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**Table 49. Flash memory programming (continued)**

| Symbol | Parameter | Conditions | Min(1) | Typ | Max(1) | Unit |
|---|---|---|---|---|---|---|
| $V_{prog}$ | Programming voltage | 32-bit program operation | 2.7 | - | 3.6 | V |
| | | 16-bit program operation | 2.1 | - | 3.6 | V |
| | | 8-bit program operation | 1.7 | - | 3.6 | V |

1. Guaranteed by characterization, not tested in production.
2. The maximum programming time is measured after 100K erase operations.

**Table 50. Flash memory programming with $V_{PP}$ voltage**

| Symbol | Parameter | Conditions | Min(1) | Typ | Max(1) | Unit |
|---|---|---|---|---|---|---|
| $t_{prog}$ | Double word programming | $T_A$ = 0 to +40 °C<br>$V_{DD}$ = 3.3 V<br>$V_{PP}$ = 8.5 V | - | 16 | 100(2) | µs |
| $t_{ERASE16KB}$ | Sector (16 KB) erase time | | - | 230 | - | ms |
| $t_{ERASE64KB}$ | Sector (64 KB) erase time | | - | 490 | - | |
| $t_{ERASE128KB}$ | Sector (128 KB) erase time | | - | 875 | - | |
| $t_{ME}$ | Mass erase time | | - | 6.9 | - | s |
| $V_{prog}$ | Programming voltage | - | 2.7 | - | 3.6 | V |
| $V_{PP}$ | $V_{PP}$ voltage range | - | 7 | - | 9 | V |
| $I_{PP}$ | Minimum current sunk on the $V_{PP}$ pin | - | 10 | - | - | mA |
| $t_{VPP}$(3) | Cumulative time during which $V_{PP}$ is applied | - | - | - | 1 | hour |

1. Guaranteed by design, not tested in production.
2. The maximum programming time is measured after 100K erase operations.
3. $V_{PP}$ should only be connected during programming/erasing.

**Table 51. Flash memory endurance and data retention**

| Symbol | Parameter | Conditions | Value | Unit |
|---|---|---|---|---|
| | | | Min(1) | |
| $N_{END}$ | Endurance | $T_A$ = -40 to +85 °C (temp. range 6)<br>$T_A$ = -40 to +105 °C (temp. range 7)<br>$T_A$ = -40 to +125 °C (temp. range 3) | 10 | kcycles |
| $t_{RET}$ | Data retention | 1 kcycle(2) at $T_A$ = 85 °C | 30 | Years |
| | | 1 kcycle(2) at $T_A$ = 105 °C | 10 | |
| | | 1 kcycle(2) at $T_A$ = 125 °C | 3 | |
| | | 10 kcycle(2) at $T_A$ = 55 °C | 20 | |

1. Guaranteed by characterization, not tested in production.
2. Cycling performed over the whole temperature range.



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### 6.3.13 EMC characteristics

Susceptibility tests are performed on a sample basis during device characterization.

#### Functional EMS (electromagnetic susceptibility)

While a simple application is executed on the device (toggling 2 LEDs through I/O ports). the device is stressed by two electromagnetic events until a failure occurs. The failure is indicated by the LEDs:

- **Electrostatic discharge (ESD)** (positive and negative) is applied to all device pins until a functional disturbance occurs. This test is compliant with the IEC 61000-4-2 standard.
- **FTB**: A burst of fast transient voltage (positive and negative) is applied to $V_{DD}$ and $V_{SS}$ through a 100 pF capacitor, until a functional disturbance occurs. This test is compliant with the IEC 61000-4-4 standard.

A device reset allows normal operations to be resumed.

The test results are given in *Table 53*. They are based on the EMS levels and classes defined in application note AN1709.

**Table 52. EMS characteristics for LQFP144 package**

| Symbol | Parameter | Conditions | Level/ Class |
|---|---|---|---|
| $V_{FESD}$ | Voltage limits to be applied on any I/O pin to induce a functional disturbance | $V_{DD}$ = 3.3 V, LQFP144<br>$T_A$ = +25 °C, $f_{HCLK}$ = 100 MHz,<br>conforms to IEC 61000-4-2 | 2B |
| $V_{EFTB}$ | Fast transient voltage burst limits to be applied through 100 pF on $V_{DD}$ and $V_{SS}$ pins to induce a functional disturbance | $V_{DD}$ = 3.3 V, LQFP144<br>$T_A$ = +25 °C, $f_{HCLK}$ = 100 MHz,<br>conforms to IEC 61000-4-4 | 4B |

When the application is exposed to a noisy environment, it is recommended to avoid pin exposition to disturbances. The pins showing a middle range robustness are: PA0, PA1, PA2, on LQFP144 packages and PDR_ON on WLCSP49.

As a consequence, it is recommended to add a serial resistor (1 kΩ maximum) located as close as possible to the MCU to the pins exposed to noise (connected to tracks longer than 50 mm on PCB).

#### Designing hardened software to avoid noise problems

EMC characterization and optimization are performed at component level with a typical application environment and simplified MCU software. It should be noted that good EMC performance is highly dependent on the user application and the software in particular.

Therefore it is recommended that the user applies EMC software optimization and prequalification tests in relation with the EMC level requested for his application.

**Software recommendations**

The software flowchart must include the management of runaway conditions such as:

- Corrupted program counter
- Unexpected reset
- Critical Data corruption (control registers...)



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### Prequalification trials

Most of the common failures (unexpected reset and program counter corruption) can be reproduced by manually forcing a low state on the NRST pin or the Oscillator pins for 1 second.

To complete these trials, ESD stress can be applied directly on the device, over the range of specification values. When unexpected behavior is detected, the software can be hardened to prevent unrecoverable errors occurring (see application note AN1015).

## Electromagnetic Interference (EMI)

The electromagnetic field emitted by the device are monitored while a simple application, executing EEMBC code, is running. This emission test is compliant with IEC61967-2 standard which specifies the test board and the pin loading.

**Table 53. EMI characteristics for LQFP144**

| Symbol | Parameter | Conditions | Monitored frequency band | Max vs. [$f_{HSE}/f_{CPU}$] | Unit |
|---|---|---|---|---|---|
| | | | | 8/100 MHz | |
| $S_{EMI}$ | Peak level | $V_{DD}$ = 3.6 V, $T_A$ = 25 °C, LQFP144 package, conforming to IEC 61967-2, EEMBC, ART ON, all peripheral clocks enabled, clock dithering disabled. | 0.1 to 30 MHz | 20 | dBµV |
| | | | 30 to 130 MHz | 28 | |
| | | | 130 MHz to 1 GHz | 21 | |
| | | | EMI Level | 3.5 | - |



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### 6.3.14 Absolute maximum ratings (electrical sensitivity)

Based on three different tests (ESD, LU) using specific measurement methods, the device is stressed in order to determine its performance in terms of electrical sensitivity.

#### Electrostatic discharge (ESD)

Electrostatic discharges (a positive then a negative pulse separated by 1 second) are applied to the pins of each sample according to each pin combination. The sample size depends on the number of supply pins in the device (3 parts × (n+1) supply pins). This test conforms to the JESD22-A114/C101 standard.

**Table 54. ESD absolute maximum ratings**

| Symbol | Ratings | Conditions | Class | Maximum value(1) | Unit |
|---|---|---|---|---|---|
| $V_{ESD(HBM)}$ | Electrostatic discharge voltage (human body model) | $T_A$ = +25 °C conforming to JESD22-A114 | 2 | 2000 | V |
| $V_{ESD(CDM)}$ | Electrostatic discharge voltage (charge device model) | $T_A$ = +25 °C conforming to ANSI/ESD STM5.3.1, UFBGA144, UFBGA100, LQFP100, LQFP64, UFQFPN48 | 4 | 500 | |
| | | $T_A$ = +25 °C conforming to ANSI/ESD STM5.3.1, WLCSP64 | 3 | 400 | |
| | | $T_A$ = +25 °C conforming to ANSI/ESD STM5.3.1, LQFP144 | 3 | 250 | |

1. Guaranteed by characterization, not tested in production.

#### Static latchup

Two complementary static tests are required on six parts to assess the latchup performance:

- A supply overvoltage is applied to each power supply pin
- A current injection is applied to each input, output and configurable I/O pin

These tests are compliant with EIA/JESD 78A IC latchup standard.

**Table 55. Electrical sensitivities**

| Symbol | Parameter | Conditions | Class |
|---|---|---|---|
| LU | Static latch-up class | $T_A$ = +125 °C conforming to JESD78A | II level A |



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### 6.3.15 I/O current injection characteristics

As a general rule, current injection to the I/O pins, due to external voltage below $V_{SS}$ or above $V_{DD}$ (for standard, 3 V-capable I/O pins) should be avoided during normal product operation. However, in order to give an indication of the robustness of the microcontroller in cases when abnormal injection accidentally happens, susceptibility tests are performed on a sample basis during device characterization.

#### Functional susceptibility to I/O current injection

While a simple application is executed on the device, the device is stressed by injecting current into the I/O pins programmed in floating input mode. While current is injected into the I/O pin, one at a time, the device is checked for functional failures.

The failure is indicated by an out of range parameter: ADC error above a certain limit (>5 LSB TUE), out of conventional limits of induced leakage current on adjacent pins (out of –5 µA/+0 µA range), or other functional failure (for example reset, oscillator frequency deviation).

Negative induced leakage current is caused by negative injection and positive induced leakage current by positive injection.

The test results are given in *Table 56*.

**Table 56. I/O current injection susceptibility(1)**

| Symbol | Description | Functional susceptibility | | Unit |
|---|---|---|---|---|
| | | Negative injection | Positive injection | |
| $I_{INJ}$ | Injected current on BOOT0 pin | –0 | NA | mA |
| | Injected current on NRST pin | –0 | NA | |
| | Injected current on PB3, PB4, PB5, PB6, PB7, PB8, PB9, PC13, PC14, PC15, PH1, PDR_ON, PC0, PC1,PC2, PC3, PD1, PD5, PD6, PD7, PE0, PE2, PE3, PE4, PE5, PE6 | –0 | NA | |
| | Injected current on any other FT pin | –5 | NA | |
| | Injected current on any other pins | –5 | +5 | |

1. NA = not applicable.

*Note: It is recommended to add a Schottky diode (pin to ground) to analog pins which may potentially inject negative currents.*



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## 6.3.16 I/O port characteristics

### General input/output characteristics

Unless otherwise specified, the parameters given in *Table 57* are derived from tests performed under the conditions summarized in *Table 16*. All I/Os are CMOS and TTL compliant.

**Table 57. I/O static characteristics**

| Symbol | Parameter | | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|---|
| $V_{IL}$ | FT, TC and NRST I/O input low level voltage | | 1.7 V ≤ $V_{DD}$ ≤ 3.6 V | - | - | $0.3V_{DD}$(1) | V |
| | BOOT0 I/O input low level voltage | | 1.75 V ≤ $V_{DD}$ ≤ 3.6 V, -40 °C ≤ $T_A$ ≤ 125 °C | - | - | $0.1V_{DD}+0.1$(2) | |
| | | | 1.7 V ≤ $V_{DD}$ ≤ 3.6 V, 0 °C ≤ $T_A$ ≤ 125 °C | - | - | | |
| $V_{IH}$ | FT, TC and NRST I/O input high level voltage(5) | | 1.7 V ≤ $V_{DD}$ ≤ 3.6 V | $0.7V_{DD}$(1) | - | - | V |
| | BOOT0 I/O input high level voltage | | 1.75 V ≤ $V_{DD}$ ≤ 3.6 V, -40 °C ≤ $T_A$ ≤ 125 °C | $0.17V_{DD}+0.7$(2) | - | - | |
| | | | 1.7 V ≤ $V_{DD}$ ≤ 3.6 V, 0 °C ≤ $T_A$ ≤ 125 °C | | | | |
| $V_{HYS}$ | FT, TC and NRST I/O input hysteresis | | 1.7 V ≤ $V_{DD}$ ≤ 3.6 V | 10% $V_{DD}$(2)(3) | - | - | V |
| | BOOT0 I/O input hysteresis | | 1.75 V ≤ $V_{DD}$ ≤ 3.6 V, -40 °C ≤ $T_A$ ≤ 125 °C | 0.1 | - | - | |
| | | | 1.7 V ≤ $V_{DD}$ ≤ 3.6 V, 0 °C ≤ $T_A$ ≤ 125 °C | | | | |
| $I_{lkg}$ | I/O input leakage current (4) | | $V_{SS}$ ≤ $V_{IN}$ ≤ $V_{DD}$ | - | - | ±1 | µA |
| | I/O FT/TC input leakage current (5) | | $V_{IN}$ = 5 V | - | - | 3 | |
| $R_{PU}$ | Weak pull-up equivalent resistor(6) | All pins except for PA10 (OTG_FS_ID) | $V_{IN}$ = $V_{SS}$ | 30 | 40 | 50 | kΩ |
| | | PA10 (OTG_FS_ID) | - | 7 | 10 | 14 | |
| $R_{PD}$ | Weak pull-down equivalent resistor(7) | All pins except for PA10 (OTG_FS_ID) | $V_{IN}$ = $V_{DD}$ | 30 | 40 | 50 | |
| | | PA10 (OTG_FS_ID) | - | 7 | 10 | 14 | |
| $C_{IO}$(8) | I/O pin capacitance | | - | - | 5 | - | pF |

1. Guaranteed by test in production.
2. Guaranteed by design, not tested in production.

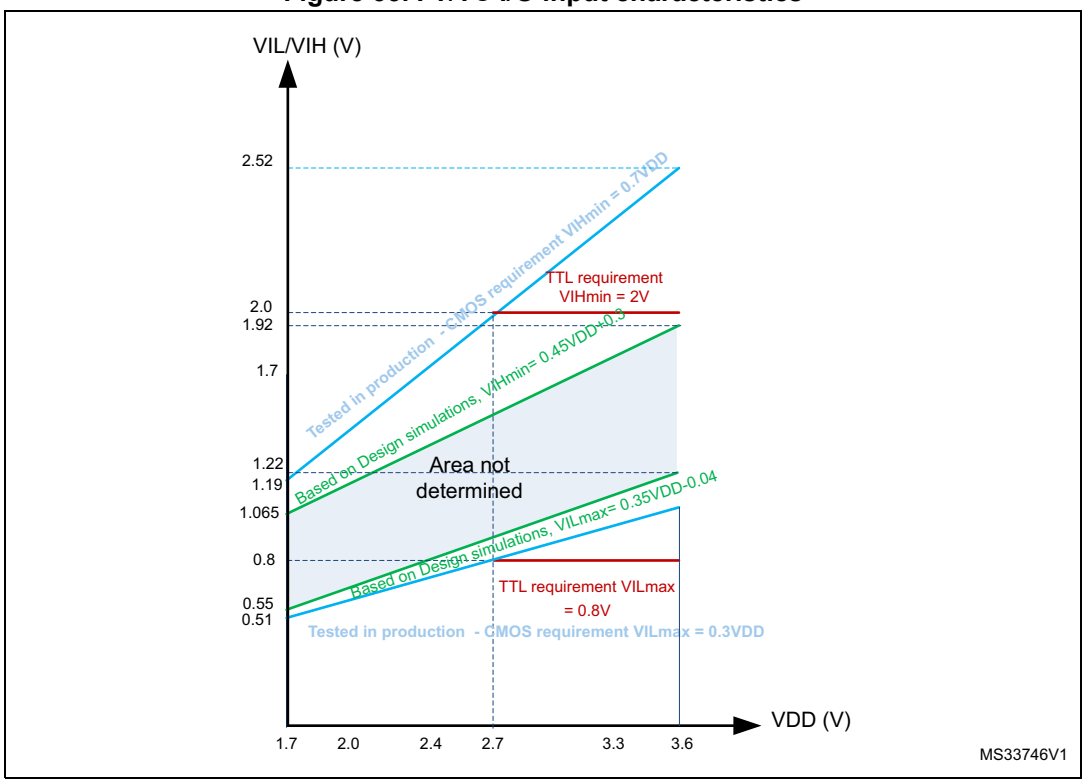


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3. With a minimum of 200 mV.
4. Leakage could be higher than the maximum value, if negative current is injected on adjacent pins, Refer to *Table 56: I/O current injection susceptibility*
5. To sustain a voltage higher than VDD +0.3 V, the internal pull-up/pull-down resistors must be disabled. Leakage could be higher than the maximum value, if negative current is injected on adjacent pins.Refer to *Table 56: I/O current injection susceptibility*
6. Pull-up resistors are designed with a true resistance in series with a switchable PMOS. This PMOS contribution to the series resistance is minimum (~10% order).
7. Pull-down resistors are designed with a true resistance in series with a switchable NMOS. This NMOS contribution to the series resistance is minimum (~10% order).
8. Hysteresis voltage between Schmitt trigger switching levels. Guaranteed by characterization, not tested in production.

All I/Os are CMOS and TTL compliant (no software configuration required). Their characteristics cover more than the strict CMOS-technology or TTL parameters. The coverage of these requirements for FT and TC I/Os is shown in *Figure 35*.

**Figure 35. FT/TC I/O input characteristics**






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### Output driving current

The GPIOs (general purpose input/outputs) can sink or source up to ±8 mA, and sink or source up to ±20 mA (with a relaxed $V_{OL}/V_{OH}$) except PC13, PC14 and PC15 which can sink or source up to ±3mA. When using the PC13 to PC15 GPIOs in output mode, the speed should not exceed 2 MHz with a maximum load of 30 pF.

In the user application, the number of I/O pins which can drive current must be limited to respect the absolute maximum rating specified in *Section 6.2*. In particular:

- The sum of the currents sourced by all the I/Os on $V_{DD,}$ plus the maximum Run consumption of the MCU sourced on $V_{DD,}$ cannot exceed the absolute maximum rating $\Sigma I_{VDD}$ (see *Table 14*).
- The sum of the currents sunk by all the I/Os on $V_{SS}$ plus the maximum Run consumption of the MCU sunk on $V_{SS}$ cannot exceed the absolute maximum rating $\Sigma I_{VSS}$ (see *Table 14*).

### Output voltage levels

Unless otherwise specified, the parameters given in *Table 58* are derived from tests performed under ambient temperature and $V_{DD}$ supply voltage conditions summarized in *Table 16*. All I/Os are CMOS and TTL compliant.

**Table 58. Output voltage characteristics**

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---|---|---|---|---|---|
| $V_{OL}$(1) | Output low level voltage for an I/O pin | CMOS port(2) $I_{IO}$ = +8 mA 2.7 V ≤ $V_{DD}$ ≤ 3.6 V | - | 0.4 | V |
| $V_{OH}$(3) | Output high level voltage for an I/O pin | | $V_{DD}$–0.4 | - | |
| $V_{OL}$ (1) | Output low level voltage for an I/O pin | TTL port(2) $I_{IO}$ =+8 mA 2.7 V ≤ $V_{DD}$ ≤ 3.6 V | - | 0.4 | V |
| $V_{OH}$ (3) | Output high level voltage for an I/O pin | | 2.4 | - | |
| $V_{OL}$(1) | Output low level voltage for an I/O pin | $I_{IO}$ = +20 mA 2.7 V ≤ $V_{DD}$ ≤ 3.6 V | - | 1.3(4) | V |
| $V_{OH}$(3) | Output high level voltage for an I/O pin | | $V_{DD}$–1.3(4) | - | |
| $V_{OL}$(1) | Output low level voltage for an I/O pin | $I_{IO}$ = +6 mA 1.8 V ≤ $V_{DD}$ ≤ 3.6 V | - | 0.4(4) | V |
| $V_{OH}$(3) | Output high level voltage for an I/O pin | | $V_{DD}$–0.4(4) | - | |
| $V_{OL}$(1) | Output low level voltage for an I/O pin | $I_{IO}$ = +4 mA 1.7 V ≤ $V_{DD}$ ≤ 3.6 V | - | 0.4(5) | V |
| $V_{OH}$(3) | Output high level voltage for an I/O pin | | $V_{DD}$–0.4(5) | - | |

1. The $I_{IO}$ current sunk by the device must always respect the absolute maximum rating specified in *Table 14*. and the sum of $I_{IO}$ (I/O ports and control pins) must not exceed $I_{VSS}$.
2. TTL and CMOS outputs are compatible with JEDEC standards JESD36 and JESD52.
3. The $I_{IO}$ current sourced by the device must always respect the absolute maximum rating specified in *Table 14* and the sum of $I_{IO}$ (I/O ports and control pins) must not exceed $I_{VDD}$.
4. Guaranteed by characterization results, not tested in production.
5. Guaranteed by design, not tested in production.

### Input/output AC characteristics

The definition and values of input/output AC characteristics are given in *Figure 36* and *Table 59*, respectively.



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Unless otherwise specified, the parameters given in *Table 59* are derived from tests performed under the ambient temperature and $V_{DD}$ supply voltage conditions summarized in *Table 16*.

**Table 59. I/O AC characteristics(1)(2)**

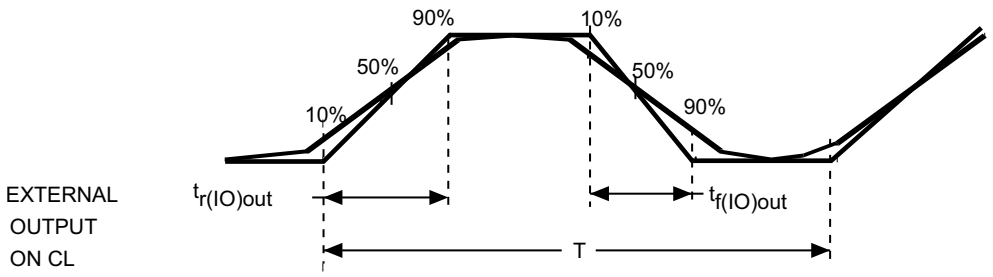
| OSPEEDRy [1:0] bit value(1) | Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|---|
| 00 | $f_{max(IO)out}$ | Maximum frequency(3) | $C_L$ = 50 pF, $V_{DD}$ ≥ 2.70 V | - | - | 4 | MHz |
| | | | $C_L$ = 50 pF, $V_{DD}$≥ 1.7 V | - | - | 2 | |
| | | | $C_L$ = 10 pF, $V_{DD}$ ≥ 2.70 V | - | - | 8 | |
| | | | $C_L$ = 10 pF, $V_{DD}$ ≥ 1.7 V | - | - | 4 | |
| | $t_{f(IO)out}$/ $t_{r(IO)out}$ | Output high to low level fall time and output low to high level rise time | $C_L$ = 50 pF, $V_{DD}$ = 1.7 V to 3.6 V | - | - | 100 | ns |
| 01 | $f_{max(IO)out}$ | Maximum frequency(3) | $C_L$ = 50 pF, $V_{DD}$ ≥ 2.70 V | - | - | 25 | MHz |
| | | | $C_L$ = 50 pF, $V_{DD}$ ≥ 1.7 V | - | - | 12.5 | |
| | | | $C_L$ = 10 pF, $V_{DD}$ ≥ 2.70 V | - | - | 50 | |
| | | | $C_L$ = 10 pF, $V_{DD}$ ≥ 1.7 V | - | - | 20 | |
| | $t_{f(IO)out}$/ $t_{r(IO)out}$ | Output high to low level fall time and output low to high level rise time | $C_L$ = 50 pF, $V_{DD}$ ≥2.7 V | - | - | 10 | ns |
| | | | $C_L$ = 50 pF, $V_{DD}$ ≥ 1.7 V | - | - | 20 | |
| | | | $C_L$ = 10 pF, $V_{DD}$ ≥ 2.70 V | - | - | 6 | |
| | | | $C_L$ = 10 pF, $V_{DD}$ ≥ 1.7 V | - | - | 10 | |
| 10 | $f_{max(IO)out}$ | Maximum frequency(3) | $C_L$ = 40 pF, $V_{DD}$ ≥ 2.70 V | - | - | 50(4) | MHz |
| | | | $C_L$ = 40 pF, $V_{DD}$ ≥ 1.7 V | - | - | 25 | |
| | | | $C_L$ = 10 pF, $V_{DD}$ ≥ 2.70 V | - | - | 100(4) | |
| | | | $C_L$ = 10 pF, $V_{DD}$ ≥ 1.7 V | - | - | 50(4) | |
| | $t_{f(IO)out}$/ $t_{r(IO)out}$ | Output high to low level fall time and output low to high level rise time | $C_L$ = 40 pF, $V_{DD}$≥ 2.70 V | - | - | 6 | ns |
| | | | $C_L$ = 40 pF, $V_{DD}$≥ 1.7 V | - | - | 10 | |
| | | | $C_L$ = 10 pF, $V_{DD}$≥ 2.70 V | - | - | 4 | |
| | | | $C_L$ = 10 pF, $V_{DD}$≥ 1.7 V | - | - | 6 | |
| 11 | $F_{max(IO)out}$ | Maximum frequency(3) | $C_L$ = 30 pF, $V_{DD}$ ≥ 2.70 V | - | - | 100(4) | MHz |
| | | | $C_L$ = 30 pF, $V_{DD}$ ≥ 1.7 V | - | - | 50(4) | |
| | $t_{f(IO)out}$/ $t_{r(IO)out}$ | Output high to low level fall time and output low to high level rise time | $C_L$ = 30 pF, $V_{DD}$ ≥ 2.70 V | - | - | 4 | ns |
| | | | $C_L$ = 30 pF, $V_{DD}$ ≥ 1.7 V | - | - | 6 | |
| | | | $C_L$ = 10 pF, $V_{DD}$≥ 2.70 V | - | - | 2.5 | |
| | | | $C_L$ = 10 pF, $V_{DD}$≥ 1.7 V | - | - | 4 | |
| - | $t_{EXTIpw}$ | Pulse width of external signals detected by the EXTI controller | - | 10 | - | - | ns |



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1. Guaranteed by characterization, not tested in production.
2. The I/O speed is configured using the OSPEEDRy[1:0] bits. Refer to the STM32F4xx reference manual for a description of the GPIOx_SPEEDR GPIO port output speed register.
3. The maximum frequency is defined in *Figure 36*.
4. For maximum frequencies above 50 MHz and $V_{DD}$ > 2.4 V, the compensation cell should be used.

**Figure 36. I/O AC characteristics definition**




Maximum frequency is achieved if ($t_r$ + $t_f$) ≤ (2/3)T and if the duty cycle is (45-55%) when loaded by CL specified in the table " *I/O AC characteristics*".

ai14131d

## 6.3.17 NRST pin characteristics

The NRST pin input driver uses CMOS technology. It is connected to a permanent pull-up resistor, $R_{PU}$ (see *Table 57*).

Unless otherwise specified, the parameters given in *Table 60* are derived from tests performed under the ambient temperature and $V_{DD}$ supply voltage conditions summarized in *Table 16*. Refer to *Table 57: I/O static characteristics* for the values of VIH and VIL for NRST pin.

**Table 60. NRST pin characteristics**

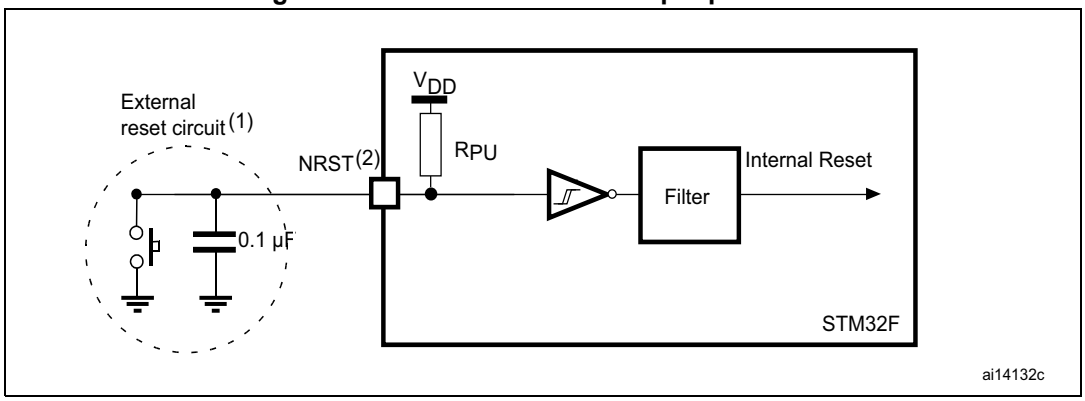
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $R_{PU}$ | Weak pull-up equivalent resistor(1) | $V_{IN}$ = $V_{SS}$ | 30 | 40 | 50 | kΩ |
| $V_{F(NRST)}$(2) | NRST Input filtered pulse | - | - | - | 100 | ns |
| $V_{NF(NRST)}$(2) | NRST Input not filtered pulse | $V_{DD}$ > 2.7 V | 300 | - | - | ns |
| $T_{NRST_OUT}$ | Generated reset pulse duration | Internal Reset source | 20 | - | - | µs |

1. The pull-up is designed with a true resistance in series with a switchable PMOS. This PMOS contribution to the series resistance must be minimum (~10% order).
2. Guaranteed by design, not tested in production.



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**Figure 37. Recommended NRST pin protection**




1. The reset network protects the device against parasitic resets.
2. The user must ensure that the level on the NRST pin can go below the $V_{IL(NRST)}$ max level specified in *Table 60*. Otherwise the reset is not taken into account by the device.

## 6.3.18 TIM timer characteristics

The parameters given in *Table 61* are guaranteed by design.

Refer to *Section 6.3.16: I/O port characteristics* for details on the input/output alternate function characteristics (output compare, input capture, external clock, PWM output).

**Table 61. TIMx characteristics(1)(2)**

| Symbol | Parameter | Conditions(3) | Min | Max | Unit |
|---|---|---|---|---|---|
| $t_{res(TIM)}$ | Timer resolution time | AHB/APBx prescaler=1 or 2 or 4, $f_{TIMxCLK}$ = 100 MHz | 1 | - | $t_{TIMxCLK}$ |
| | | | 11.9 | - | ns |
| | | AHB/APBx prescaler>4, $f_{TIMxCLK}$ = 100 MHz | 1 | - | $t_{TIMxCLK}$ |
| | | | 11.9 | - | ns |
| $f_{EXT}$ | Timer external clock frequency on CH1 to CH4 | $f_{TIMxCLK}$ = 100 MHz | 0 | $f_{TIMxCLK}/2$ | MHz |
| | | | 0 | 50 | MHz |
| $Res_{TIM}$ | Timer resolution | | - | 16/32 | bit |
| $t_{COUNTER}$ | 16-bit counter clock period when internal clock is selected | $f_{TIMxCLK}$ = 100 MHz | 0.0119 | 780 | µs |
| $t_{MAX_COUNT}$ | Maximum possible count with 32-bit counter | - | - | 65536 × 65536 | $t_{TIMxCLK}$ |
| | | $f_{TIMxCLK}$ = 100 MHz | - | 51.1 | S |

1. TIMx is used as a general term to refer to the TIM1 to TIM11 timers.
2. Guaranteed by design, not tested in production.
3. The maximum timer frequency on APB1 is 50 MHz and on APB2 is up to 100 MHz, by setting the TIMPRE bit in the RCC_DCKCFGR register, if APBx prescaler is 1 or 2 or 4, then TIMxCLK = HCKL, otherwise TIMxCLK >= 4x PCLKx.



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## 6.3.19 Communications interfaces

### I²C interface characteristics

The I²C interface meets the requirements of the standard I²C communication protocol with the following restrictions: the I/O pins SDA and SCL are mapped to are not “true” open-drain. When configured as open-drain, the PMOS connected between the I/O pin and $V_{DD}$ is disabled, but is still present.

The I²C characteristics are described in *Table 62*. Refer also to *Section 6.3.16: I/O port characteristics* for more details on the input/output alternate function characteristics (SDA and SCL).

The I²C bus interface supports standard mode (up to 100 kHz) and fast mode (up to 400 kHz). The I²C bus frequency can be increased up to 1 MHz. For more details about the complete solution, contact your local ST sales representative.

**Table 62. I²C characteristics**

| Symbol | Parameter | Standard mode I²C(1)(2) | | Fast mode I²C(1)(2) | | Unit |
|---|---|---|---|---|---|---|
| | | Min | Max | Min | Max | |
| $t_{w(SCLL)}$ | SCL clock low time | 4.7 | - | 1.3 | - | µs |
| $t_{w(SCLH)}$ | SCL clock high time | 4.0 | - | 0.6 | - | |
| $t_{su(SDA)}$ | SDA setup time | 250 | - | 100 | - | ns |
| $t_{h(SDA)}$ | SDA data hold time | 0 | 3450(3) | 0 | 900(4) | |
| $t_{r(SDA)}$ $t_{r(SCL)}$ | SDA and SCL rise time | - | 1000 | - | 300 | |
| $t_{f(SDA)}$ $t_{f(SCL)}$ | SDA and SCL fall time | - | 300 | - | 300 | |
| $t_{h(STA)}$ | Start condition hold time | 4.0 | - | 0.6 | - | µs |
| $t_{su(STA)}$ | Repeated Start condition setup time | 4.7 | - | 0.6 | - | |
| $t_{su(STO)}$ | Stop condition setup time | 4.0 | - | 0.6 | - | µs |
| $t_{w(STO:STA)}$ | Stop to Start condition time (bus free) | 4.7 | - | 1.3 | - | µs |
| $t_{SP}$ | Pulse width of the spikes that are suppressed by the analog filter for standard fast mode | - | - | 50 | 120(5) | ns |
| $C_b$ | Capacitive load for each bus line | - | 400 | - | 400 | pF |

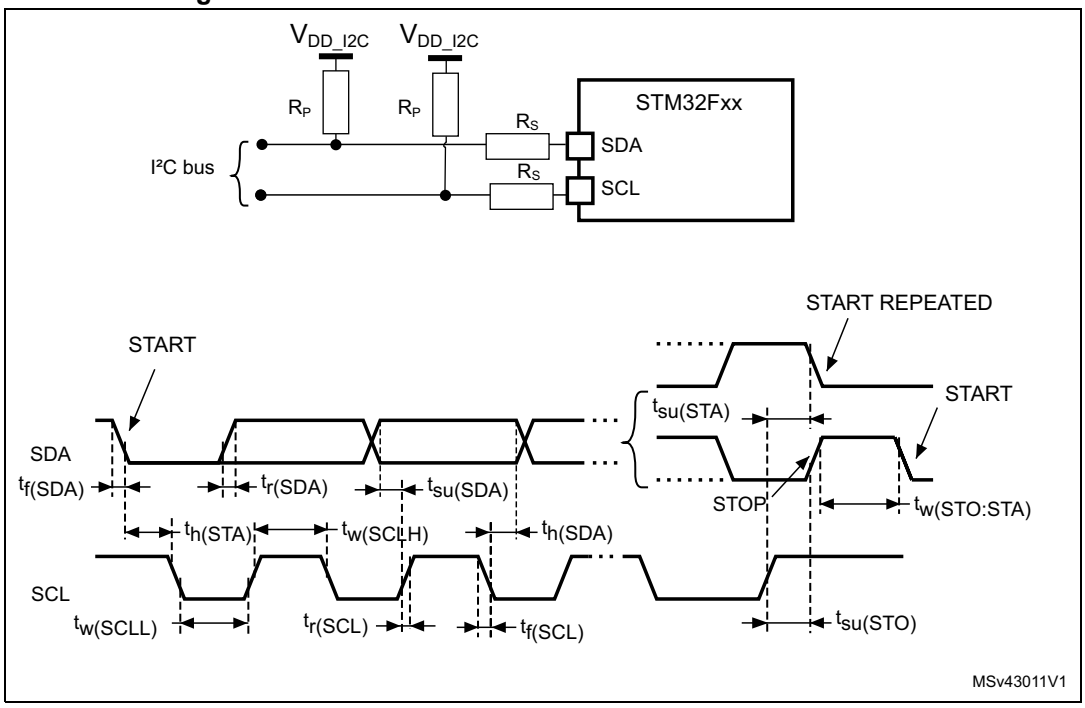
1. Guaranteed by design, not tested in production.
2. $f_{PCLK1}$ must be at least 2 MHz to achieve standard mode I²C frequencies. It must be at least 4 MHz to achieve fast mode I²C frequencies, and a multiple of 10 MHz to reach the 400 kHz maximum I²C fast mode clock.
3. The device must internally provide a hold time of at least 300 ns for the SDA signal in order to bridge the undefined region of the falling edge of SCL.



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4. The maximum data hold time has only to be met if the interface does not stretch the low period of SCL signal.
5. The minimum width of the spikes filtered by the analog filter is above $t_{SP}$ (max)

**Figure 38. I²C bus AC waveforms and measurement circuit**




1. $R_S$ = series protection resistor.
2. $R_P$ = external pull-up resistor.
3. $V_{DD_I2C}$ is the I2C bus power supply.

**Table 63. SCL frequency ($f_{PCLK1}$= 50 MHz, $V_{DD}$ = $V_{DD_I2C}$ = 3.3 V)(1)(2)**

| $f_{SCL}$ (kHz) | I2C_CCR value |
|---|---|
| | $R_P$ = 4.7 kΩ |
| 400 | 0x8019 |
| 300 | 0x8021 |
| 200 | 0x8032 |
| 100 | 0x0096 |
| 50 | 0x012C |
| 20 | 0x02EE |

1. $R_P$ = External pull-up resistance, $f_{SCL}$ = I²C speed
2. For speeds around 200 kHz, the tolerance on the achieved speed is ±5%. For other speed ranges, the tolerance on the achieved speed is ±2%. These variations depend on the accuracy of the external components used to design the application.



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### FMPI$^2$C characteristics

The following table presents FMPI$^2$C characteristics.

Refer also to *Section 6.3.16: I/O port characteristics* for more details on the input/output function characteristics (SDA and SCL).

**Table 64. FMPI$^2$C characteristics(1)**

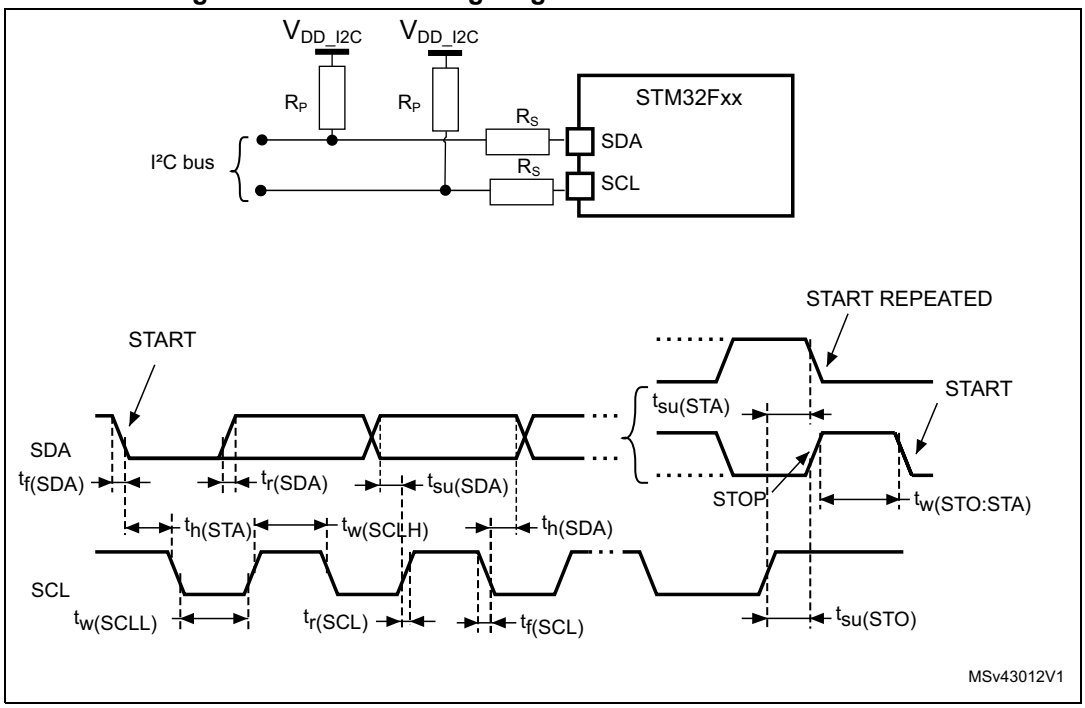
| | Parameter | Standard mode | | Fast mode | | Fast+ mode | | Unit |
|---|---|---|---|---|---|---|---|---|
| | | Min | Max | Min | Max | Min | Max | |
| $f_{FMPI2CC}$ | $F_{MPI2CCLK}$ frequency | 2 | - | 8 | - | 18 | - | µs |
| $t_{w(SCLL)}$ | SCL clock low time | 4.7 | - | 1.3 | - | 0.5 | - | |
| $t_{w(SCLH)}$ | SCL clock high time | 4.0 | - | 0.6 | - | 0.26 | - | |
| $t_{su(SDA)}$ | SDA setup time | 0.25 | - | 0.10 | - | 0.05 | - | |
| $t_{H(SDA)}$ | SDA data hold time | 0 | - | 0 | - | 0 | - | |
| $t_{v(SDA,ACK)}$ | Data, ACK valid time | - | 3.45 | - | 0.9 | - | 0.45 | |
| $t_{r(SDA)}$ $t_{r(SCL)}$ | SDA and SCL rise time | - | 1.0 | - | 0.30 | - | 0.12 | |
| $t_{f(SDA)}$ $t_{f(SCL)}$ | SDA and SCL fall time | - | 0.30 | - | 0.30 | - | 0.12 | |
| $t_{h(STA)}$ | Start condition hold time | 4 | - | 0.6 | - | 0.26 | - | |
| $t_{su(STA)}$ | Repeated Start condition setup time | 4.7 | - | 0.6 | - | 0.26 | - | |
| $t_{su(STO)}$ | Stop condition setup time | 4 | - | 0.6 | - | 0.26 | - | |
| $t_{w(STO:STA)}$ | Stop to Start condition time (bus free) | 4.7 | - | 1.3 | - | 0.5 | - | |
| $t_{SP}$ | Pulse width of the spikes that are suppressed by the analog filter for standard and fast mode | - | - | 0.05 | 0.1 | 0.05 | 0.1 | |
| $C_b$ | Capacitive load for each bus Line | - | 400 | - | 400 | - | 550(2) | pF |

1. Based on characterization results, not tested in production.
2. Can be limited. Maximum supported value can be retrieved by referring to the following formulas:
   $t_{r(SDA/SCL)} = 0.8473 \times R_p \times C_{load}$
   $R_{p(min)} = (V_{DD} - V_{OL(max)}) / I_{OL(max)}$



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**Figure 39. FMPI$^2$C timing diagram and measurement circuit**






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### SPI interface characteristics

Unless otherwise specified, the parameters given in *Table 65* for the SPI interface are derived from tests performed under the ambient temperature, $f_{PCLKx}$ frequency and $V_{DD}$ supply voltage conditions summarized in *Table 16*, with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 10
- Capacitive load C = 30 pF
- Measurement points are done at CMOS levels: $0.5V_{DD}$

Refer to *Section 6.3.16: I/O port characteristics* for more details on the input/output alternate function characteristics (NSS, SCK, MOSI, MISO for SPI).

**Table 65. SPI dynamic characteristics(1)**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $f_{SCK}$ $1/t_{c(SCK)}$ | SPI clock frequency | Master full duplex/receiver mode, 2.7 V < $V_{DD}$ < 3.6 V SPI1/4/5 | - | - | 50 | MHz |
| | | Master transmitter mode 1.7 V < $V_{DD}$ < 3.6 V SPI1/4/5 | - | - | 50 | |
| | | Master mode 1.7 V < $V_{DD}$ < 3.6 V SPI1/2/3/4/5 | - | - | 25 | |
| | | Slave transmitter/full duplex mode 2.7 V < $V_{DD}$ < 3.6 V SPI1//4/5 | - | - | 50 | |
| | | Slave transmitter/full duplex mode 1.7 V < $V_{DD}$ < 3.6 V SPI1/4/5 | - | - | 35(2) | |
| | | Slave receiver mode, 1.7 V < $V_{DD}$ < 3.6 V SPI1/4/5 | - | - | 50 | |
| | | Slave mode, 1.7 V < $V_{DD}$ < 3.6 V SPI2/3 | - | - | 25 | |
| Duty(SCK) | Duty cycle of SPI clock frequency | Slave mode | 30 | 50 | 70 | % |
| $t_{w(SCKH)}$ $t_{w(SCKL)}$ | SCK high and low time | Master mode, SPI presc = 2 | $T_{PCLK}$-1.5 | $T_{PCLK}$ | $T_{PCLK}$ +1.5 | ns |
| $t_{su(NSS)}$ | NSS setup time | Slave mode, SPI presc = 2 | $3T_{PCLK}$ | - | - | ns |
| $t_{h(NSS)}$ | NSS hold time | Slave mode, SPI presc = 2 | $2T_{PCLK}$ | - | - | ns |
| $t_{su(MI)}$ | Data input setup time | Master mode | 4.5 | - | - | ns |
| $t_{su(SI)}$ | | Slave mode | 1.5 | - | - | ns |
| $t_{h(MI)}$ | Data input hold time | Master mode | 5 | - | - | ns |
| $t_{h(SI)}$ | | Slave mode | 0.5 | - | - | ns |



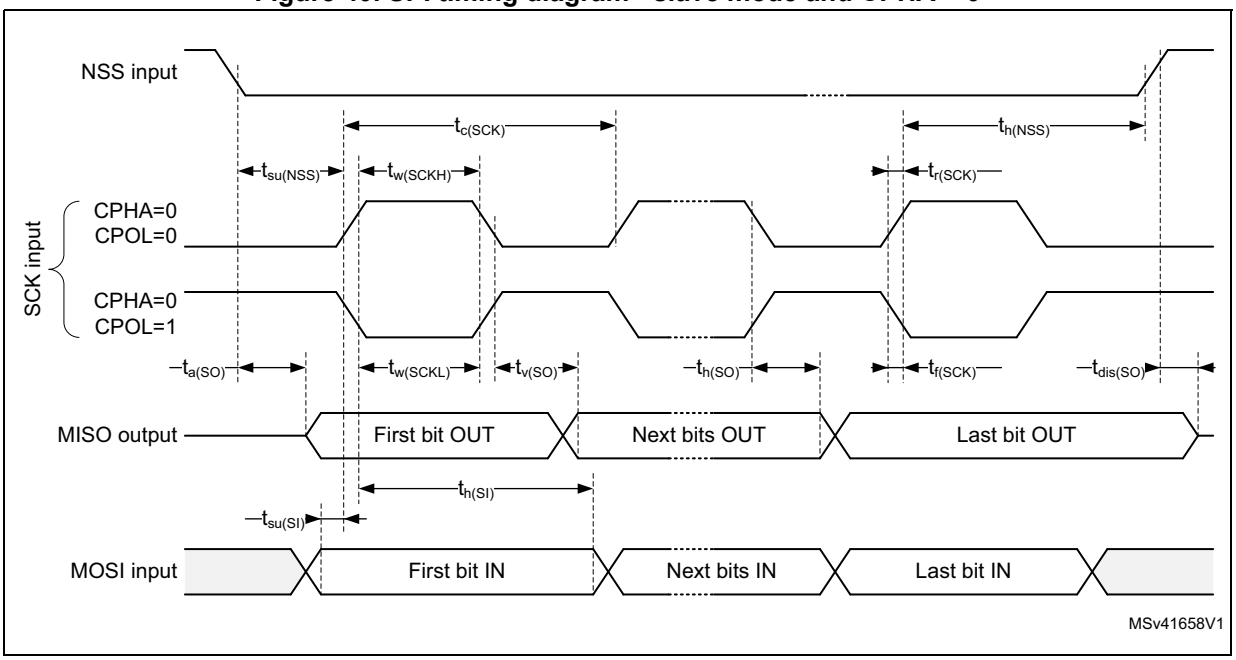
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**Table 65. SPI dynamic characteristics(1) (continued)**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $t_{a(SO)}$ | Data output access time | Slave mode | 7 | - | 21 | ns |
| $t_{dis(SO)}$ | Data output disable time | Slave mode | 5 | - | 12 | ns |
| $t_{v(SO)}$ | Data output valid time | Slave mode (after enable edge), 2.7 V < $V_{DD}$ < 3.6 V | - | 7.5 | 9 | ns |
| | | Slave mode (after enable edge), 1.7 V < $V_{DD}$ < 3.6 V | - | 7.5 | 14 | ns |
| $t_{h(SO)}$ | Data output hold time | Slave mode (after enable edge), 1.7 V < $V_{DD}$ < 3.6 V | 5.5 | - | - | ns |
| $t_{v(MO)}$ | Data output valid time | Master mode (after enable edge) | - | 3 | 8 | ns |
| $t_{h(MO)}$ | Data output hold time | Master mode (after enable edge) | 2 | - | - | ns |

1. Guaranteed by characterization, not tested in production.
2. Maximum frequency in Slave transmitter mode is determined by the sum of $t_{v(SO)}$ and $t_{su(MI)}$ which has to fit into SCK low or high phase preceding the SCK sampling edge. This value can be achieved when the SPI communicates with a master having $t_{su(MI)}$ = 0 while Duty(SCK) = 50%

**Figure 40. SPI timing diagram - slave mode and CPHA = 0**






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**Figure 41. SPI timing diagram - slave mode and CPHA = 1(1)**

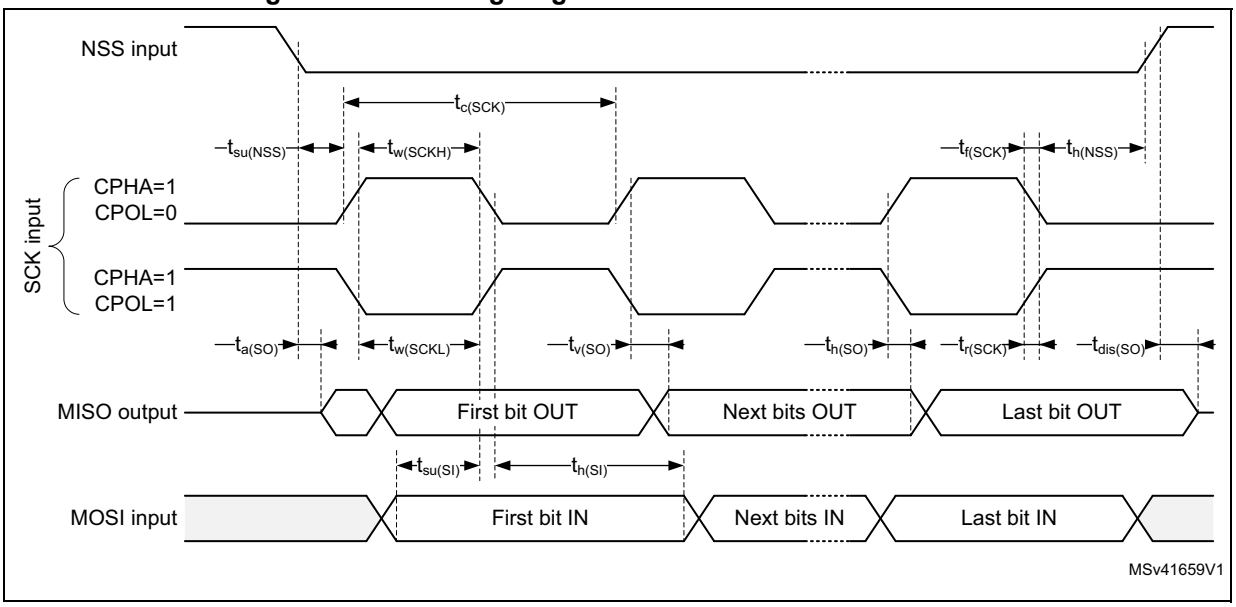
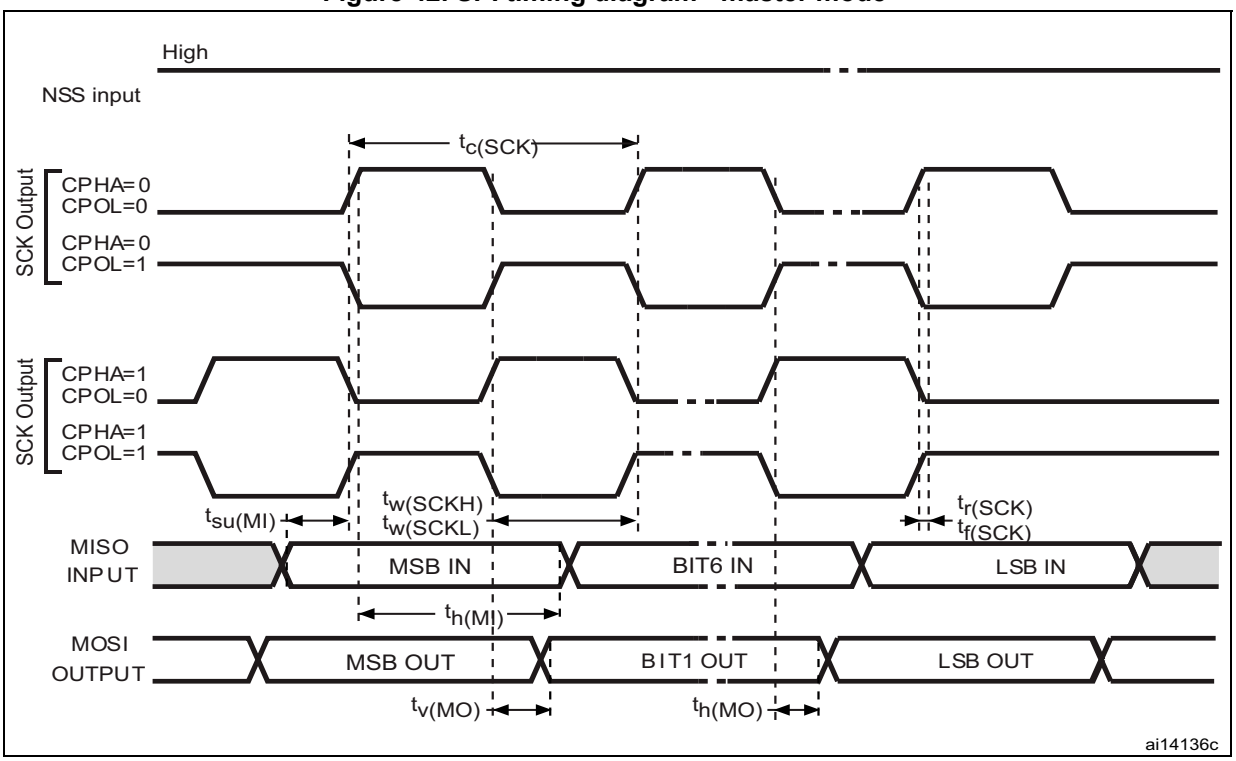



**Figure 42. SPI timing diagram - master mode(1)**






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### I²S interface characteristics

Unless otherwise specified, the parameters given in *Table 66* for the I²S interface are derived from tests performed under the ambient temperature, $f_{PCLKx}$ frequency and $V_{DD}$ supply voltage conditions summarized in *Table 16*, with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 10
- Capacitive load C = 30 pF
- Measurement points are done at CMOS levels: $0.5V_{DD}$

Refer to *Section 6.3.16: I/O port characteristics* for more details on the input/output alternate function characteristics (CK, SD, WS).

**Table 66. I²S dynamic characteristics(1)**

| Symbol | Parameter | Conditions | Min | Max | Unit |
|---|---|---|---|---|---|
| $f_{MCK}$ | I2S Main clock output | - | 256x8K | 256xFs(2) | MHz |
| $f_{CK}$ | I2S clock frequency | Master data: 32 bits | - | 64xFs | MHz |
| | | Slave data: 32 bits | - | 64xFs | |
| $D_{CK}$ | I2S clock frequency duty cycle | Slave receiver | 30 | 70 | % |
| $t_{v(WS)}$ | WS valid time | Master mode | - | 5 | ns |
| $t_{h(WS)}$ | WS hold time | Master mode | 0 | - | |
| $t_{su(WS)}$ | WS setup time | Slave mode | 2 | - | |
| $t_{h(WS)}$ | WS hold time | Slave mode | 0.5 | - | |
| $t_{su(SD_MR)}$ | Data input setup time | Master receiver | 0 | - | |
| $t_{su(SD_SR)}$ | | Slave receiver | 2 | - | |
| $t_{h(SD_MR)}$ | Data input hold time | Master receiver | 0 | - | |
| $t_{h(SD_SR)}$ | | Slave receiver | 2.5 | - | |
| $t_{v(SD_ST)}$ | Data output valid time | Slave transmitter (after enable edge) | - | 15 | |
| $t_{v(SD_MT)}$ | | Master transmitter (after enable edge) | - | 2.5 | |
| $t_{h(SD_ST)}$ | Data output hold time | Slave transmitter (after enable edge) | 6 | - | |
| $t_{h(SD_MT)}$ | | Master transmitter (after enable edge) | 0 | - | |

1. Guaranteed by characterization, not tested in production.
2. The maximum value of 256xFs is 50 MHz (APB1 maximum frequency).

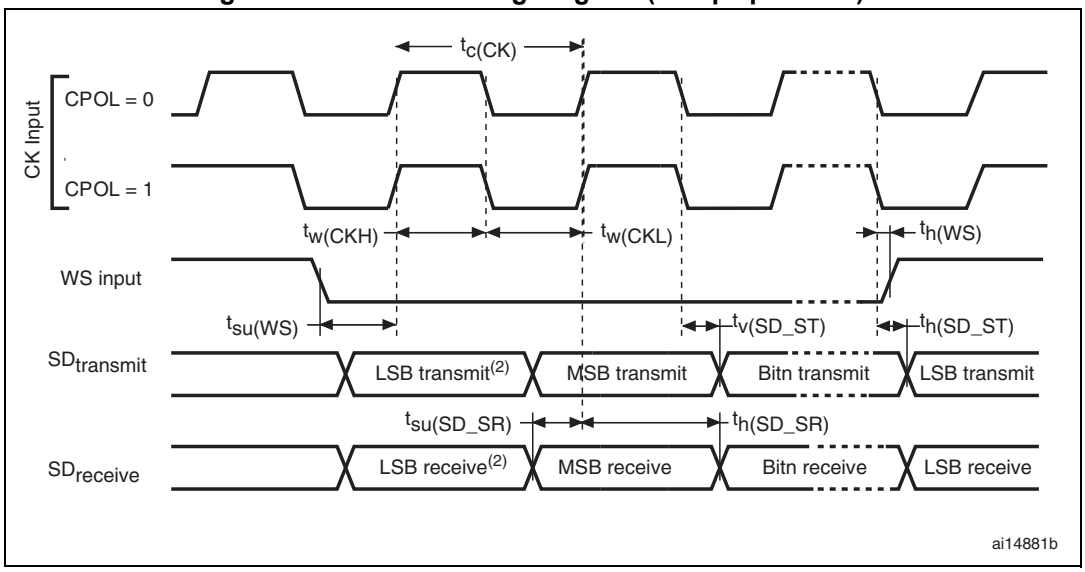
*Note: Refer to the I2S section of RM0383 reference manual for more details on the sampling frequency ($F_S$).*

*$f_{MCK}$, $f_{CK}$, and $D_{CK}$ values reflect only the digital peripheral behavior. The values of these parameters might be slightly impacted by the source clock precision. $D_{CK}$ depends mainly on the value of ODD bit. The digital contribution leads to a minimum value of (I2SDIV/(2*I2SDIV+ODD) and a maximum value of (I2SDIV+ODD)/(2*I2SDIV+ODD). $F_S$ maximum value is supported for each mode/condition.*



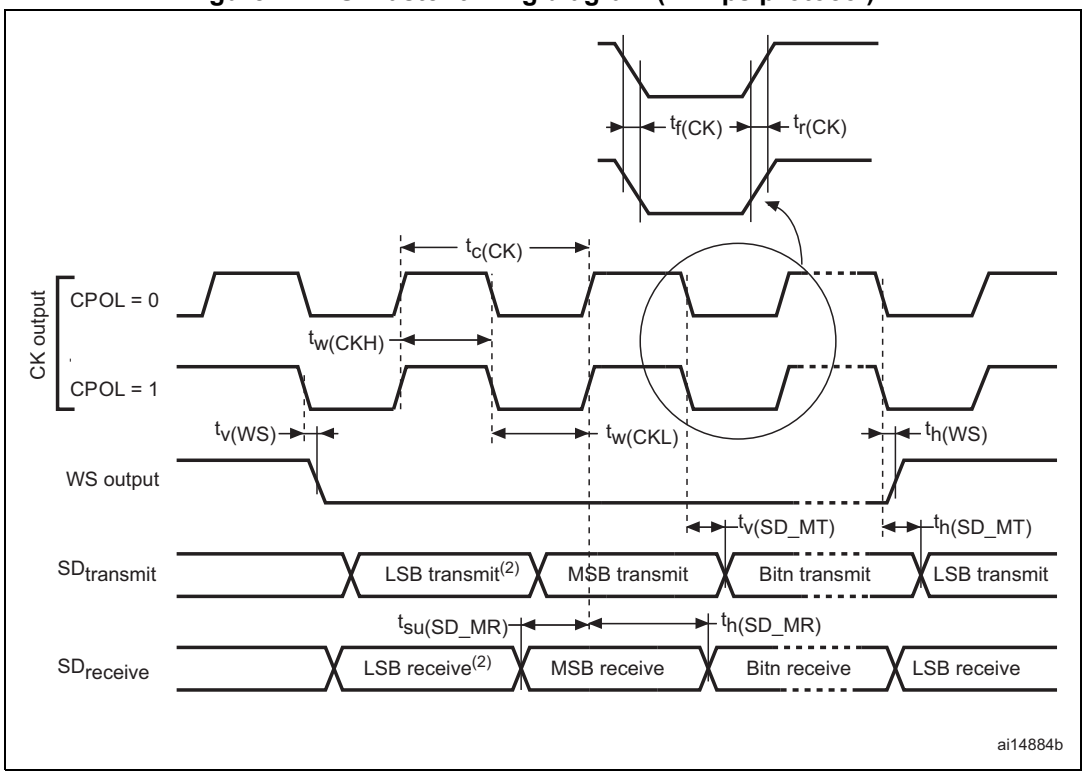
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**Figure 43. I²S slave timing diagram (Philips protocol)(1)**




1. LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.

**Figure 44. I²S master timing diagram (Philips protocol)(1)**




1. LSB transmit/receive of the previously transmitted byte. No LSB transmit/receive is sent before the first byte.



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### QSPI interface characteristics

Unless otherwise specified, the parameters given in the following tables for QSPI are derived from tests performed under the ambient temperature, $f_{AHB}$ frequency and $V_{DD}$ supply voltage conditions summarized in *Table 16*, with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 11
- Capacitive load C=20pF
- Measurement points are done at CMOS levels: 0.5VDD

Refer to *Section 6.3.16: I/O port characteristics* for more details on the input/output alternate function characteristics.

**Table 67. QSPI dynamic characteristics in SDR mode(1)**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $f_{SCK}$ $1/t_{c(SCK)}$ | QSPI clock frequency | Write mode 1.71 V≤$V_{DD}$≤3.6 V $C_{load}$ = 15 pF | - | - | 80 | MHz |
| | | Read mode 2.7 V<$V_{DD}$<3.6 V $C_{load}$ = 15 pF | - | - | 100 | |
| | | 1.71 V≤$V_{DD}$≤3.6 V | - | - | 50 | |
| $t_{w(CKH)}$ | QSPI clock high and low | - | ($T_{(CK)}$ / 2)-1 | - | $T_{(CK)}$ / 2 | ns |
| $t_{w(CKL)}$ | | | $T_{(CK)}$ / 2) | - | ($T_{(CK)}$ / 2)+1 | |
| $t_{s(IN)}$ | Data input setup time | - | 0.5 | - | - | |
| $t_{h(IN)}$ | Data input hold time | - | 3.5 | - | - | |
| $t_{v(OUT)}$ | Data output valid time | - | - | 1 | 1.5 | |
| $t_{h(OUT)}$ | Data output hold time | - | 0.5 | - | - | |

1. Guaranteed by characterization results, not tested in production.

**Table 68. QSPI dynamic characteristics in DDR mode(1)**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $f_{SCK}$ $1/t_{c(SCK)}$ | QSPI clock frequency | Write mode 1.71 V≤$V_{DD}$≤3.6 V $C_{load}$ = 15 pF | - | - | 80 | MHz |
| | | Read mode 2.7 V<$V_{DD}$<3.6 V $C_{load}$ = 15 pF | - | - | 80 | |
| | | 1.71 V≤$V_{DD}$≤3.6 V | - | - | 50 | |



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**Table 68. QSPI dynamic characteristics in DDR mode(1) (continued)**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $t_{w(CKH)}$ | QSPI clock high and low | - | $(T_{(CK)} / 2)-1$ | - | $T_{(CK)} / 2$ | ns |
| $t_{w(CKL)}$ | | | $T_{(CK)} / 2)$ | - | $(T_{(CK)} / 2)+1$ | |
| $t_{s(IN)}$ | Data input setup time | - | 0 | - | - | |
| $t_{h(IN)}$ | Data input hold time | - | 4 | - | - | |
| $t_{v(OUT)}$ | Data output valid time | 2.7 V<$V_{DD}$<3.6 V | - | 8 | 10.5 | |
| | | 1.71 V<$V_{DD}$<3.6 V | - | 8 | 13 | |
| $t_{h(OUT)}$ | Data output hold time | - | 7.5 | - | - | |

1. Guaranteed by characterization results, not tested in production.

## USB OTG full speed (FS) characteristics

This interface is present in USB OTG FS controller.

**Table 69. USB OTG FS startup time**

| Symbol | Parameter | Max | Unit |
|---|---|---|---|
| $t_{STARTUP}$(1) | USB OTG FS transceiver startup time | 1 | µs |

1. Guaranteed by design, not tested in production.

**Table 70. USB OTG FS DC electrical characteristics**

| Symbol | | Parameter | Conditions | Min.(1) | Typ. | Max.(1) | Unit |
|---|---|---|---|---|---|---|---|
| Input levels | $V_{DD}$ | USB OTG FS operating voltage | | 3.0(2) | - | 3.6 | V |
| | $V_{DI}$(3) | Differential input sensitivity | I(USB_FS_DP/DM) | 0.2 | - | - | V |
| | $V_{CM}$(3) | Differential common mode range | Includes $V_{DI}$ range | 0.8 | - | 2.5 | |
| | $V_{SE}$(3) | Single ended receiver threshold | | 1.3 | - | 2.0 | |
| Output levels | $V_{OL}$ | Static output level low | $R_L$ of 1.5 kΩ to 3.6 V(4) | - | - | 0.3 | V |
| | $V_{OH}$ | Static output level high | $R_L$ of 15 kΩ to $V_{SS}$(4) | 2.8 | - | 3.6 | |
| $R_{PD}$ | | PA11, PA12 (USB_FS_DM/DP) | $V_{IN}$ = $V_{DD}$ | 17 | 21 | 24 | kΩ |
| | | PA9 (OTG_FS_VBUS) | | 0.65 | 1.1 | 2.0 | |
| $R_{PU}$ | | PA11, PA12 (USB_FS_DM/DP) | $V_{IN}$ = $V_{SS}$ | 1.5 | 1.8 | 2.1 | |
| | | PA9 (OTG_FS_VBUS) | $V_{IN}$ = $V_{SS}$ | 0.25 | 0.37 | 0.55 | |

1. All the voltages are measured from the local ground potential.



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2. The USB OTG FS functionality is ensured down to 2.7 V but not the full USB full speed electrical characteristics which are degraded in the 2.7-to-3.0 V $V_{DD}$ voltage range.
3. Guaranteed by design, not tested in production.
4. $R_L$ is the load connected on the USB OTG FS drivers.

*Note: When VBUS sensing feature is enabled, PA9 should be left at their default state (floating input), not as alternate function. A typical 200 µA current consumption of the embedded sensing block (current to voltage conversion to determine the different sessions) can be observed on PA9 when the feature is enabled.*

**Figure 45. USB OTG FS timings: definition of data signal rise and fall time**

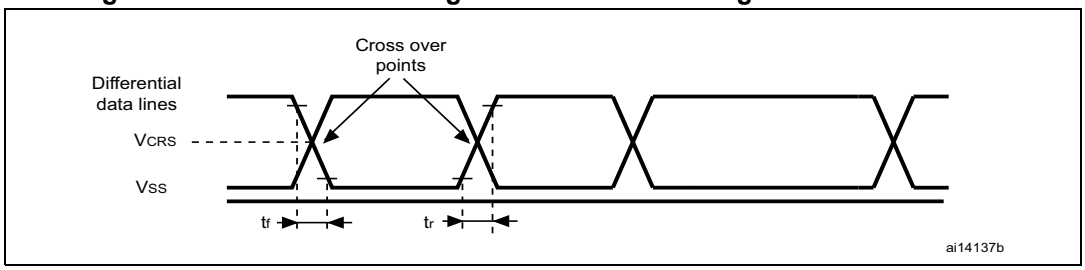



**Table 71. USB OTG FS electrical characteristics(1)**

| Driver characteristics | | | | | |
|---|---|---|---|---|---|
| **Symbol** | **Parameter** | **Conditions** | **Min** | **Max** | **Unit** |
| $t_r$ | Rise time(2) | $C_L$ = 50 pF | 4 | 20 | ns |
| $t_f$ | Fall time(2) | $C_L$ = 50 pF | 4 | 20 | ns |
| $t_{rfm}$ | Rise/ fall time matching | $t_r/t_f$ | 90 | 110 | % |
| $V_{CRS}$ | Output signal crossover voltage | | 1.3 | 2.0 | V |

1. Guaranteed by design, not tested in production.
2. Measured from 10% to 90% of the data signal. For more detailed informations, refer to USB Specification - Chapter 7 (version 2.0).

## CAN (controller area network) interface

Refer to *Section 6.3.16: I/O port characteristics* for more details on the input/output alternate function characteristics (CANx_TX and CANx_RX).



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### 6.3.20 12-bit ADC characteristics

Unless otherwise specified, the parameters given in *Table 72* are derived from tests performed under the ambient temperature, $f_{PCLK2}$ frequency and $V_{DDA}$ supply voltage conditions summarized in *Table 16*.

**Table 72. ADC characteristics**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $V_{DDA}$ | Power supply | $V_{DDA}$ –$V_{REF+}$ < 1.2 V | 1.7(1) | - | 3.6 | V |
| $V_{REF+}$ | Positive reference voltage | | 1.7(1) | - | $V_{DDA}$ | V |
| $f_{ADC}$ | ADC clock frequency | $V_{DDA}$ = 1.7(1) to 2.4 V | 0.6 | 15 | 18 | MHz |
| | | $V_{DDA}$ = 2.4 to 3.6 V | 0.6 | 30 | 36 | MHz |
| $f_{TRIG}$(2) | External trigger frequency | $f_{ADC}$ = 30 MHz, 12-bit resolution | - | - | 1764 | kHz |
| | | - | - | - | 17 | $1/f_{ADC}$ |
| $V_{AIN}$ | Conversion voltage range(3) | - | 0 ($V_{SSA}$ or $V_{REF-}$ tied to ground) | - | $V_{REF+}$ | V |
| $R_{AIN}$(2) | External input impedance | See *Equation 1* for details | - | - | 50 | kΩ |
| $R_{ADC}$(2)(4) | Sampling switch resistance | - | - | - | 6 | kΩ |
| $C_{ADC}$(2) | Internal sample and hold capacitor | - | - | 4 | 7 | pF |
| $t_{lat}$(2) | Injection trigger conversion latency | $f_{ADC}$ = 30 MHz | - | - | 0.100 | µs |
| | | - | - | - | 3(5) | $1/f_{ADC}$ |
| $t_{latr}$(2) | Regular trigger conversion latency | $f_{ADC}$ = 30 MHz | - | - | 0.067 | µs |
| | | - | - | - | 2(5) | $1/f_{ADC}$ |
| $t_S$(2) | Sampling time | $f_{ADC}$ = 30 MHz | 0.100 | - | 16 | µs |
| | | - | 3 | - | 480 | $1/f_{ADC}$ |
| $t_{STAB}$(2) | Power-up time | - | - | 2 | 3 | µs |
| $t_{CONV}$(2) | Total conversion time (including sampling time) | $f_{ADC}$ = 30 MHz 12-bit resolution | 0.50 | - | 16.40 | µs |
| | | $f_{ADC}$ = 30 MHz 10-bit resolution | 0.43 | - | 16.34 | µs |
| | | $f_{ADC}$ = 30 MHz 8-bit resolution | 0.37 | - | 16.27 | µs |
| | | $f_{ADC}$ = 30 MHz 6-bit resolution | 0.30 | - | 16.20 | µs |
| | | 9 to 492 ($t_S$ for sampling +n-bit resolution for successive approximation) | | | | $1/f_{ADC}$ |



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**Table 72. ADC characteristics (continued)**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $f_S$(2) | Sampling rate ($f_{ADC}$ = 30 MHz, and $t_S$ = 3 ADC cycles) | 12-bit resolution Single ADC | - | - | 2 | Msps |
| | | 12-bit resolution Interleave Dual ADC mode | - | - | 3.75 | Msps |
| | | 12-bit resolution Interleave Triple ADC mode | - | - | 6 | Msps |
| $I_{VREF+}$(2) | ADC $V_{REF}$ DC current consumption in conversion mode | - | - | 300 | 500 | µA |
| $I_{VDDA}$(2) | ADC $V_{DDA}$ DC current consumption in conversion mode | - | - | 1.6 | 1.8 | mA |

1. $V_{DDA}$ minimum value of 1.7 V is possible with the use of an external power supply supervisor (refer to *Section 3.18.2: Internal reset OFF*).
2. Guaranteed by characterization, not tested in production.
3. $V_{REF+}$ is internally connected to $V_{DDA}$ and $V_{REF-}$ is internally connected to $V_{SSA}$.
4. $R_{ADC}$ maximum value is given for $V_{DD}$=1.7 V, and minimum value for $V_{DD}$=3.3 V.
5. For external triggers, a delay of $1/f_{PCLK2}$ must be added to the latency specified in *Table 72*.

**Equation 1: $R_{AIN}$ max formula**

$$R_{AIN} = \frac{(k - 0.5)}{f_{ADC} \times C_{ADC} \times \ln(2^{N+2})} - R_{ADC}$$

The formula above (*Equation 1*) is used to determine the maximum external impedance allowed for an error below 1/4 of LSB. N = 12 (from 12-bit resolution) and k is the number of sampling periods defined in the ADC_SMPR1 register.

**Table 73. ADC accuracy at $f_{ADC}$ = 18 MHz(1)**

| Symbol | Parameter | Test conditions | Typ | Max(2) | Unit |
|---|---|---|---|---|---|
| ET | Total unadjusted error | $f_{ADC}$ =18 MHz<br>$V_{DDA}$ = 1.7 to 3.6 V<br>$V_{REF}$ = 1.7 to 3.6 V<br>$V_{DDA} - V_{REF}$ < 1.2 V | ±3 | ±4 | LSB |
| EO | Offset error | | ±2 | ±3 | |
| EG | Gain error | | ±1 | ±3 | |
| ED | Differential linearity error | | ±1 | ±2 | |
| EL | Integral linearity error | | ±2 | ±3 | |

1. Better performance could be achieved in restricted $V_{DD}$, frequency and temperature ranges.
2. Guaranteed by characterization, not tested in production.



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**Table 74. ADC accuracy at $f_{ADC}$ = 30 MHz(1)**

| Symbol | Parameter | Test conditions | Typ | Max(2) | Unit |
|---|---|---|---|---|---|
| ET | Total unadjusted error | $f_{ADC}$ = 30 MHz, $R_{AIN}$ < 10 kΩ, $V_{DDA}$ = 2.4 to 3.6 V, $V_{REF}$ = 1.7 to 3.6 V, $V_{DDA}$ –$V_{REF}$ < 1.2 V | ±2 | ±5 | LSB |
| EO | Offset error | | ±1.5 | ±2.5 | |
| EG | Gain error | | ±1.5 | ±4 | |
| ED | Differential linearity error | | ±1 | ±2 | |
| EL | Integral linearity error | | ±1.5 | ±3 | |

1. Better performance could be achieved in restricted $V_{DD}$, frequency and temperature ranges.
2. Guaranteed by characterization, not tested in production.

**Table 75. ADC accuracy at $f_{ADC}$ = 36 MHz(1)**

| Symbol | Parameter | Test conditions | Typ | Max(2) | Unit |
|---|---|---|---|---|---|
| ET | Total unadjusted error | $f_{ADC}$ =36 MHz, $V_{DDA}$ = 2.4 to 3.6 V, $V_{REF}$ = 1.7 to 3.6 V $V_{DDA}$ –$V_{REF}$ < 1.2 V | ±4 | ±7 | LSB |
| EO | Offset error | | ±2 | ±3 | |
| EG | Gain error | | ±3 | ±6 | |
| ED | Differential linearity error | | ±2 | ±3 | |
| EL | Integral linearity error | | ±3 | ±6 | |

1. Better performance could be achieved in restricted $V_{DD}$, frequency and temperature ranges.
2. Guaranteed by characterization, not tested in production.

**Table 76. ADC dynamic accuracy at $f_{ADC}$ = 18 MHz - limited test conditions(1)**

| Symbol | Parameter | Test conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| ENOB | Effective number of bits | $f_{ADC}$ =18 MHz $V_{DDA}$ = $V_{REF+}$= 1.7 V Input Frequency = 20 kHz Temperature = 25 °C | 10.3 | 10.4 | - | bits |
| SINAD | Signal-to-noise and distortion ratio | | 64 | 64.2 | - | dB |
| SNR | Signal-to-noise ratio | | 64 | 65 | - | |
| THD | Total harmonic distortion | | - | -72 | -67 | |

1. Guaranteed by characterization, not tested in production.

**Table 77. ADC dynamic accuracy at $f_{ADC}$ = 36 MHz - limited test conditions(1)**

| Symbol | Parameter | Test conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| ENOB | Effective number of bits | $f_{ADC}$ = 36 MHz $V_{DDA}$ = $V_{REF+}$ = 3.3 V Input Frequency = 20 kHz Temperature = 25 °C | 10.6 | 10.8 | - | bits |
| SINAD | Signal-to noise and distortion ratio | | 66 | 67 | - | dB |
| SNR | Signal-to noise ratio | | 64 | 68 | - | |
| THD | Total harmonic distortion | | - | -72 | -70 | |

1. Guaranteed by characterization, not tested in production.

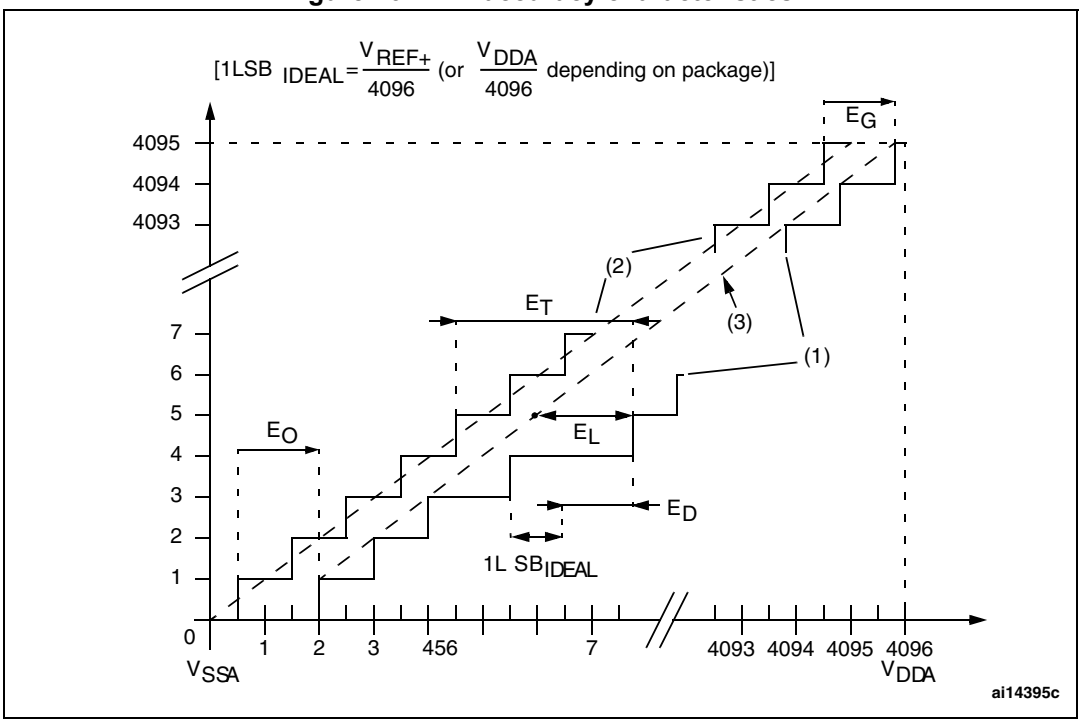


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Note: ADC accuracy vs. negative injection current: injecting a negative current on any analog input pins should be avoided as this significantly reduces the accuracy of the conversion being performed on another analog input. It is recommended to add a Schottky diode (pin to ground) to analog pins which may potentially inject negative currents.

Any positive injection current within the limits specified for $I_{INJ(PIN)}$ and $\Sigma I_{INJ(PIN)}$ in *Section 6.3.16* does not affect the ADC accuracy.

**Figure 46. ADC accuracy characteristics**

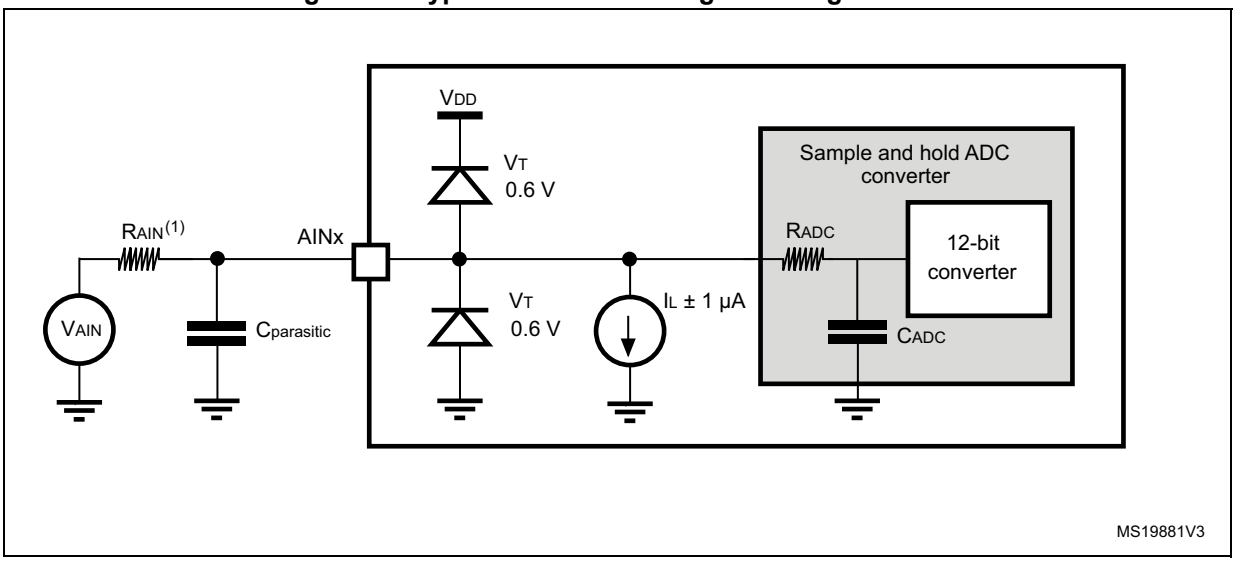



1. See also *Table 74*.
2. Example of an actual transfer curve.
3. Ideal transfer curve.
4. End point correlation line.
5. $E_T$ = Total Unadjusted Error: maximum deviation between the actual and the ideal transfer curves.
   EO = Offset Error: deviation between the first actual transition and the first ideal one.
   EG = Gain Error: deviation between the last ideal transition and the last actual one.
   ED = Differential Linearity Error: maximum deviation between actual steps and the ideal one.
   EL = Integral Linearity Error: maximum deviation between any actual transition and the end point correlation line.



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**Figure 47. Typical connection diagram using the ADC**




1. Refer to *Table 72* for the values of $R_{AIN}$, $R_{ADC}$ and $C_{ADC}$.
2. $C_{parasitic}$ represents the capacitance of the PCB (dependent on soldering and PCB layout quality) plus the pad capacitance (roughly 5 pF). A high $C_{parasitic}$ value downgrades conversion accuracy. To remedy this, $f_{ADC}$ should be reduced.

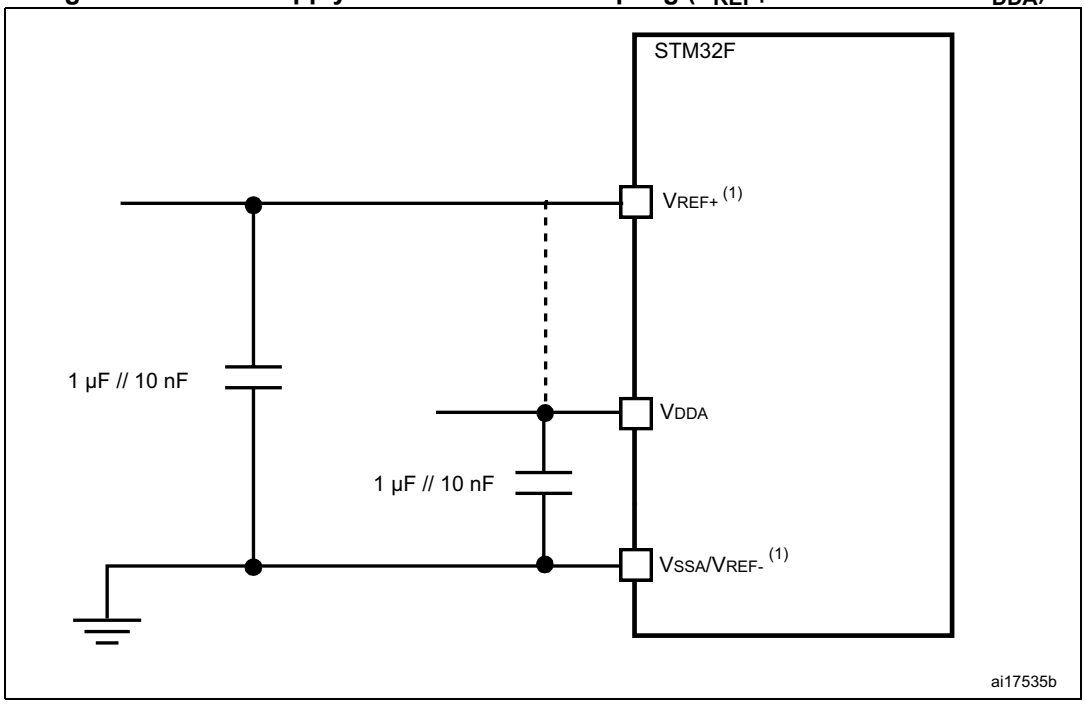


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### General PCB design guidelines

Power supply decoupling should be performed as shown in *Figure 48* or *Figure 49*, depending on whether $V_{REF+}$ is connected to $V_{DDA}$ or not. The 10 nF capacitors should be ceramic (good quality). They should be placed them as close as possible to the chip.

**Figure 48. Power supply and reference decoupling ($V_{REF+}$ not connected to $V_{DDA}$)**

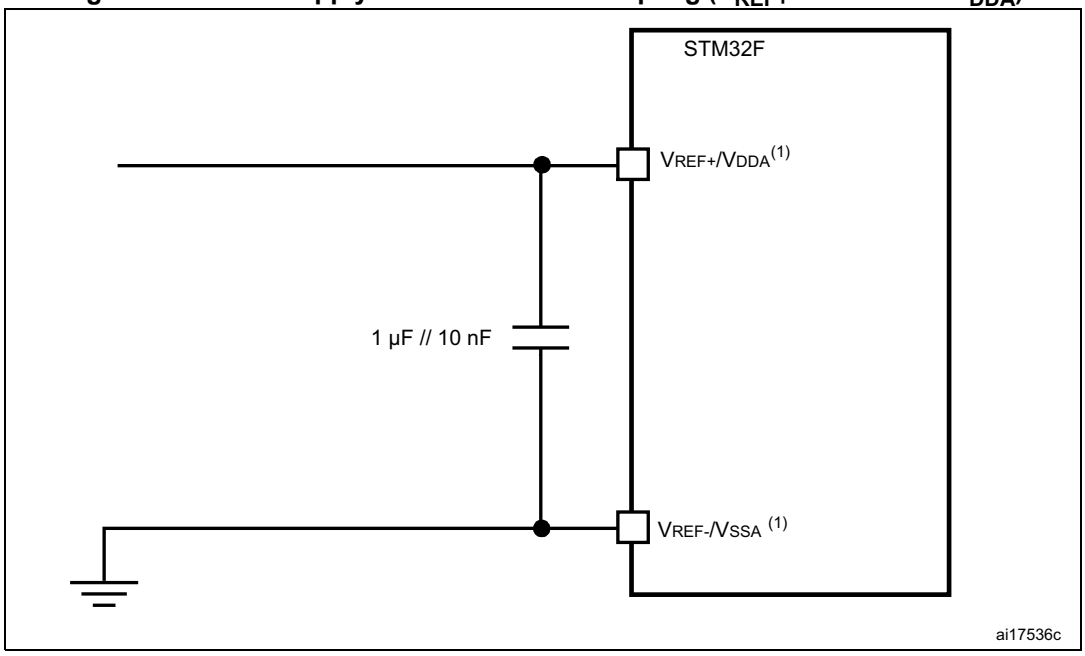



1. $V_{REF+}$ and $V_{REF-}$ inputs are both available on UFBGA100. $V_{REF+}$ is also available on LQFP100. When $V_{REF+}$ and $V_{REF-}$ are not available, they are internally connected to $V_{DDA}$ and $V_{SSA}$.



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**Figure 49. Power supply and reference decoupling ($V_{REF+}$ connected to $V_{DDA}$)**




1. $V_{REF+}$ and $V_{REF-}$ inputs are both available on UFBGA100. $V_{REF+}$ is also available on LQFP100. When $V_{REF+}$ and $V_{REF-}$ are not available, they are internally connected to $V_{DDA}$ and $V_{SSA}$.

## 6.3.21 Temperature sensor characteristics

**Table 78. Temperature sensor characteristics**

| Symbol | Parameter | Min | Typ | Max | Unit |
|---|---|---|---|---|---|
| $T_L$(1) | $V_{SENSE}$ linearity with temperature | - | ±1 | ±2 | °C |
| Avg_Slope(1) | Average slope | - | 2.5 | - | mV/°C |
| $V_{25}$(1) | Voltage at 25 °C | - | 0.76 | - | V |
| $t_{START}$(2) | Startup time | - | 6 | 10 | µs |
| $T_{S_temp}$(2) | ADC sampling time when reading the temperature (1 °C accuracy) | 10 | - | - | µs |

1. Guaranteed by characterization, not tested in production.
2. Guaranteed by design, not tested in production.

**Table 79. Temperature sensor calibration values**

| Symbol | Parameter | Memory address |
|---|---|---|
| TS_CAL1 | TS ADC raw data acquired at temperature of 30 °C, $V_{DDA}$= 3.3 V | 0x1FFF 7A2C - 0x1FFF 7A2D |
| TS_CAL2 | TS ADC raw data acquired at temperature of 110 °C, $V_{DDA}$= 3.3 V | 0x1FFF 7A2E - 0x1FFF 7A2F |



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### 6.3.22 $V_{BAT}$ monitoring characteristics

**Table 80. $V_{BAT}$ monitoring characteristics**

| Symbol | Parameter | Min | Typ | Max | Unit |
|---|---|---|---|---|---|
| R | Resistor bridge for $V_{BAT}$ | - | 50 | - | KΩ |
| Q | Ratio on $V_{BAT}$ measurement | - | 4 | - | |
| Er(1) | Error on Q | –1 | - | +1 | % |
| $T_{S_vbat}$(2)(2) | ADC sampling time when reading the $V_{BAT}$ 1 mV accuracy | 5 | - | - | µs |

1. Guaranteed by design, not tested in production.
2. Shortest sampling time can be determined in the application by multiple iterations.

### 6.3.23 Embedded reference voltage

The parameters given in *Table 81* are derived from tests performed under ambient temperature and $V_{DD}$ supply voltage conditions summarized in *Table 16*.

**Table 81. Embedded internal reference voltage**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $V_{REFINT}$ | Internal reference voltage | - 40 °C < $T_A$ < +125 °C | 1.18 | 1.21 | 1.24 | V |
| $T_{S_vrefint}$(1) | ADC sampling time when reading the internal reference voltage | - | 10 | - | - | µs |
| $V_{RERINT_s}$(2) | Internal reference voltage spread over the temperature range | $V_{DD}$ = 3V ± 10mV | - | 3 | 5 | mV |
| $T_{Coeff}$(2) | Temperature coefficient | - | - | 30 | 50 | ppm/°C |
| $t_{START}$(2) | Startup time | - | - | 6 | 10 | µs |

1. Shortest sampling time can be determined in the application by multiple iterations.
2. Guaranteed by design, not tested in production

**Table 82. Internal reference voltage calibration values**

| Symbol | Parameter | Memory address |
|---|---|---|
| $V_{REFIN_CAL}$ | Raw data acquired at temperature of 30 °C $V_{DDA}$ = 3.3 V | 0x1FFF 7A2A - 0x1FFF 7A2B |



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### 6.3.24 DFSDM characteristics

Unless otherwise specified, the parameters given in *Table 83* for DFSDM are derived from tests performed under the ambient temperature, $f_{APB2}$ frequency and $V_{DD}$ supply voltage conditions summarized in *Table 16: General operating conditions*.

- Output speed is set to OSPEEDRy[1:0] = 10
- Capacitive load C = 30 pF
- Measurement points are done at CMOS levels: 0.5 x VDD

Refer to *Section 6.3.16: I/O port characteristics* for more details on the input/output alternate function characteristics (DFSDM_CKINy, DFSDM_DATINy, DFSDM_CKOUT for DFSDM).

**Table 83. DFSDM characteristics(1)**

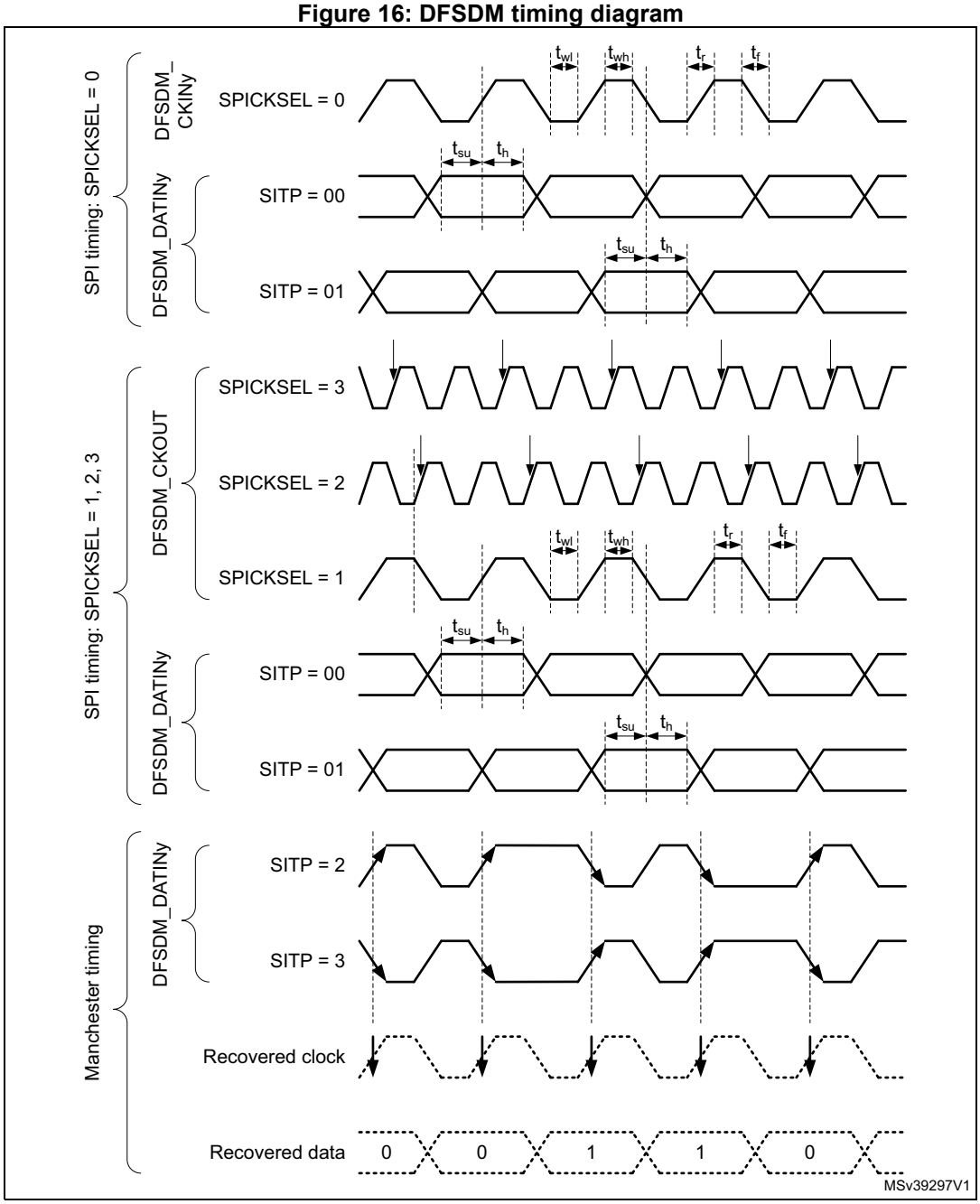
| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $f_{DFSDMCLK}$ | DFSDM clock | - | - | - | $f_{SYSCLK}$ | MHz |
| $f_{CKIN}$ ($1/T_{CKIN}$) | Input clock frequency | SPI mode (SITP[1:0] = 01) | - | - | 20 ($f_{DFSDMCLK}/4$) | |
| $f_{CKOUT}$ | Output clock frequency | - | - | - | 20 | MHz |
| $DuCy_{CKOUT}$ | Output clock frequency duty cycle | - | 30 | 50 | 75 | % |
| $t_{wh(CKIN)}$ $t_{wl(CKIN)}$ | Input clock high and low time | SPI mode (SITP[1:0] = 01), External clock mode (SPICKSEL[1:0] = 0) | $T_{CKIN}/2-0.5$ | $T_{CKIN}/2$ | - | ns |
| $t_{su}$ | Data input setup time | SPI mode (SITP[1:0]=01), External clock mode (SPICKSEL[1:0] = 0) | 1 | - | - | |
| $t_h$ | Data input hold time | SPI mode (SITP[1:0]=01), External clock mode (SPICKSEL[1:0] = 0) | 1 | - | - | |
| $T_{Manchester}$ | Manchester data period (recovered clock period) | Manchester mode (SITP[1:0] = 10 or 11), Internal clock mode (SPICKSEL[1:0] ≠ 0) | (CKOUT DIV+1) x $T_{DFSDMCLK}$ | - | (2 x CKOUTDIV) x $T_{DFSDMCLK}$ | |

1. Data based on characterization results, not tested in production.



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**Figure 16: DFSDM timing diagram**




## 6.3.25 FSMC characteristics

Unless otherwise specified, the parameters given in *Table 84* to *Table 91* for the FSMC interface are derived from tests performed under the ambient temperature, $f_{HCLK}$ frequency and $V_{DD}$ supply voltage conditions summarized in *Table 15*, with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 10
- Capacitance load C = 30 pF
- Measurement points are done at CMOS levels: $0.5.V_{DD}$



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Refer to *Section 6.3.16: I/O port characteristics* for more details on the input/output characteristics.

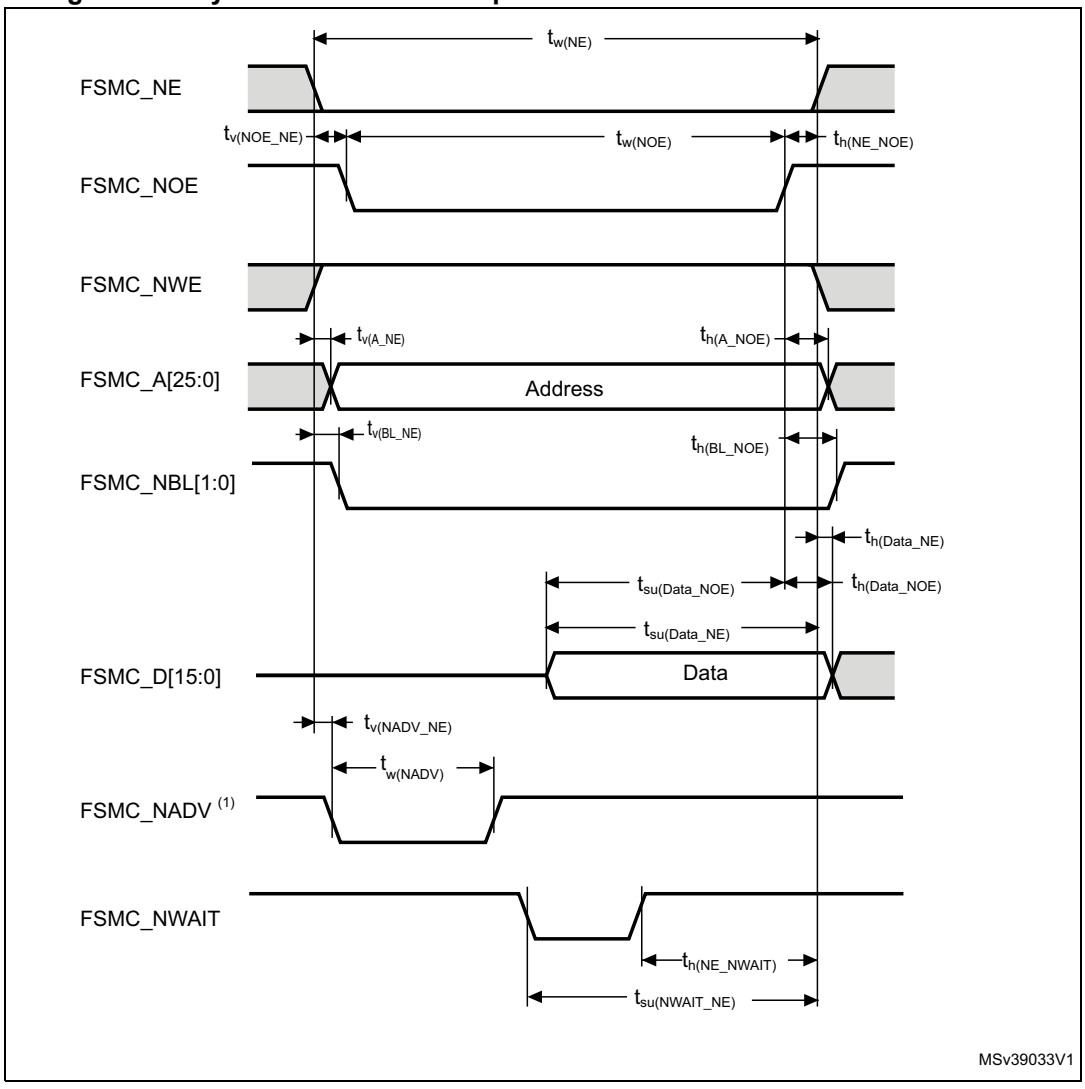
### Asynchronous waveforms and timings

*Figure 50* through *Figure 53* represent asynchronous waveforms and *Table 84* through *Table 91* provide the corresponding timings. The results shown in these tables are obtained with the following FSMC configuration:

- AddressSetupTime = 0x1
- AddressHoldTime = 0x1
- DataSetupTime = 0x1 (except for asynchronous NWAIT mode, DataSetupTime = 0x5)
- BusTurnAroundDuration = 0x0

In all timing tables, the $T_{HCLK}$ is the HCLK clock period.

**Figure 50. Asynchronous non-multiplexed SRAM/PSRAM/NOR read waveforms**




1. Mode 2/B, C and D only. In Mode 1, FSMC_NADV is not used.



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**Table 84. Asynchronous non-multiplexed SRAM/PSRAM/NOR - read timings(1)(2)**

| Symbol | Parameter | Min | Max | Unit |
|---|---|---|---|---|
| $t_{w(NE)}$ | FSMC_NE low time | $2T_{HCLK} – 1$ | $2\ T_{HCLK} + 0.5$ | ns |
| $t_{v(NOE_NE)}$ | FSMC_NEx low to FSMC_NOE low | 0 | 1 | |
| $t_{w(NOE)}$ | FSMC_NOE low time | $2T_{HCLK}$ - 1.5 | $2T_{HCLK}$ | |
| $t_{h(NE_NOE)}$ | FSMC_NOE high to FSMC_NE high hold time | 0 | - | |
| $t_{v(A_NE)}$ | FSMC_NEx low to FSMC_A valid | - | 1.5 | |
| $t_{h(A_NOE)}$ | Address hold time after FSMC_NOE high | 0 | - | |
| $t_{v(BL_NE)}$ | FSMC_NEx low to FSMC_BL valid | - | 0.5 | |
| $t_{h(BL_NOE)}$ | FSMC_BL hold time after FSMC_NOE high | 0 | - | |
| $t_{su(Data_NE)}$ | Data to FSMC_NEx high setup time | $T_{HCLK}$ - 1 | - | |
| $t_{su(Data_NOE)}$ | Data to FSMC_NOEx high setup time | $T_{HCLK}$ - 1 | - | |
| $t_{h(Data_NOE)}$ | Data hold time after FSMC_NOE high | 0 | - | |
| $t_{h(Data_NE)}$ | Data hold time after FSMC_NEx high | 0 | - | |
| $t_{v(NADV_NE)}$ | FSMC_NEx low to FSMC_NADV low | - | 0 | |
| $t_{w(NADV)}$ | FSMC_NADV low time | - | $T_{HCLK} + 0.5$ | |

1. $C_L$ = 30 pF.
2. Based on characterization, not tested in production.

**Table 85. Asynchronous non-multiplexed SRAM/PSRAM/NOR read - NWAIT timings(1)(2)**

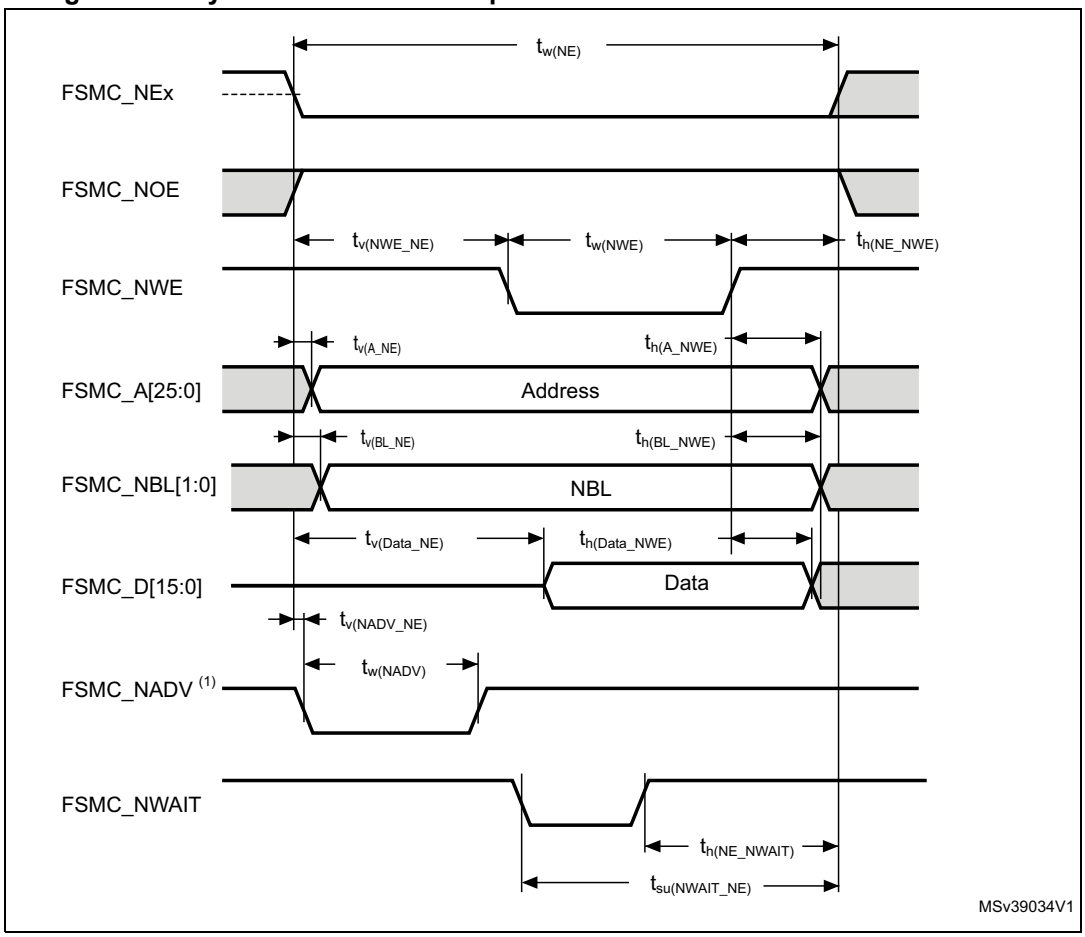
| Symbol | Parameter | Min | Max | Unit |
|---|---|---|---|---|
| $t_{w(NE)}$ | FSMC_NE low time | $7T_{HCLK}$ - 1 | $7T_{HCLK} + 0.5$ | ns |
| $t_{w(NOE)}$ | FSMC_NWE low time | $5T_{HCLK} – 1.5$ | $5T_{HCLK}$ | |
| $t_{w(NWAIT)}$ | FSMC_NWAIT low time | $T_{HCLK} – 0.5$ | - | |
| $t_{su(NWAIT_NE)}$ | FSMC_NWAIT valid before FSMC_NEx high | $5T_{HCLK}$ -1 | - | |
| $t_{h(NE_NWAIT)}$ | FSMC_NEx hold time after FSMC_NWAIT invalid | $4T_{HCLK} + 1$ | - | |

1. $C_L$ = 30 pF.
2. Based on characterization, not tested in production.



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**Figure 51. Asynchronous non-multiplexed SRAM/PSRAM/NOR write waveforms**




1. Mode 2/B, C and D only. In Mode 1, FSMC_NADV is not used.

**Table 86. Asynchronous non-multiplexed SRAM/PSRAM/NOR write timings(1)(2)**

| Symbol | Parameter | Min | Max | Unit |
|---|---|---|---|---|
| $t_{w(NE)}$ | FSMC_NE low time | 3 $T_{HCLK}$ - 1 | 3 $T_{HCLK}$ +0.5 | ns |
| $t_{v(NWE_NE)}$ | FSMC_NEx low to FSMC_NWE low | $T_{HCLK}$ + 0.5 | $T_{HCLK}$ + 0.5 | |
| $t_{w(NWE)}$ | FSMC_NWE low time | $T_{HCLK}$ – 1.5 | $T_{HCLK}$+ 1 | |
| $t_{h(NE_NWE)}$ | FSMC_NWE high to FSMC_NE high hold time | $T_{HCLK}$ - 1 | - | |
| $t_{v(A_NE)}$ | FSMC_NEx low to FSMC_A valid | - | 0.5 | |
| $t_{h(A_NWE)}$ | Address hold time after FSMC_NWE high | $T_{HCLK}$ - 0.5 | - | |
| $t_{v(BL_NE)}$ | FSMC_NEx low to FSMC_BL valid | - | 1 | |
| $t_{h(BL_NWE)}$ | FSMC_BL hold time after FSMC_NWE high | $T_{HCLK}$ - 1 | - | |
| $t_{v(Data_NE)}$ | Data to FSMC_NEx low to Data valid | - | $T_{HCLK}$ + 2 | |
| $t_{h(Data_NWE)}$ | Data hold time after FSMC_NWE high | $T_{HCLK}$ + 0.5 | - | |
| $t_{v(NADV_NE)}$ | FSMC_NEx low to FSMC_NADV low | - | 1 | |
| $t_{w(NADV)}$ | FSMC_NADV low time | - | $T_{HCLK}$+ 0.5 | |



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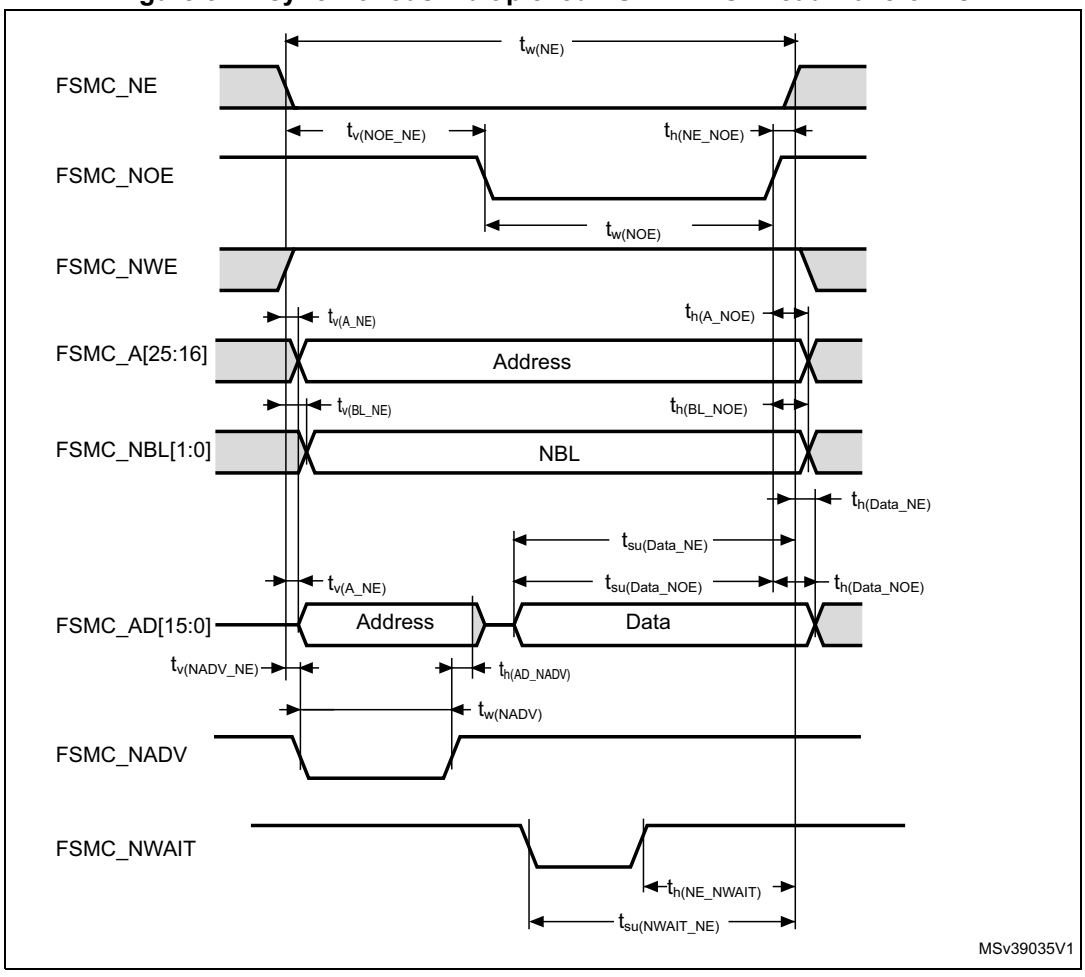
1. $C_L$ = 30 pF.
2. Based on characterization, not tested in production.

**Table 87. Asynchronous non-multiplexed SRAM/PSRAM/NOR write - NWAIT timings(1)(2)**

| Symbol | Parameter | Min | Max | Unit |
|---|---|---|---|---|
| $t_{w(NE)}$ | FSMC_NE low time | $8T_{HCLK}$ - 1 | $8T_{HCLK}$ + 0.5 | ns |
| $t_{w(NWE)}$ | FSMC_NWE low time | $6T_{HCLK}$ + 0.5 | $6T_{HCLK}$ + 1 | |
| $t_{su(NWAIT_NE)}$ | FSMC_NWAIT valid before FSMC_NEx high | $6T_{HCLK}$ + 0.5 | - | |
| $t_{h(NE_NWAIT)}$ | FSMC_NEx hold time after FSMC_NWAIT invalid | $4T_{HCLK}$ + 1 | - | |

1. $C_L$ = 30 pF.
2. Based on characterization, not tested in production.

**Figure 52. Asynchronous multiplexed PSRAM/NOR read waveforms**






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**Table 88. Asynchronous multiplexed PSRAM/NOR read timings(1)(2)**

| Symbol | Parameter | Min | Max | Unit |
|---|---|---|---|---|
| $t_{w(NE)}$ | FSMC_NE low time | $3T_{HCLK} – 1$ | $3T_{HCLK} + 0.5$ | ns |
| $t_{v(NOE_NE)}$ | FSMC_NEx low to FSMC_NOE low | $2T_{HCLK}$ | $2T_{HCLK} + 1$ | |
| $t_{tw(NOE)}$ | FSMC_NOE low time | $T_{HCLK} – 1.5$ | $T_{HCLK}$ | |
| $t_{h(NE_NOE)}$ | FSMC_NOE high to FSMC_NE high hold time | 0 | - | |
| $t_{v(A_NE)}$ | FSMC_NEx low to FSMC_A valid | - | 0.5 | |
| $t_{v(NADV_NE)}$ | FSMC_NEx low to FSMC_NADV low | 0 | 1 | |
| $t_{w(NADV)}$ | FSMC_NADV low time | $T_{HCLK} – 0.5$ | $T_{HCLK} + 0.5$ | |
| $t_{h(AD_NADV)}$ | FSMC_AD(address) valid hold time after FSMC_NADV high) | 0 | - | |
| $t_{h(A_NOE)}$ | Address hold time after FSMC_NOE high | $T_{HCLK} – 0.5$ | - | |
| $t_{h(BL_NOE)}$ | FSMC_BL time after FSMC_NOE high | 0 | - | |
| $t_{v(BL_NE)}$ | FSMC_NEx low to FSMC_BL valid | - | 0.5 | |
| $t_{su(Data_NE)}$ | Data to FSMC_NEx high setup time | $T_{HCLK}$ - 2 | - | |
| $t_{su(Data_NOE)}$ | Data to FSMC_NOE high setup time | $T_{HCLK}$ - 2 | - | |
| $t_{h(Data_NE)}$ | Data hold time after FSMC_NEx high | 0 | - | |
| $t_{h(Data_NOE)}$ | Data hold time after FSMC_NOE high | 0 | - | |

1. $C_L$ = 30 pF.
2. Based on characterization, not tested in production.

**Table 89. Asynchronous multiplexed PSRAM/NOR read-NWAIT timings(1)(2)**

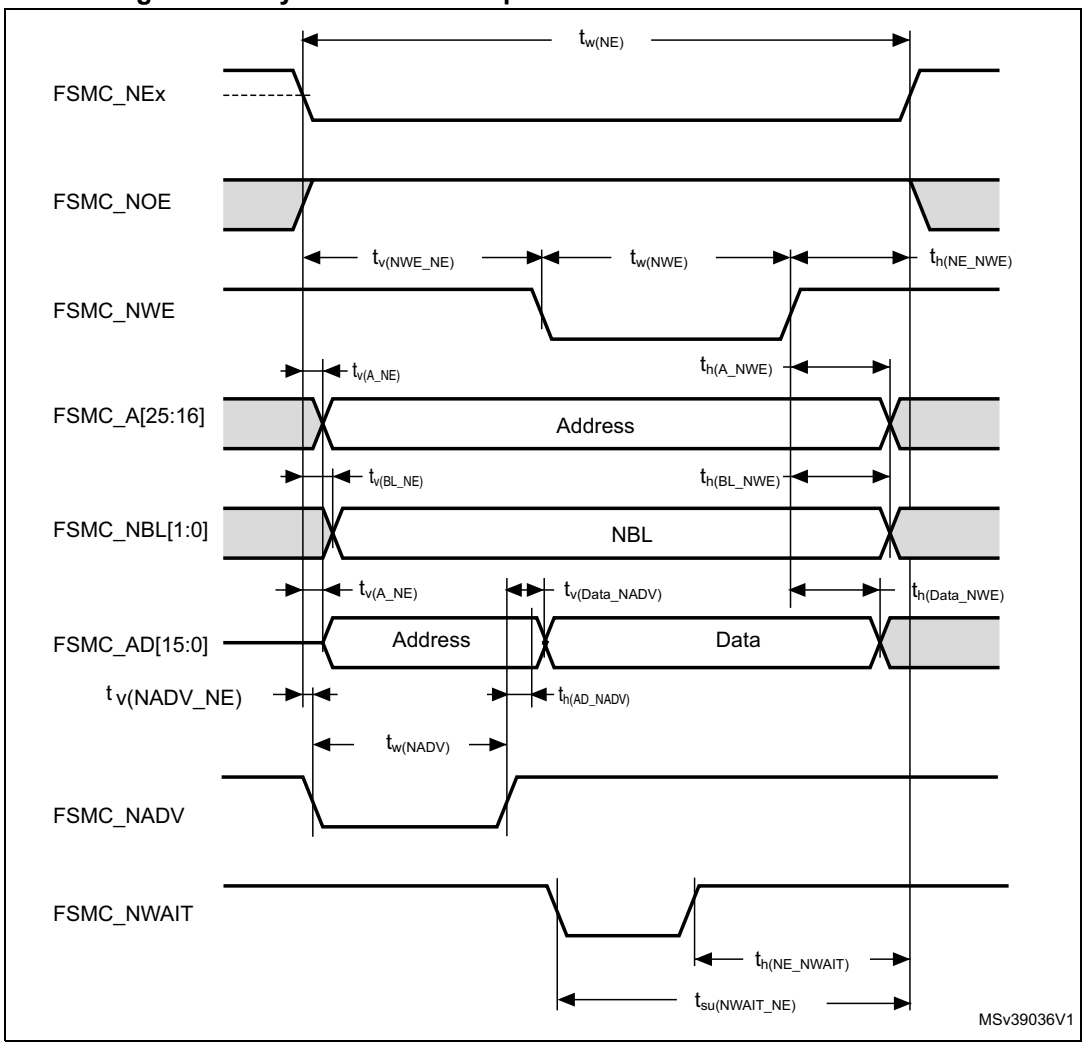
| Symbol | Parameter | Min | Max | Unit |
|---|---|---|---|---|
| $t_{w(NE)}$ | FSMC_NE low time | $8T_{HCLK}$ - 1 | $8T_{HCLK} + 0.5$ | ns |
| $t_{w(NOE)}$ | FSMC_NWE low time | $5T_{HCLK}$ | $5T_{HCLK} + 0.5$ | |
| $t_{su(NWAIT_NE)}$ | FSMC_NWAIT valid before FSMC_NEx high | $5T_{HCLK}$ - 1 | - | |
| $t_{h(NE_NWAIT)}$ | FSMC_NEx hold time after FSMC_NWAIT invalid | $4T_{HCLK} + 1$ | - | |

1. $C_L$ = 30 pF.
2. Based on characterization, not tested in production.



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**Figure 53. Asynchronous multiplexed PSRAM/NOR write waveforms**






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**Table 90. Asynchronous multiplexed PSRAM/NOR write timings(1)(2)**

| Symbol | Parameter | Min | Max | Unit |
|---|---|---|---|---|
| $t_{w(NE)}$ | FSMC_NE low time | $4T_{HCLK}$ - 1 | $4T_{HCLK}$+0.5 | ns |
| $t_{v(NWE_NE)}$ | FSMC_NEx low to FSMC_NWE low | $T_{HCLK}$ | $T_{HCLK}$ + 1 | |
| $t_{w(NWE)}$ | FSMC_NWE low time | $2T_{HCLK}$ - 1 | $2T_{HCLK}$ + 0.5 | |
| $t_{h(NE_NWE)}$ | FSMC_NWE high to FSMC_NE high hold time | $T_{HCLK}$ - 1.5 | - | |
| $t_{v(A_NE)}$ | FSMC_NEx low to FSMC_A valid | - | 2 | |
| $t_{v(NADV_NE)}$ | FSMC_NEx low to FSMC_NADV low | 0 | 1 | |
| $t_{w(NADV)}$ | FSMC_NADV low time | $T_{HCLK}$ – 0.5 | $T_{HCLK}$+ 0.5 | |
| $t_{h(AD_NADV)}$ | FSMC_AD(adress) valid hold time after FSMC_NADV high) | $T_{HCLK}$ | - | |
| $t_{h(A_NWE)}$ | Address hold time after FSMC_NWE high | $T_{HCLK}$- 1.5 | - | |
| $t_{h(BL_NWE)}$ | FSMC_BL hold time after FSMC_NWE high | $T_{HCLK}$ | - | |
| $t_{v(BL_NE)}$ | FSMC_NEx low to FSMC_BL valid | - | 1.5 | |
| $t_{v(Data_NADV)}$ | FSMC_NADV high to Data valid | - | $T_{HCLK}$ + 2 | |
| $t_{h(Data_NWE)}$ | Data hold time after FSMC_NWE high | $T_{HCLK}$ + 0.5 | - | |

1. $C_L$ = 30 pF.
2. Based on characterization, not tested in production.

**Table 91. Asynchronous multiplexed PSRAM/NOR write-NWAIT timings(1)(2)**

| Symbol | Parameter | Min | Max | Unit |
|---|---|---|---|---|
| $t_{w(NE)}$ | FSMC_NE low time | $9T_{HCLK}$ - 1 | $9T_{HCLK}$ + 0.5 | ns |
| $t_{w(NWE)}$ | FSMC_NWE low time | $7T_{HCLK}$ - 1 | $7T_{HCLK}$ + 0.5 | |
| $t_{su(NWAIT_NE)}$ | FSMC_NWAIT valid before FSMC_NEx high | $6T_{HCLK}$ -1 | - | |
| $t_{h(NE_NWAIT)}$ | FSMC_NEx hold time after FSMC_NWAIT invalid | $4T_{HCLK}$ + 1 | - | |

1. $C_L$ = 30 pF.
2. Based on characterization, not tested in production.

## Synchronous waveforms and timings

*Figure 54* through *Figure 57* represent synchronous waveforms and *Table 92* through *Table 95* provide the corresponding timings. The results shown in these tables are obtained with the following FSMC configuration:

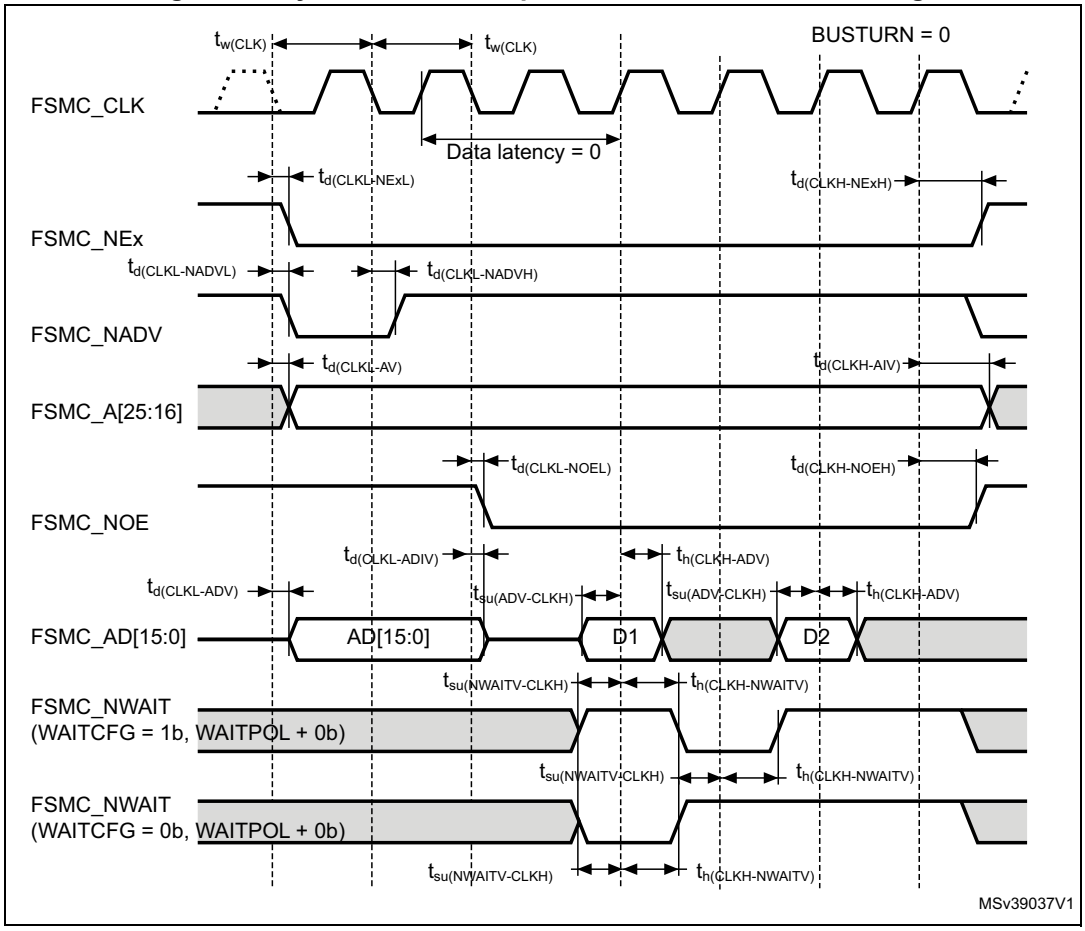
- BurstAccessMode = FSMC_BurstAccessMode_Enable;
- MemoryType = FSMC_MemoryType_CRAM;
- WriteBurst = FSMC_WriteBurst_Enable;
- CLKDivision = 1; (0 is not supported, see the STM32F446 reference manual: RM0390)
- DataLatency = 1 for NOR Flash; DataLatency = 0 for PSRAM



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In all timing tables, the $T_{HCLK}$ is the HCLK clock period (with maximum FSMC_CLK = 90 MHz).

**Figure 54. Synchronous multiplexed NOR/PSRAM read timings**






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**Table 92. Synchronous multiplexed NOR/PSRAM read timings(1)(2)**

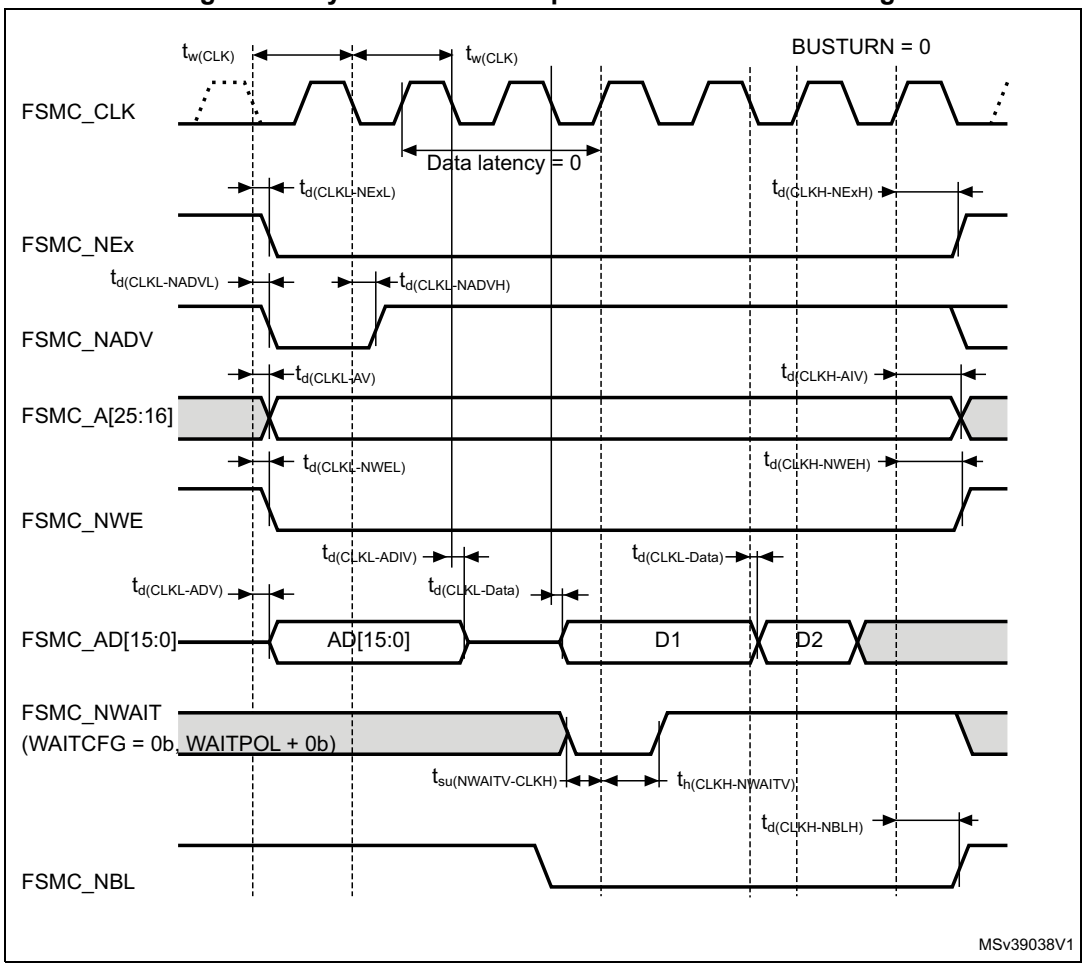
| Symbol | Parameter | Min | Max | Unit |
|---|---|---|---|---|
| $t_{w(CLK)}$ | FSMC_CLK period | $2T_{HCLK}$ - 0.5 | - | ns |
| $t_{d(CLKL-NExL)}$ | FSMC_CLK low to FSMC_NEx low (x=0..2) | - | 1 | |
| $t_{d(CLKH_NExH)}$ | FSMC_CLK high to FSMC_NEx high (x= 0…2) | $T_{HCLK}$ + 0.5 | - | |
| $t_{d(CLKL-NADVL)}$ | FSMC_CLK low to FSMC_NADV low | - | 1 | |
| $t_{d(CLKL-NADVH)}$ | FSMC_CLK low to FSMC_NADV high | 0 | - | |
| $t_{d(CLKL-AV)}$ | FSMC_CLK low to FSMC_Ax valid (x=16…25) | - | 2 | |
| $t_{d(CLKH-AIV)}$ | FSMC_CLK high to FSMC_Ax invalid (x=16…25) | $T_{HCLK}$ | - | |
| $t_{d(CLKL-NOEL)}$ | FSMC_CLK low to FSMC_NOE low | - | 1.5 | |
| $t_{d(CLKH-NOEH)}$ | FSMC_CLK high to FSMC_NOE high | $T_{HCLK}$ | - | |
| $t_{d(CLKL-ADV)}$ | FSMC_CLK low to FSMC_AD[15:0] valid | - | 2.5 | |
| $t_{d(CLKL-ADIV)}$ | FSMC_CLK low to FSMC_AD[15:0] invalid | 0 | - | |
| $t_{su(ADV-CLKH)}$ | FSMC_A/D[15:0] valid data before FSMC_CLK high | 1 | - | |
| $t_{h(CLKH-ADV)}$ | FSMC_A/D[15:0] valid data after FSMC_CLK high | 2 | - | |
| $t_{su(NWAIT-CLKH)}$ | FSMC_NWAIT valid before FSMC_CLK high | 2 | - | |
| $t_{h(CLKH-NWAIT)}$ | FSMC_NWAIT valid after FSMC_CLK high | 2 | - | |

1. $C_L$ = 30 pF.
2. Based on characterization, not tested in production.



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**Figure 55. Synchronous multiplexed PSRAM write timings**






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**Table 93. Synchronous multiplexed PSRAM write timings(1)(2)**

| Symbol | Parameter | Min | Max | Unit |
|---|---|---|---|---|
| $t_{w(CLK)}$ | FSMC_CLK period, $V_{DD}$ range= 2.7 to 3.6 V | $2T_{HCLK}$ - 0.5 | - | ns |
| $t_{d(CLKL-NExL)}$ | FSMC_CLK low to FSMC_NEx low (x= 0...2) | - | 1 | |
| $t_{d(CLKH-NExH)}$ | FSMC_CLK high to FSMC_NEx high (x= 0…2) | $T_{HCLK}$ + 0.5 | - | |
| $t_{d(CLKL-NADVL)}$ | FSMC_CLK low to FSMC_NADV low | - | 1 | |
| $t_{d(CLKL-NADVH)}$ | FSMC_CLK low to FSMC_NADV high | 0 | - | |
| $t_{d(CLKL-AV)}$ | FSMC_CLK low to FSMC_Ax valid (x=16…25) | - | 2 | |
| $t_{d(CLKH-AIV)}$ | FSMC_CLK high to FSMC_Ax invalid (x=16…25) | $T_{HCLK}$ | - | |
| $t_{d(CLKL-NWEL)}$ | FSMC_CLK low to FSMC_NWE low | - | 1.5 | |
| $t_{(CLKH-NWEH)}$ | FSMC_CLK high to FSMC_NWE high | $T_{HCLK}$ + 0.5 | - | |
| $t_{d(CLKL-ADV)}$ | FSMC_CLK low to FSMC_AD[15:0] valid | - | 2.5 | |
| $t_{d(CLKL-ADIV)}$ | FSMC_CLK low to FSMC_AD[15:0] invalid | 0 | - | |
| $t_{d(CLKL-DATA)}$ | FSMC_A/D[15:0] valid data after FSMC_CLK low | - | 4 | |
| $t_{d(CLKL-NBLL)}$ | FSMC_CLK low to FSMC_NBL low | - | 3 | |
| $t_{d(CLKH-NBLH)}$ | FSMC_CLK high to FSMC_NBL high | $T_{HCLK}$ | - | |
| $t_{su(NWAIT-CLKH)}$ | FSMC_NWAIT valid before FSMC_CLK high | 2 | - | |
| $t_{h(CLKH-NWAIT)}$ | FSMC_NWAIT valid after FSMC_CLK high | 2 | - | |

1. $C_L$ = 30 pF.
2. Based on characterization, not tested in production.



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**Figure 56. Synchronous non-multiplexed NOR/PSRAM read timings**

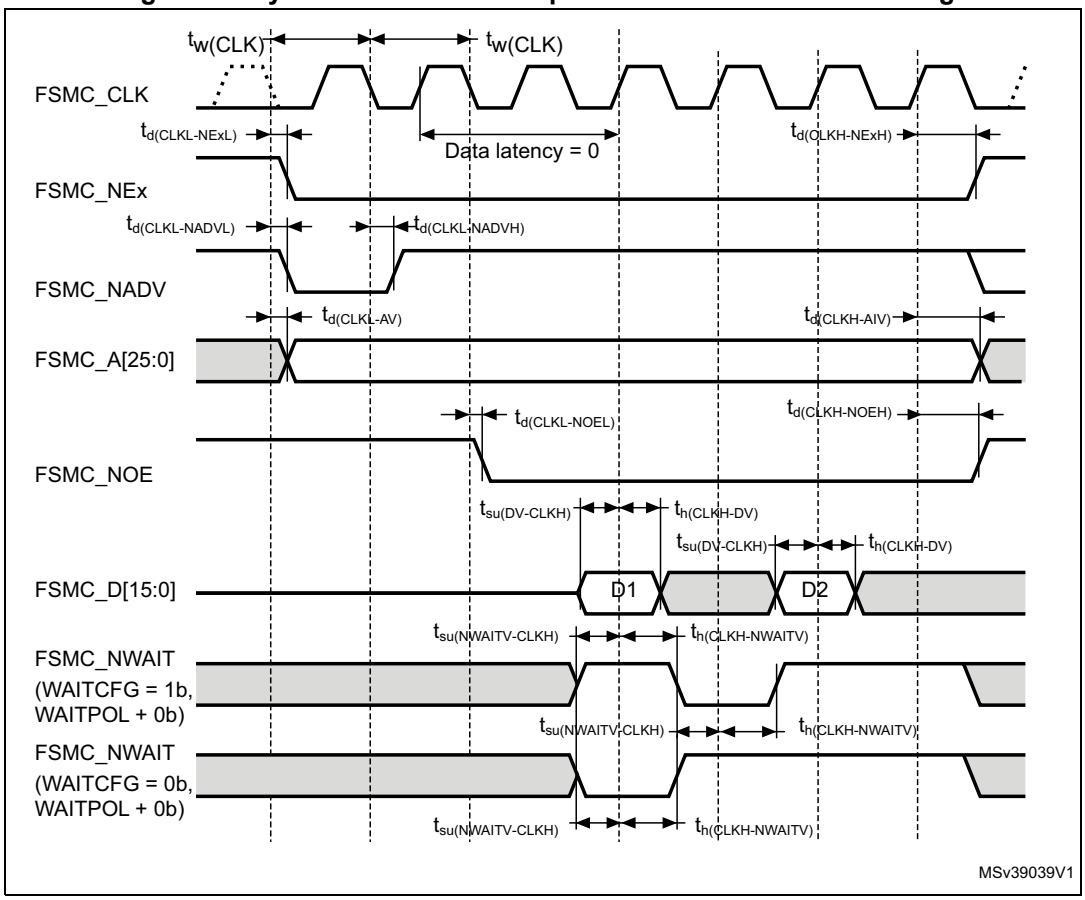



**Table 94. Synchronous non-multiplexed NOR/PSRAM read timings(1)(2)**

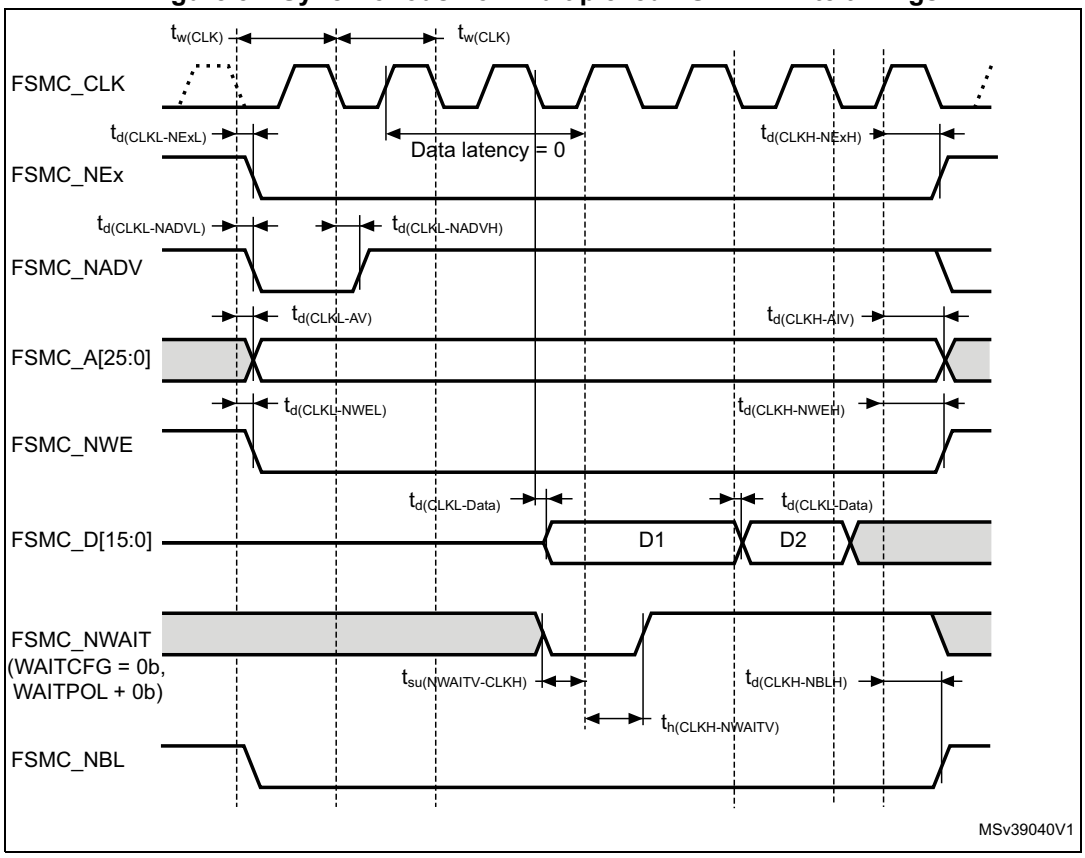
| Symbol | Parameter | Min | Max | Unit |
|---|---|---|---|---|
| $t_{w(CLK)}$ | FSMC_CLK period | $2T_{HCLK} – 0.5$ | - | ns |
| $t_{(CLKL-NExL)}$ | FSMC_CLK low to FSMC_NEx low (x=0..2) | - | 1 | |
| $t_{d(CLKH-NExH)}$ | FSMC_CLK high to FSMC_NEx high (x= 0…2) | $T_{HCLK}$ +0.5 | - | |
| $t_{d(CLKL-NADVL)}$ | FSMC_CLK low to FSMC_NADV low | - | 1 | |
| $t_{d(CLKL-NADVH)}$ | FSMC_CLK low to FSMC_NADV high | 0 | - | |
| $t_{d(CLKL-AV)}$ | FSMC_CLK low to FSMC_Ax valid (x=16…25) | - | 2 | |
| $t_{d(CLKH-AIV)}$ | FSMC_CLK high to FSMC_Ax invalid (x=16…25) | $T_{HCLK}$ | - | |
| $t_{d(CLKL-NOEL)}$ | FSMC_CLK low to FSMC_NOE low | - | 1.5 | |
| $t_{d(CLKH-NOEH)}$ | FSMC_CLK high to FSMC_NOE high | $T_{HCLK}$ | - | |
| $t_{su(DV-CLKH)}$ | FSMC_D[15:0] valid data before FSMC_CLK high | 1 | - | |
| $t_{h(CLKH-DV)}$ | FSMC_D[15:0] valid data after FSMC_CLK high | 2 | - | |
| $t_{su(NWAIT-CLKH)}$ | FSMC_NWAIT valid before FSMC_CLK high | 2 | - | |
| $t_{h(CLKH-NWAIT)}$ | FSMC_NWAIT valid after FSMC_CLK high | 2 | - | |



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1. $C_L$ = 30 pF.
2. Based on characterization, not tested in production.

**Figure 57. Synchronous non-multiplexed PSRAM write timings**






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**Table 95. Synchronous non-multiplexed PSRAM write timings(1)(2)**

| Symbol | Parameter | Min | Max | Unit |
|---|---|---|---|---|
| $t_{w(CLK)}$ | FSMC_CLK period | $2T_{HCLK} - 0.5$ | - | ns |
| $t_{d(CLKL-NExL)}$ | FSMC_CLK low to FSMC_NEx low (x=0..2) | - | 1 | |
| $t_{d(CLKH-NExH)}$ | FSMC_CLK high to FSMC_NEx high (x= 0…2) | $T_{HCLK} + 0.5$ | - | |
| $t_{d(CLKL-NADVL)}$ | FSMC_CLK low to FSMC_NADV low | - | 1 | |
| $t_{d(CLKL-NADVH)}$ | FSMC_CLK low to FSMC_NADV high | 0 | - | |
| $t_{d(CLKL-AV)}$ | FSMC_CLK low to FSMC_Ax valid (x=16…25) | - | 2 | |
| $t_{d(CLKH-AIV)}$ | FSMC_CLK high to FSMC_Ax invalid (x=16…25) | $T_{HCLK}$ | - | |
| $t_{d(CLKL-NWEL)}$ | FSMC_CLK low to FSMC_NWE low | - | 1.5 | |
| $t_{d(CLKH-NWEH)}$ | FSMC_CLK high to FSMC_NWE high | $T_{HCLK} + 0.5$ | - | |
| $t_{d(CLKL-Data)}$ | FSMC_D[15:0] valid data after FSMC_CLK low | - | 4 | |
| $t_{d(CLKL-NBLL)}$ | FSMC_CLK low to FSMC_NBL low | - | 3 | |
| $t_{d(CLKH-NBLH)}$ | FSMC_CLK high to FSMC_NBL high | $T_{HCLK}$ | - | |
| $t_{su(NWAIT-CLKH)}$ | FSMC_NWAIT valid before FSMC_CLK high | 2 | - | |
| $t_{h(CLKH-NWAIT)}$ | FSMC_NWAIT valid after FSMC_CLK high | 2 | - | |

1. $C_L$ = 30 pF.
2. Based on characterization, not tested in production.

## 6.3.26 SD/SDIO MMC/eMMC card host interface (SDIO) characteristics

Unless otherwise specified, the parameters given in *Table 96* for the SDIO are derived from tests performed under the ambient temperature, $f_{PCLK2}$ frequency and $V_{DD}$ supply voltage conditions summarized in *Table 16*, with the following configuration:

- Output speed is set to OSPEEDRy[1:0] = 10
- Capacitive load C = 30 pF
- Measurement points are done at CMOS levels: $0.5V_{DD}$

Refer to *Section 6.3.16: I/O port characteristics* for more details on the input/output characteristics.



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**Figure 58. SDIO high-speed mode**

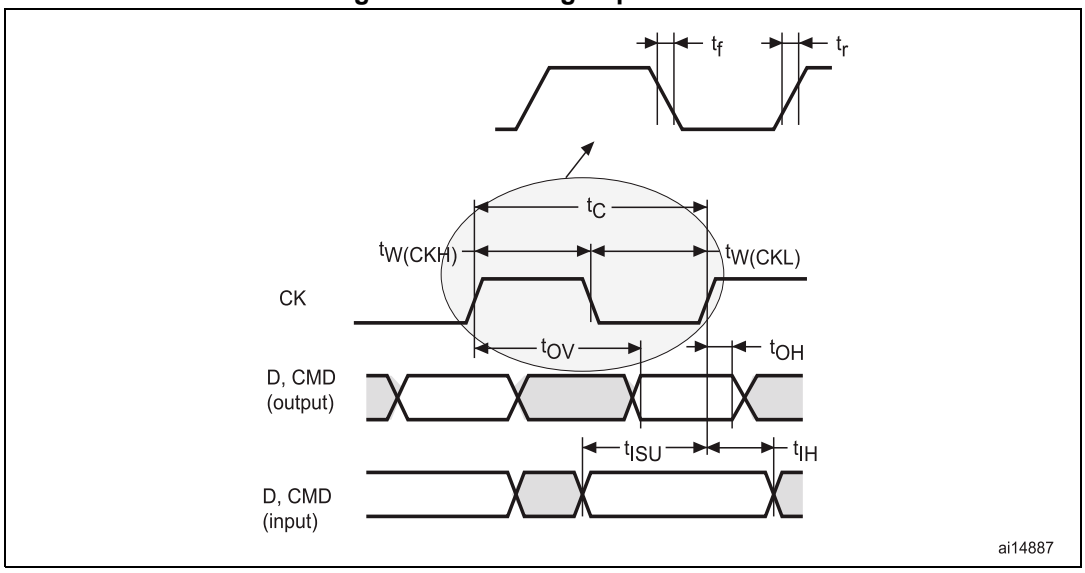



**Figure 59. SD default mode**

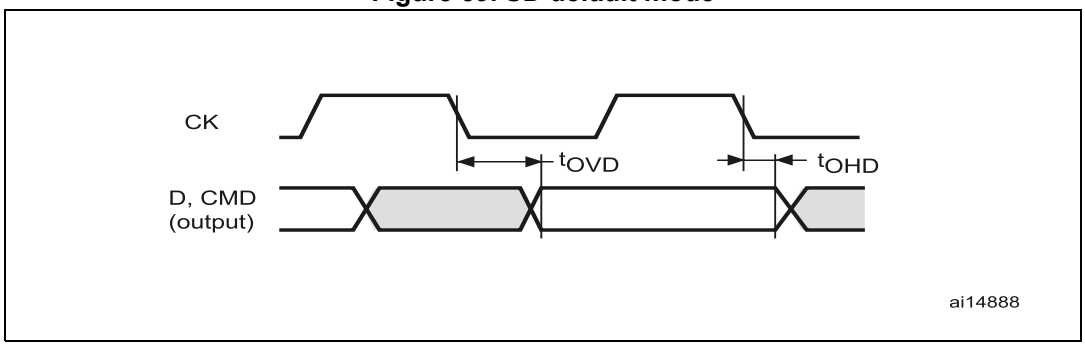



**Table 96. Dynamic characteristics: SD / MMC characteristics(1)(2)**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $f_{PP}$ | Clock frequency in data transfer mode | - | 0 | - | 50 | MHz |
| - | SDIO_CK/fPCLK2 frequency ratio | - | - | - | 8/3 | - |
| $t_{W(CKL)}$ | Clock low time | fpp =50MHz | 9.5 | 10.5 | - | ns |
| $t_{W(CKH)}$ | Clock high time | fpp =50MHz | 8.5 | 9.5 | - | |
| **CMD, D inputs (referenced to CK) in MMC and SD HS mode** | | | | | | |
| $t_{ISU}$ | Input setup time HS | fpp =50MHz | 4 | - | - | ns |
| $t_{IH}$ | Input hold time HS | fpp =50MHz | 2.5 | - | - | |
| **CMD, D outputs (referenced to CK) in MMC and SD HS mode** | | | | | | |
| $t_{OV}$ | Output valid time HS | fpp =50MHz | - | 13 | 13.5 | ns |
| $t_{OH}$ | Output hold time HS | fpp =50MHz | 11 | - | - | |



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**Table 96. Dynamic characteristics: SD / MMC characteristics(1)(2) (continued)**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| **CMD, D inputs (referenced to CK) in SD default mode** | | | | | | |
| $t_{ISUD}$ | Input setup time SD | fpp =25MHz | 2.5 | - | - | ns |
| $t_{IHD}$ | Input hold time SD | fpp =25MHz | 2.5 | - | - | |
| **CMD, D outputs (referenced to CK) in SD default mode** | | | | | | |
| $t_{OVD}$ | Output valid default time SD | fpp =25 MHz | - | 1.5 | 2 | ns |
| $t_{OHD}$ | Output hold default time SD | fpp =25 MHz | 0.5 | - | - | |

1. Guaranteed by characterization results, not tested in production.
2. $V_{DD}$ = 2.7 to 3.6 V.

**Table 97. Dynamic characteristics: eMMC characteristics $V_{DD}$ = 1.7 V to 1.9 V(1)(2)**

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---|---|---|---|---|---|
| $f_{PP}$ | Clock frequency in data transfer mode | - | 0 | - | 50 | MHz |
| - | SDIO_CK/fPCLK2 frequency ratio | - | - | - | 8/3 | - |
| $t_{W(CKL)}$ | Clock low time | fpp =50MHz | 9.5 | 10.5 | - | ns |
| $t_{W(CKH)}$ | Clock high time | fpp =50MHz | 8.5 | 9.5 | - | |
| **CMD, D inputs (referenced to CK) in eMMC mode** | | | | | | |
| $t_{ISU}$ | Input setup time HS | fpp =50MHz | 3.5 | - | - | ns |
| $t_{IH}$ | Input hold time HS | fpp =50MHz | 4 | - | - | |
| **CMD, D outputs (referenced to CK) in eMMC mode** | | | | | | |
| $t_{OV}$ | Output valid time HS | fpp =50MHz | - | 13.5 | 15 | ns |
| $t_{OH}$ | Output hold time HS | fpp =50MHz | 12 | - | - | |

1. Guaranteed by characterization results, not tested in production.
2. $C_{LOAD}$ = 20 pF.

## 6.3.27 RTC characteristics

**Table 98. RTC characteristics**

| Symbol | Parameter | Conditions | Min | Max |
|---|---|---|---|---|
| - | $f_{PCLK1}$/RTCCLK frequency ratio | Any read/write operation from/to an RTC register | 4 | - |



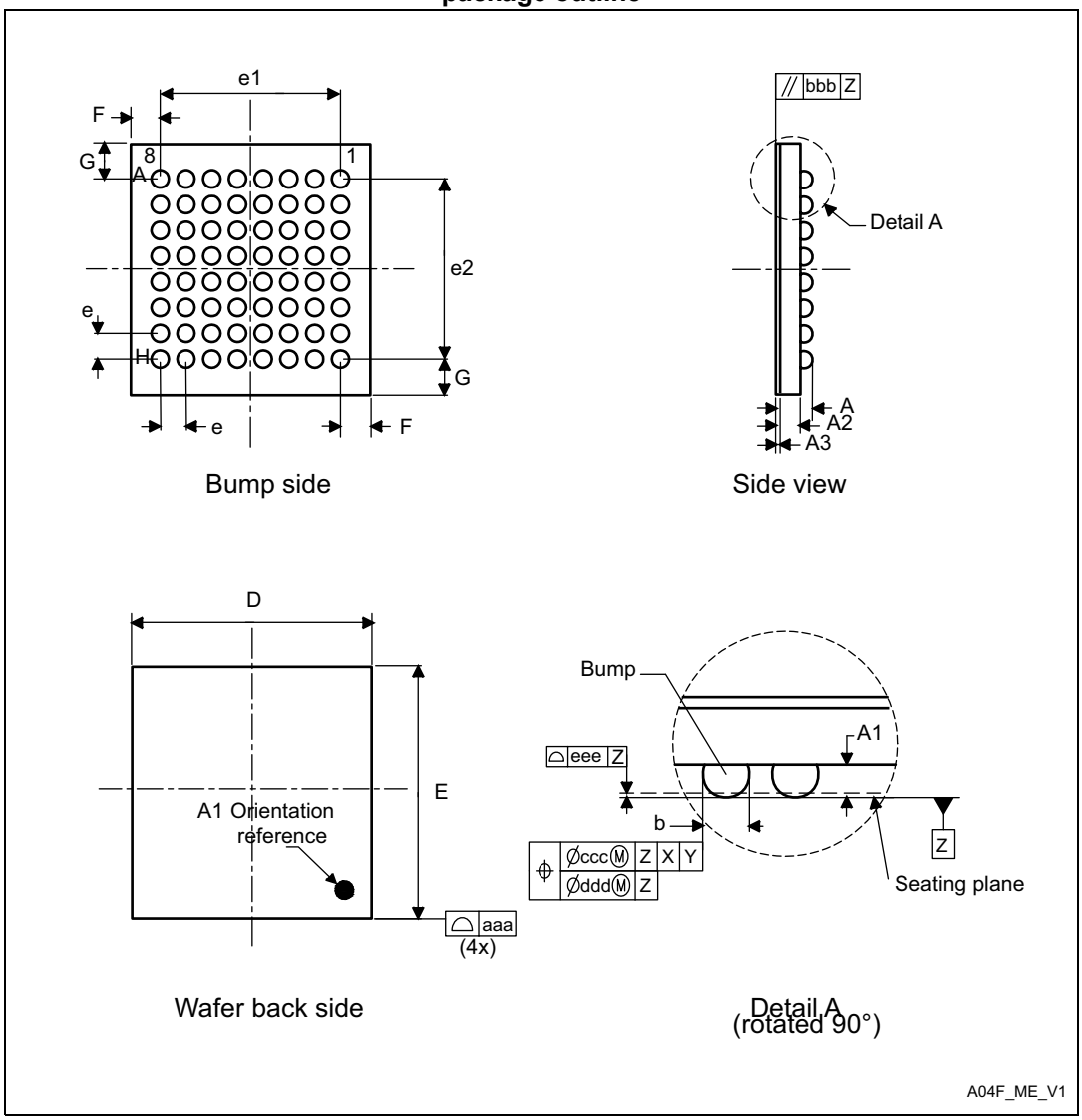
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# 7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: *www.st.com.* ECOPACK® is an ST trademark.

## 7.1 WLCSP64 package information

**Figure 60. WLCSP64 - 64-pin, 3.658 x 3.686 mm, 0.4 mm pitch wafer level chip scale package outline**




1. Drawing is not to scale.



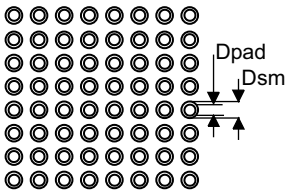
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**Table 99. WLCSP64 - 64-pin, 3.658 x 3.686 mm, 0.4 mm pitch wafer level chip scale package mechanical data**

| Symbol | millimeters | | | inches[1] | | |
|---|---|---|---|---|---|---|
| | Min | Typ | Max | Min | Typ | Max |
| A | 0.525 | 0.555 | 0.585 | 0.0207 | 0.0219 | 0.0230 |
| A1 | - | 0.170 | - | - | 0.0067 | - |
| A2 | - | 0.380 | - | - | 0.0150 | - |
| A3[2] | - | 0.025 | - | - | 0.0010 | - |
| b[3] | 0.220 | 0.250 | 0.280 | 0.0087 | 0.0098 | 0.0110 |
| D | 3.588 | 3.623 | 3.658 | 0.1413 | 0.1426 | 0.1440 |
| E | 3.616 | 3.651 | 3.686 | 0.1424 | 0.1437 | 0.1451 |
| e | - | 0.400 | - | - | 0.0157 | - |
| e1 | - | 2.800 | - | - | 0.1102 | - |
| e2 | - | 2.800 | - | - | 0.1102 | - |
| F | - | 0.4115 | - | - | 0.0162 | - |
| G | - | 0.4255 | - | - | 0.0168 | - |
| aaa | - | - | 0.100 | - | - | 0.0039 |
| bbb | - | - | 0.100 | - | - | 0.0039 |
| ccc | - | - | 0.100 | - | - | 0.0039 |
| ddd | - | - | 0.050 | - | - | 0.0020 |
| eee | - | - | 0.050 | - | - | 0.0020 |

1. Values in inches are converted from mm and rounded to 4 decimal digits.
2. Back side coating.
3. Dimension is measured at the maximum bump diameter parallel to primary datum Z.

**Figure 61. WLCSP64 - 64-pin, 3.658 x 3.686 mm, 0.4 mm pitch wafer level chip scale recommended footprint**






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**Table 100. WLCSP64 recommended PCB design rules (0.4 mm pitch)**

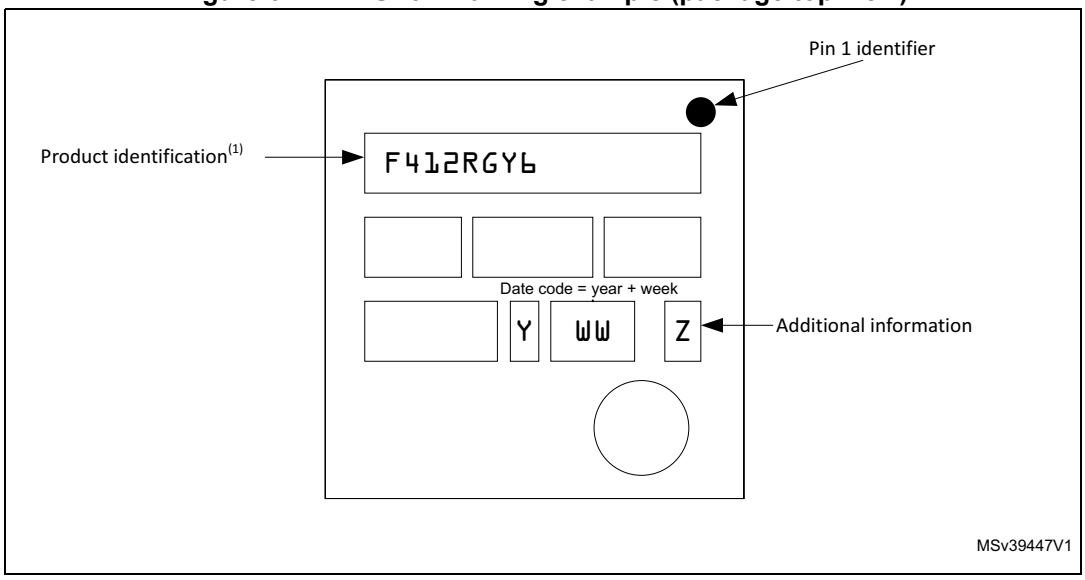
| Dimension | Recommended values |
|---|---|
| Pitch | 0.4 mm |
| Dpad | 0.225 mm |
| Dsm | 0.290 mm typ. (depends on the soldermask registration tolerance) |
| Stencil opening | 0.250 mm |
| Stencil thickness | 0.100 mm |

### Device marking for WLCSP64

The following figure gives an example of topside marking and pin 1 position identifier location.

Other optional marking or inset/upset marks, which depend on supply chain operations, are not indicated below.

**Figure 62. WLCSP64 marking example (package top view)**



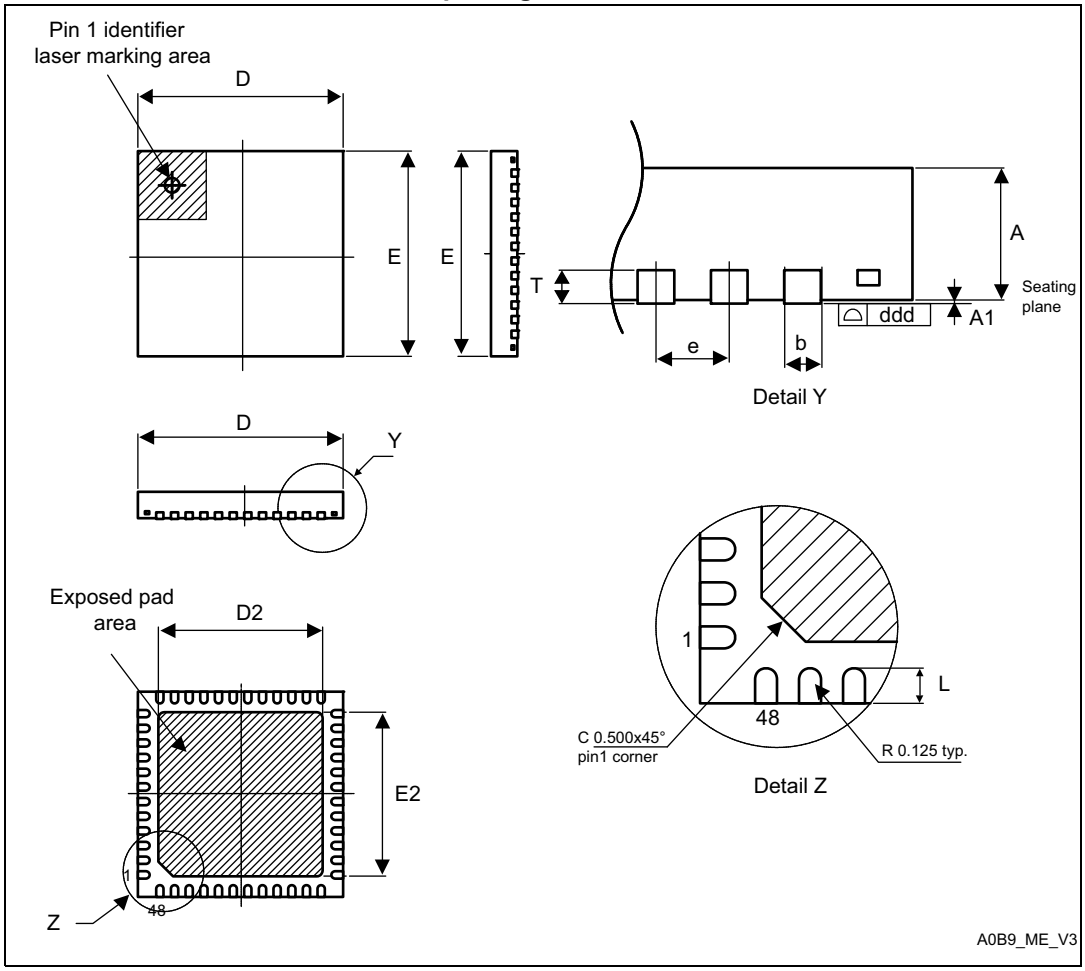

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## 7.2 UFQFPN48 package information

**Figure 63. UFQFPN48 - 48-lead, 7x7 mm, 0.5 mm pitch, ultra thin fine pitch quad flat package outline**




1. Drawing is not to scale.
2. All leads/pads should also be soldered to the PCB to improve the lead/pad solder joint life.
3. There is an exposed die pad on the underside of the UFQFPN package. It is recommended to connect and solder this back-side pad to PCB ground.

**Table 101. UFQFPN48 - 48-lead, 7x7 mm, 0.5 mm pitch, ultra thin fine pitch quad flat package mechanical data**

| Symbol | millimeters | | | inches[1] | | |
|---|---|---|---|---|---|---|
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 0.500 | 0.550 | 0.600 | 0.0197 | 0.0217 | 0.0236 |
| A1 | 0.000 | 0.020 | 0.050 | 0.0000 | 0.0008 | 0.0020 |
| D | 6.900 | 7.000 | 7.100 | 0.2717 | 0.2756 | 0.2795 |
| E | 6.900 | 7.000 | 7.100 | 0.2717 | 0.2756 | 0.2795 |
| D2 | 5.500 | 5.600 | 5.700 | 0.2165 | 0.2205 | 0.2244 |



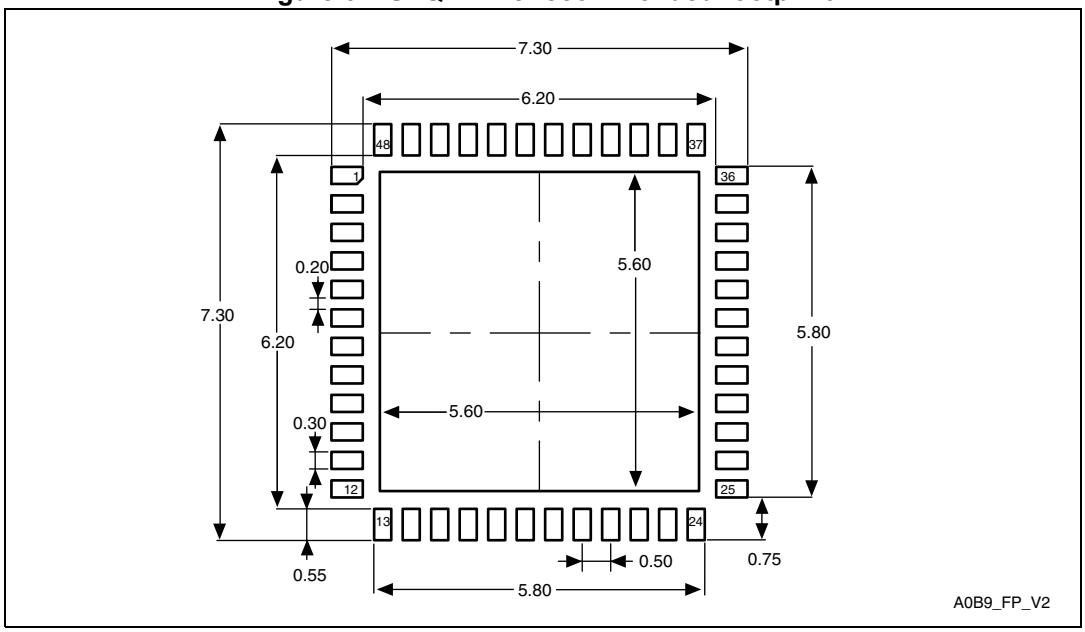
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**Table 101. UFQFPN48 - 48-lead, 7x7 mm, 0.5 mm pitch, ultra thin fine pitch quad flat package mechanical data (continued)**

| Symbol | millimeters | | | inches[1] | | |
|---|---|---|---|---|---|---|
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| E2 | 5.500 | 5.600 | 5.700 | 0.2165 | 0.2205 | 0.2244 |
| L | 0.300 | 0.400 | 0.500 | 0.0118 | 0.0157 | 0.0197 |
| T | - | 0.152 | - | - | 0.0060 | - |
| b | 0.200 | 0.250 | 0.300 | 0.0079 | 0.0098 | 0.0118 |
| e | - | 0.500 | - | - | 0.0197 | - |
| ddd | - | - | 0.080 | - | - | 0.0031 |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

**Figure 64. UFQFPN48 recommended footprint**




1. Dimensions are in millimeters.



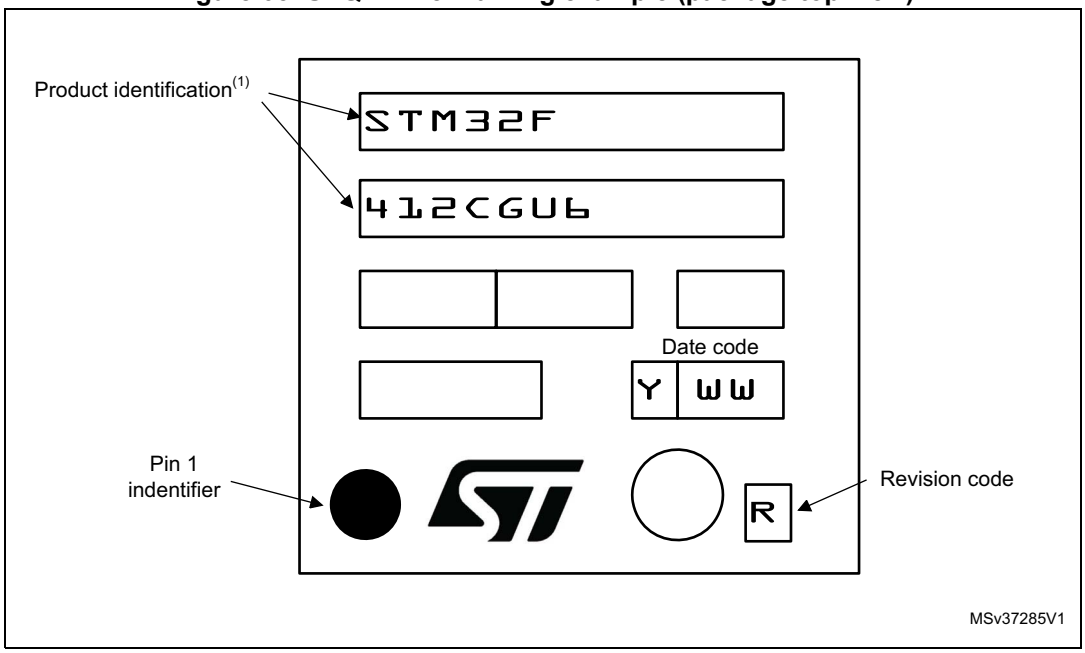
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### Device marking for UFQFPN48

The following figure gives an example of topside marking and pin 1 position identifier location.

Other optional marking or inset/upset marks, which depend on supply chain operations, are not indicated below.

**Figure 65. UFQFPN48 marking example (package top view)**



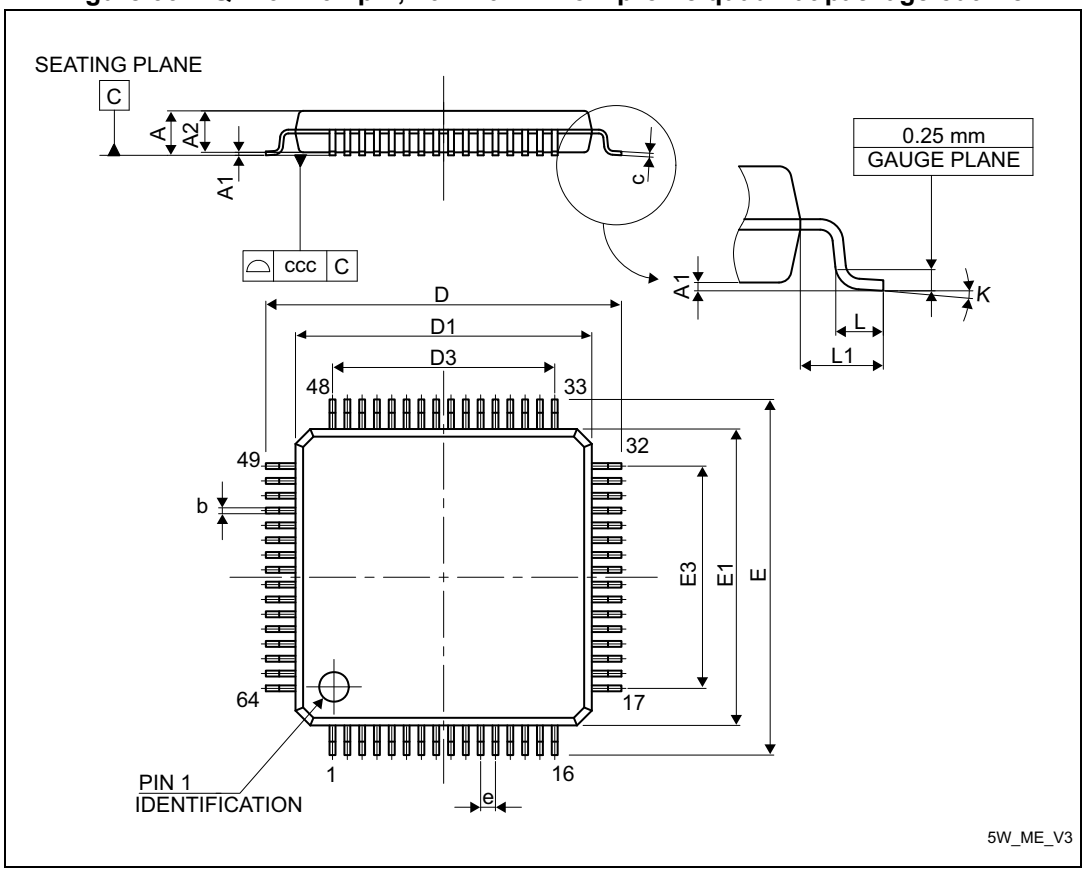

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## 7.3 LQFP64 package information

**Figure 66. LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat package outline**




1. Drawing is not to scale.



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**Table 102. LQFP64 - 64-pin, 10 x 10 mm low-profile quad flat package mechanical data**

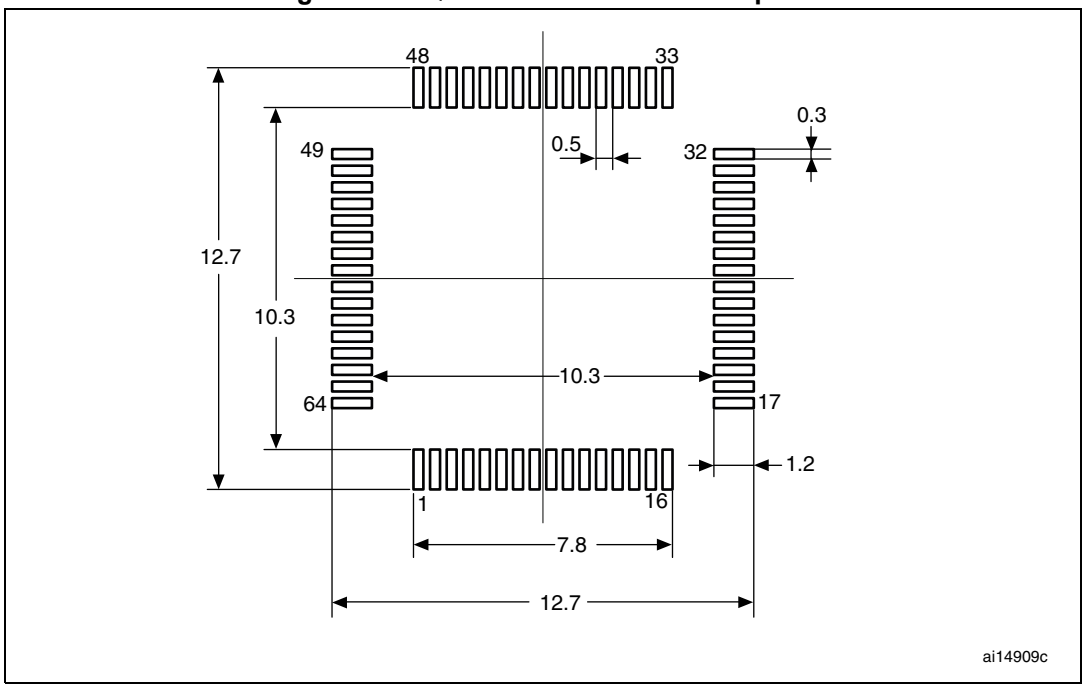
| Symbol | millimeters | | | inches[1] | | |
|---|---|---|---|---|---|---|
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | - | - | 1.600 | - | - | 0.0630 |
| A1 | 0.050 | - | 0.150 | 0.0020 | - | 0.0059 |
| A2 | 1.350 | 1.400 | 1.450 | 0.0531 | 0.0551 | 0.0571 |
| b | 0.170 | 0.220 | 0.270 | 0.0067 | 0.0087 | 0.0106 |
| c | 0.090 | - | 0.200 | 0.0035 | - | 0.0079 |
| D | - | 12.000 | - | - | 0.4724 | - |
| D1 | - | 10.000 | - | - | 0.3937 | - |
| D3 | - | 7.500 | - | - | 0.2953 | - |
| E | - | 12.000 | - | - | 0.4724 | - |
| E1 | - | 10.000 | - | - | 0.3937 | - |
| E3 | - | 7.500 | - | - | 0.2953 | - |
| e | - | 0.500 | - | - | 0.0197 | - |
| K | 0° | 3.5° | 7° | 0° | 3.5° | 7° |
| L | 0.450 | 0.600 | 0.750 | 0.0177 | 0.0236 | 0.0295 |
| L1 | - | 1.000 | - | - | 0.0394 | - |
| ccc | - | - | 0.080 | - | - | 0.0031 |

1. Values in inches are converted from mm and rounded to 4 decimal digits.



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**Figure 67. LQFP64 recommended footprint**




1. Dimensions are in millimeters.



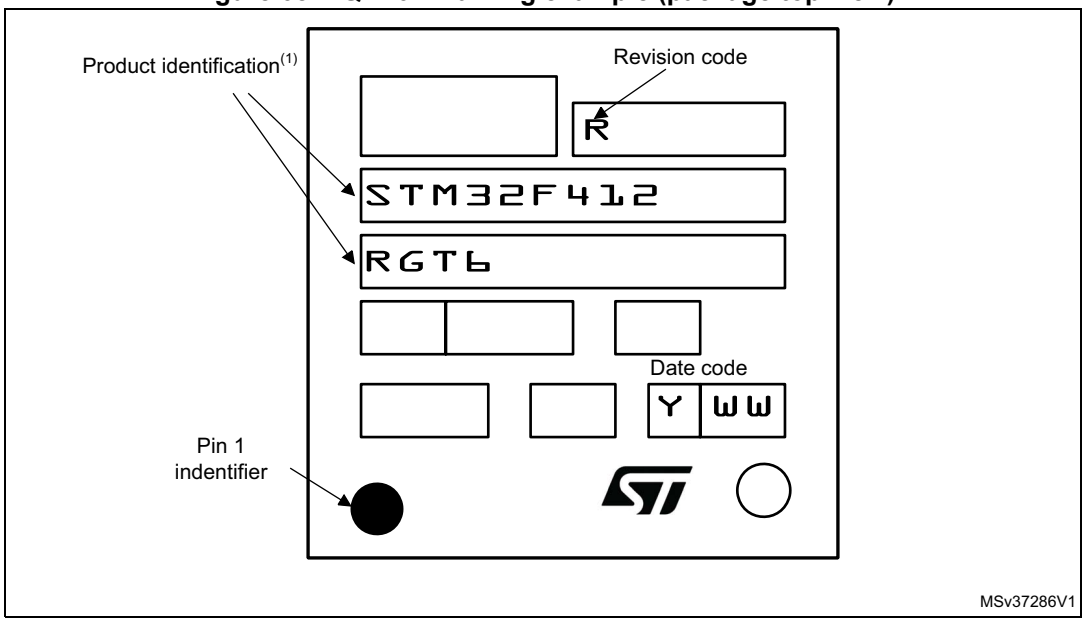
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### Device marking for LQFP64

The following figure gives an example of topside marking and pin 1 position identifier location.

Other optional marking or inset/upset marks, which depend on supply chain operations, are not indicated below.

**Figure 68. LQFP64 marking example (package top view)**



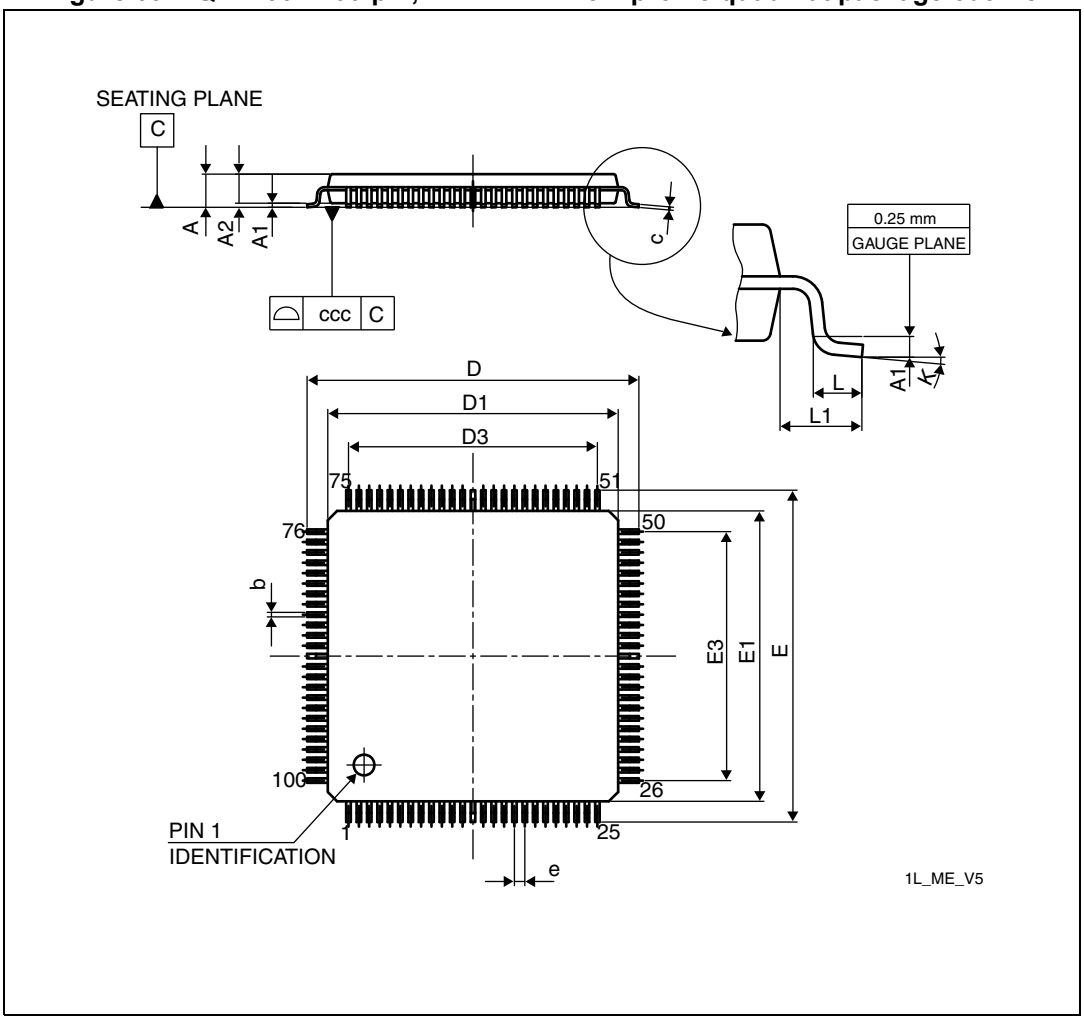

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## 7.4 LQFP100 package information

**Figure 69. LQFP100 - 100-pin, 14 x 14 mm low-profile quad flat package outline**




1. Drawing is not to scale. Dimensions are in millimeters.

**Table 103. LQPF100 - 100-pin, 14 x 14 mm low-profile quad flat package mechanical data**

| Symbol | millimeters | | | inches(1) | | |
|---|---|---|---|---|---|---|
| | Min | Typ | Max | Min | Typ | Max |
| A | - | - | 1.600 | - | - | 0.0630 |
| A1 | 0.050 | - | 0.150 | 0.0020 | - | 0.0059 |
| A2 | 1.350 | 1.400 | 1.450 | 0.0531 | 0.0551 | 0.0571 |
| b | 0.170 | 0.220 | 0.270 | 0.0067 | 0.0087 | 0.0106 |
| c | 0.090 | - | 0.200 | 0.0035 | - | 0.0079 |
| D | 15.800 | 16.000 | 16.200 | 0.6220 | 0.6299 | 0.6378 |
| D1 | 13.800 | 14.000 | 14.200 | 0.5433 | 0.5512 | 0.5591 |



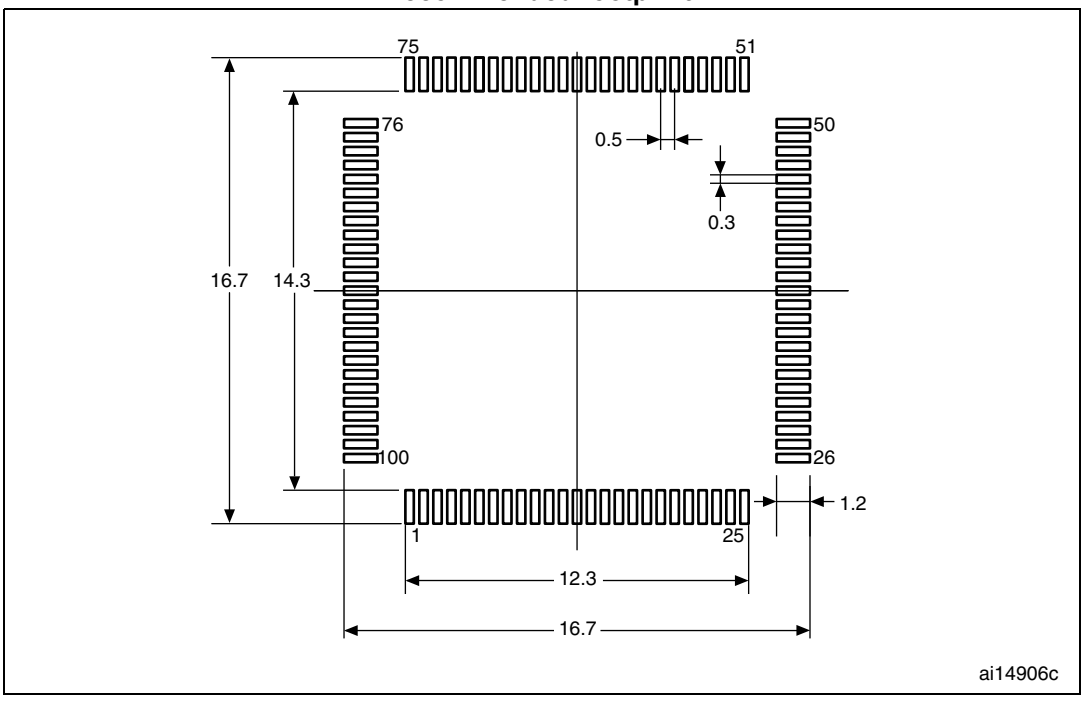
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**Table 103. LQPF100 - 100-pin, 14 x 14 mm low-profile quad flat package mechanical data (continued)**

| Symbol | millimeters | | | inches[1] | | |
|---|---|---|---|---|---|---|
| | Min | Typ | Max | Min | Typ | Max |
| D3 | - | 12.000 | - | - | 0.4724 | - |
| E | 15.800 | 16.000 | 16.200 | 0.6220 | 0.6299 | 0.6378 |
| E1 | 13.800 | 14.000 | 14.200 | 0.5433 | 0.5512 | 0.5591 |
| E3 | - | 12.000 | - | - | 0.4724 | - |
| e | - | 0.500 | - | - | 0.0197 | - |
| L | 0.450 | 0.600 | 0.750 | 0.0177 | 0.0236 | 0.0295 |
| L1 | - | 1.000 | - | - | 0.0394 | - |
| k | 0.0° | 3.5° | 7.0° | 0.0° | 3.5° | 7.0° |
| ccc | - | - | 0.080 | - | - | 0.0031 |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

**Figure 70. LQFP100 - 100-pin, 14 x 14 mm low-profile quad flat recommended footprint**




1. Dimensions are in millimeters.



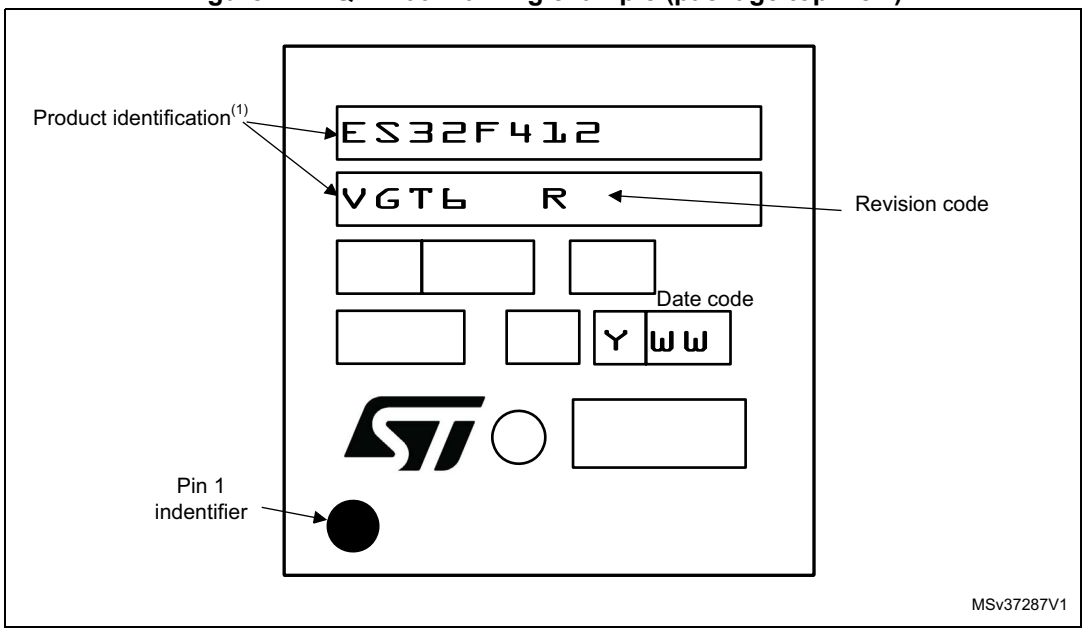
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### Device marking for LQFP100

The following figure gives an example of topside marking and pin 1 position identifier location.

Other optional marking or inset/upset marks, which depend on supply chain operations, are not indicated below.

**Figure 71. LQFP100 marking example (package top view)**



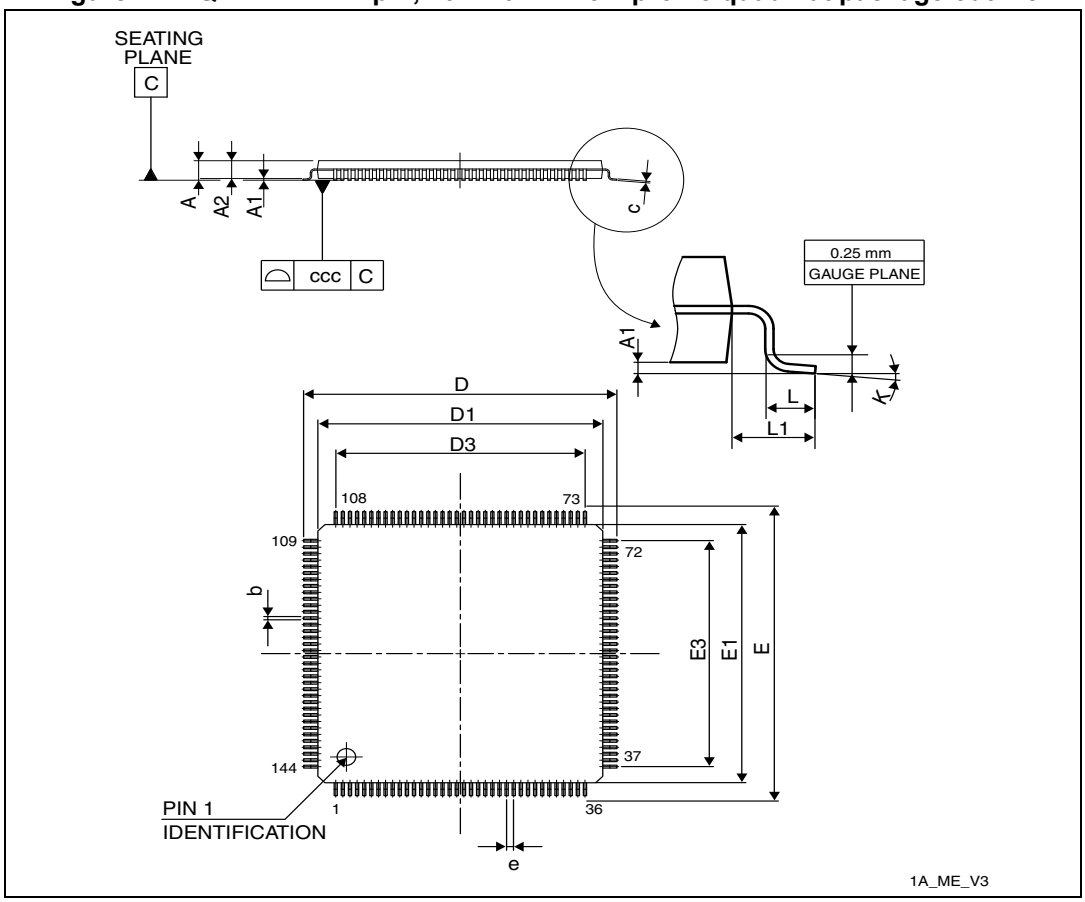

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## 7.5 LQFP144 package information

**Figure 72. LQFP144 - 144-pin, 20 x 20 mm low-profile quad flat package outline**




1. Drawing is not to scale.



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**Table 104. LQFP144 - 144-pin, 20 x 20 mm low-profile quad flat package mechanical data**

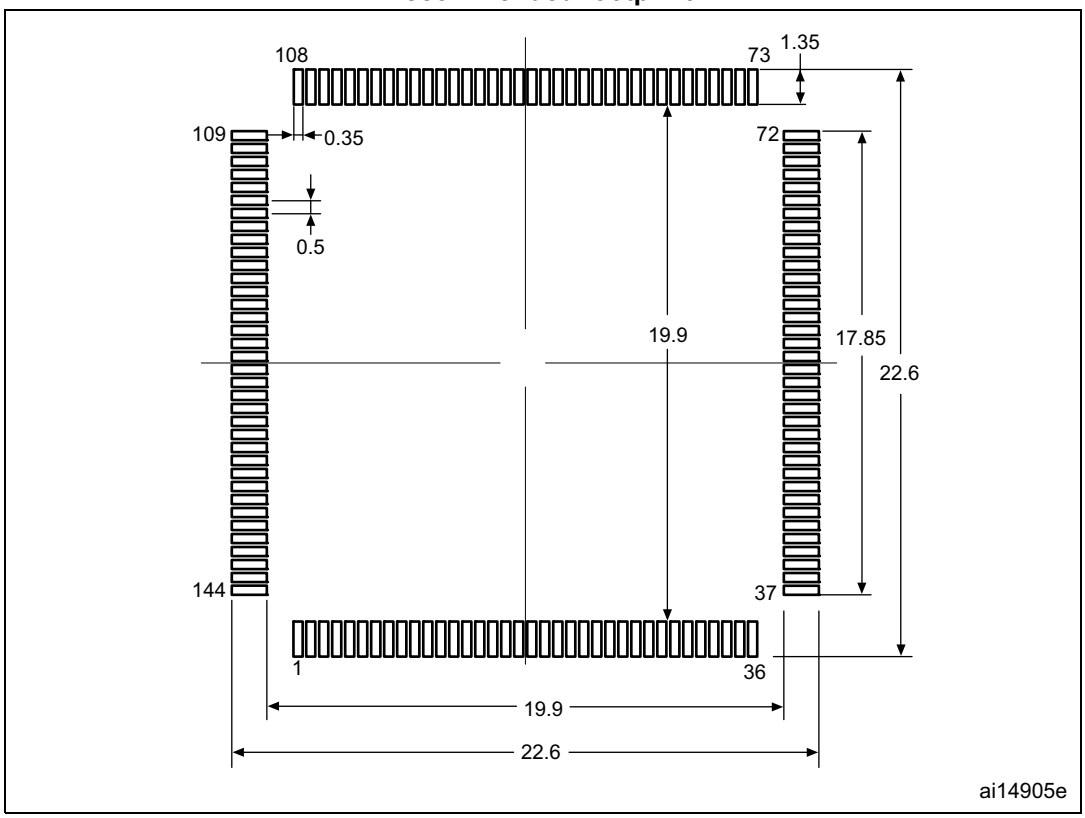
| Symbol | millimeters | | | inches[1] | | |
|---|---|---|---|---|---|---|
| | Min | Typ | Max | Min | Typ | Max |
| A | - | - | 1.600 | - | - | 0.0630 |
| A1 | 0.050 | - | 0.150 | 0.0020 | - | 0.0059 |
| A2 | 1.350 | 1.400 | 1.450 | 0.0531 | 0.0551 | 0.0571 |
| b | 0.170 | 0.220 | 0.270 | 0.0067 | 0.0087 | 0.0106 |
| c | 0.090 | - | 0.200 | 0.0035 | - | 0.0079 |
| D | 21.800 | 22.000 | 22.200 | 0.8583 | 0.8661 | 0.8740 |
| D1 | 19.800 | 20.000 | 20.200 | 0.7795 | 0.7874 | 0.7953 |
| D3 | - | 17.500 | - | - | 0.6890 | - |
| E | 21.800 | 22.000 | 22.200 | 0.8583 | 0.8661 | 0.8740 |
| E1 | 19.800 | 20.000 | 20.200 | 0.7795 | 0.7874 | 0.7953 |
| E3 | - | 17.500 | - | - | 0.6890 | - |
| e | - | 0.500 | - | - | 0.0197 | - |
| L | 0.450 | 0.600 | 0.750 | 0.0177 | 0.0236 | 0.0295 |
| L1 | - | 1.000 | - | - | 0.0394 | - |
| k | 0° | 3.5° | 7° | 0° | 3.5° | 7° |
| ccc | - | - | 0.080 | - | - | 0.0031 |

1. Values in inches are converted from mm and rounded to 4 decimal digits.



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**Figure 73. LQFP144 - 144-pin,20 x 20 mm low-profile quad flat package recommended footprint**




1. Dimensions are expressed in millimeters.



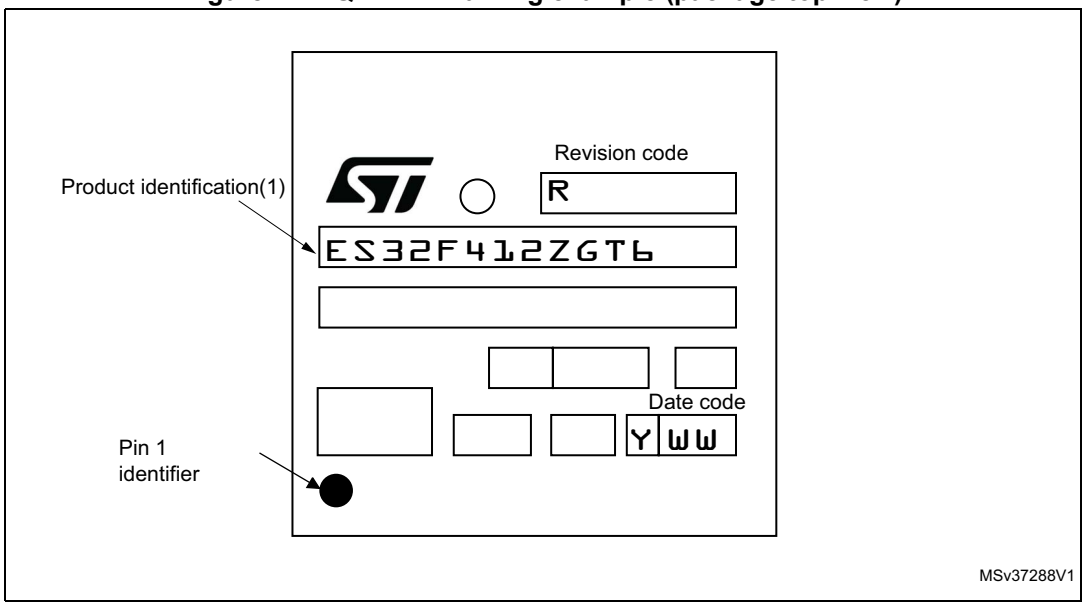
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### Device marking for LQFP144

The following figure gives an example of topside marking and pin 1 position identifier location.

Other optional marking or inset/upset marks, which depend on supply chain operations, are not indicated below.

**Figure 74. LQFP144 marking example (package top view)**



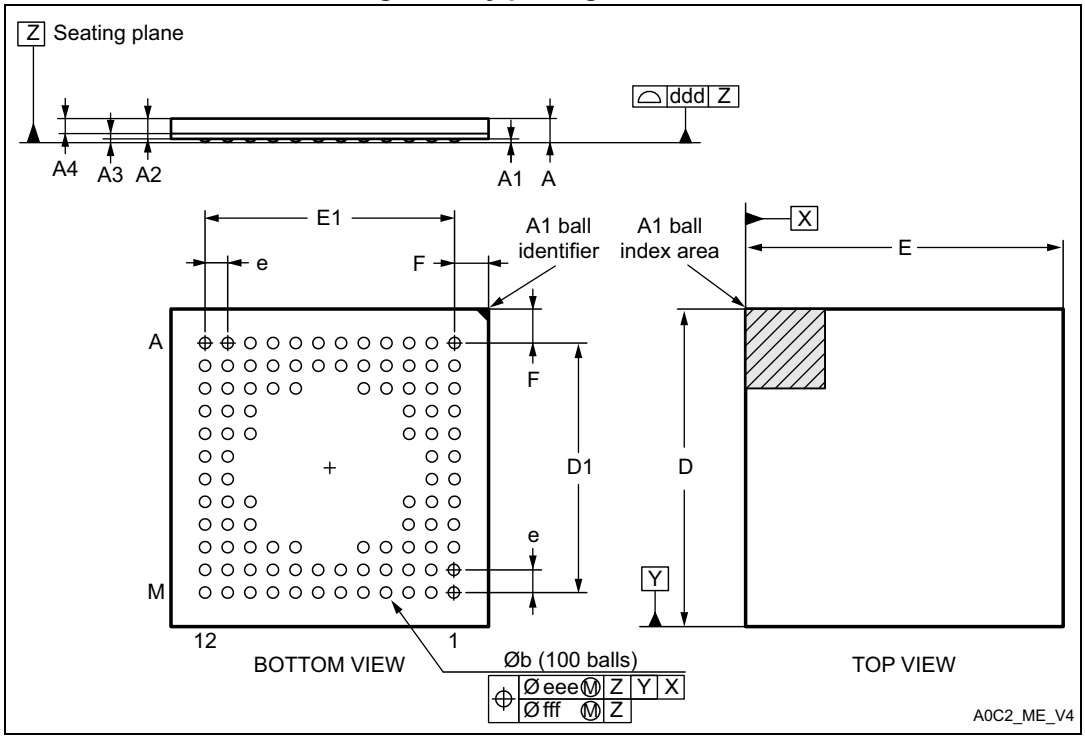

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## 7.6 UFBGA100 package information

**Figure 75. UFBGA100 - 100-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package outline**




1. Drawing is not to scale.

**Table 105. UFBGA100 - 100-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package mechanical data**

| Symbol | millimeters | | | inches(1) | | |
|---|---|---|---|---|---|---|
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 0.460 | 0.530 | 0.600 | 0.0181 | 0.0209 | 0.0236 |
| A1 | 0.050 | 0.080 | 0.110 | 0.0020 | 0.0031 | 0.0043 |
| A2 | 0.400 | 0.450 | 0.500 | 0.0157 | 0.0177 | 0.0197 |
| A3 | - | 0.130 | - | - | 0.0051 | - |
| A4 | 0.270 | 0.320 | 0.370 | 0.0106 | 0.0126 | 0.0146 |
| b | 0.200 | 0.250 | 0.300 | 0.0079 | 0.0098 | 0.0118 |
| D | 6.950 | 7.000 | 7.050 | 0.2736 | 0.2756 | 0.2776 |
| D1 | 5.450 | 5.500 | 5.550 | 0.2146 | 0.2165 | 0.2185 |
| E | 6.950 | 7.000 | 7.050 | 0.2736 | 0.2756 | 0.2776 |
| E1 | 5.450 | 5.500 | 5.550 | 0.2146 | 0.2165 | 0.2185 |
| e | - | 0.500 | - | - | 0.0197 | - |
| F | 0.700 | 0.750 | 0.800 | 0.0276 | 0.0295 | 0.0315 |



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**Table 105. UFBGA100 - 100-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package mechanical data (continued)**

| Symbol | millimeters | | | inches[1] | | |
|---|---|---|---|---|---|---|
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| ddd | - | - | 0.100 | - | - | 0.0039 |
| eee | - | - | 0.150 | - | - | 0.0059 |
| fff | - | - | 0.050 | - | - | 0.0020 |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

**Figure 76. UFBGA100 - 100-pin, 7 x 7 mm, 0.50 mm pitch, ultra fine pitch ball grid array package recommended footprint**

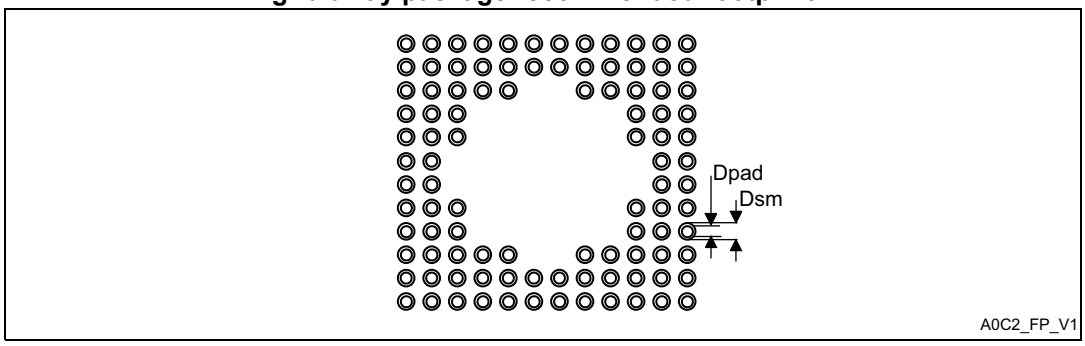



**Table 106. UFBGA100 recommended PCB design rules (0.5 mm pitch BGA)**

| Dimension | Recommended values |
|---|---|
| Pitch | 0.5 |
| Dpad | 0.280 mm |
| Dsm | 0.370 mm typ. (depends on the soldermask registration tolerance) |
| Stencil opening | 0.280 mm |
| Stencil thickness | Between 0.100 mm and 0.125 mm |



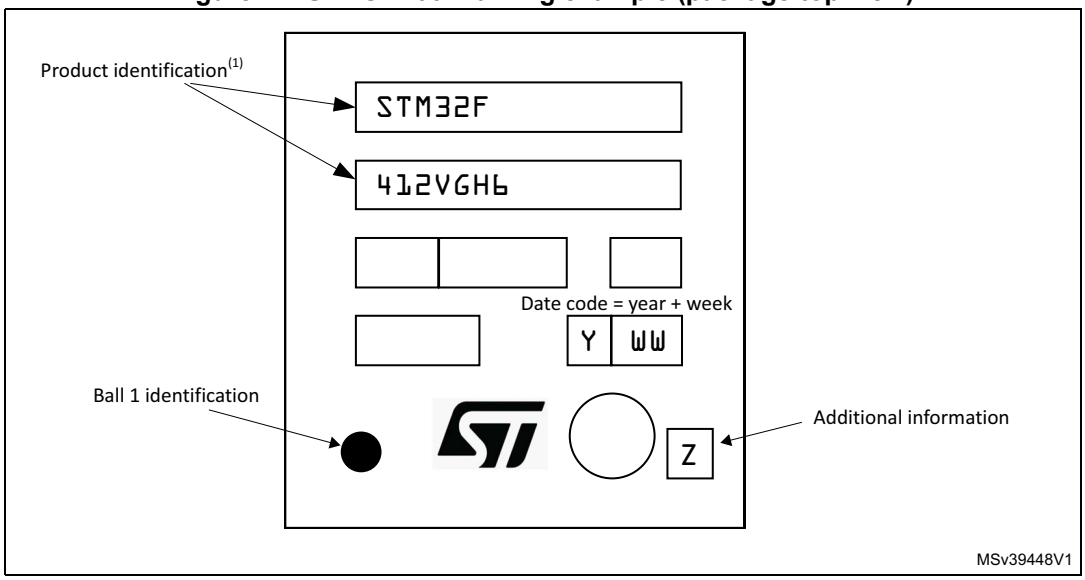
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### Device marking for UFBGA100

The following figure gives an example of topside marking and ball 1 position identifier location.

Other optional marking or inset/upset marks, which depend on supply chain operations, are not indicated below.

**Figure 77. UFBGA100 marking example (package top view)**



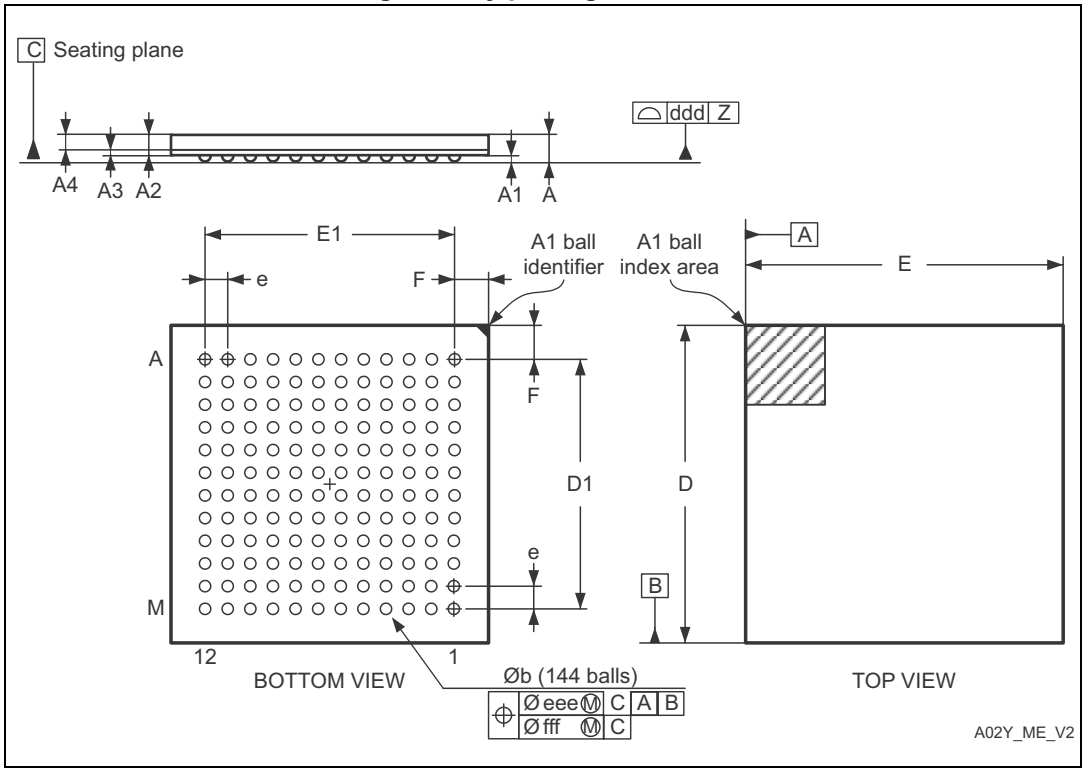

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## 7.7 UFBGA144 package information

**Figure 78. UFBGA144 - 144-pin, 10 x 10 mm, 0.80 mm pitch, ultra fine pitch ball grid array package outline**




1. Drawing is not to scale.

**Table 107. UFBGA144 - 144-pin, 10 x 10 mm, 0.80 mm pitch, ultra fine pitch ball grid array package mechanical data**

| Symbol | millimeters | | | inches(1) | | |
|---|---|---|---|---|---|---|
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 0.460 | 0.530 | 0.600 | 0.0181 | 0.0209 | 0.0236 |
| A1 | 0.050 | 0.080 | 0.110 | 0.0020 | 0.0031 | 0.0043 |
| A2 | 0.400 | 0.450 | 0.500 | 0.0157 | 0.0177 | 0.0197 |
| A3 | - | 0.130 | - | - | 0.0051 | - |
| A4 | - | 0.320 | - | - | 0.0126 | - |
| b | 0.360 | 0.400 | 0.440 | 0.0142 | 0.0157 | 0.0173 |
| D | 9.950 | 10.000 | 10.050 | 0.3917 | 0.3937 | 0.3957 |
| D1 | 8.750 | 8.800 | 8.850 | 0.3445 | 0.3465 | 0.3484 |
| E | 9.950 | 10.000 | 10.050 | 0.3917 | 0.3937 | 0.3957 |
| E1 | 8.750 | 8.800 | 8.850 | 0.3445 | 0.3465 | 0.3484 |
| e | 0.750 | 0.800 | 0.850 | 0.0295 | 0.0315 | 0.0335 |



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**Table 107. UFBGA144 - 144-pin, 10 x 10 mm, 0.80 mm pitch, ultra fine pitch ball grid array package mechanical data (continued)**

| Symbol | millimeters | | | inches[1] | | |
|---|---|---|---|---|---|---|
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| F | 0.550 | 0.600 | 0.650 | 0.0217 | 0.0236 | 0.0256 |
| ddd | - | - | 0.080 | - | - | 0.0031 |
| eee | - | - | 0.150 | - | - | 0.0059 |
| fff | - | - | 0.080 | - | - | 0.0031 |

1. Values in inches are converted from mm and rounded to 4 decimal digits.

**Figure 79. UFBGA144 - 144-pin, 10 x 10 mm, 0.80 mm pitch, ultra fine pitch ball grid array recommended footprint**

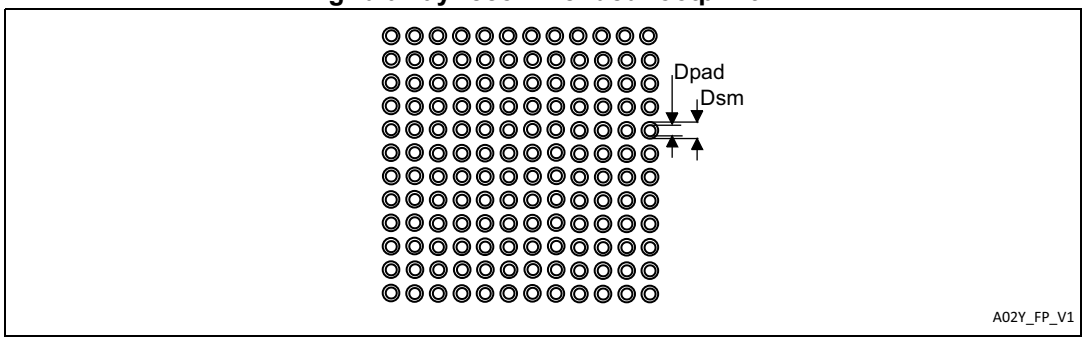



**Table 108. UFBGA144 recommended PCB design rules (0.80 mm pitch BGA)**

| Dimension | Recommended values |
|---|---|
| Pitch | 0.80 mm |
| Dpad | 0.400 mm |
| Dsm | 0.550 mm typ. (depends on the soldermask registration tolerance) |

*Note: Non solder mask defined (NSMD) pads are recommended.*

*4 to 6 mils solder paste screen printing process.*

*Stencil opening is 0.400 mm.*

*Stencil thickness is between 0.100 mm and 0.125 mm.*

*Pad trace width is 0.120 mm.*



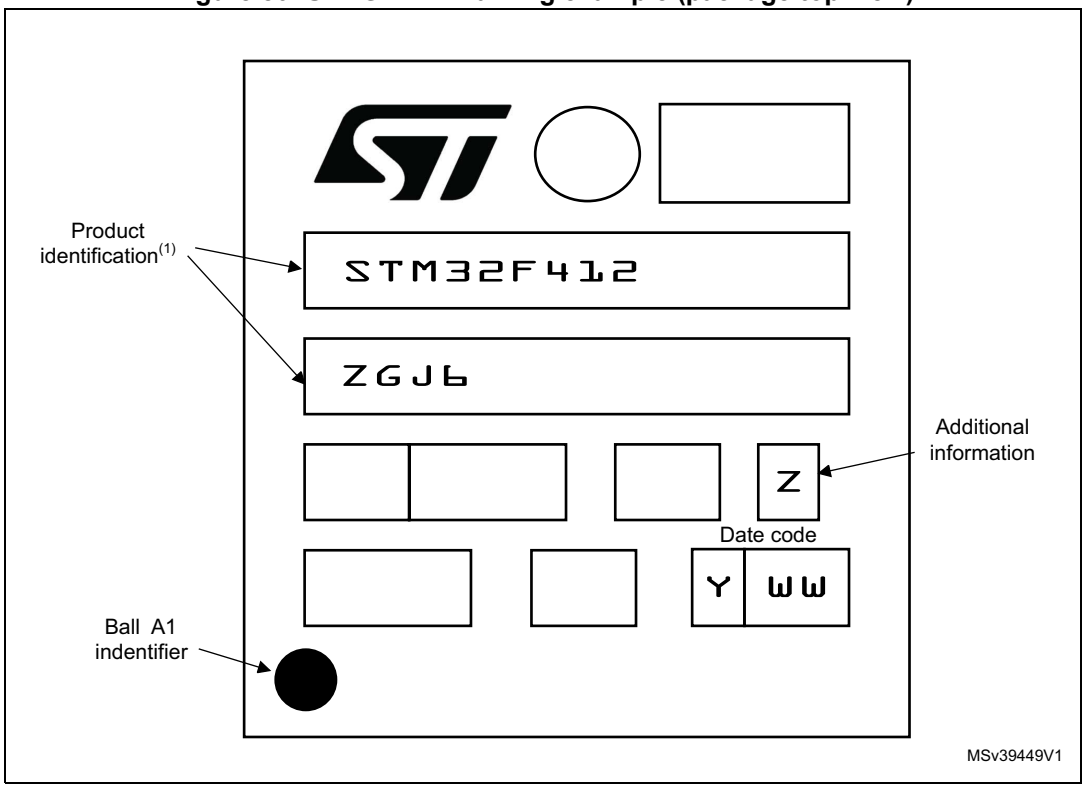
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### Device marking for UFBGA144

The following figure gives an example of topside marking and ball A1 position identifier location.

Other optional marking or inset/upset marks, which depend on supply chain operations, are not indicated below.

**Figure 80. UFBGA144 marking example (package top view)**




1. Parts marked as “ES” or “E” or accompanied by an Engineering Sample notification letter are not yet qualified and therefore not approved for use in production. ST is not responsible for any consequences resulting from such use. In no event will ST be liable for the customer using any of these engineering samples in production. ST’s Quality department must be contacted prior to any decision to use these engineering samples to run a qualification activity.



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## 7.8 Thermal characteristics

The maximum chip junction temperature ($T_J$max) must never exceed the values given in *Table 16: General operating conditions on page 82*.

The maximum chip-junction temperature, $T_J$ max., in degrees Celsius, may be calculated using the following equation:

$T_J$ max = $T_A$ max + (PD max x $\Theta_{JA}$)

Where:

- $T_A$ max is the maximum ambient temperature in °C,
- $\Theta_{JA}$ is the package junction-to-ambient thermal resistance, in °C/W,
- PD max is the sum of $P_{INT}$ max and $P_{I/O}$ max (PD max = $P_{INT}$ max + $P_{I/O}$max),
- $P_{INT}$ max is the product of $I_{DD}$ and $V_{DD}$, expressed in Watts. This is the maximum chip internal power.

$P_{I/O}$ max represents the maximum power dissipation on output pins where:

$$P_{I/O} \text{ max} = \Sigma (V_{OL} \times I_{OL}) + \Sigma((V_{DD} - V_{OH}) \times I_{OH}),$$

taking into account the actual $V_{OL}$ / $I_{OL}$ and $V_{OH}$ / $I_{OH}$ of the I/Os at low and high level in the application.

**Table 109. Package thermal characteristics**

| Symbol | Parameter | Value | Unit |
|---|---|---|---|
| $\Theta_{JA}$ | **Thermal resistance junction-ambient** LQFP144 - 20 x 20 mm | 35 | °C/W |
| | **Thermal resistance junction-ambient** LQFP100 - 14 x 14 mm | 43 | |
| | **Thermal resistance junction-ambient** LQFP64 - 10 x 10 mm | 47 | |
| | **Thermal resistance junction-ambient** UFBGA144 - 10 x 10 mm / 0.8 mm pitch | 48 | |
| | **Thermal resistance junction-ambient** UFBGA100 - 7 x 7 mm | 57 | |
| | **Thermal resistance junction-ambient** WLCSP64 - 3.623 x 3.651 mm | 51 | |
| | **Thermal resistance junction-ambient** UFQFPN48 - 7 x 7 mm | 32 | |

### 7.8.1 Reference document

JESD51-2 Integrated Circuits Thermal Test Method Environment Conditions - Natural Convection (Still Air). Available from www.jedec.org.



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# 8 Part numbering

**Table 110. Ordering information scheme**

Example: STM32 F 412 C E T 6 P TR

**Device family**

STM32 = Arm®-based 32-bit microcontroller

**Product type**

F = General-purpose

**Device subfamily**

412 = 412 line

**Pin count**

C = 48 pins

R = 64 pins

V = 100 pins

Z = 144 pins

**Flash memory size**

E = 512 Kbytes of Flash memory

G = 1024 Kbytes of Flash memory

**Package**

H = UFBGA 7 x 7 mm

J = UFBGA 10 x 10 mm

T = LQFP

U = UFQFPN

Y = WLCSP

**Temperature range**

6 = Industrial temperature range, -40 to 85 °C

7 = Industrial temperature range, -40 to 105 °C

3 = Industrial temperature range, -40 to 125°C

**Option**

Blank = Standard production

P = Internal regulator disabled

Packing

TR = tape and reel

No character = tray or tube



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# Appendix A Recommendations when using the internal reset OFF

When the internal reset is OFF, the following integrated features are no longer supported:

- The integrated power-on-reset (POR)/power-down reset (PDR) circuitry is disabled.
- The brownout reset (BOR) circuitry must be disabled. By default BOR is OFF.
- The embedded programmable voltage detector (PVD) is disabled.
- $V_{BAT}$ functionality is no more available and VBAT pin should be connected to $V_{DD}$.

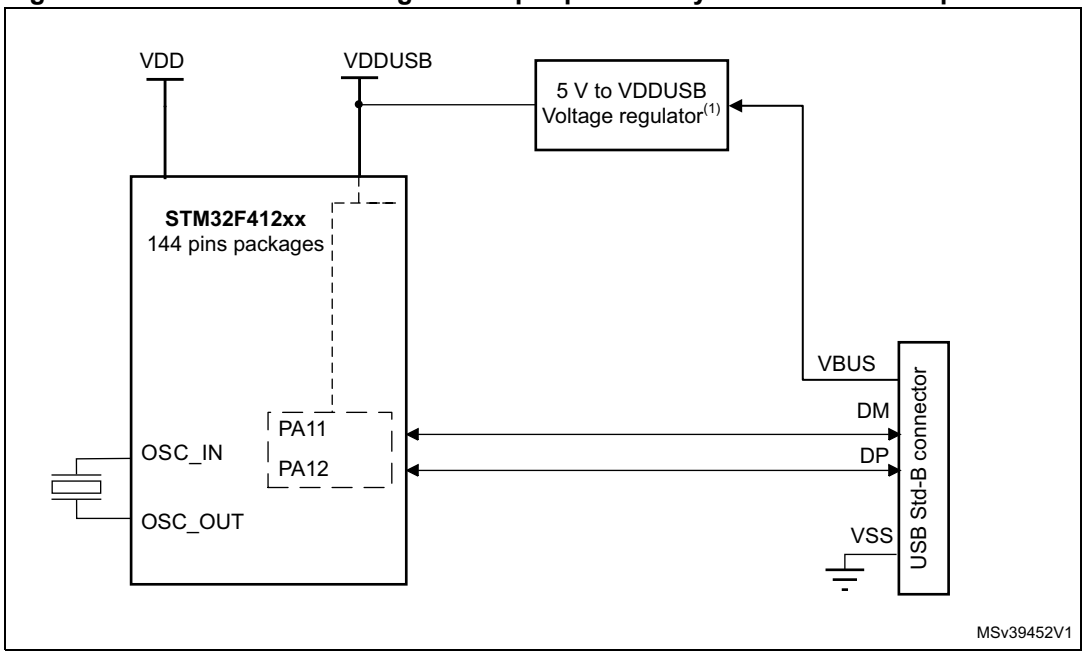


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# Appendix B Application block diagrams

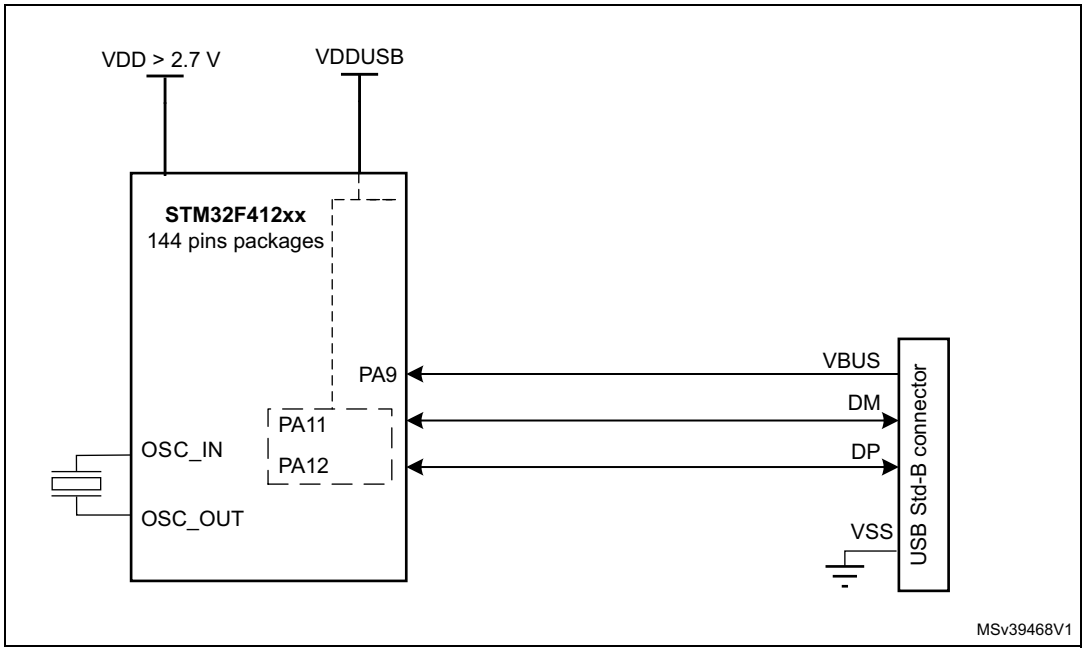
## B.1 USB OTG full speed (FS) interface solutions

**Figure 81. USB controller configured as peripheral-only and used in Full speed mode**




1. External voltage regulator only needed when building a $V_{BUS}$ powered device.

**Figure 82. USB peripheral-only Full speed mode with direct connection for VBUS sense**

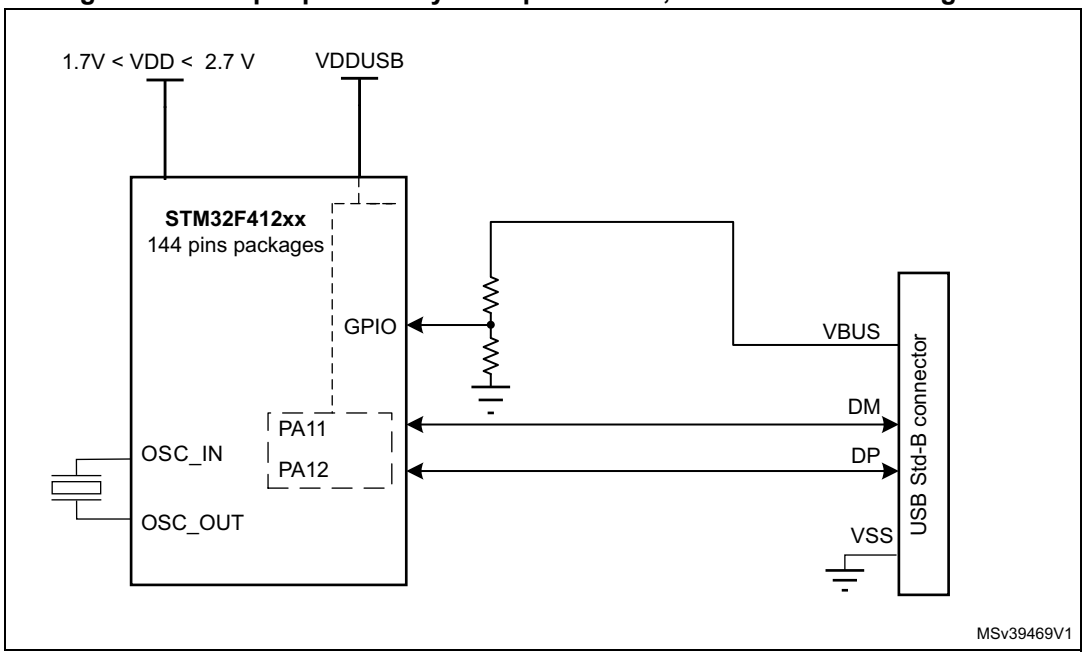



1. External voltage regulator only needed when building a $V_{BUS}$ powered device.



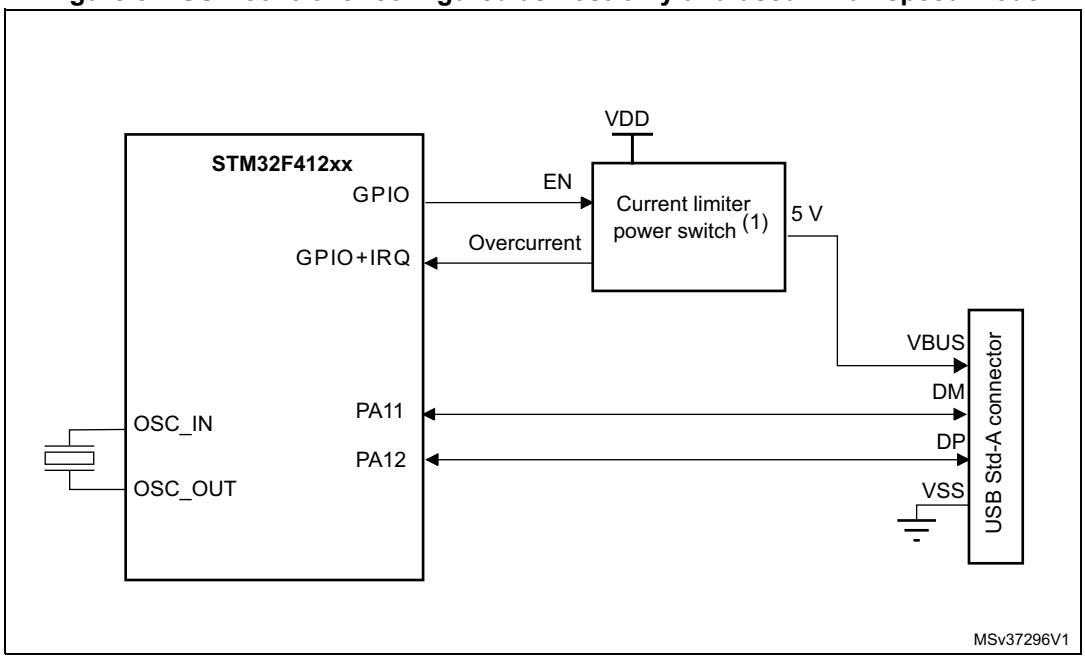
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**Figure 83. USB peripheral-only Full speed mode, VBUS detection using GPIO**




1. External voltage regulator only needed when building a $V_{BUS}$ powered device.

**Figure 84. USB controller configured as host-only and used in full speed mode**

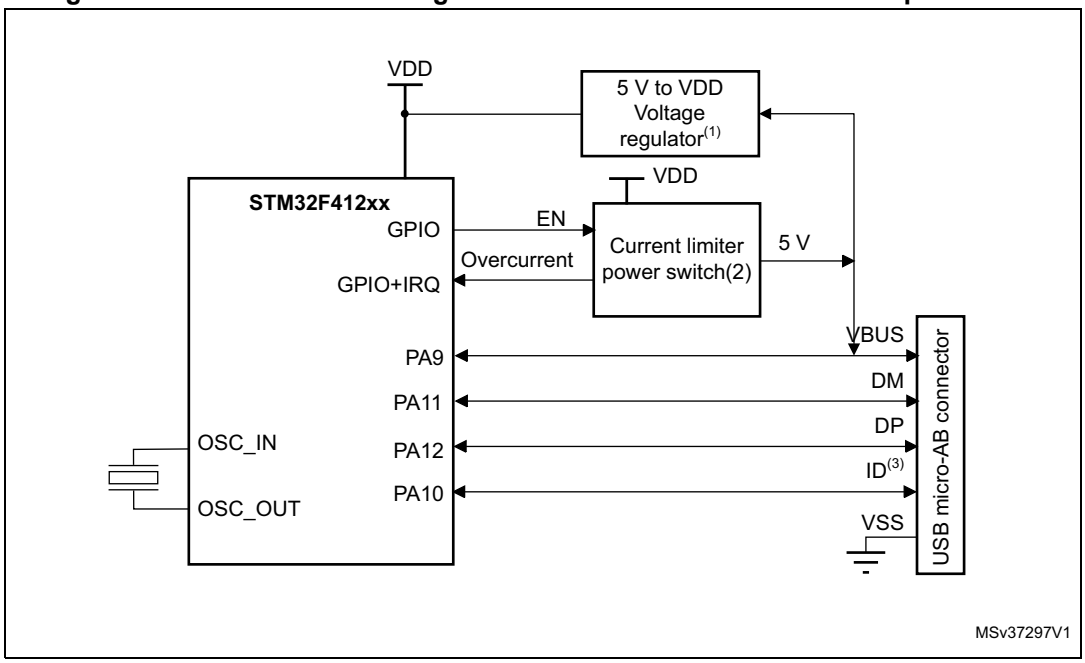



1. The current limiter is required only if the application has to support a $V_{BUS}$ powered device. A basic power switch can be used if 5 V are available on the application board.



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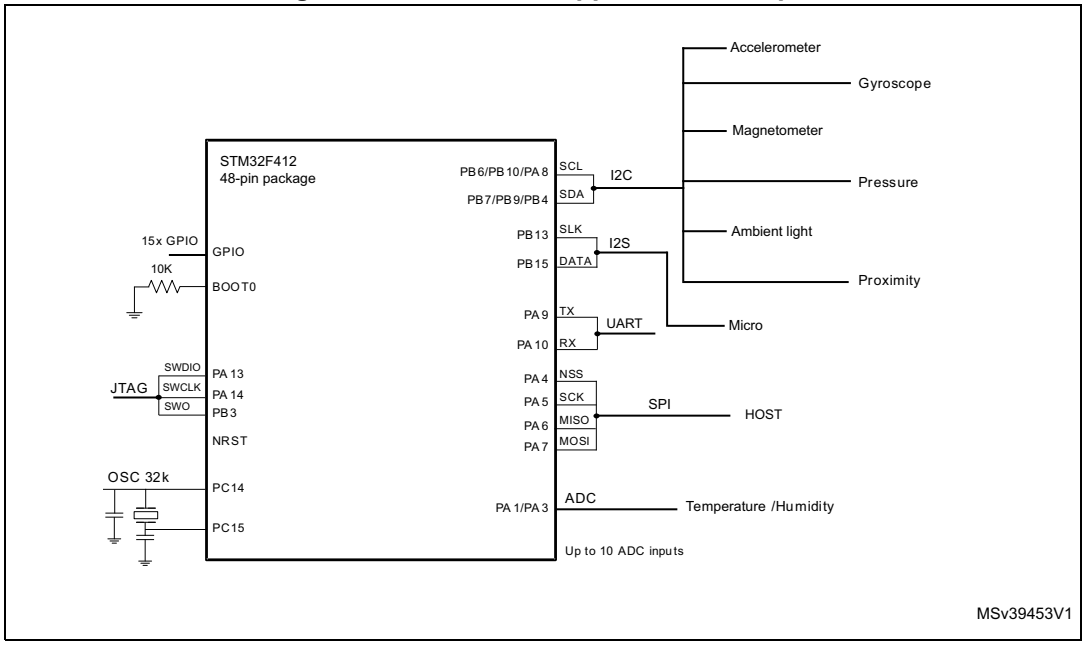
**Figure 85. USB controller configured in dual mode and used in full speed mode**




1. External voltage regulator only needed when building a $V_{BUS}$ powered device.
2. The current limiter is required only if the application has to support a $V_{BUS}$ powered device. A basic power switch can be used if 5 V are available on the application board.
3. The ID pin is required in dual role only.

## B.2 Sensor Hub application example

**Figure 86. Sensor Hub application example**

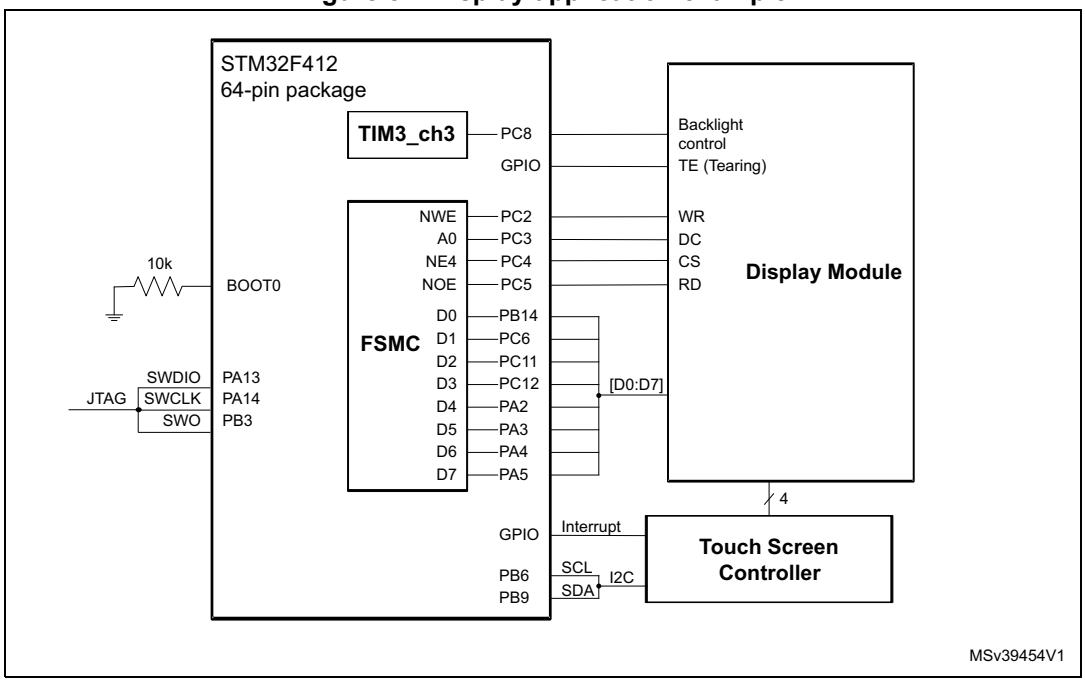





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## B.3 Display application example

**Figure 87. Display application example**




*Note: 16 bit displays interfaces can be addressed with 100 and 144 pins packages.*



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# Revision history

**Table 111. Document revision history**

| Date | Revision | Changes |
|---|---|---|
| 10-Nov-2015 | 1 | Initial release. |
| 01-Feb-2016 | 2 | Added:<br>– *Table 3: Embedded bootloader interfaces*<br>– *Figure 3: Compatible board design for LQFP144 package*<br>– *Figure 62: WLCSP64 marking example (package top view)*<br>– *Figure 77: UFBGA100 marking example (package top view)*<br>Updated:<br>– *Section 3.17: Power supply schemes*<br>– *Section 3.23: Timers and watchdogs*<br>– *Section 3.32: Universal serial bus on-the-go full-speed (USB_OTG_FS)*<br>– *Figure 1: Compatible board design for LQFP100 package*<br>– *Figure 2: Compatible board design for LQFP64 package*<br>– *Figure 14: STM32F412xE/G LQFP100 pinout*<br>– *Figure 16: STM32F412xE/G UFBGA100 pinout*<br>– *Figure 17: STM32F412xE/G UFBGA144 pinout*<br>– *Figure 20: Input voltage measurement*<br>– *Figure 80: UFBGA144 marking example (package top view)*<br>– *Table 2: STM32F412xE/G features and peripheral counts*<br>– *Table 9: STM32F412xE/G pin definition*<br>– *Table 13: Voltage characteristics*<br>– *Table 14: Current characteristics*<br>– *Table 16: General operating conditions*<br>– *Table 37: Peripheral current consumption*<br>– *Table 52: EMS characteristics for LQFP144 package*<br>– *Table 64: FMPI$^2$C characteristics* |
| 25-Mar-2016 | 3 | Added:<br>– *Figure 82: USB peripheral-only Full speed mode with direct connection for VBUS sense*<br>– *Figure 83: USB peripheral-only Full speed mode, VBUS detection using GPIO*<br>Updated:<br>– *Figure 15: STM32F412xE/G LQFP144 pinout*<br>– *Section 6.3.6: Supply current characteristics*<br>– *Table 9: STM32F412xE/G pin definition*<br>– *Table 11: STM32F412xE/G alternate functions*<br>– *Table 12: STM32F412xE/G register boundary addresses*<br>– *Table 16: General operating conditions*<br>– *Table 37: Peripheral current consumption*<br>– *Table 97: Dynamic characteristics: eMMC characteristics VDD = 1.7 V to 1.9 V* |



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**Table 111. Document revision history**

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|---|---|---|
| 27-May-2016 | 4 | Updated:<br>– *Section 3.23.2: General-purpose timers (TIMx)*<br>– *Table 22: Typical and maximum current consumption, code with data processing (ART accelerator disabled) running from SRAM - $V_{DD}$ = 1.7 V*<br>– *Table 23: Typical and maximum current consumption, code with data processing (ART accelerator disabled) running from SRAM - $V_{DD}$ = 3.6 V*<br>– *Table 24: Typical and maximum current consumption in run mode, code with data processing (ART accelerator enabled except prefetch) running from Flash memory- $V_{DD}$ = 1.7 V*<br>– *Table 25: Typical and maximum current consumption in run mode, code with data processing (ART accelerator enabled except prefetch) running from Flash memory - $V_{DD}$ = 3.6 V*<br>– *Table 26: Typical and maximum current consumption in run mode, code with data processing (ART accelerator disabled) running from Flash memory - $V_{DD}$ = 3.6 V*<br>– *Table 27: Typical and maximum current consumption in run mode, code with data processing (ART accelerator disabled) running from Flash memory - $V_{DD}$ = 1.7 V*<br>– *Table 28: Typical and maximum current consumption in run mode, code with data processing (ART accelerator enabled with prefetch) running from Flash memory - $V_{DD}$ = 3.6 V*<br>– *Table 29: Typical and maximum current consumption in Sleep mode - $V_{DD}$ = 3.6 V*<br>– *Table 30: Typical and maximum current consumption in Sleep mode - $V_{DD}$ = 1.7 V*<br>– *Table 38: Low-power mode wakeup timings(1)*<br>– *Figure 38: $I^2C$ bus AC waveforms and measurement circuit*<br>– *Figure 39: FMP$I^2C$ timing diagram and measurement circuit* |



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**Table 111. Document revision history**

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|---|---|---|
| 23-May-2017 | 5 | Updated:<br>– *Section 2: Description*<br>– *Table 2: STM32F412xE/G features and peripheral counts*<br>– *Section 3.19.1: Regulator ON*<br>– *Section 3.19.2: Regulator OFF*<br>– *Table 4: Regulator ON/OFF and internal power supply supervisor availability*<br>– *Table 15: Thermal characteristics*<br>– *Table 16: General operating conditions*<br>– *Table 21: Embedded reset and power control block characteristics*<br>– Table from: *Table 22: Typical and maximum current consumption, code with data processing (ART accelerator disabled) running from SRAM - $V_{DD}$ = 1.7 V* to *Table 35: Typical and maximum current consumptions in $V_{BAT}$ mode*<br>– *Figure 24: Typical $V_{BAT}$ current consumption (LSE and RTC ON/LSE oscillator "low power" mode selection)*<br>– *Figure 25: Typical $V_{BAT}$ current consumption (LSE and RTC ON/LSE oscillator "high drive" mode selection)*<br>– *Table 43: HSI oscillator characteristics*<br>– *Table 44: LSI oscillator characteristics*<br>– *Table 51: Flash memory endurance and data retention*<br>– *Table 55: Electrical sensitivities*<br>– *Table 57: I/O static characteristics*<br>– *Table 88: Asynchronous multiplexed PSRAM/NOR read timings*<br>– Note *1.* in *Figure 62: WLCSP64 marking example (package top view)*<br>– Note *1.* in *Figure 65: UFQFPN48 marking example (package top view)*<br>– Note *1.* in *Figure 68: LQFP64 marking example (package top view)*<br>– Note *1.* in *Figure 71: LQFP100 marking example (package top view)*<br>– Note *1.* in *Figure 74: LQFP144 marking example (package top view)*<br>– Note *1.* in *Figure 77: UFBGA100 marking example (package top view)*<br>– Note *1.* in *Figure 80: UFBGA144 marking example (package top view)*<br>– *Table 110: Ordering information scheme* |



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**Table 111. Document revision history**

| Date | Revision | Changes |
|---|---|---|
| 13-Jul-2017 | 6 | Updated:<br>– *Table 2: STM32F412xE/G features and peripheral counts*<br>– *Table 7: USART feature comparison*<br>– *Table 9: STM32F412xE/G pin definition*<br>– *Section 3.29: Digital filter for sigma-delta modulators (DFSDM)*<br>– *Table 107: UFBGA144 - 144-pin, 10 x 10 mm, 0.80 mm pitch, ultra fine pitch ball grid array package mechanical data*<br>Added:<br>– *Section 4.1: WLSCP64 pinout description*<br>– *Section 4.2: UFQFPN48 pinout description*<br>– *Section 4.3: LQFP64 pinout description*<br>– *Section 4.4: LQFP100 pinout description*<br>– *Section 4.5: LQFP144 pinout description*<br>– *Section 4.6: UFBGA100 pinout description*<br>– *Section 4.7: UFBGA144 pinout description*<br>– *Section 4.8: Pin definition*<br>– *Table 10: FSMC pin definition* |
| 19-Dec-2017 | 7 | Updated:<br>– *Table 23: Typical and maximum current consumption, code with data processing (ART accelerator disabled) running from SRAM - $V_{DD}$ = 3.6 V*<br>– *Table 23: Typical and maximum current consumption, code with data processing (ART accelerator disabled) running from SRAM - $V_{DD}$ = 3.6 V*<br>– *Table 32: Typical and maximum current consumption in Stop mode - $V_{DD}$=3.6 V*<br>– *Table 34: Typical and maximum current consumption in Standby mode - $V_{DD}$= 3.6 V* |



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